

### SERVICE MANUAL

# SPECTRUM ANALYZER MS2601A/J

		• ,	
			i.

## SERVICE MANUAL SPECTRUM ANALYZER MS2601A/J



#### ANRITRU CORPORATION

Applicable Serial Nos. start from M04160 1989.10 Ver. I Printed in Japan 1990.02 x 100 N-9(Y)

#### CERTIFICATION

ANRITSU CORPORATION certifies that this instrument has been thoroughly tested and inspected, and found to meet published specifications prior to shipping.

Anritsu further certifies that its calibration measurements are based on the Japanese Electrotechnical Laboratory and Radio Research Laboratory standards.

#### WARRANTY

All parts of this product are warranted by Anritsu Corporation of Japan against defects in material or workmanship for a period of one year from the date of delivery. In the event of a defect occurring during the warranty period, Anritsu Corporation will repair or replace this product within a reasonable period of time after notification, free-of-charge, provided that: it is returned to Anritsu; has not been misused; has not been damaged by an act of God; and that the user has followed the instructions in the operation manual.

Any unauthorized modification, repair, or attempt to repair, will render this warranty void.

This warranty is effective only for the original purchaser of this product and is not transferable if it is resold.

ALL OTHER EXPRESSED WARRANTIES ARE DISCLAIMED AND ALL IMPLIED WARRANTIES FOR THIS PRODUCT, INCLUDING THE WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE, ARE LIMITED IN DURATION TO A PERIOD OF ONE YEAR FROM THE DATE OF DELIVERY. IN NO EVENT SHALL ANRITSU CORPORATION BE LIABLE TO THE CUSTOMER FOR ANY DAMAGES, INCLUDING LOST PROFITS, OR OTHER INCIDENTAL OR CONSEQUENTIAL DAMAGES, ARISING OUT OF THE USE OR INABILITY TO USE THIS PRODUCT.

All requests for repair or replacement under this warranty must be made as soon as possible after the defect has been noticed and must be directed to Anritsu Corporation or its representative in your area.

Copyright © 1988 by ANRITSU CORPORATION Printed in Japan. All rights reserved. No part of this manual may be reproduced in any form without written permission of ANRITSU CORPORATION.

#### Note 1:

1. The instrument is operable on a nominal voltage of 85 to 140 Vac or 170 to 250 Vac by changing the connections on the power transformer taps. (\$ee the Z4 REGULATOR circuit diagram 27.)

The voltage and current ratings are indicated on the rear panel when the instrument is shipped from the factory.

To operate on the other voltage, change the connections on the power supply transformer. The plate on the rear panel indicating the voltage and current ratings should be changed to the appropriate one. Order the plate from ANRITSU CORP. if needed.

- 2. In this manual, the power supply voltage and current ratings are represented by \*\*Vac and \*\*\*A, respectively.
- 3. The relationship between power supply voltage and current rating is shown below.

**Vac				***A	
85	to	140	٧	3.15 A	
170	to	250	v	1.6 A	

#### Note 2:

WARNINGS, CAUTIONS, Notes, and Explanatory footnotes are used in this manual. Their meanings are given below:

WARNING: WARNING is used when there is a personal injury hazard.

CAUTION: CAUTION is used when the equipment may be damaged.

Note: Note is used to provide information about exceptions, corrections, and restrictions.

#### Explanatory footnote:

Explanatory footnotes provide comments on the same page as the text, figure or table. They are referenced by either an asterisk (\*) or by combination of an asterisk and numeral.

## HISTORY OF MODIFICATIONS (MS2601A/J Ser.)

	(115200	IA/J Ser.)	
ITEM	DESC	Applicable	
11111	Before Modification	After Modification	Applicable Serial No.
P.3-19	MS2601A Circuit Diagram		
	33w29909 1/1	33W29909 1/1 M-1	
			From M04160
			H =
•			
		·	
	\		

#### TABLE OF CONTENTS

		Page
SECTION 1	GENERAL	1-1
SECTION 2	MECHANICAL ASSEMBLY	
2.1	Introduction	2-1
2.2	Cabinet Disassembly	2-1
2.3	Front Panel Removal	2-3
2.4	Main Unit Removal (A2, A3, A4, A6, A8, and A10)	2-4
2.5	Rear Panel Removal	2-5
2.6	A7 REF OSC Unit Removal	2-6
2.7	Z3 CRT Unit and Z4 REGULATOR Unit Removal	2-6
2.8	Z1 YTO Removal	2-8
2.9	Al RF/PLL BLOCK Disassembly	2-8
2.10	Options and Panel Displays	2-8
SECTION 3	TROUBLESHOOTING AND ADJUSTMENT	
3.1	Introduction	3-1
3.1.1	Composition	3-1
3.1.2	Checking and Replacement of Parts	3-4
3.2	Overall Troubleshooting 1	3-7
3.2.1	Overall circuit description	3-7
3.2.2	Overall troubleshooting	3-9
(1)	Abnormal CRT display	3-9
(2)	Frequency abnormality	3-10

		Page
(3)	Level abnormality	3-12
(4)	Defective front panel key setting	3-14
3.3	Troubleshooting and Adjustment of Each Circuit	3-21
3.3.1	Introduction	3-21
3.3.2	Equipment required for troubleshooting, repair and adjustment	3-21
3.3.3	Z4 REGULATOR 27	3-28
(1)	Circuit description	3-28
(2)	Symptom	3-31
(3)	Troubleshooting	3-31
(4)	Adjustment	3-34
3.3.4	A1 RF/PLL BLOCK 2 to 15	3-39
(1)	Circuit description	3-39
	(a) RF section	3-39
	(b) PLL section (LOCAL section)	3-40
(2)	Symptom and cause	3-45
(3)	Troubleshooting	3-46
	(a) RF section troubleshooting	3-46
	(b) PLL section (LOCAL section) troubleshooting	3-50
(4)	A1 RF/PLL BLOCK Adjustment	3-67
	(a) RF section adjustment	3-67
	(b) PLL section adjustment	3-69

		Page
3.3.5	A2 IF BPF 16	3-123
(1)	Circuit description	3-123
(2)	Symptom and cause	3-131
(3)	Troubleshooting	3-131
(4)	Adjustment	3-137
3.3.6	A3 IF LOG/DET 17	3-163
(1)	Circuit description	3-163
(2)	Symptoms and causes	3-169
(3)	Troubleshooting	3-170
(4)	Adjustment	3-176
3.3.7	A5 FRONT BOARD 18	3-195
(1)	Circuit description	3-195
(2)	Symptom	3-195
(3)	Troubleshooting	3-195
3.3.8	A6 SCAN/YTO DRIVE, Z1 YTO 19	3-205
(1)	Circuit description	3-205
(2)	Symptom and cause	3-209
(3)	Troubleshooting A6 SCAN/YTO DRIVE	3-209
(4)	A6 SCAN/YTO DRIVE Adjustment	3-219

		Page
3.3.9	A7 REF OSC 20	3-237
(1)	Circuit description	3-237
(2)	Symptoms	3-239
(3)	Troubleshooting	3-239
(4)	Adjustment	3-242
3.3.10	A8 MAIN CPU 21	3-247
(1)	Circuit description	3-247
(2)	Symptoms	3-247
(3)	Troubleshooting	3-247
3.3.11	A9 GP-IB <b>22</b>	3-265
(1)	Circuit description	3-265
(2)	Symptom	3-265
(3)	Troubleshooting	3-265
3.3.12	A10 DISP CPU 23	3-271
(1)	Circuit description	3-271
(2)	Symptoms	3-272
(3)	Troubleshooting	3-272
3.3.13	A13 MAIN MOTHERBOARD 24 , A14 SUB	
	MOTHERBOARD 25 , and A15 LED 26	3-287

		Page
3.3.14	A4 PTA BOARD (Option 01, 04) 29	3-307
(1)	Circuit description	3-307
(2)	Symptoms	3-307
(3)	Troubleshooting	3-307
3.3.15	A22 RS-232C BOARD (Option 02) 30	3-325
(1)	Circuit description	3-325
(2)	Symptom	3-325
(3)	Troubleshooting	3-325
SECTION 4	CALIBRATION OF COMPENSATION DATA	
4.1	Frequency Response Calibration	4-1
4.2	CAL Level Calibration	4-6
SECTION 5	REPLACEABLE PARTS	
5.1	Introduction	5-1
5.2	Ordering Information	5-1
5.3	Reading Capacitance and Resistance	5-4
5.4	Semiconductor Makings	5-8
5.5	Parts List	5-9

		•

#### SECTION 1

#### GENERAL

This manual describes how to troubleshoot and adjust the MS2601A/J Spectrum Analyzer. It is composed of the following sections.

#### SECTION 2 MECHANICAL CONFIGURATION

This section describes the mechanical parts and how to disassemble each unit (PCB etc.)

#### SECTION 3 TROUBLESHOOTING AND ADJUSTMENT

This section describes the operation of each circuit, troubleshooting procedures, and adjustment procedures.

#### SECTION 4 CALIBRATION OF COMPENSATION DATA

This section describes how to enter the compensation data for internal characteristics after repair.

#### SECTION 5 REPLACEABLE PARTS

This section includes the parts list and describes how to order replaceable parts.

#### SECTION 2

#### MECHANICAL ASSEMBLY

#### 2.1 Introduction

This section describes the mechanical structure, the position of the internal units, and the procedures for removing these units to disassemble/reassemble the MS2601A/J.

The numbers in Figs. 2-1 to 2-6 indicate the mechanical parts. Tables 2-1 to 2-6 lists the parts with the corresponding numbers.

Figure 2-7 shows the relationship between the options and panel displays.

#### — CAUTION —

When disassembling/reassembling the MS2601A/J, turn off the POWER switch on the front panel and unplug the power supply cord from the ac outlet.

#### 2.2 Cabinet Disassembly

This paragraph describes how to remove the covers with reference to Fig. 2-1.

(1) Top cover removal

Step	Procedure				
1	Remove the two screws #1 at the rear of the top cover.				
2	Slightly lift the back of the top cover 5 and slide it backwards. Separate the top cover from the front frame and lift it off.				

- (2) Right and left side cover removal
  - (a) Left side cover 7 removal

Step	Procedure
1	Use a screwdriver to open the screw covers (parts marked with *1) on each end of the handle at the center of the side covers 7.
2	Remove the handle $9$ and the side cover $7$ by removing the screws $#2$ under the screw covers.
3	Remove four screws #3 at the corners of the side cover 7.

- (b) Right side cover (8) removal

  Remove four screws #4 at the corners of the side cover (8).
- (3) Bottom cover 6 removal

Step	Procedure
1	Remove the two screws $\#5$ at the rear of the bottom cover $\boxed{6}$ .
2	Remove the bottom cover by sliding it until it separates from the frame.

#### 2.3 Front Panel Removal

#### (1) Key top removal

To replace the key tops shown in Fig. 2-2, remove the decorative panel 50 using the following procedures and pull off the key tops by holding them with pliers.

Step	Procedure		
1	Remove the CRT cover (21) by pulling it toward you while lifting the part marked with *2 with both hands. (See Fig. 2-3.)		
2	Remove the top cover (5) as described in paragraph 2.2.		
3	Loosen the screw $\#6$ and remove the knob $2$		
4	Remove two screws $\#7$ at the bottom and two screws $\#8$ at the top and remove both clamps $\boxed{51}$ and $\boxed{52}$ .		

#### (2) Front panel removal

To disassemble the front panel, remove the top cover 5 as described in paragraph 2.2 and follow the procedures described below.

Step	Procedure			
1	Remove two screws #7 at the bottom and two screws at			
	the top by referring to Fig. 2-3 and remove both clamps $(51)$ and $(52)$ .			
2	Remove the W1 connector connected to A5 FRONT BOARD.			

Step	Procedure	
3	Slide the front panel 53 little by little towards	
	you.	

- 2.4 Main Unit Removal (A2, A3, A4, A6, A8, and A10)
  - 1. A2 IF BPF
  - 2. A3 IF LOG/DET
  - 3. A4 PTA (OPT 01)
  - 4. A6 YTO DRIVE/SCAN
  - 5. A8 MAIN CPU and A9 GP-IB or All RS-232C (OPT 02)
  - 6. AlO DISP CPU

To remove the above-mentioned unit, remove the top cover (5) as described in paragraph 2.2 and follow the procedures described below. (See Fig. 2-3)

Step	Procedure	
1	Remove the screw #9 and the clamp (59.	
2	Remove the connectors connected to the unit.	
3	Lift the ejector at both sides of the unit as shown in $*3$ (Fig. 2-3).	
4	Hold the ejector and slide the unit out little by little.	
	Note:	
	Since the unit is under spring tension, some force is required to remove it.	

#### 2.5 Rear Panel Removal

Step	Procedure	
1	Remove the top cover $(5)$ , side covers $(7)$ $(8)$ and bottom cover $(6)$ as described in paragraph 2.2.	
2	Remove the rear panel $70$ as described below by referring to Fig. 2-4.	
	<ol> <li>Remove the screw #10 at the center of the rear panel.</li> </ol>	
	2) Remove the four screws (two at each side) #11 at the sides of the rear panel.	
	3) Remove the connectors J29, J16, J7 (OPT 01) and W3 connected to each unit.	
	4) Remove the rear panel by sliding it backwards little by little.	
	Note:	
	If it is tight and difficult to remove, loosen the screw #12 and it can be removed easily.	

#### 2.6 A7 REF OSC Unit Removal

Step	Procedure	
1	Remove the top cover (5) as described in paragraph 2.2.	
2	Remove the A7 REF OSC as described below by referring to Fig. 2-4.	
	1) Remove the screw #13 and then the clamp $(91)$ .	
	2) Remove the three screws #14 and then remove the cover $6$ .	
	3) Pinch the part marked with *4 with pliers and lift it up.	
	Note:	
	Since it is under spring tension, some force is required to remove it.	

#### 2.7 Z3 CRT Unit, and Z4 REGULATOR Unit Removal

To remove the Z3 CRT unit, first remove the Z4 REGULATOR unit.

The following paragraph describes how to remove the REGULATOR unit and CRT unit with reference to Fig. 2-5.

#### (1) Z4 REGULATOR removal

Step	Procedure	
1	Remove the top cover (5) as described in paragraph 2.2.	
2	Remove the screw #13 and then remove the clamp $91$ by referring to Fig. 2-4.	
3	Remove the screw #15 by referring to Fig. 2-5.	
4	Remove the connectors J24, J27, J28, and J29.	
5	Lift out the Z4 REGULATOR unit.	

#### (2) Z3 CRT unit removal

Step	Procedure
1	Remove the Z4 REGULATOR unit as described in paragraph 2.7 (1).
2.	Remove the screw #16.
3	Remove the left side cover $\bigcirc{7}$ as described in paragraph 2.2.
4	Remove the two screws #17.
5	Lift out the Z3 CRT unit while sliding it backwards.

#### 2.8 Z1 YTO Removal

Step	Proc	edure	
1	Remove the front panel paragraph 2.3 (2).	<b>69 53</b>	as described in

Step	Procedure		
2	Remove the Z1 YTO by following the below procedures and referring to Fig. 2-5.		
	1) Remove the screw #18 and the cover $\widehat{110}$ .		
	2) Remove the screw #19 and the upper case $108$ .		
	3) Remove the screw $\#20$ and the bracket $105$ .		
	4) Remove the support (102) and move the Z1 YTO to the left to remove the W1 connector.		
	5) Remove J11 (Fig. 2-3).		

#### 2.9 A1 RF/PLL BLOCK Disassembly

The shield case, chassis, etc. are integrated in the Al RF/PLL BLOCK, which cannot be disassembled.

Figure 2-6 shows the position of each unit in the Al RF/PLL BLOCK and the cover assembly diagram.

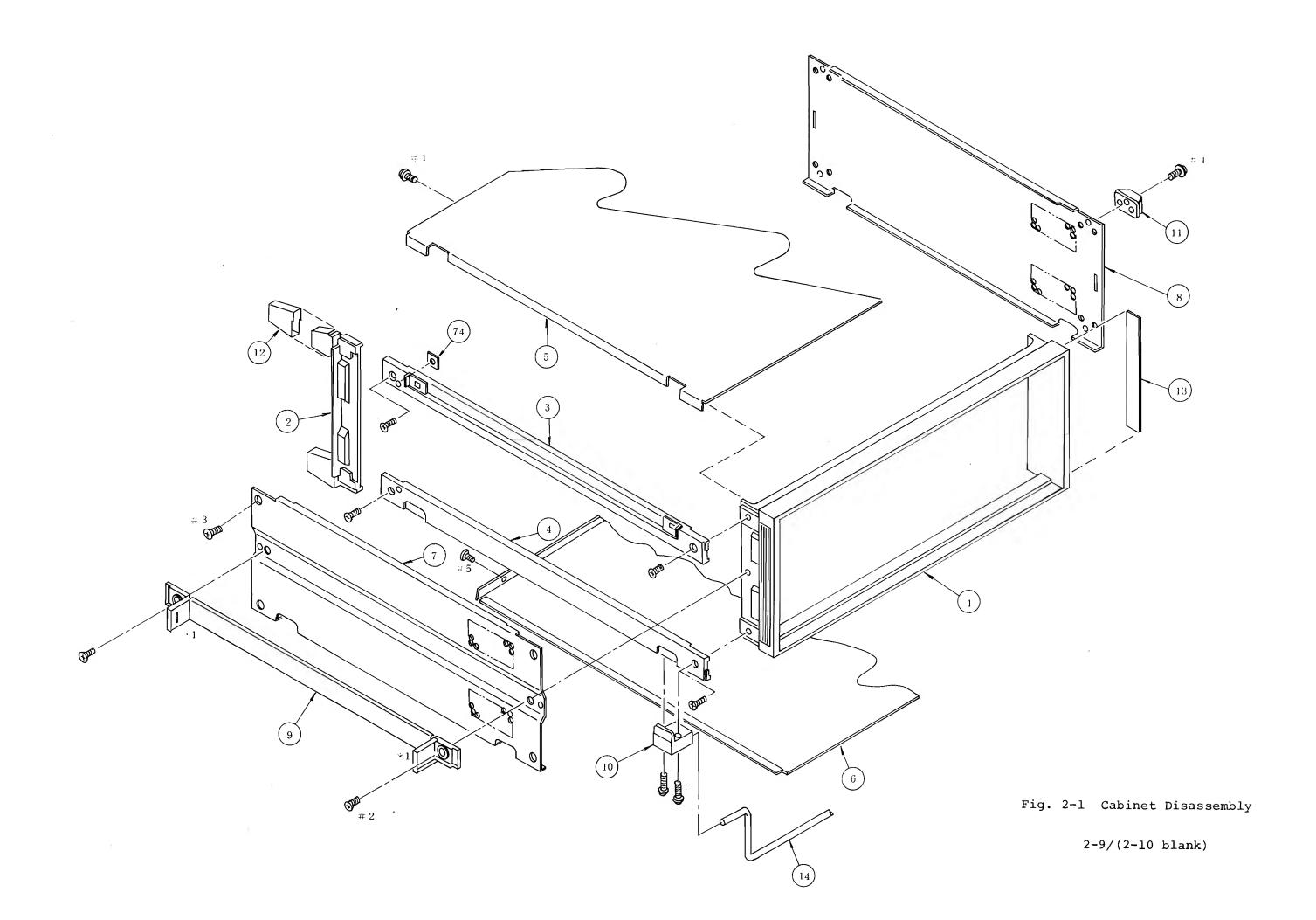
When checking and adjusting the unit, refer to this Fig. 2-6.

Remove the bottom cover as described in paragraph 2.2 to obtain the condition shown in Fig. 2-6.

#### 2.10 Options and Panel Displays

Figure 2-7 shows the difference between the displays of the front and rear panels when the A-type, J-type, and options are added.

The table in Item 3 shows the relationship between the panel displays and part numbers.



,			

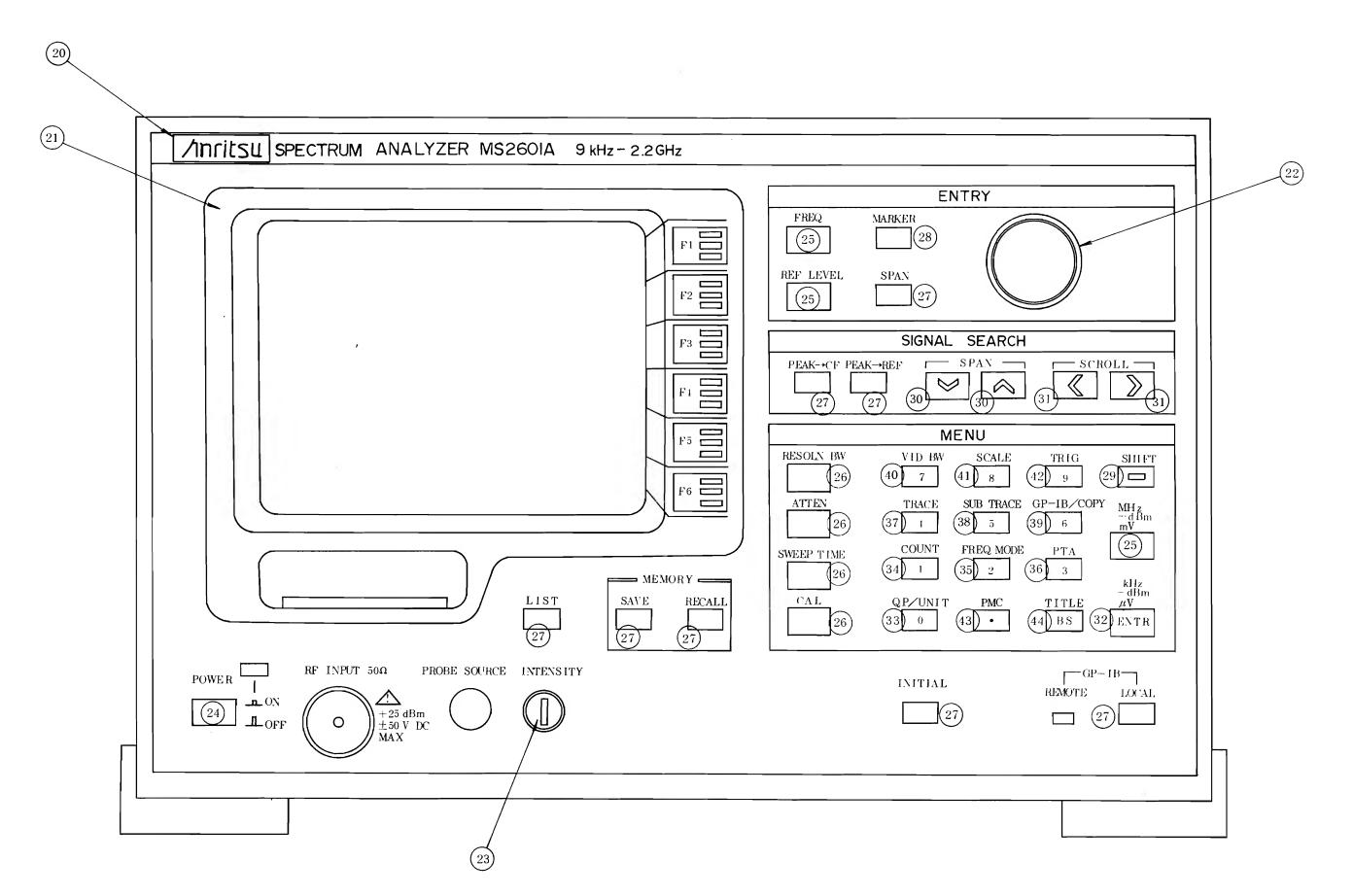


Fig. 2-2 Key Top Layout

,			

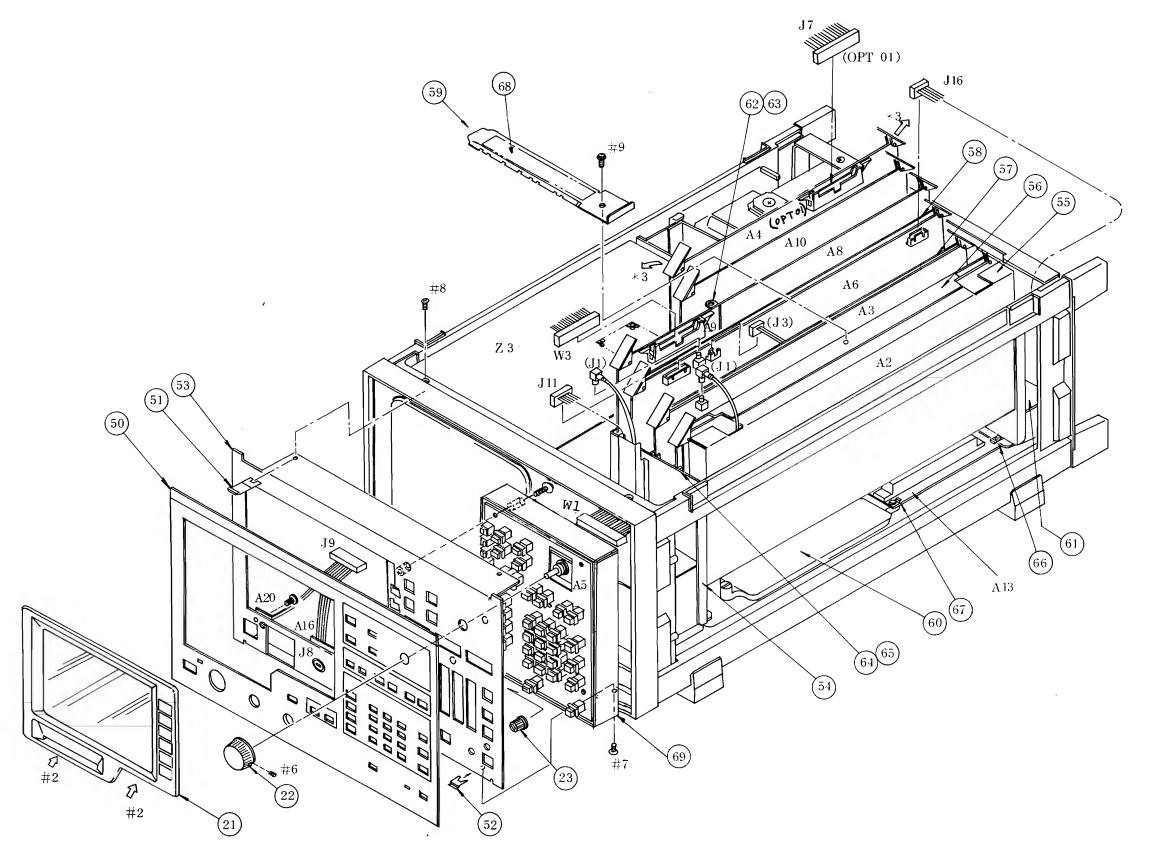


Fig. 2-3 Front Panel/Main Unit (A2, A3, A4, A6, A8, A10) Removal

2-13/(2-14 blank)

,			

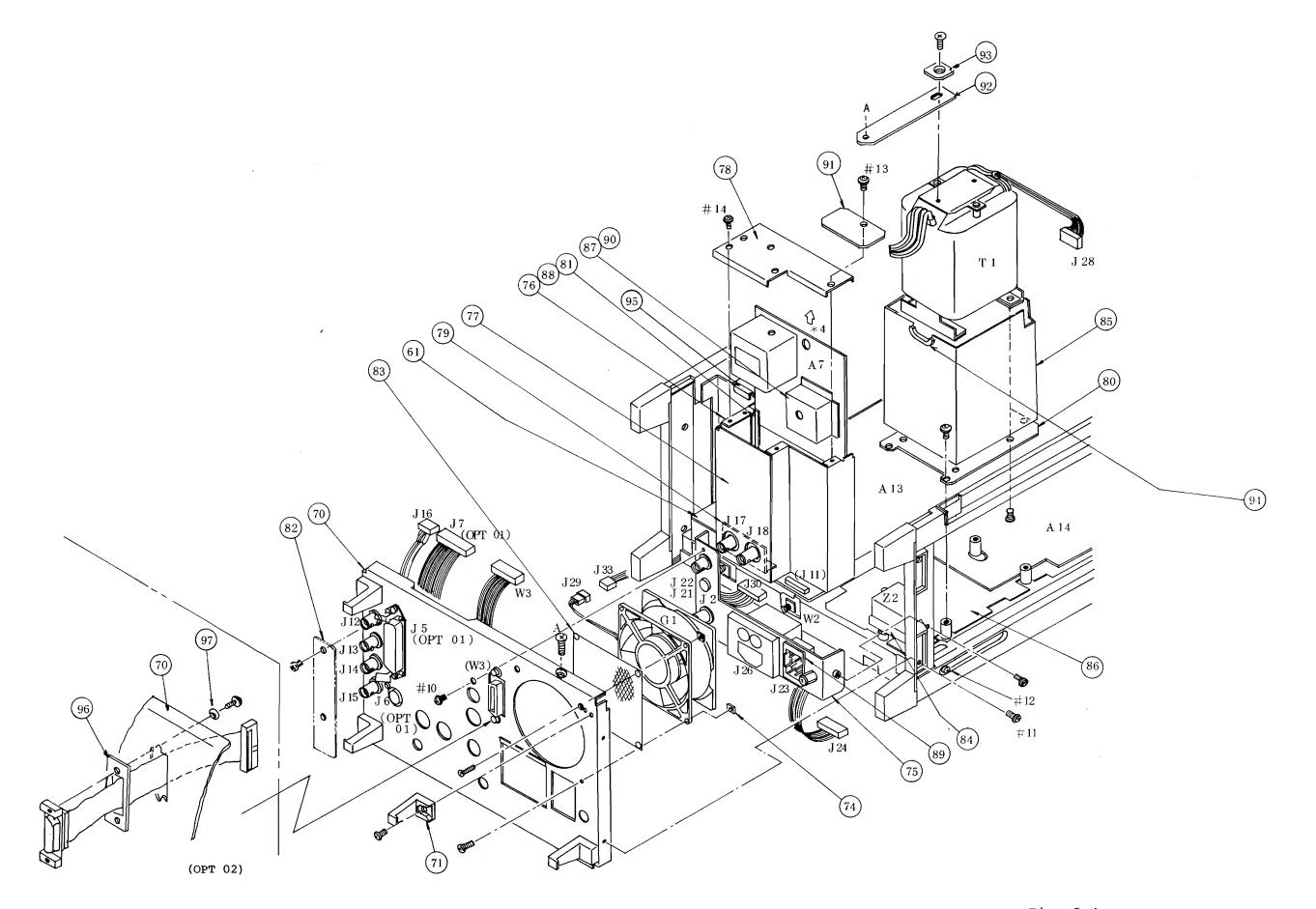


Fig. 2-4 Rear Panel Removal

,			

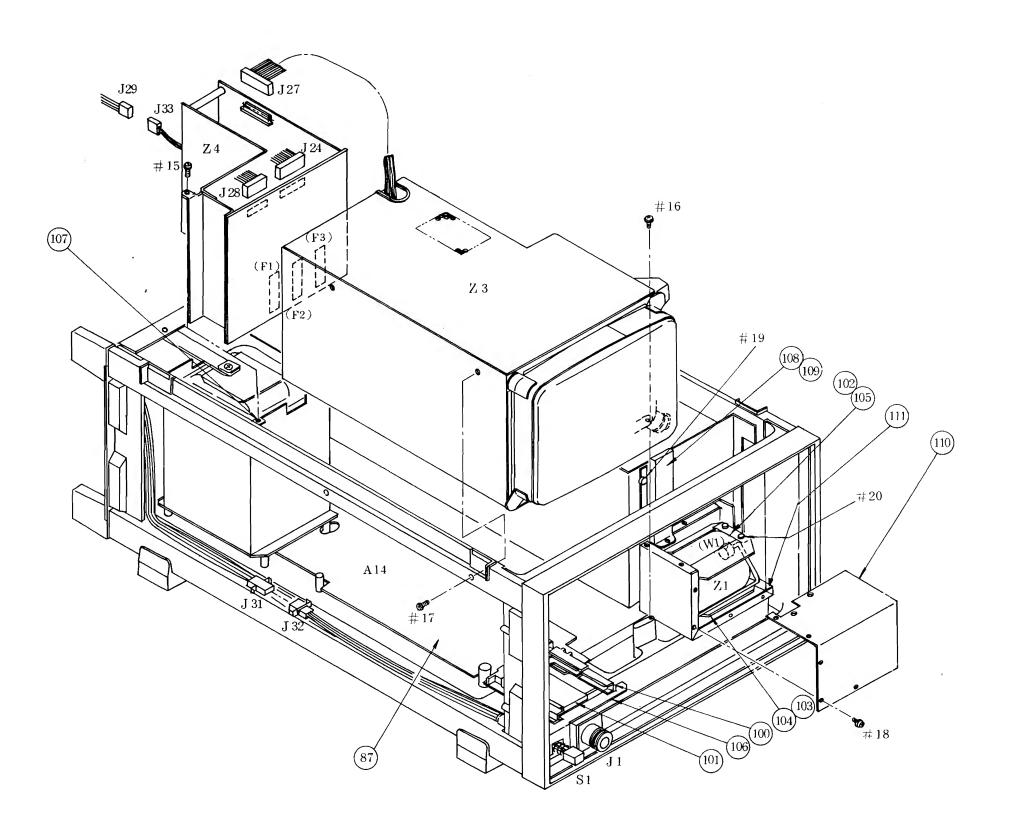
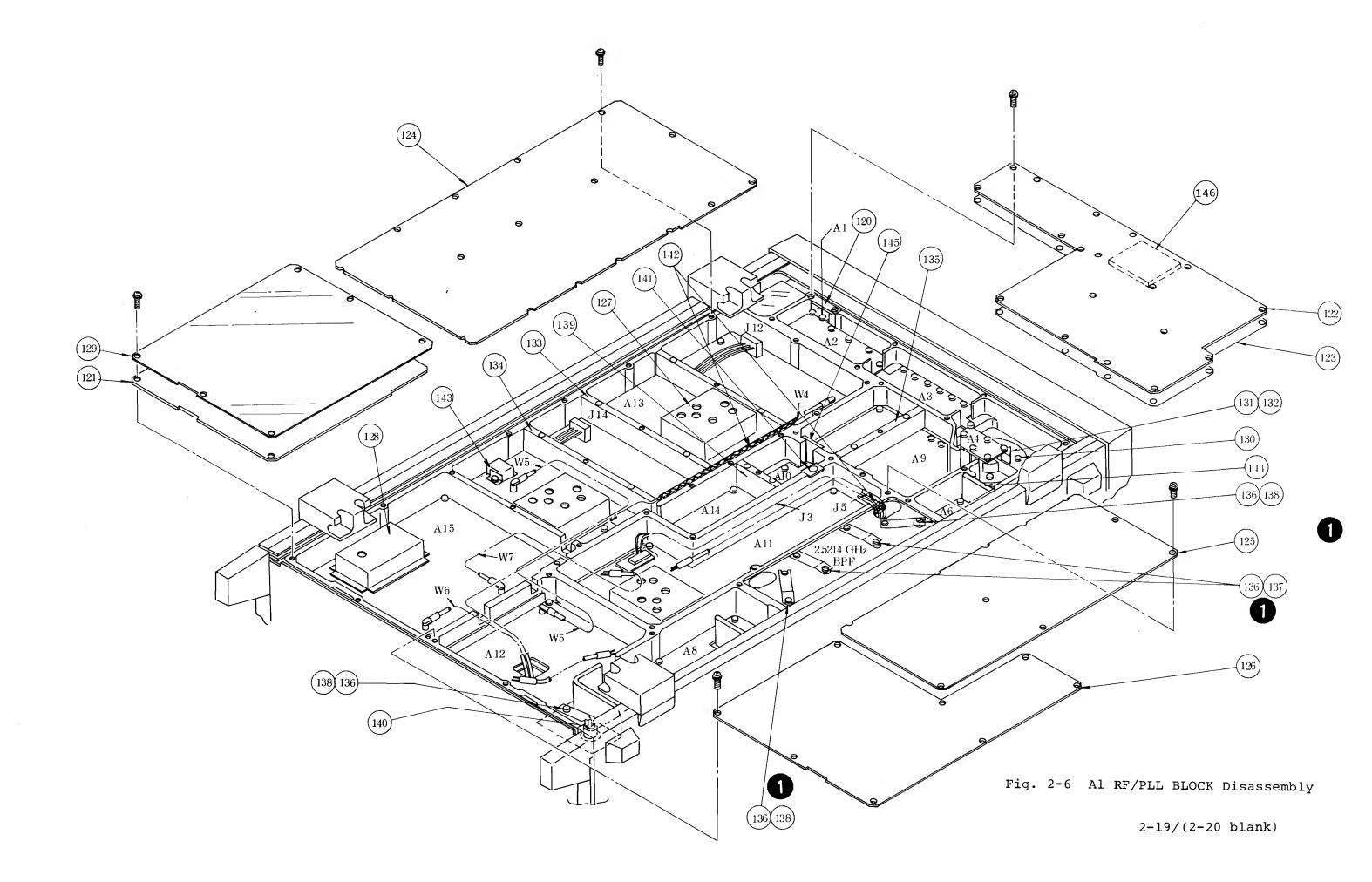
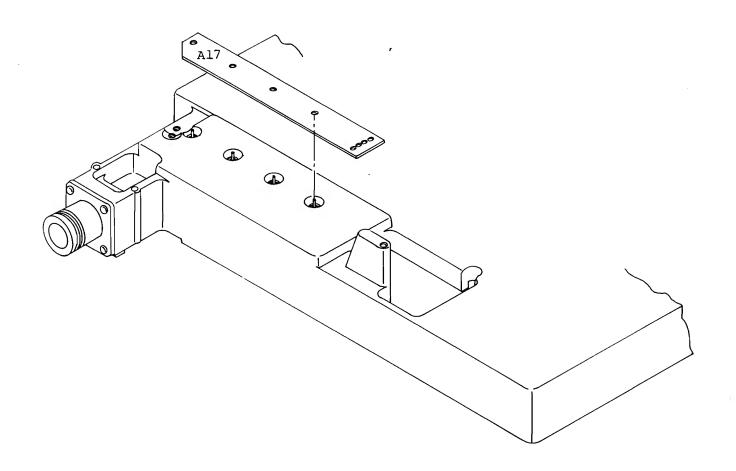


Fig. 2-5 Z3 CRT Unit, Z4 REGULATOR Unit, and Z1 YTO Unit Removal

,			



,			



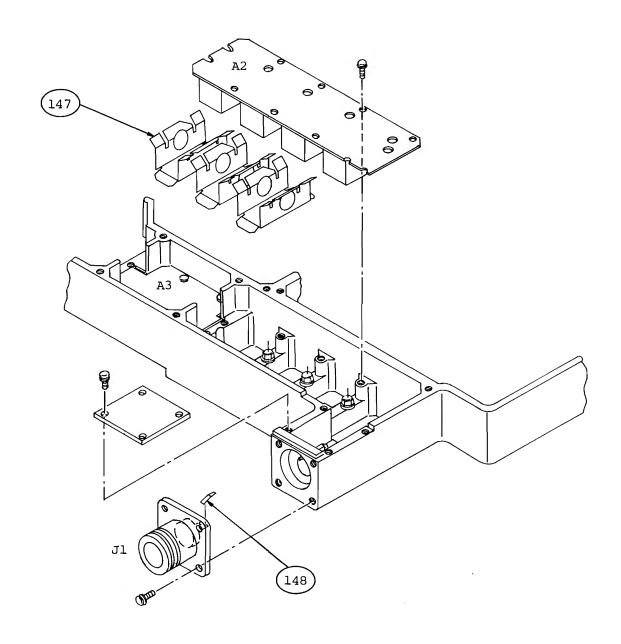


Fig. 2-7 Al RF/PLL Block Disassembly

2-21/(2-22 blank)

,			

Table 2-1 Mechanical Parts List for Fig. 2-1

No.	Part No.	Description	Remarks	Q'ty.
1	32B7680	Frame	2/3MU	1
2	32B7666	Channel	4U	2
3	32B7670	Upper channel	450	2
4	32B7671	Lower channel	450	2
5	33B22455	Top cover	2/3MW4U	1
6	33B22624	Bottom cover	2/3MW4U	1
7	33B22516B	Left side cover	450D	1
8	33B28978B	Right side cover	450D	1
9	349B73661C	Handle	450D	1
10	322B7672	Unit leg		4
11	34E84192	Side leg		4
12	33B20662	Protector		4
13	34B73660C	Side sheet		2
14)	34B73674B	Tilt stand		1

Table 2-2 Mechanical Parts List for Fig. 2-2

No.	Part No.	Description	Remarks	Q'ty.
20	34N39557	Nameplate		1
21)	333E29148	CRT cover		1
22	342E91592	Rotary encoder knob	φ27	1
23	34E73722	Knob	φ11	1
24)	44E68583	Knob		1
25	44E85793	Key top	10	2
26	44E85793B	Key top	10	5
27	34E91915	Key top	10-S	8
28	34E91915B	Key top	10-S	1
29	34E91915C	Key top	10-S	1
30	342E92806	Key top		2
31)	342E92806	Key top	< ⋅ >	2
32	342E92806	Key top	ENTR	1
33	342E92807	Key top	0	1
34)	342E92807	Key top	1	1
35	342E92807	Key top	· 2	1
36	342E92807	Key top	3	1
37	342E92807	Key top	4	1
38	342E92807	Key top	5	1
39	342E92807	Key top	6	1
40	342E92807	Key top	7	1
41	342E92807	Key top	8	1
42	342E92807	Key top	9	1
43	342E92807	Key top	•	1
44	342E92807	Key top	BS	1
$-\underline{\smile}$				

Table 2-3 Mechanical Parts List for Fig. 2-3

No.	Part No.	Description	Remarks	Q'ty.
50	322B10452[]	Decorative panel	See paragraph 2.10	1
51	34B7833D	Clamp		2
52	34B78330B	Clamp		2
53	322B10454	Front panel		1
54)	322B10383	Shield plate		1
<u>(55)</u>	322B10574	Shield case		1
56	322B10573	Shield plate		1
<b>5</b> 7	332B28887	Shield plate		1
58	332B28887B	Shield plate		1
59	34B92505	PC board clamp		1
60	34B91176	Cover		1
61)	34B91177	Cover		1
62	34B91672	Angle		1
63	34B91672B	Angle		1
64)	34B91345	Guide		6
65	34H59371E	Spring		6
66	34B93233	Earth spring		1
67	34B93233B	Earth spring		1
68	34N94674	Shield plate		1
69	342B95145	Shield plate		1

Table 2-4 Mechanical Parts List for Fig. 2-4

No.	Part No.	Description Remarks	Q'ty.
70	333B29164	Rear panel	1
71)	34B73670	Cord holder	4
72	Not assigned		
73	Not assigned		
74)	34B73668	Floating nut	8
75	332B28885	Angle	1
76	332B28892	Shield case	1
77	34B91179	Cover	1
78	34B91180	Cover	1
79	34B91181	Bracket	1
80	34B91182	Plate	1
81)	34B91345	Guide	2
82	34B92799	Plate Not assigned for option 01	1
83	34B64690	Guide	1
84)	34B92416	Shield case	1
85	332B29511	Transformer case	1
86	33B29513	Shield plate	1
87	34B91356	Shield case	1
88	34H59371E	Spring	2
89	34B93519	Spacer	2
90	34B91355	Shield case	1
91)	34B92504	Clamp plate	1
92	342B93867	Plate	1
93	34B93868	Washer	1

Table 2-4 Mechanical Parts List for Fig. 2-4 (Cont'd)

No.	Part No.	Description	Remarks	Q'ty.
94)	C4W005890	KG016 flexible bush		0.5
95	44D55830	CE-012 edging		0.3
96	342B92800	Plate		1
97	34H92803	Collar		2

Table 2-5 Mechanical Parts List for Fig. 2-5

No.	Parts No.	Description	Remarks	Q'ty.
100	33E29405	Guide		2
101	34B93313	Earth spring		1
102	34B91613A	Support	l=43 M2.6	4
103	34н39509	Support	l=8 M2.6	4
104)	34B91401	Bracket		1
105	34B91401B	Bracket		1
106	34B91580	Angle	_	1
107	34B92688	Angle		1
108	34B92414	Upper case		1
109	34B92415	Rear case		1
110	34B92418	Cover		1
111	332B29512	Shield case		1

Table 2-6 Mechanical Parts List for Fig. 2-6

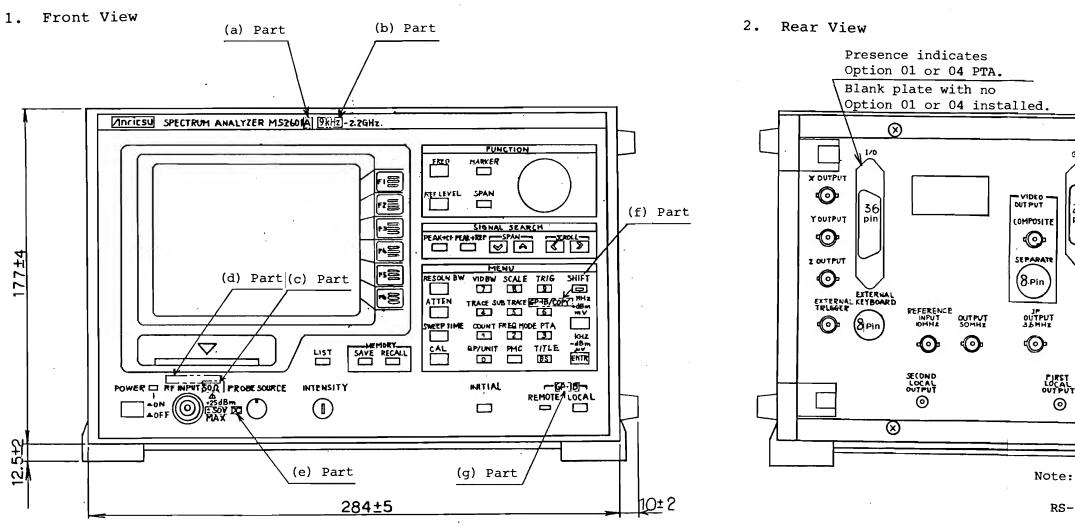
No.	Part No.	Description	Remarks	Q'ty.
120	34B91175	Cover		1
121	34B91178	Cover		1
122	33B28888	Cover		1
123	33B29703	Cover		1
(124)	33B28889	Cover		1
125	33B28890	Cover		1
126	33B28891	Cover		1
127	34B91323	Shield case		3
128	34B91324	Shield case		1
129	34B92417	Shield plate		1
130	342Н85560	MIX assembly		1
131)	34B85886	Diode ring		1
132	34B90180	Cover		1
133	34H91185	Partition plate		1
134	34H91185B	Partition plate		2
135	34H91186	Partition plate		1
136	34н79935	Spring		5
137	34H84919	Trimmer		2
138	34H84919B	Trimmer		3
139	34H91187	Partition plate		1
140	349Н80146	Oscillator assembly		1
(41)	34H93481	Clamp plate		1

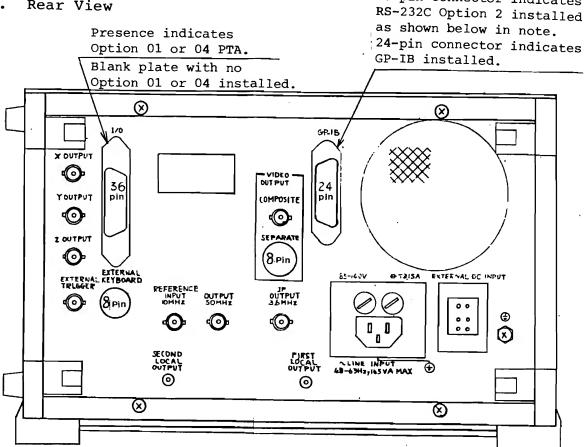
Table 2-6 Mechanical Parts List for Fig. 2-6 (Cont'd)

No.	Part No.	Description	Remarks	Q'ty.
142	34D94376	Shield type		20 cm
143	34B92557	Earth spring		2
144)	342H93387	Wave absorber		1
145	34B94334	Shield plate		1
146	342Z96135	Wave absorber		1

Table 2-7 Mechanical Parts List for Fig. 2-7

No.	Part No.	Description	Remarks	Q'ty.
147)	34B96362	Spring		3
148	34B96292	Conductor		1





RS-232C connector Option 02

25-pin connector indicates

3. Front panel trim options (Above figure shows standard trim 332B10452A Decorative panel)

Impe- dance	Model name	OPTION	(a)	(b)	(c)	(d)	(e)	(f)	(g)	Part No.
		01;04	A	10 kHz	50 Ω		±50 V DC	GP-IB/ COPY	GP-IB	322B10452A
50 Ω	A	02,01&02; 04&02	A	10 kHz	50 Ω		±50 V DC	COPY	RS-232C	322B10452C
		05;01&05; 04&05	A	100 Hz	50 Ω		±0 V DC	GP-IB/ COPY	GP-IB	322B10452E
		02&05;01&02& 05;02&04&05	A	100 Hz	50 Ω		±0 V DC	COPY	RS-232C	322B10452G
		01;04	J	10 kHz	75 Ω	USE THE NC TYPE PLUG	±50 V DC	GP-IB/ COPY	GP-IB	322B10452B
75 Ω	J	02,01&02;04&	J	10 kHz	75 Ω	USE THE NC TYPE PLUG	±50 V DC	COPY	RS-232C	322B10452D
		05;01&05;04& 05	J	100 Hz	75 Ω	USE THE NC TYPE PLUG	±0 V DC	GP-IB/ COPY	GP-IB	322B10452F
		02&05;01&02& 05;02&04&05	J	100 Hz	75 Ω	USE THE NC TYPE PLUG	±0 V DC	COPY	RS-232C	322В10452Н

Fig. 2-8 Options and Panel Appearance

2-31/(2-32 blank)

,			

#### SECTION 3

#### TROUBLESHOOTING AND ADJUSTMENT

#### 3.1 Introduction

### 3.1.1 Composition

This section describes how the circuit operates, and how to troubleshoot and adjust the MS2601A/J after repair, etc.

When making a repair, first refer to paragraph 3.2 and determine the defective unit and locate the problem in the unit by referring to paragraph 3.3

Table 3-1 lists the circuit diagrams, parts lists and PC boards.

#### Note:

Calibration of compensation data

The MS2601A/J measuring accuracy can be improved by entering the compensation data shown below in the built-in memory.

- 1. Frequency response compensation value
- 2. CAL level compensation value

If the specifications are not met for the performance test described in paragraph 4.4 of the operation manual after the circuit related to these compensation data has been repaired, the compensation data must be reentered. The input method is described in Section 4.

Table 3-1 Circuit Reference

Schematic No.	A-No.	Name	PC Board No.	Parts List No.
1		MS2601A/J		34W93351
2	A1	RF/PLL BLOCK		34W93317
3	A1-A1	DC BLOCK	342091131	34W93328
4	A1-A2	P-ATT	332030567	34W96386
5	A1-A3	2.2 G LPF	34U95036	•
6	A1-A4	EQU	342091129	34w93330
7	A1-A6	2.5214 GHz PRE AMP	332028853	34W93331
8	A1-A8	2nd CONV	332U28847	34W93332
9	A1-A9	1st LO AMP	332U28861	34W93333
10	A1-A10	SAMPLER	342U92018	34W93334
11	A1-A12	2nd LOCAL PLL	332028857	34W93335
12	A1-A13	50 k/50 M STEP SYNTH	322010359	34W93336
13	A1-A14	PULSE AMP	332U28855	34W93337
14	A1-A15	20 Hz STEP VCO CONT	322U10357	34W93338
15	A1-A16	YTO PLL PD & LOOP FILTER	322U10367	34w93339
16	A2	IF BPF	322010365	34W93318
17	A3	IF LOG/DET	322U10419	34W93319
18	A5	FRONT BOARD	332U28863	34W93320
19	A6	SCAN/YTO DRIVE	322U10369	34W93321
20	A7	REF OSC	322U10421	34W93322

Table 3-1 Circuit Reference (Cont'd)

Schematic No.	A-No.	Name	PC Board No.	Parts List No.
21	A8	MAIN CPU	332U28843	34W93323
22	A9	GP-IB	332U28859	34W93324
23	A10	DISP CPU	332U28845	34W93325
24	A13	MAIN MOTHER BOARD	322U10415	34W93326
25	A14	SUB MOTHER BOARD	322U10462	34W93327
26	A15	LED	342U91135	34W93349
27	Z4	REGULATOR	3A22-49A53	22-49A36
28	A16	FILTER	342U95236	34W95267
29	A4	PTA (OPT 01, 04)	332U29991	34W94043
30	A11	RS232 (OPT 02)	3 <b>4</b> 2U93955	34W94044
31	A17	CONNECTOR	342U96122	

## Note:

The A1-A3 2.2 GHz LPF and A17 CONNECTOR consist of a PC board only without a capacitor, resistor, or semiconductor etc.

So, a A1-A3 and A17 parts lists are not provided.

# 3.1.2 Checking and Replacement of Parts

(1) Explanation of identification markings on the PC board

As shown in Fig. 3-1, the MS2601A/J PC board has the A number, PC board number with the revision number, PC board name, and test point name.

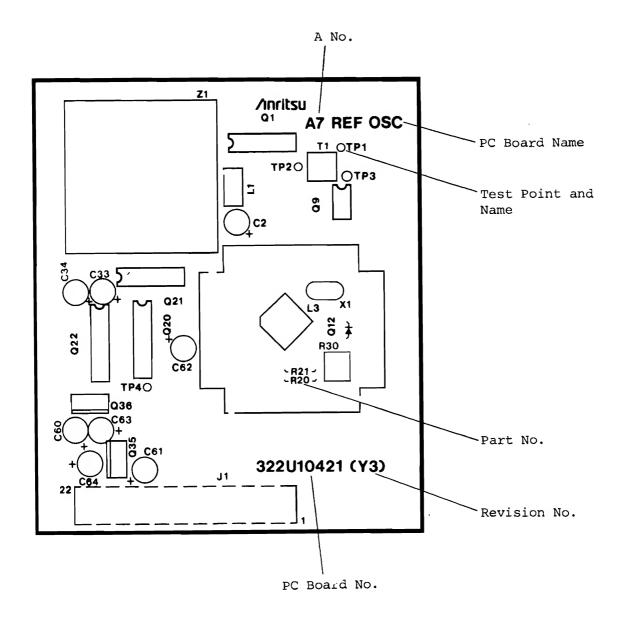


Fig. 3-1 PC Board Identification Markings

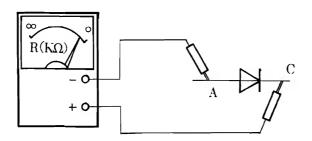
- (2) Notes on soldering
  - 1. Use an ordinary 30 to 40 watt pencil type soldering iron.
  - Before using the soldering iron, be sure it is insulated. If not, it may damage the part.
  - 3. When removing a soldered part from a circuit board or soldering in a new part, nip the part lead with tweezers to shunt heat.
  - 4. The tips of major part leads are bend behind the PC board to ensure tight support. To remove a part, first lift up the tips of the leads and then remove the part.
- (3) Transistor and diode check
  - Transistors can be checked for acceptable quality in the operating state by measuring the base and emitter potentials. The NPN type silicon transistor shows a value that the base potential is 0.6 or 0.7 V higher than the emitter potential. In the PNP silicon transistor, the former is 0.6 or 0.7 V lower than the latter. Transistors are, therefore, faulty if these relationships are not satisfied.
  - (b) Check of transistors removed from the PC board Transistors can be checked by measuring the resistance values among the emitter, base, and collector using a circuit tester. Standard values are given in Table 3-2. Note that this check should be performed at a measuring current of less than 100  $\mu$ A.

Table 3-2 Test of Transistors Removed from the PC Board

Type of	Connector	Resistance to be measured (ohm)	
transistor	Positive lead to Negative lead to		
PNP silicon	Emitter, collector	Base	1 to 10 k
	Emitter	Collector	Very high
NPN silicon	Base	Emitter, Collector	1 to 10 k
	Emitter	Collector	Very high

Check of diodes removed from the PC board

Diodes can be checked by measuring the resistance between the anode and cathode and the cathode and anode. If the resistance between the anode and cathode (A-C) is high and the resistance between C-A is low, when measured with an ohmmeter as shown in Fig. 3-2, the diode is normal.



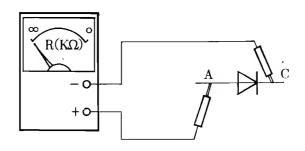
(1) Between C-A

Example: 1S953

**A-C:** ∞

C-A: ≅9 kΩ

Fig. 3-2 Diode Check



#### (2) Between A-C

Fig. 3-2 Diode Check (Continued)

## 3.2 Overall Troubleshooting

Figure 3-3 and 1 show the overall block diagram and the overall circuit diagram, respectively.

The following paragraphs describe the overall circuit opetation and troubleshooting.

## 3.2.1 Overall circuit description

The MS2601A/J is a superheterodyne system scanning-type spectrum analyzer. The input signal is mixed with the 1st LOCAL signal at the [RF/PLL BLOCK] 1st MIXER and is converted to the 2.5214 GHz 1st IF signal.

The 1st IF signal is mixed with the 2nd LOCAL signal at the 2nd MIXER and is converted to the 21.4 MHz 2nd IF signal.

The 1st and 2nd LOCAL OSC frequencies are stabilized in the PLL (Phase Locked Loop) circuits based on the reference signal supplied by [REFERENCE OSC]. The SCAN GENERATOR circuit of [SCAN/YTO DEIVE] sweeps the YTO (1st LOCAL OSC) frequency.

The 21.4 MHz 2nd IF signal is mixed with the 3rd LOCAL signal at the 3rd MIXER of [IF BPF] and is converted to the 3.6 MHz final IF signal. The 3.6 MHz IF signal passes through variable gain amplifiers and BPFs which determine RBW (resolution bandwidth) and also passes through LOG or LIN amplifiers of [IF LOG/DET] for detection.

「IF LOG/DET] sends CAL signal to the RF section for internal calibration of LOG linearity and reference level accuracy.

The detected signal passes through the VF (Video Filter) or QP detector and is converted to a digital signal by the A/D converter.

The converted digital signal is processed at [MAIN CPU] and also sent to [DISP CPU] for display on the CRT.

The data (frequency, reference level value, etc.) entered at the [FRONT BOARD] panel keys is sent to the [MAIN CPU] which controls each unit depending on the data content.

[MAIN CPU], [DISP CPU], and [PTA] have each one CPU, and configure the multi-processor system through a common bus and common RAM. (Refer to Fig. 3-3 (1/2)). The [GP-IB (or RS-232C)] is connected to the [MAIN CPU] CPU bus. The [FRONT BOARD] is connected with [MAIN CPU] I/O bus.

# 3.2.2 Overall troubleshooting

Problems are roughly divided into the following four categories. Locate the defective unit from the symptom.

- 1. Abnormal CRT display
- 2. Abnormal frequency
- Abnormal level
- 4. Abnormal front panel key entry
- (1) Abnormal CRT display

Locate the faulty unit by referring to the symptoms listed in Table 3-3.

Table 3-3 Abnormal CRT Display

		Syn	nptom		Cause	Unit to be checked
1.			een is dark and g is displayed			
	a.	POW	WER ON lamp is off	i)	AC fuse is blown	Rear panel (J26) Z4 REGULATOR
				ii)	DC fuse for +5 V is blown	Z4 REGULATOR
	b. POWER ON lamp is on					
		1)	When the INTENSITY knob is turned clockwise, the graduation lines and characters are displayed on the CRT.	Inte	ensity shortage	
		2)	When the INTENSITY knob is turned clockwise, the	i)	Defective power reset signal	Z4 REGULATOR A10 DISP CPU A8 MAIN CPU
			screen brightens	ii)	Defective CRT drive signal	

Table 3-3 Abnormal CRT Display (Continued)

	Sym	nptom	Cause		Unit to be checked
	3)	When the INTENSITY knob is turned clockwise, nothing is displayed	i)	DC fuse for +12 V is blown or CRT power supply is defective	Z4 REGULATOR
			ii)	Defective CRT	Z3 CRT UNIT
2.	2. The screen is bright and nothing is displayed	i)	Defective power reset signal	Z4 REGULATOR	
			ii)	Defective CRT drive signal	Z10 DISP CPU A8 MAIN CPU

# (2) Frequency abnormality

Although the spectrum waveform or noise is displayed on the screen, if the frequency display value is abnormal, there may be a problem around the LOCAL OSC. The following describes how to find out the faulty unit by referring to the examples in Table 3-4.

Table 3-4 Abnormal Frequency Measurement

		Symptom		Cause	Unit to be checked
1.	The frequency is fluctua- ting in approx. the 10 MHz range			nd Local PLL t locked	A1 RF/PLL BLOCK
2.	<ul><li>There is a large frequency display error</li><li>a. Little or no fluctuation in frequency display value</li></ul>				
				tive 1st Local ircuit	A1 RF/PLL BLOCK
			i)	YTO PLL not locked	
				50 kHz or 50 MHz STEP SYNTH PLL not locked	
			,	Defective 20 Hz STEP VCO	
	b.	Large error at SPAN 520 kHz or more	Defect circu	tive YTO DRIVER it	A6 SCAN/ YTO DRIVE
	c.	Large error at SPAN 500 kHz or less		tive 20 Hz STEP n 1st Local PLL it	A1 RF/PLL BLOCK
	đ.	Large error to right of screen center	Defec	tive span signal	A6 SCAN/ YTO DRIVE
	e. Large error of same frequency ratio regardless of absolute frequency value  (5 x 10 <sup>-5</sup> to 5 x 10 <sup>-7</sup> )			tive Reference peration	A7 REF OSC
3.	Abn	ormal FREQ COUNT value		tive frequency er circuit	A3 IF LOG/DET

# (3) Level abnormality

The cause of the level defects is widespread in the parts ranging from the RF section to the IF section. Locate the defective unit from the display contents by referring to the examples in Table 3-5.

Table 3-5 Level Measurement Abnormality

		Symptom		Cause	Unit to be checked
1.	_	nal level very low or displayed			
	pre ent	on on the power again, ess the [INITIAL] key to eer the FULL SPAN mode check the following:			
	a.	Zero beat signal and noise displayed Zero beat: >-30 dBm	i)	Defective input ATT	Al RF/PLL BLOCK
		Noise: -60 to -70 dBm	ii)	Defective 1st MIXER	
	b.	Noise displayed but zero beat not displayed	i)	Defective 1st local oscillation	A6 SCAN/ YTO DRIVE Z1 YTO
			ii)	Defective 2nd local oscillation	Al RF/PLL BLOCK
	c. Both zero beat and noise low			ective circuit near or 3rd MIXER	Al RF/PLL BLOCK A2 IF BPF
	d.	Neither zero beat nor noise displayed	i)	Defective detector or circuit near A/D	A3 IF LOG/DET
			ii)	Defective final RBW (BPF) circuit	A2 IF BPF

Table 3-5 Level Measurement Abnormality (Continued)

		Symptom		Cause	Unit to be checked
2.	Lar err	ge level measurement or			
	aga	form LEVEL CAL in and check following:			
	a.	Reference level accuracy out of specification	Defective CAL signal level		A3 IF LOG/DET
	b.	LOG linearity out of specification	Defe	ective CAL ATT	A3 IF LOG/DET
	c.	Large error depending on frequency	i)	Defective input ATT	A1 RF/PLL BLOCK
			ii)	Defective 1st MIXER	
3.	Oth	er symptoms			
		n on the power again check the following:			
	a.	Large RBW switching deviation	Defective RBW switching circuit		A2 IF BPF
	b.	Signal level value fluctuates with REF LEVEL	i)	Defective input ATT	A1 RF/PLL BLOCK
		PEAPT	ii)	Defective IF variable gain amplifier switch- ing circuit	A2 IF BPF
	С.	Signal level decreases for cases other than above	in e defe	tuning slippage each IF stage or ective IF ifiers	A1 RF/PLL BLOCK A2 IF BPF A3 IF LOG/DET

# (4) Defective front panel key setting

Table 3-6 Defective Panel Key Setting

	Symptom	Cause	Unit to be checked
1.	Setting impossible at all keys	Defective CPU or FRONT BOARD	A8 MAIN CPU A5 FRONT BOARD
2.	Setting impossible at some keys	Defective key select circuit	A5 FRONT BOARD
3.	Setting impossible at a specify key	Defective key switch	A5 FRONT BOARD

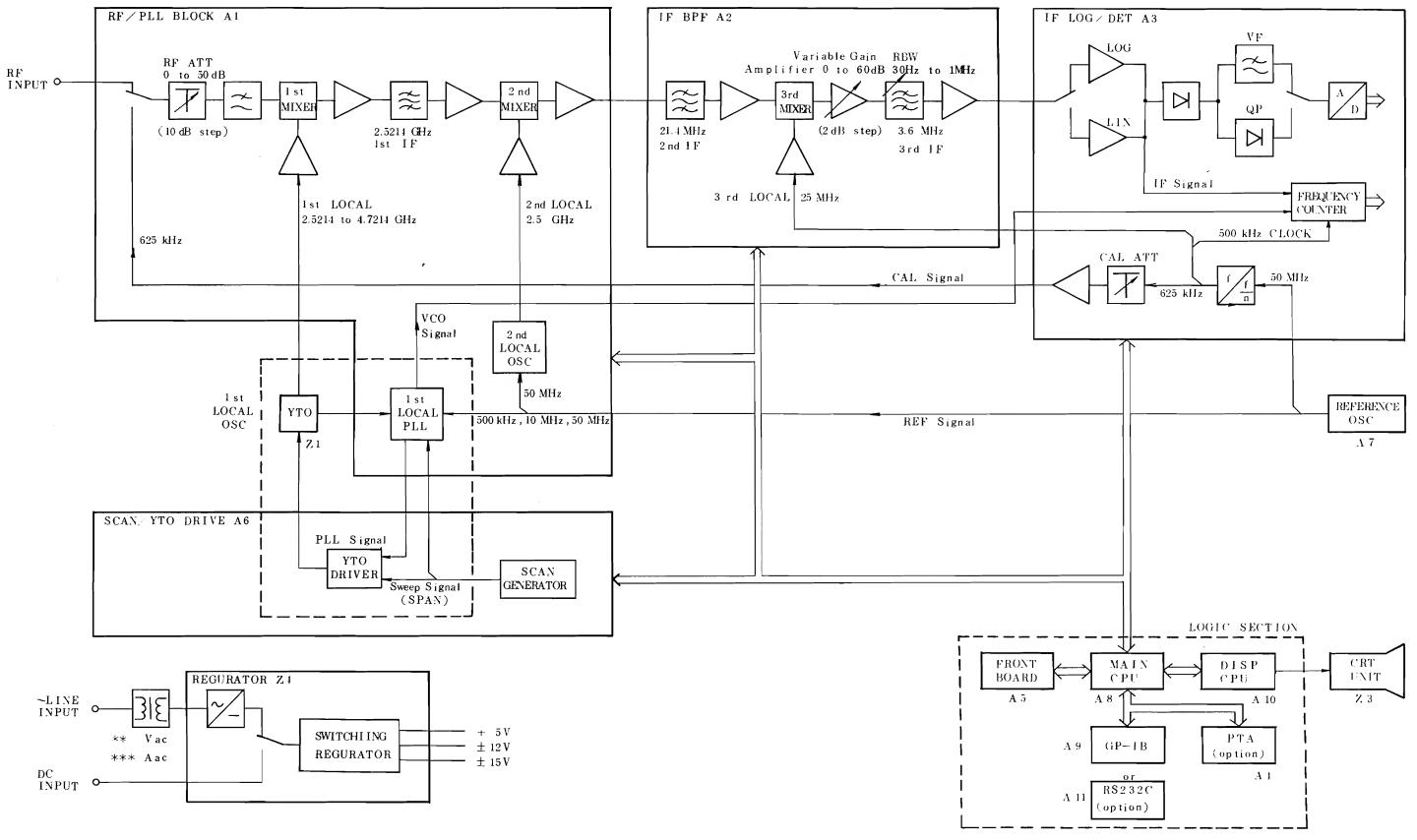
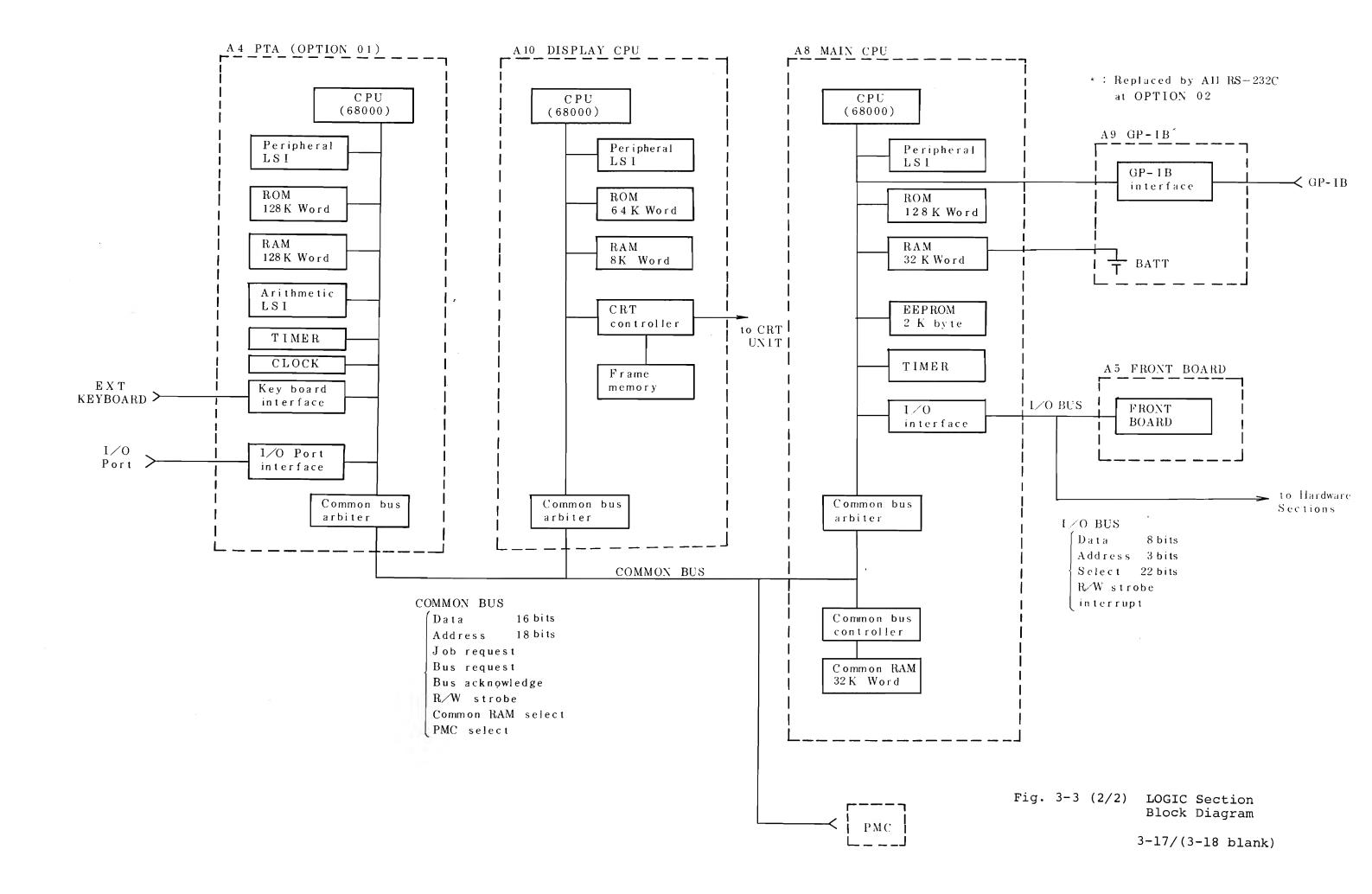
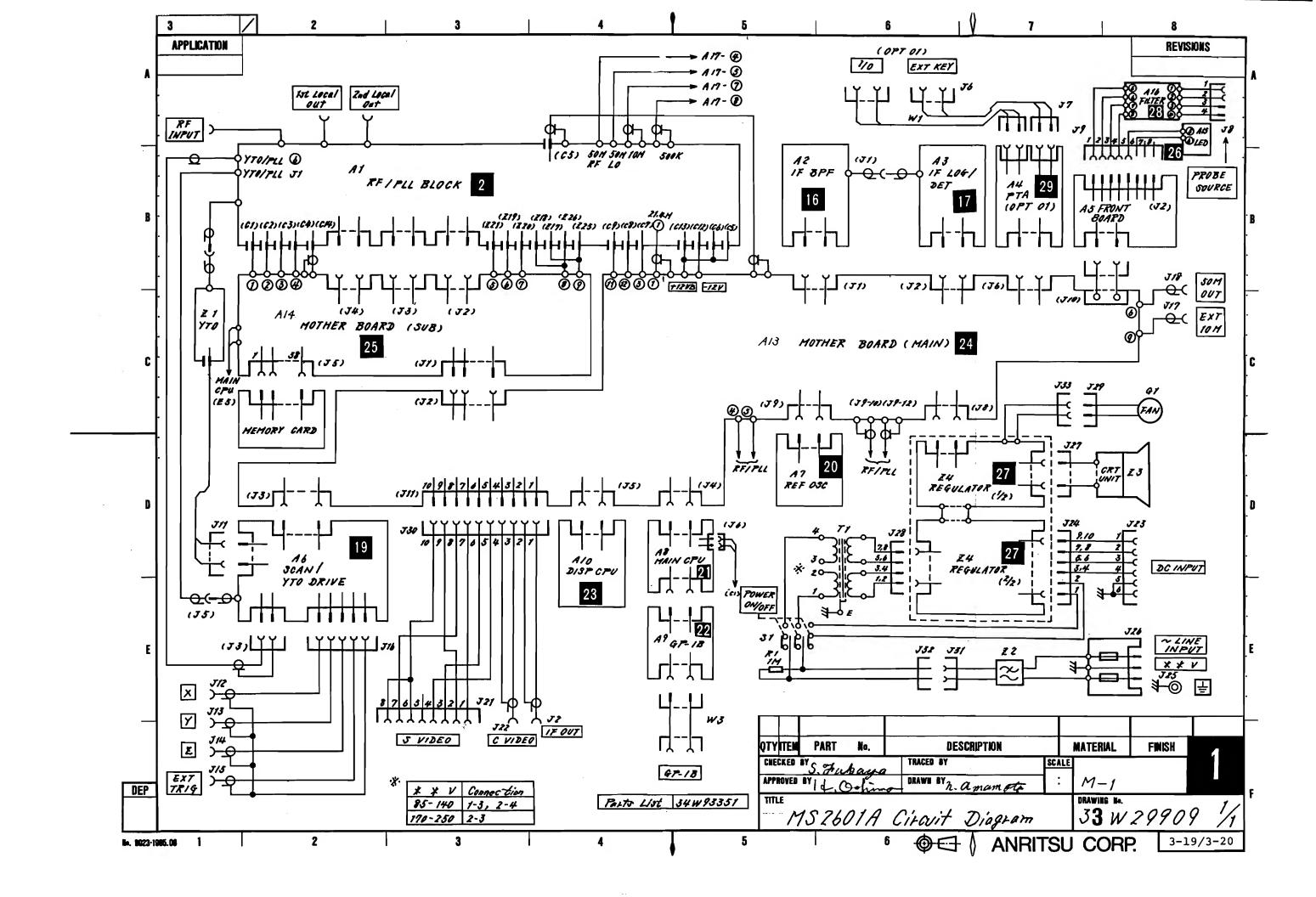


Fig. 3-3 (1/2) Overall Block Diagram 3-15/(3-16 blank)

,			



,			



,				
			·	

3.3 Troubleshooting and Adjustment of Each Circuit

## 3.3.1 Introduction

This paragraph describes the PC boards and units indicated by numbers A and Z.

1. Circuit description

Describes circuit operation using circuit diagram or block diagram

2. Symptom

Describes symptoms when trouble has occurred

3. Troubleshooting

Describes troubleshooting showing the normal value at checkpoint (waveform, signal level, etc.) using circuit diagram, PC board layout diagram, etc.

If the normal value does not appear, repair the related circuit.

4. Adjustment

Describes adjustment locations and procedures

3.3.2 Equipment required for troubleshooting, repair and adjustment

Troubleshoot, repair and adjust using the measuring instruments listed in Table 3-7. In addition, use the service kit (sold separately), including an extender board, extender cable, etc. for dedicated use shown in Table 3-8.

Table 3-7 Equipment Required for Troubleshooting, Repair and Adjustment

nstrument Required Performance		Model (Anritsu)
Digital voltmeter	5 digits, Maximum digit: 1 mV	
Oscilloscope	Dc to 200 MHz	
Frequency counter	Frequency range: 100 kHz to 5 GHz	MF76A
Spectrum analyzer Frequency range: 100 kHz to 5 GHz		MS612A
with High impedance probe	Frequency range: 100 kHz to 200 MHz	
Signal generator	Frequency range: 10 kHz to 2 GHz	MG649A
Network/Spectrum analyzer	Frequency range: 10 kHz to 30 MHz	MS420K
Signal generator	al generator Frequency range: 10 kHz to 30 MHz	
Dc voltage standard	Output: 0 to 99.9 V, 3 digits	
50 Ω Terminator (feed-through)	Connector: BNC	
Slide regulator	0 to 300 Vac output	

Table 3-8 Service Kit

[mm Unit]

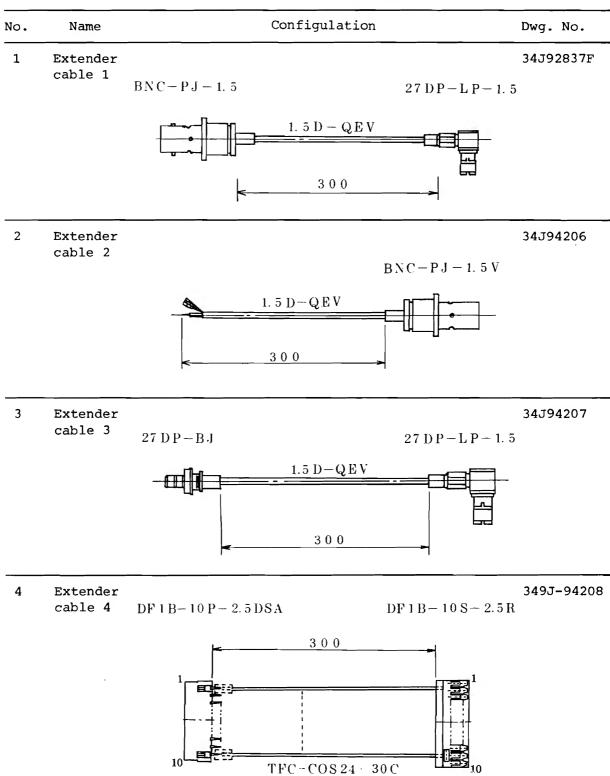


Table 3-8 Service Kit (Cont.)

No.	Name	Configulation	Dwg. No.
5	Extender cable 5	DF1-2P2.5DSA, DF1-2S2.5R24 n=2	449J81722G
6	Extender cable 6	DF1-8P2.5DSA, DF1-8S2.5R24 n=8	449J81722C
7	Extender cable 7	DF1-10P2.5DSA, DF1-10S2.5R24 n=10	449J81722D
		300	
8	Extender cable 8	BNC-P BNC-P	34J88878A
	-	C ord bush 1000	_
9	Extender cable 9	5 0 0	449J25501F
		3 D 2 W	
		HRM 202B	

Table 3-8 Service Kit (Cont.)

No.	Name	Configuration	Dwg. No.
10	Conversion adapter NP-NMJ	SMA-J NP	No. 1289
11	Adjustment bar 1	31.5	24Z92109
	-	A   121.5	
		$\Lambda - \Lambda$ Cross section	
12	Adjustment bar 2		34281433

Table 3-8 Service Kit (Cont.)

13 Extender board 1 315	322U10455
315	
$1) 1 \times 41612 - 6480$	
DIN41612-64 SQ	
170	
D1N41612-64PB	
14 Extender	332U29124
board 2	
D1N41612-96SR	
DIN 41612-96 PC	
D(.V.11012 301 C	
15 Extender	332029125
board 3 DIN41612-44SQ	
$\frac{122.5}{} (34 \text{ J } 89755)$	
(349 89733)	
110	
D1 N 41612 - 44 P B	
<u> </u>	

Table 3-8 Service Kit (Cont.)

No.	Name	Configuration	Dwg. No.
16	Reference extender	U-PB2219 100 2021 U-SB2201	342U91137
17	Carrying case for service kit		

## 3.3.3 Z4 REGULATOR 27

### (1) Circuit description

The Z4 REGULATOR consists of two PC boards, each of which is clamped with screws to a heat sink to form a block.

The Z4 REGULATOR unit rectifies input ac voltage, stabilizes it, generates the dc power supplies, and feeds them to each unit.

The Z4 REGULATOR also has a ac power source voltage monitor circuit and a dc input selecting circuit.

A detailed circuit description is given below with reference to Fig. 3-4 and 27.

The output from power transformer T1 is rectified by the Q2 and Q4 bridge rectifiers. The ripple component is decreased by capacitors C3 to C7 and C8 to C10.

The positive output is stabilized by two switching regulators; one has a switching frequency of approximately 35 kHz. This output is sent to three 3-terminal regulators (Q7, Q9 and Q11), is stabilized, and becomes the +12 V power supply. Another switching regulator has a switching frequency of approximately 20 kHz and this output becomes the +5 V power supply.

The negative output is stabilized by a switching regulator which has a switching frequency of approximately 20 kHz. This output is sent to two 3-terminal regulators (Q18 and Q20), is stabilized, and becomes the -12 V power supply.

This switching regulator output for -12 V is also stepped-up by a up-converter, is sent to two 3-terminal regulators (Q28 and Q29), and becomes the  $\pm 15$  V power supply.

The ac power source voltage monitor circuit generates a reset signal at regular interval after power-on.

The ac power source voltage monitor circuit quickly detects the voltage drop when the ac power source is turned off, and sends a power fail signal (NPWRFAIL) to the A8 MAIN CPU.

When the A8 MAIN CPU receives this fail signal, it stores the setting parameter contents in the backed-up internal memory.

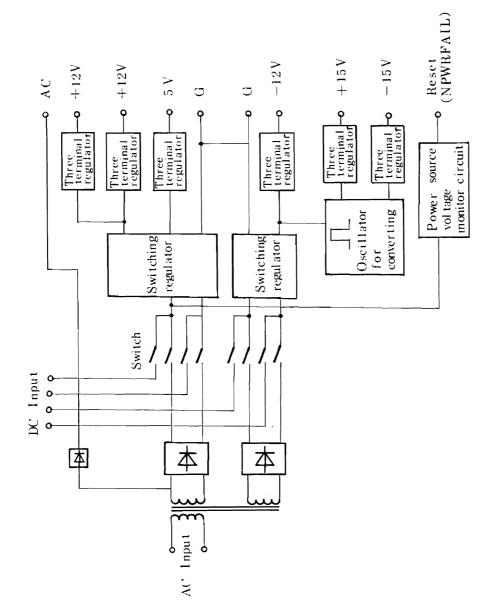


Fig. 3-4 Z4 REGULATOR Block Diagram

(2) Symptom

When the Z4 REGULATOR unit is faulty, the MS2601A/J does not operate at all or malfunctions frequently (e.g. abnormal CRT display).

- (3) Troubleshooting
  - (a) Required equipment
     Digital voltmeter
     Oscilloscope
  - (b) Preparation

---- CAUTION ----

Turn off the power before disassembly.

Step	Procedure
1	Remove the Z4 REGULATOR unit by referring to paragraph 2.7.
2	Remount the Z4 REGULATOR unit using an extender board.
3	Reconnect J28 from T1 to the Z4 REGULATOR unit using an extender cable (Fig. 2-5).

#### (c) Troubleshooting

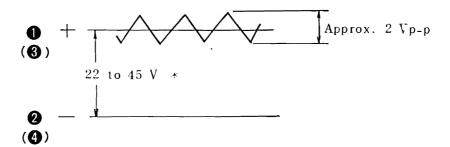
Check each checkpoint with reference to Fig. 3-6 and 27.

Table 3-9 Z3 Troubleshooting

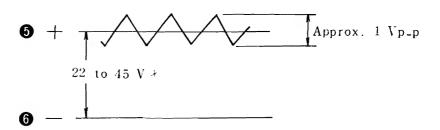
Checkpoint Normal condition

## 1. Rectified voltage check









- \* When the ac power source voltage is 100  ${\tt V}$ (with a 100 V system: 85 to 140 V) or 200 V (with a 200 V system: 170 to 250 V), this voltage is approx. 30 V.
- Switching regulator output voltage check

+12.5 to +14 V

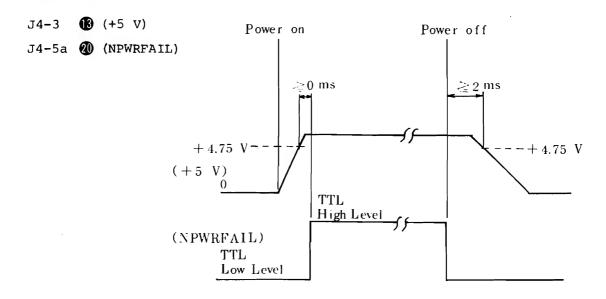
(+) (-)

or9 - 10 (+) (-)

Table 3-9 Z3 Troubleshooting

	Checkpoint	Normal condition
3.	Input voltage check for ±15 V three terminal regulators	*
	① - [GROUND]	+16.5 to +18 V
	₱ - [GROUND]	-16.5 to -18 V
4.	Output voltage check	(With reference to [GROUND] in 27)
	J4-3 <b>(3</b> )	+4.75 to +5.25 V
	J4-13 <b>(4</b> )	+14.3 to +15.7 V
	J4-14 <b>(b</b> )	+11.5 to +12.5 V
	J4-16 <b>(b</b> )	+11.5 to +12.5 V
	J4 <b>-1</b> 9 <b>17</b>	-11.5 to -12.5 V
	J4-22 <b>®</b>	-14.3 to -15.7 V
	J3-1 <b>(9</b> )	+11.5 to +12.5 V

5. Power fail signal check



## (4) Adjustment

The power source voltage monitor circuit is adjusted as follows:

## (a) Setup

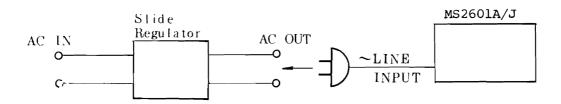


Fig. 3-5 Z3 Adjustment Setup

## (b) Adjustment

Step	Procedure
1	When $\sim$ LINE INPUT range is 85 to 140 V with a 100 V system, set the ac output voltage of the slide regulator to 75 ±1 V. (When $\sim$ LINE INPUT range is 170 to 250 V with a 200 V system, set the ac output voltage of the slide regulator to 150 ±2 V [75 V x 2].)
2	Turn R23 <b>(1)</b> fully clockwise, graduation lines or setting parameters on the CRT should disappear.
3	Turn R23 ② counterclockwise little-by-little until the CRT becomes normal.
4	When $\sim$ LINE INPUT range is 85 to 140 V with a 100 V system, confirm that the MS2601A/J operates normally even when the ac input voltage is set to 140 V. (Set this voltage to 250 V when the $\sim$ LINE INPUT range is 170 to 250 V with a 200 V system).

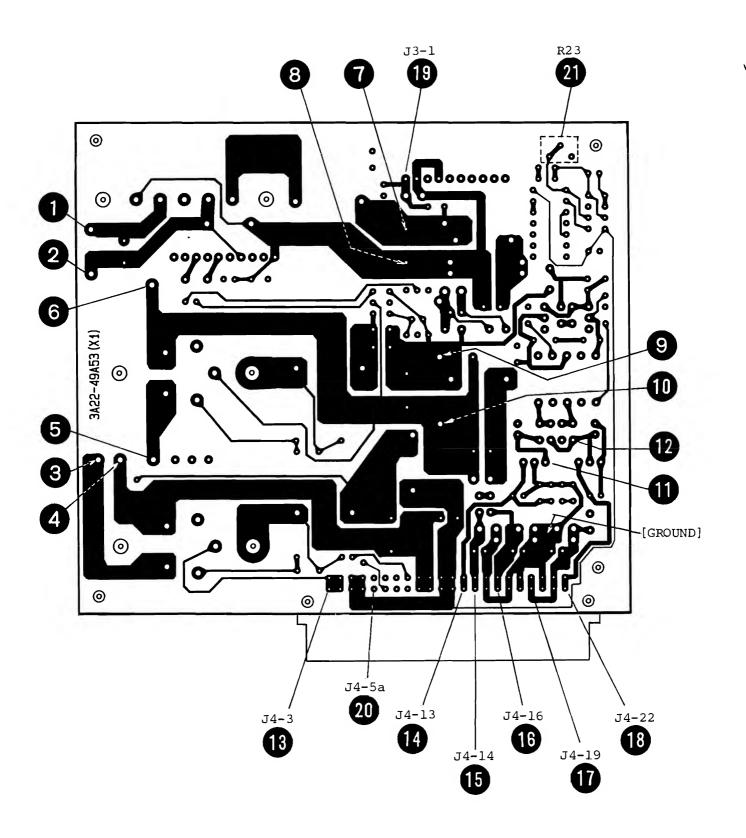
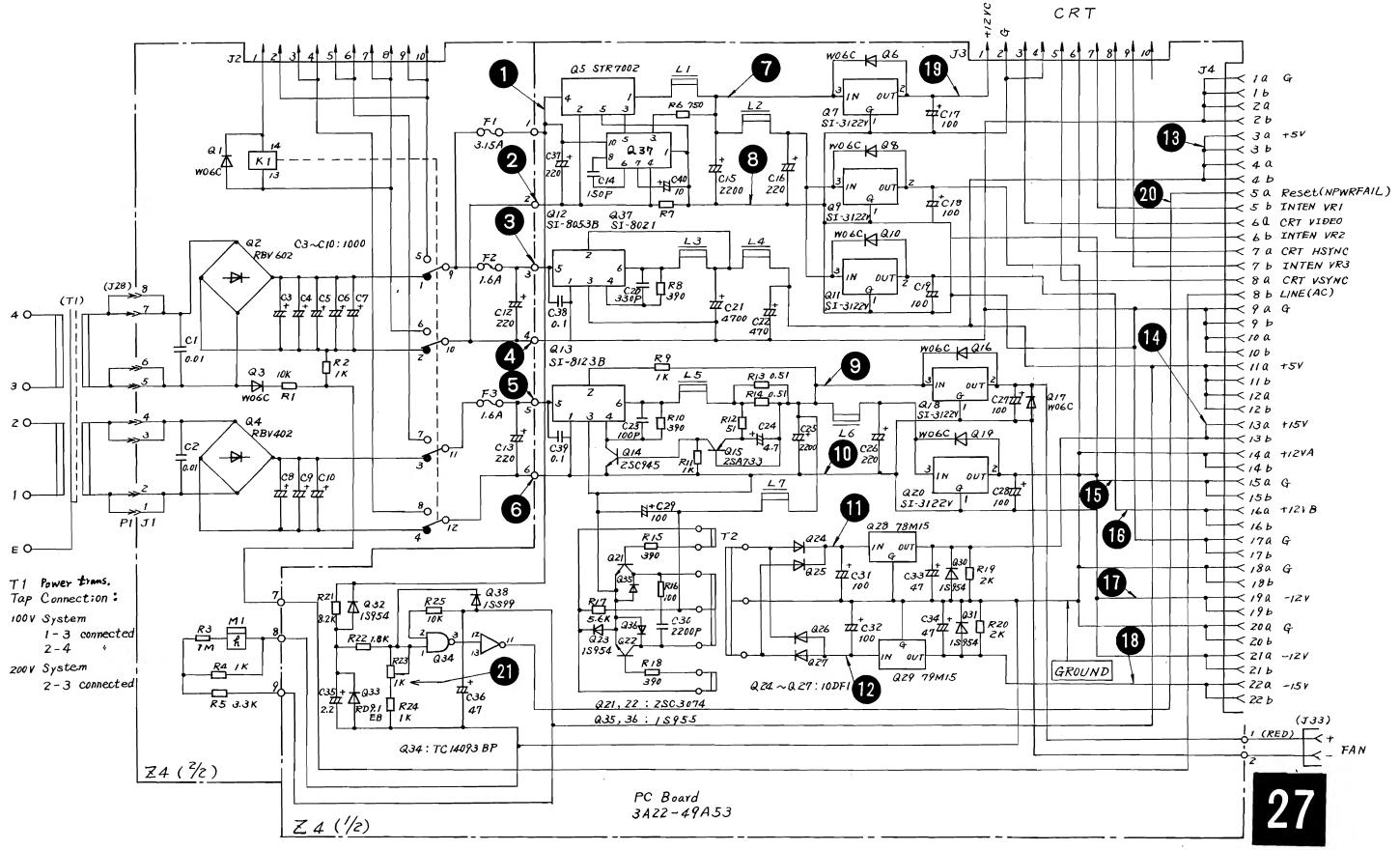


Fig. 3-6 Z4 REGULATOR PC Board Parts Layout



Parts List: 22-49A36

,			

# 3.3.4 A1 RF/PLL BLOCK 2 to 15

## (1) Circuit description

The A1 RF/PLL BLOCK is composed of the RF section and the PLL section (LOCAL section). The following paragraphs describe the circuits of each section with reference to Fig. 3-7.

## (a) RF section

(i) A1-A1 DC BLOCK

The dc component of the input RF signal from the RF INPUT connector is removed here.

(ii) A1-A2 P ATT 4

This circuit is composed of a switching section and the ATT section of the RF/CAL signals. The ATT section consists of three parts: 20 dB, 10 dB, and 20 dB attenuators.

(iii) A1-A3 2.2 GHz LPF 5

This circuit is composed of a PC board only, and does not have a fixed capacitor, resistor, and semiconductor.

This printed circuit board LPF lowers the image frequency component reception.

(iv) Al-A4 EQU/lst MIXER 6

These circuits mix the input signal with the local signal from A1-A8 1st LOCAL AMP and converts it to the 1st IF signal (2.5214 GHz).

(v) A1-A6 2.5214 GHz PRE AMP
The 1st IF signal (2.5214 GHz) is amplified

### (vi) A1- 2.5214 GHz BPF

here by 5 dB.

This is the 1st IF BPF which is composed of 4 cavity stages. In this BPF, the image frequency component 42.8 MHz apart from the 1st IF signal is removed to convert the 1st IF signal to the 2nd IF signal (21.4 MHz) at the 2nd converter.

## (vii) A1-A8 2nd CONV

The 1st IF sginal (2.5214 GHz) is mixed with the 2nd local signal (2.5 GHz) and is converted to the 21.4 MHz 2nd IF signal to be amplified.

Furthermore, the 2.5 GHz 2nd local signal is also supplied to A1-A12 2nd LOCAL PLL to stabilize the oscillation frequency of A1-2.5 GHz OSC.

### (b) PLL section (LOCAL section)

# (i) A1-A9 1st LO AMP 9

This circuit is composed of an amplifier, which amplifies the Z1 YTO output signal to supply the local signal to A1-A4 1st MIX, and an isolation amplifier which supplies the RF signal to A1-A10 SAMPLER. The isolation amplifier reduces the leak level to A1-A4 1st MIX due to the high-level harmonic frequency component generated by A1-A4 PULSE AMP.

# (ii) A1-A10 SAMPLER 10

This circuit mixes the Z1 YTO output with the harmonic frequency output (A1-A10 SAMPLER output), and converts the Z1 output frequency to 11.0 to 11.5 MHz.

# (iii) A1-A12 2nd LOCAL PLL 11

This circuit receives the 50 MHz reference frequency from the A7 REF OSC, generates a pulse, supplies it to the MIX sampler, and samples the signal from the A1- 2.5 GHz CAVITY OSC.

The sampler output locks the A1- 2.5 GHz CAVITY OSC frequency to 2.5 GHz.

# (iv) A1-A13 50 kHz/50 MHz STEP SYNTH 12

This circuit is composed of a 50 kHz-step synthesizer, that changes in 50 kHz steps, and a 50 MHz-step synthesizer that changes in 50 MHz steps. The output frequency of the 50 kHz-step synthesizer is divided by 2 M to make a reference signal for the 50 MHz-step synthesizer. The output of the 50 MHz-step synthesizer is supplied to the A1-A14 PULSE AMP.

The output frequency changes of the 50 kHz-step synthesizer is equal to that of Z1 YTO. The output frequency change of the 50 MHz-step synthesizer is 1/M of that of Z1 YTO.

## (v) A1-A14 PULSE AMP 13

This circuit amplifies the output signal of the A1-A13 50 kHz/50 MHz STEP SYNTH and generate a sampling pulse which is supplied to the A1-A10 SAMPLER.

# (vi) A1-A15 20 Hz STEP VCO CONT 14

This circuit is a feedback control circuit to improve the frequency stability and sweep linearity of the 11 to 11.55 MHz VCO mounted in the A1-A16 YTO PLL PD & LOOP FILTER.

Furthermore, the signal in this control circuit is supplied to the A3 IF LOG/DET and used when the frequency count function is selected or the frequency is calibrated.

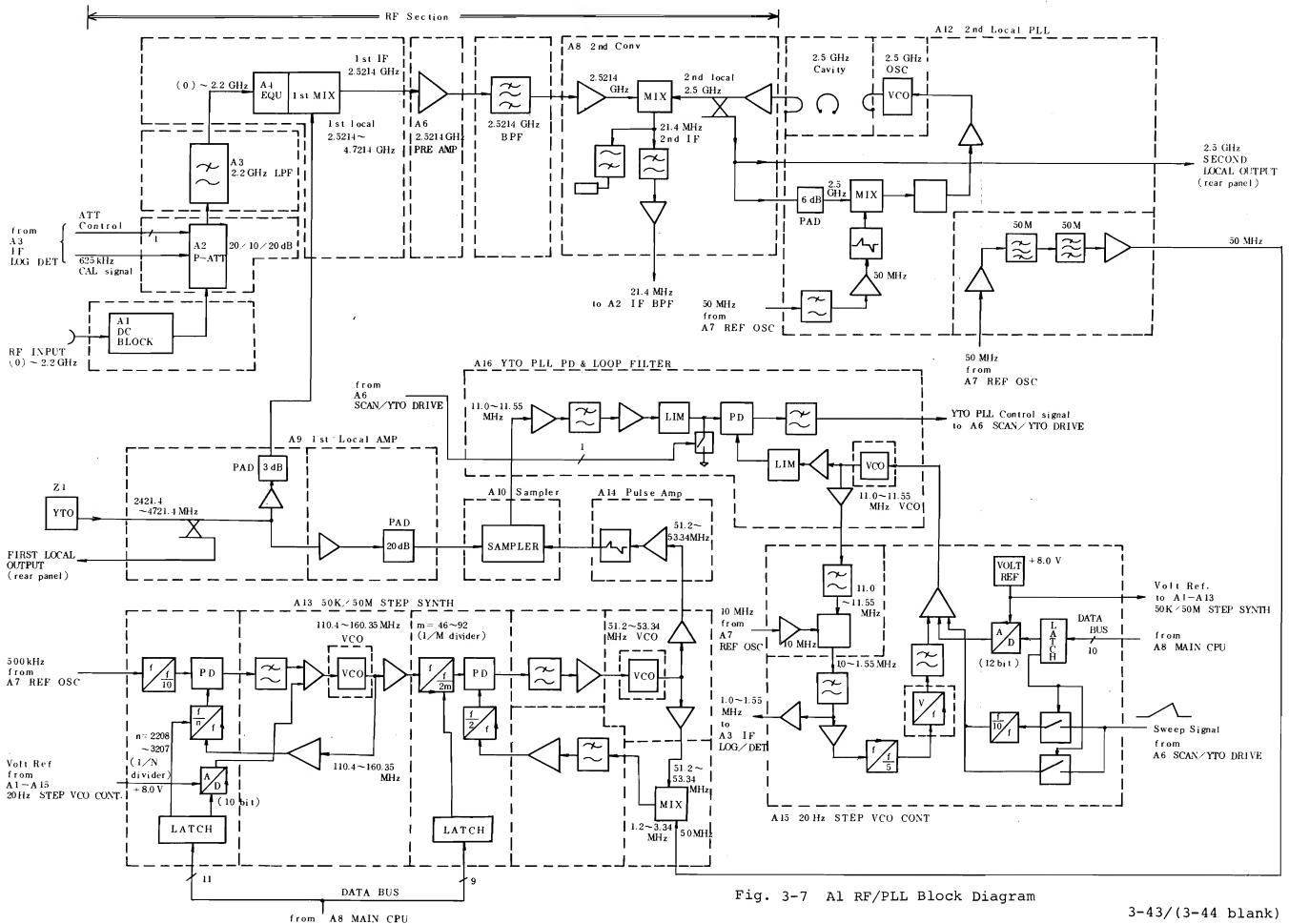
# (vii) A1-A16 YTO PLL PD & LOOP FILTER 15

This circuit is composed of an amplifier for the A1-A10 SAMPLER output signal, 11 to 11.55 MHz VCO which can be changed in 20 Hz steps, a phase/frequency detector of the YTO PLL, and a loop filter of the YTO PLL. The amplified output signal from the A1-A10 SAMPLER is compared to the 11 to 11.55 MHz VCO output signal by the phase/frequency detector.

The comparison result passes through the loop filter and is supplied to the A6 SCAN YTO DRIVER and finally controls Z1 YTO.

### (viii) A1- 2.5 GHz CAVITY OSC

This is a 2.5 GHz oscillator used as the 2nd Local oscillator.



,			

# (2) Symptom and cause

	Symptom		Cause	Unit to be checked
(RF	section)			
1.	Inferior frequency response	(a)	Defective input ATT	A1-A2 P-ATT
		(b)	Defective 1st MIX	A1-A4 EQU/1st MIX
2.	Signal level is low	(a)	Defective IF amplifier	A1-A6 2.5214 GHz Pre Amp A1-A8 2nd CONV
		(b)	1st BPF tuning slippage	A1- 2.5214 GHz BPF
(PL	L section [Local secti	.on])		
1.	Frequency drifts more than 10 MHz	(a)	YTO PLL is unlocked	A1-A16 YTO PLL PD & LOOP FILTER
		(b)	Output signal of the A1-A10 SAMPLER is faulty	A1-A10 SAMPLER
2.	Frequency drifts less than 10 MHz	(a)	50 kHz STEP SYNTH is unlocked	A1-A13 50 kHz/ 50 MHz STEP SYNTH
		(b)	50 MHz STEP SYNTH is unlocked	A1-A13 50 kHz/ 50 MHz STEP SYNTH
		(c)	11.0 to 11.55 MHz VCO output fre- quency is not correct	A1-A16 YTO PLL PD & LOOP FILTER A1-A15 20 Hz STEP VCO CONT
3.	Does not sweep properly when the SPAN is set to 500 kHz or less	(a)	Sweep frequency width of the 11.0 to 11.55 MHz VCO output is not correct	A1-A16 YTO PLL PD & LOOP FILTER A1-A15 20 Hz STEP VCO CONT
4.	Whole waveform swings from left to right and vice	(a)	2nd LOCAL PLL is unlocked	A1-A12 2nd LOCAL PLL
	versa	(b)	YTO PLL is unlocked	A1-A16 YTO PLL PD & LOOP FILTER

## (3) Troubleshooting

This paragraph first describes how to trouble-shoot the RF section and then the PLL section (LOCAL section).

- (a) RF section troubleshooting
  - (i) Required equipment

Digital voltmeter

Signal generator: MG649A

Spectrum analyzer: MS612A (with high-

impedance probe)

(ii) Preparation

- CAUTION -

o For the MS2601J, connect the MB-009 impedance transformer to the RF output of the MG649A signal generator.

When connecting the impedance transformer, set the signal generator output level 6 dB higher than the setting for the MS2601A.

o Turn off the power before disassembly.

Step	Procedure
1	Remove the bottom cover (paragraph 2.2).
2	Remove the cover of the unit to be checked by referring to Fig. 2-6.

## (iii) Troubleshooting

Check each part as shown below by referring to the level diagram in Fig. 3-8.

Step	Proce	edure
1	Apply the 100 MHz, -30 d	Bm signal to the RF INPUT.
2	Set the MS2601A/J as sho	own below.
	SPAN: 0 kHz	
	ATT: 0 dB	
3	Check A1-A8 2nd CONV 8 (Fig. 3-16, 8).	as shown below
	Checkpoint	Normal condition
	Terminal (7), 21.4 MHz	-26 to -30 dBm (Use high-impedance probe.)

(continued)

Step		Procedure			COITCI				
4	Check the 1st local	signal a	as shown	below.					
	Check the output le	vel from	the FIR	ST LOCA	L OUT	PUT			
	10 dBm or more (	2.6214 GF	łz)						
5	Check A1-A6 2.5214 (Fig. 3-15, 7).	GHz PRF A	AMP 7	as show	n bel	.OW			
	. +12 V ① : +11.5	to +12.5	5 V.						
6	Check A1-A2 P ATT (Fig. 3-12, 4).	4 as sho	own belo	W					
	Check point	Norma	al condit:	ion					
	(I/O level)	-30 dBm							
	0,2								
	(K1 to K4 control								
	voltage)	Input swi	tching	K1 <b>3</b>					
	K1 <b>3</b>	RF	<del></del>						
	K2 <b>4</b>	CAL		0					
	кз <b>б</b>	("0" during CAL)							
	K4 <b>6</b>	•	3						
		ATT set value	K2 <b>4</b>	кз <b>б</b>	K4	6			
		0 dB	0	0	0				
		10 dB	0	1	0				
		20 dB 30 dB	1 1	0 1	0				
		40 dB	1	0	1				
		50 dB	1	1	1				
		0: Indica							

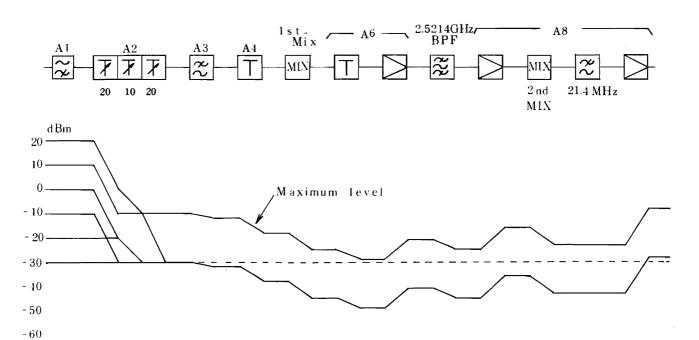


Fig. 3-8 (a) RF Section Level Diagram (MS2601A)

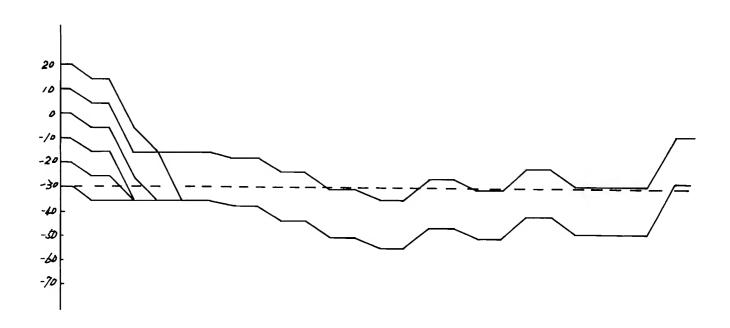


Fig. 3-8 (b) RF Section Level Diagram (MS2601J)

- (b) PLL section (LOCAL section) troubleshooting
  - (i) Required equipment

Digital voltmeter

Frequency counter: MF76A

Oscilloscope

Spectrum analyzer: MS612A (with high-

impedance probe)

(ii) Preparation

——— CAUTION ———

Turn off the power before disassembly

Step	Procedure							
1	Remove the bottom cover (Paragraph 2.2).							
2	Remove the cover of the unit to be checked by referring to Fig. 2-6.							

### (iii) Troubleshooting

The troubleshooting procedures for the following circuits are described below.

- 1. A1-A13 50 kHz/50 MHz STEP SYNTH
- 2. A1-A15 20 Hz STEP VCO CONT
- 3. A1-A16 YTO PLL PD & LOOP FILTER
- 4. A1-A12 2nd LOCAL PLL

a) Al-Al3 50 kHz/50 MHz STEP SYNTH (Fig. 3-20, 12) troubleshooting

Step	Pro	ocedure
1	on. If they are both	r not the Q10 and Q44 LEDs are off, the 50 kHz-step z-step synthesizer are locking
	If only the Q10 LED i	- ·
	If only the Q44 LED i synthesizer is unlock	<u>-</u>
	When Q10 is on, check check steps 6 to 8.	steps 2 to 5; when Q44 is on,
	Troubleshooting the 5 described in steps 2	0 kHz-step synthesizer is to 6.
	- 50 kHz-step synthesi	zer troubleshooting
2	Check the following v	oltages.
	Checkpoint	Normal condition
	J9-13	+11.5 to +12.5 V
	Terminal (1) 2	-11.5 to -12.5 V
	Q16-16 <b>3</b>	+4.75 to +5.25 V

neck the J1 reference input (500 kHz).  1 4 500 kHz TTL level  1 neck the linearity of the 110.4 to 160.35 MHz VCO  2 sing the following procedures.
neck the linearity of the 110.4 to 160.35 MHz VCO
-
then short-circuit between pins 2 and 3 of J6 6 with J5 (the synthesizer enters an unlocked condition).
2) Set the MS2601A/J as follows:
START FREQ: 0 Hz
SPAN: 0 Hz
Change the START FREQ setting, and check that the 110.4 to 160.35 MHz VCO output frequency (J2 6) changes according to the following table.

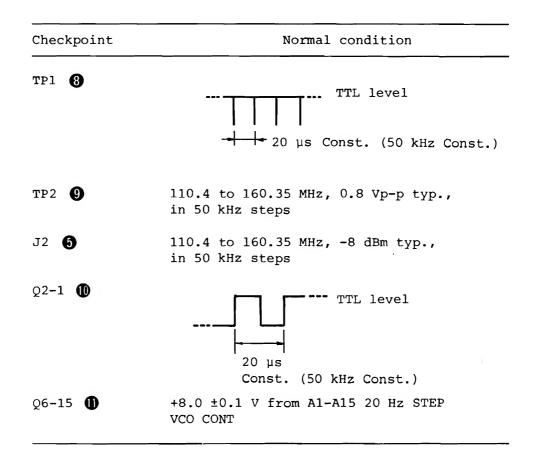
START FREQ Setting	TP3 voltage 7	Frequency at J2 6
0 Hz	-4.5 V typ.	110.4 MHz ±1.0 MHz
49.95 MHz	+5 V typ.	160.35 MHz ±4.0 MHz

If the 110.4 to 160.35 MHz VCO output frequency is abnormal, readjust the linearity of the 110.4 to 160.35 MHz VCO (paragraph 3.3.4 (4) (iii)).

(continued)

Step	Procedure	

5 Check the signal at each checkpoint according to the following table.



### Notes:

 The output frequency (J2 6) of the 50 kHzstep synthesizer changes in 50 kHz steps, which is equal to the 50 kHz step changes of the START or CENTER FREQ.

		(cont
Step	Pro	ocedure
5 (Cont.)	Notes: (cont.)	
	1. (cont.)	
	Example	
	START FREO (MHz)	50 kHz-step synthesizer

START FREQ (MHz)	output frequency (MHz)
x x00.00x xxx	110.400
X X00.05X XXX	110.450
X X00.10X XXX	110.500
:	<b>:</b> :
x x49.95x xxx	160.350
x x50.00x xxx	110.400
x x50.05x xxx : :	110.450
X x99.95x XXX	160.350

- 2. The signal purity and spurious allowance of the 50 kHz-step synthesizer output are as follows:
  - . Signal purity (observed by MS612A)
     <-65 dBc at ±2 kHz offset from output
     frequency (At RBW 100 Hz of the MS612A)
     <-75 dBc at ±10 kHz offset from output
     frequency (At RBW 100 Hz of the MS612A)</pre>
  - . Spurious
     <-55 dBc at ±50 kHz offset from output
    frequency.</pre>

Step Procedure

6 Check the set value of the 1/N divider and D/A converter according to Table 3-10.

Table 3-10 l/N Divider and D/A Converter Set Values from the A8 MAIN CPU

VCO oscilla-			t V	alu	e o	f D	/A	Cor	ıveı	rte:	r	Set Q19		1ue	of	1/	'n D	ivi	der (Q16,	Q17	, ç	18,	and
tion fre- quency	N					6 p						Q19 pin	No		_	n N			Q17 pin No.		_		No.
(MHz)		4	5	6	7	8	9	10	11	12	13	10	1	15	9	10	1	15	15	9	10	1	15
110.40	2208	0	0	0	0	0	0	0	0	0	0	1	0	0	0	1	0	0	0	0	0	0	0
110.45	2209	0	0	0	0	0	0	0	0	0	1	1	0	0	0	1	0	0	0	0	0	0	1
110.50	2210	0	0	0	0	0	0	0	0	1	0	1	0	0	0	1	0	0	0	0	0	1	0
110.55	2211	0	0	0	0	0	0	0	0	1	1	1	0	0	0	1	0	0	0	0	0	1	1
110.60	2212	0	0	0	0	0	0	0	1	0	0	1	0	0	0	1	0	0	0	0	1	0	0
110.65	2213	0	0	0	0	0	0	0	1	0	1	1	0	0	0	1	0	0	0	0	1	0	1
110.70	2214	0	0	0	0	0	0	0	1	1	0	1	0	0	0	1	0	0	0	0	1	1	0
110.75	2215	0	0	0	0	0	0	0	1	1	1	1	0	0	0	1	0	0	0	0	1	1	1
110.80	2216	0	0	0	0	0	0	1	0	0	0	1	0	0	0	1	0	0	0	1	0	0	0
:	:						:						:				:		:			•	
:	:						:										:		:			:	
: 160.30	3206	1	1	1	1	1	:	0	1	1	0	1	:	0	0	0	:	1	: 0	0	1	:	0
160.35	3207	1	1	1	1	1	0	0	1	1	1	1	1	0	0	0	1	1	0	0	1	1	1
				_				-	_	_	_					-	_				_	_	_

Note: TTL level (positive logic)

		(Continued)
Step	Proce	dure
	Troubleshooting the 50 M described below in steps	
	50 MHz-step synthesizer	troubleshooting
7	Check the following volt	ages:
	Checkpoint	Normal condition
	Terminal 2 1	+11.5 to +12.5 V
	Terminal ③ <b>⑥</b>	+11.5 to +12.5 V
	Terminal 4	-11.5 to -12.5 V
	Terminal (7)	-11.5 to -12.5 V
	Q35-16 <b>19</b>	+4.75 to +5.25 V
8		utput TP7 <b>②</b> signal, which se detector reference input,
	The TP7 signal frequency output frequency/2M).	is (50 kHz-step synthesizer

Step Procedure

8 (Cont.)

Table 3-11 Relationship between 2M Value and the TP7 Signal

START FREQ (MHz)	2M value	TP7 <page-header> signal (MHz)</page-header>	
0	96	1.15 (110.4 MHz/96) Waveform	1
50	98	1.126530 (110.4 MHz/98)	
100	100	1.104 (110.4 MHz/100)	
150	102	1.082353 (110.4 MHz/102) TTL leve	1
•	•		
1000	136	0.811765 (110.4 MHz/136)	
:	:		
2200	184	0.6 (110.4 MHz/184)	
100.050	100	1.1045 (110.45 MHz/100)	
100.100	100	1.1050 (110.50 MHz/100)	
100.150	100 :	1.1055 (110.55 MHz/100)	
149.900	100	1.6030 (160.30 MHz/100)	
149.950	100	1.6035 (160.35 MHz/100)	
150.000	102	1.082353 (110.4 MHz/102)	
150.050	102	1.082843 (110.45 MHz/102)	

When the TP7 ② signal is abnormal, an error occurs at the 1/2M divider which is composed of Q32, Q35, Q36, Q37, etc.

Check the 2M set value in accordance with Table 3-12.

### Notes:

 The 2M value increases from 96 to 184 for START FREQ setting of 0 to 2200 MHz, and changes in double steps for a 50 MHz change in the START FREQ setting. Step Procedure

8 Notes: (cont.)
(Cont.)

2. The signal frequency at TP7 ② can be calculated from the following equation.

50 kHz-step synthesizer output frequency/2M (110.4 to 160.35 MHz)

Table 3-12 Set Value of the 1/2M Divider from the A8 MAIN CPU

START FREQ	2M	Q37 Pin No.		Q36 in				35 n N	0.
(MHz)		15			1 1	5		10	1
0	96	0	1	0	0	0	0	1	1
50	98	0	1	0	0	0	1	0	0
100	100	0	1	0	0	1	0	0	0
150	102	0	1	0	0	1	0	0	1
200	104	0	1	0	0	1	0	1	0
250	106	0	1	0	0	1	0	1	1
300	108	0	1	0	0	1	1	0	0
350	110	0	1	0	1	0	0	0	0
400	112	0	1	0	1	0	0	0	1
450	114	0	1	0	1	0	0	1	0
500	116	0	1	0	1	0	0	1	1
550	118	0	1	0	1	0	1	0	0
600	120	0	1	0	1	1	0	0	0
			•	_	_	_	•	_	
2150	182	1	0	0	0	1	0	0	1
2200	184	1	0	0	0	1	0	1	0

Note:

TTL level (positive logic)

Step	Procedure

9 Check the signal at each checkpoint in accordance with the following table.

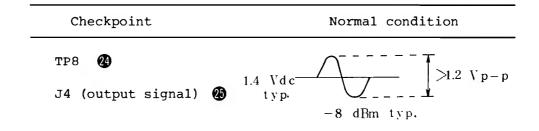


Table 3-13 Relationship between START FREQ and 50 MHz-Step Synthesizer Output (J4) Frequency

START FREQ (MHz)	М	50 MHz-step synthesizer output (J4) frequency (MHz)
0	48	52.3 (50 MHz + 1.5 MHz x 2)
50	49	52.25306 (50 MHz + 1.126530 MHz x 2)
100	50	52.208 (50 MHz + 1.104 MHz x 2)
150	51	52.164706 (50 MHz + 1.082353 MHz x 2)
•	•	: :
1000	68	51.62353 (50 MHz + 0.811765 MHz x 2)
•	:	
2200	92	51.2 (50 MHz + 0.6 MHz x 2)
100.050	50	52.209 (50 MHz + 1.1045 MHz x 2)
100.100	50	52.21 (50 MHz + 1.1050 MHz x 2)
100.150	50 :	51.211 (50 MHz + 1.1055 MHz x 2)
149.900	50	53.206 (50 MHz + 1.6030 MHz x 2)
149.950	50	53.207 (50 MHz + 1.6035 MHz x 2)
150.000	51	52.164706 (50 MHz + 1.082353 MHz x 2)
150.050	51	52.165686 (50 MHz + 1.082843 MHz x 2)

### Note:

The 50 MHz-step synthesizer output frequency (J4) can be calculated from the following equation.

(50 kHz-step synthesizer output frequency/2M) x 2 + 50 MHz = (50 kHz-step synthesizer output frequency/M) +50 MHz

b) A1-A15 20 Hz STEP VCO CONT troubleshooting (Fig. 3-22, 14)

1	Į,	Я	
	В	4	

Step		Procedur	e			
1	Check the following	g voltage	:s:			
	Checkpoint	Norm	al cond	ition		
	Terminal (1)	-11.	5 to <b>-</b> 1	2.5 V	7	
	Terminal (2) 2	+11.	5 to +1	2.5 V	,	
	Q8 <b>3</b>	+4.7	'5 to +5	.25 V	•	
		rante.				
	Checkpoint TPl (Reference +8		ormal cond	dition		
	Checkpoint	No	/dc Y	 Q7	(ana	
	Checkpoint TPl <b>5</b> (Reference +8	.00 ±0.05 V	/dc	 Q7	(ana	log n No.
	Checkpoint  TP1 (Reference +8 voltage)	.00 ±0.05 N	/dc Y	Q7 swite	(ana h) pi	n No.
	Checkpoint  TP1 (Reference +8 voltage)	.00 ±0.05 V	Y (Vp-p) Approx.	Q7 switce	(ana h) pi 8	n No.
veep Vol	Checkpoint  TP1 (Reference +8 voltage)	SPAN set value 500 kHz 50 kHz	Y (Vp-p)  Approx. 8.0 Approx.	Q7 switc 1	(ana h) pi 8	9 1

(continued)

Step			Procedure			
2 (Cont.)		_	(Cont.)			
	Chec	kpoint	Normal condition			
	TP6	•	TTL level 200 to 310 kHz			
	TP7	7 8	1 2 3 4 5 6 7 8 1 2 3  8 pulses  Approx. 250 ns (Approx 4 MHz)			

Check the relationship between the TP4 voltage and the 11.0 to 11.5 MHz VCO output frequency (A1-A16, J2 ) in accordance with the following table.

Condition	START FREQ (SPAN O Hz)	TP4	J2 <b>7</b> frequency in A1-A16
CORR D OFF	1.0 MHz	Approx. 0 V	11.0 MHz ±15 kHz
	1.049 980 MHz	Approx. 5.0 V	11.049 980 MHz ±15 kHz

If the above-mentioned frequency is abnormal, readjust the A1-A15 20 Hz STEP VCO CONT (paragraph 3.3.4 (4) (b) (ii)).

Step

#### Procedure

### 3 (Cont.)

Note:

When CORR D ON at the normal condition of frequency control, the 20 Hz STEP VCO CONT compensates the 11.0 to 11.55 MHz VCO (in Al-Al6 YTO PLL PD & LOOP FILTER) frequency error.

Frequency error, which is found during Maintenance use setting of CORR D OFF, is compensated to set the frequency to the specified value by the (+) or (-) compensation value.

Table 3-14 shows the relationship with the frequency setting.

The 11.0 to 11.5 MHz VCO frequency, which is controlled by this A1-A15 20 Hz STEP VCO CONT circuit, changes in 20 Hz steps, which is equal to the change in the START FREQ setting of 20 Hz, as shown below.

SI	ART FREQ	at (	SPAN	11.0 to	11.5 MH	ız VC	0:
0	Hz			output	frequenc	ЭУ	
X	xxx.x00	000	(MHz)	Approx.	11.000	000	(MHz)
Х	XXX.X00	020		Approx.	11.000	020	
X	XXX.X00	040		Approx.	11.000	040	
Х	XXX.X00	060		Approx.	11.000	060	
	:				:		
	:				:		
Х	XXX.X49	980		Approx.	11.049	980	
X	XXX.X50	000		Approx.	11.000	000	

Where, the above-mentioned VCO frequency value occurs after frequency calibration.

Step Procedure

3 Note: (cont.)
(Cont.)

Table 3-14 Relationship with frequency Setting

Set frequency (kHz)	11.0 to 11.55 MHz VCO (A1-A16 J2 7 , specified frequency value)	TP4 typ. (V)	(M	SB)	Q5 6	(D/:		onv 9		er)	-			(LSE	3)
+15.94 For (+) +15.92 compensation (At CORR D ON) +0.04 +0.02		+6.5	1 1 1	1 1 1		1 1 0 0	1 1 1	1 1 1 1	1 1 1	1 1 0 0		1 1 0		1 0	
49.98 49.96 Set : frequency : at CORR : D OFF 0.04 0.02 0.00	11.04998 11.04996         	+5.0	1 1 0 0	1 1 0 0	_	0 0 1 1		1 1 0 0	1 1 0 0	0 0 0	0 0 0	0 0 0	0 0 1	0 -	0.08 kHz compensa- tion
-0.02 -0.04 For (-) : compen- : sation : (At -15.94 CORR -15.96 D ON)		-1.5	0 0 0 70	0 0 0 0	0	1 1 0 0	0 0	0 0 0	0 0	1 1 0 0	1 1 0 0	1 1 0 0	0	0 -	(See example
					le	vel	. ( <u>F</u>	osi	tiv	ve 1	logi	ic)			

## Example:

When the 11.0 to 11.55 VCO frequency is larger than the specified frequency by +0.08 kHz at START FREQ X XXX.X00 040 MHz (CORR D ON), the +0.08 kHz is compensated and the signal to Q5 becomes 0011 0001 1100 as shown in Table 3-14.

4	-	
ı	J	

tep		Procedure
1	Check the followi	ng voltages:
	Checkpoint	Normal condition
	Terminal 4	+11.5 to +12.5 V
	Terminal (5) 2	-11.5 to -12.5 V
	Q12-14 <b>3</b>	+4.75 to +5.25 V
2	Check the signal with the followin	at each checkpoint in accordanc
	Checkpoint	Normal condition
	TP1 , TP2  4	\(\sigma\) \(\sigma\) \(\sigma\)
	<b>9 5</b>	dc
	4 6 Approx. 3.8 Ve	11.0 to 11.55 MHz
	Approx. 3.8 Venue of the second of the secon	-3 dBm typ. 11.0 to 11.55 MHz  +4 dBm typ.

TP4 🕕 >-50 dBm at 50 ohm termination, 11.0 to 11.55 MHz

If this TP4 **(1)** signal is abnormal, the A1-A10 sampler output may not be output normally. Therefore, check the A1-A14 PULSE AMP and A1-A9 1st LOCAL AMP.

If TP3 9 voltage is abnormal, check A6 SCAN/YTO DRIVE.

d) A1-A12 2nd LOCAL PLL (Fig. 3-19, 11) troubleshooting

Step	Procedure
1	Check the following voltages:
	Checkpoint Normal condition
	Terminal 9 1 +11.5 to +12.5 V
	Terminal (0) <b>2</b> -11.5 to -12.5 V
2	Check the signal at each checkpoint in accordance with the following table.
	Checkpoint Normal condition
	Terminal 1 >+3 dBm (Sampling signal from A7 50 MHz REF OSC) 3
	Terminal 3 +3.0 V typ.  (2.5 GHz cavity OSC control signal) 3
	Terminal (5) <b>7</b> -11.4 V typ.
	Terminal 6 8 +8.0 V typ.
	If Terminal (1) (3) is abnormal, check the A7 REF OSC.
	If terminal 3 6 is abnormal, check the sampler output and Search OSC output shown in the following table.

(continued)

Step

Procedure

2 (Cont.)

Checkpoint

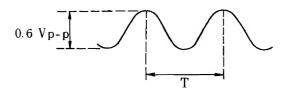
Normal condition

Check the following with J1 removed from J2 (PLL off).

(a) Sampler

TP1 (Sampler output)

9

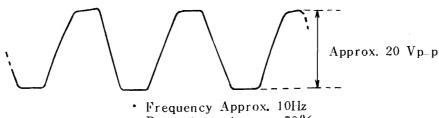


$$\left(\frac{1}{T}\right) = 2500 \text{ MHz} - \left(\begin{array}{cc} 2.5 \text{ GHz} & \text{Cavity OSC} \\ \text{output} & \text{frequency} \end{array}\right)$$

 $\leq 300 \text{ kHz}$ 

(b) Search OSC

Q9-7 pin (Search OSC output)



• Duty factor Approx. 50%

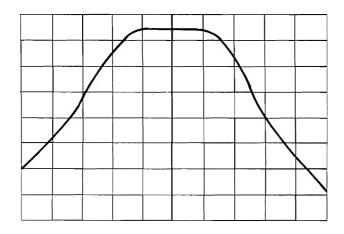
If the above-mentioned signals are abnormal, readjust the A1-A12 2nd LOCAL PLL (paragraph 3.3.4 (4) (iv)).

# (4) Al RF/PLL BLOCK Adjustment

The following paragraph first describes how to adjust the RF section and then the PLL section (LOCAL section)

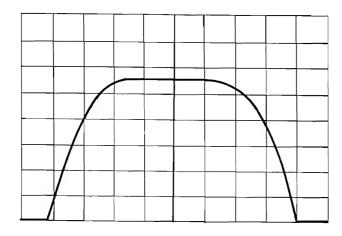
- (a) RF section adjustment
  - (i) 2.5214 GHz BPF adjustment

Step	Procedure
1	Remove the A2 IF BPF by referring to paragraph 2.4.
2	Solder the extender cable to Terminal 7 (21.4 MHz OUT) 1 in A1-A8 2nd CONV and connect the other end of the extender cable to the MS612A Spectrum Analyzer.
3	Set the MS2601A/J as shown below.  CENTER FREQ: 100 MHz
	SPAN: 20 MHz
	ATT: 0 dB
4	Input a 100 MHz, -30 dBm signal to the RF INPUT.
5	Adjust the four trimmers ① (Fig. 2-6) so that the characteristic shown in Fig. 3-9 is obtained.
6	Adjust the A1-A8 2nd CONV R11 $3$ so that the output level at 21.4 MHz OUT $1$ is -28 ±1 dBm.



CENTER FREQ 21.4 MHz SPAN 20 MHz 5 dB/DIV SWEEP TIME 5 S

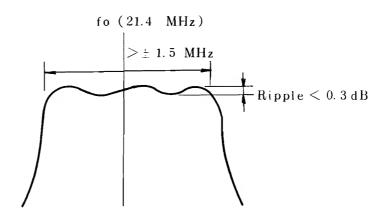
## (1) Total Pass-band/Attenuation



SPAN 10 MHz 1 dB/DIV

(2) Pass Band

Fig. 3-9 2.5214 GHz BPF Characteristics



(3) Pass Band Required Characteristic

Fig. 3-9 2.5214 GHz BPF Characteristics (Cont.)

- (b) PLL section adjustment
  - (i) A1-A16 YTO PLL PD & LOOP FILTER adjustment Adjust the 11.0 to 11.55 MHz VCO as shown below.

Step	Procedure
1	Onnect the dc voltage standard to Terminal 3  (Remove the control line connected to Terminal 3 from A1-A15 unit.)
2	Change the output voltage of the dc voltage standard as shown below and adjust the VCO oscillation frequency (J2 7) for each voltage by C39 10, L1 10 and L2 10.
	OC voltage standard output voltage (terminal 3 1 )  O V
	C39 <b>1</b> 11.50 MHz adjustment L1 <b>1</b> , L2 <b>1</b> 11.00 MHz adjustment

(ii) A1-A15 20 Hz STEP VCO CONT adjustment

Before making this adjustment, the A6 SCAN

GENERATOR adjustment (paragraph 3.3.8 (4)

(a)) and the 11.0 to 11.55 MHz VCO

adjustment (paragraph 3.3.4 (4)(b)(i)) above in the A1-A16 YTO PLL PD & LOOP FILTER must be completed.

Step	Procedure
1	Connect a digital voltmeter to TP1 $\bigcirc$ and adjust R7 $\bigcirc$ to make the voltage to +8.00 $\pm$ 0.01 V.
2	Rough-adjust the VCO tuning voltage supply circuit as shown below.
	1) Connect pin 2 to pin 3 of J5 ( with J4.
	2) Adjust R19
	3) Set the CENTER FREQ to 1.00 MHz and SPAN to 0 Hz again and adjust R13 $\textcircled{1}$ so that the TP4 $\textcircled{1}$ voltage is 0.0 $\pm$ 0.01 V.
	Afterwards, adjust R31  so that the 11.0 to 11.55 MHz VCO frequency (A1-A16 J2 ?) in the A1-A16 YTO PLL PD & LOOP FILTER is 11.0 MHz ±100 Hz.

Step		Procedure
3	Adju:	st the compensation circuit linearity as shown
	1).	Connect pin 1 to pin 2 of J5 (1) with J4.
	2)	Set the START FREQ to 1 MHz and SPAN to 500 kHz.
		Input a signal to the RF INPUT. Display the spectrum on the CRT and adjust the linearity using the following procedures.
		a) Input a 1.05 MHz signal to RF INPUT and read the signal frequency displayed on the CRT.
		b) Input a 1.45 MHz signal to RF INPUT and read the signal frequency displayed on the CRT.
		c) Adjust L7 (9) so that the frequency difference b) - a) is 400 kHz ±400 Hz.
4		lly, adjust the VCO tuning voltage supply uit as shown below.
	1)	Set the START FREQ to 1 MHz and SPAN to 0 Hz, and adjust R31  so that the 11.0 to 11.55  MHz VCO frequency (A1-A16, J2 7) is 11.0 MHz ±100 Hz.
	2)	Set the START FREQ to 1.049 980 MHz and SPAN to 0 Hz, and adjust R19  so that the 11.0 to 11.55 MHz VCO frequency is 11.049 980 MHz ±100 Hz at this time.

(iii) A1-A13 50 kHz/50 MHz STEP SYNTH adjustment
Before making this adjustment, the A7 REF
OSC (paragraph 3.3.9) and A1-A15 20 Hz STEP
VCO CONT adjustment (paragraph 3.3.4 (4)(b)
(ii)) must be completed.

Step	Procedure
خلت شک سال میں بہت	50 kHz STEP SYNTH adjustment
1	Connect pin 2 to pin 3 of J6 6 with J5.
2	Set the START FREQ to 49.95 MHz and adjust R30 $@$ so that +5.0 V is obtained at TP3 $@$ .
	Then, set the START FREQ to 0 MHz and check that approx4.5 V is obtained at TP3 7.
3	Adjust the 110.4 to 160.35 MHz VCO as shown below.
	1) Set the START FREQ to 0 MHz.
	2) Adjust L5 ② so that the VCO frequency (J2 ⑤) is 110.4 ±0.1 MHz.
	3) Set the START FREQ to 49.95 MHz.
	4) Check that the VCO frequency is 160.35 ±4 MHz.
	50 MHz STEP SYNTH adjustment
4	Adjust the 51.2 to 53.34 MHz VCO as shown below.
	1) Remove J7 connected between pins 1 and 2 of J8  ① and connect a dc voltage standard to TP19  ② .
	Connect the digital voltmeter to TP18  and adjust the dc voltage standard so that the TP18  voltage is as follows. Adjust C82  and L11  so that the VCO frequency (J4  for the TP18  voltage is as follows.

		(continued)
Step		Procedure
4 (Cont.)		
	Voltage TP18 <b>(1)</b>	VCO frequency (J4 2)
	0 V	51.2 +0 -0.1 MHz
	-5 V	53.34 ±0.1 MHz
	C82 😲 .	53.34 MHz adjustment
	L11 <b>②</b>	51.2 MHz adjustment

(iv) A1-A12 2nd LOCAL PLL adjustment

Step	Procedure						
1	Remove J1 from J2 🕕 .						
2	Connect an oscilloscope to Q9-pin 7 $ lacktriangledown$ .						
3	Adjust R20 <b>B</b> so that the duty factor of the search OSC waveform at <b>D</b> is approx. 50%.						
4	Connect an oscilloscope to TP5 9 .						
5	Turn the 2.6 GHz Cavity OSC trimmer (Fig. 3-10 ) to set the 2.5 GHz cavity OSC frequency (rear panel SECOND LOCAL OUTPUT) to 2500 MHz ±100 kHz.						
6	Adjust R21 $0$ so that the TP5 $9$ beat voltage is 0.7 Vp-p.						
7	Connect J1 to J2 $ lacktrla$						
8	Connect an oscilloscope to Q9-pin 7 $ lacktriangledown$ .						
9	Adjust the 2.5 GHz Cavity OSC trimmer (Fig. 3-10 ) so that the Q9-pin 7  voltage is approx. 0 Vdc.						

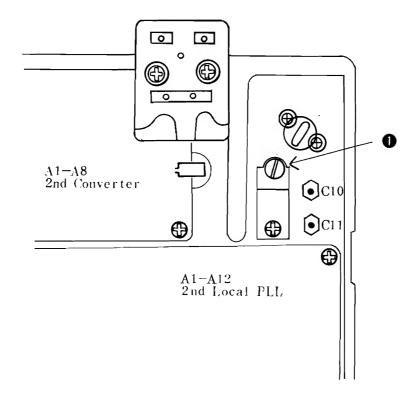
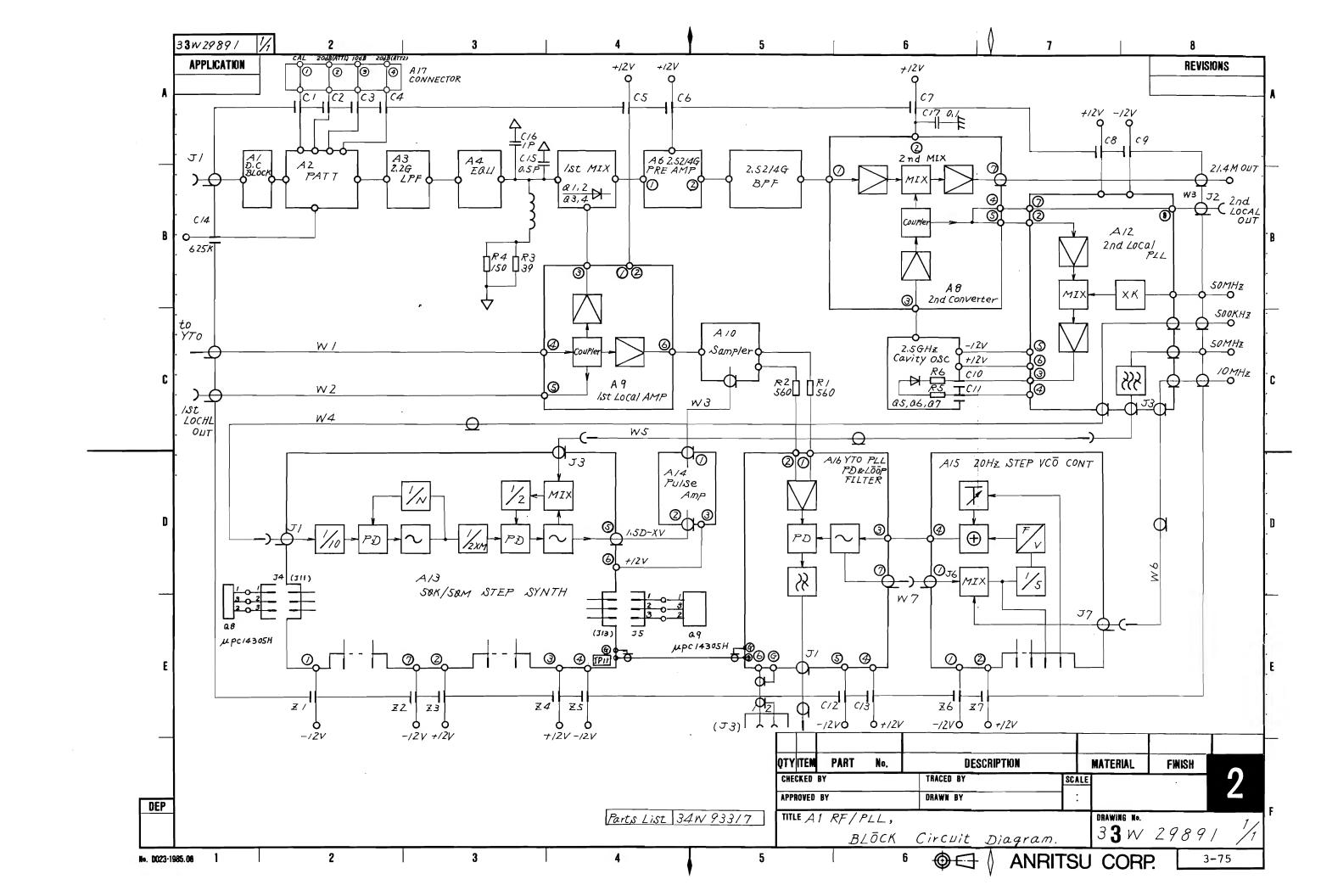
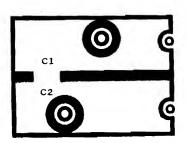


Fig. 3-10 2.5 GHz Cavity OSC





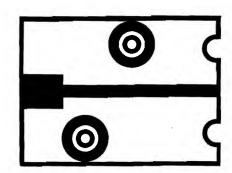
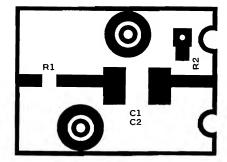


Fig. 3-11 (a) A1-A1 Dc Block
PC Board Parts
Layout
(MS2601A) 3

Fig. 3-11 (b) Al-Al Dc Block
PC Board Parts
Layout
(MS2601A OPT 05)



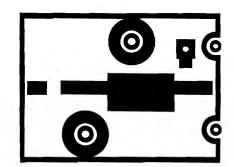
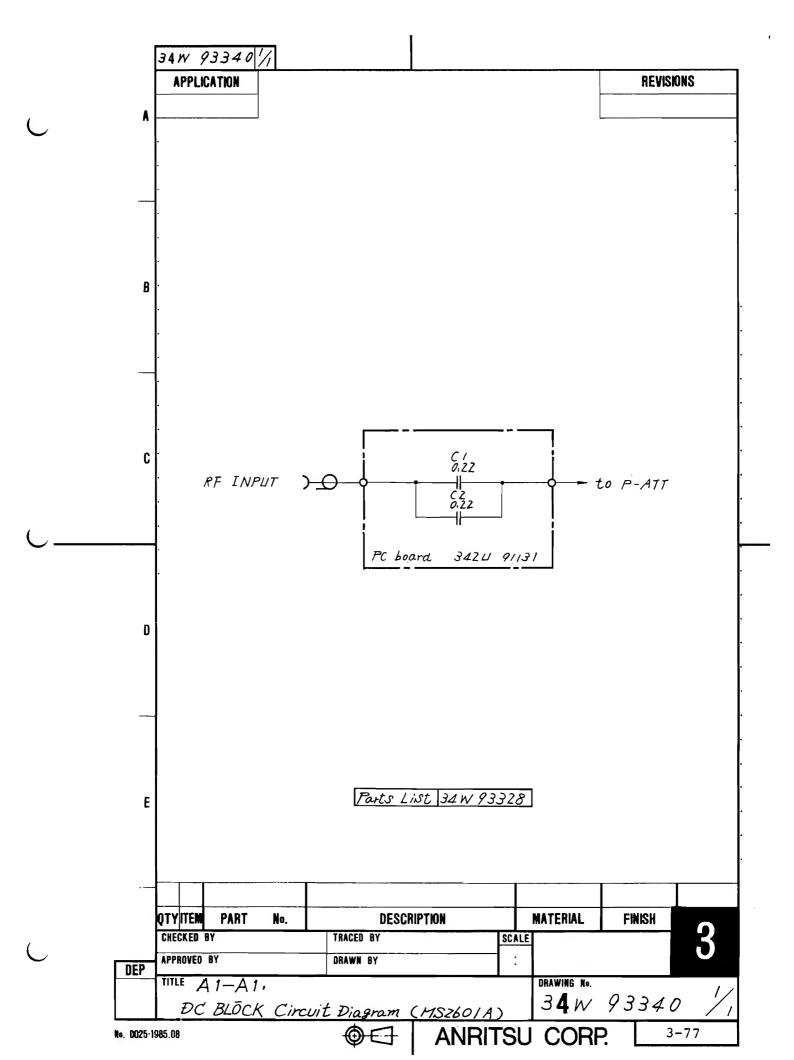
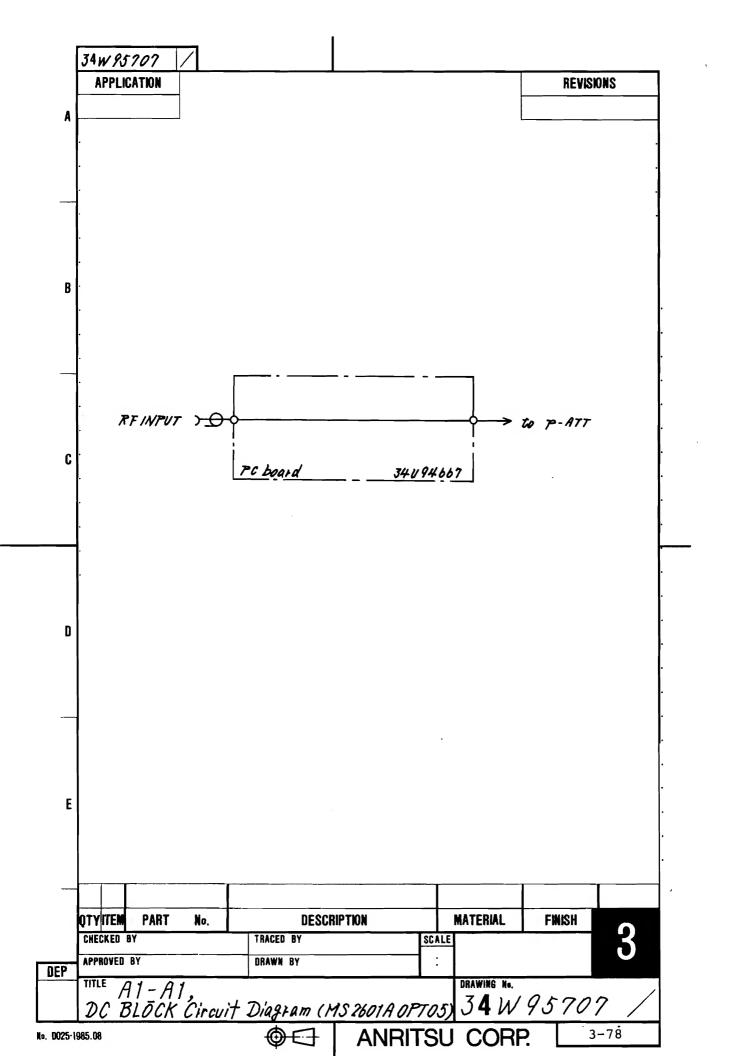
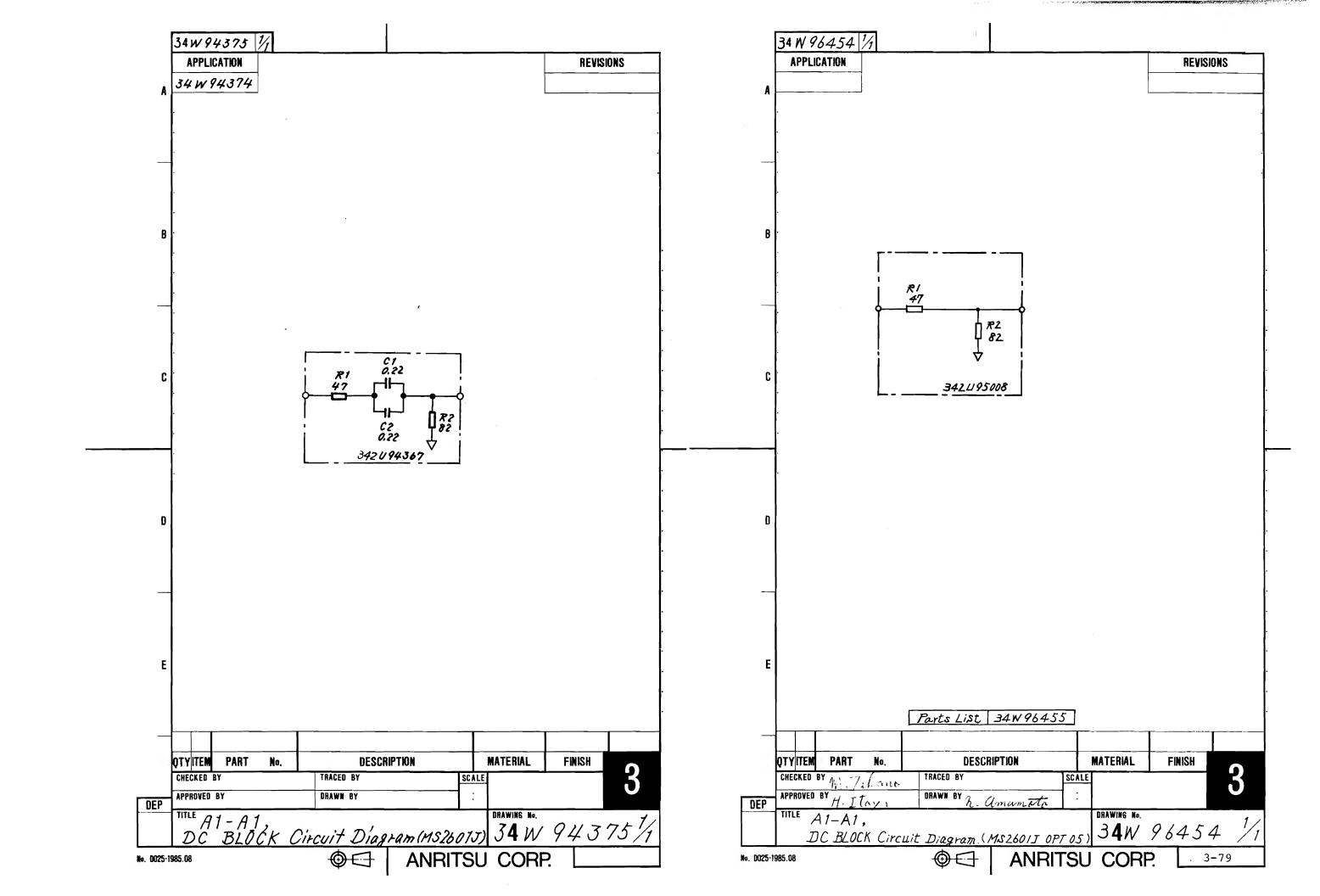


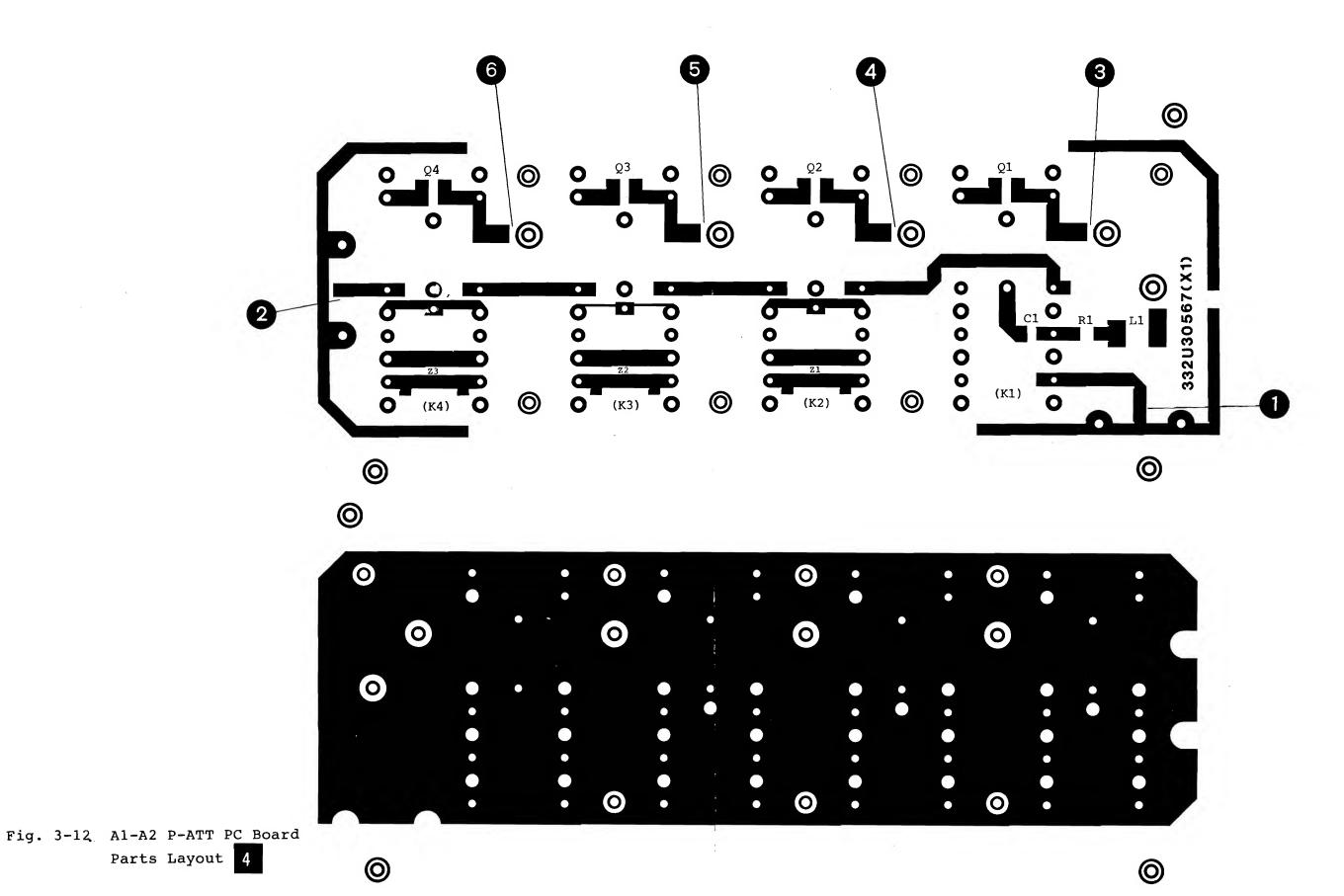
Fig. 3-11 (c) A1-A1 Dc Block PC Board Parts Layout (MS2601J)

Fig. 3-11 (d) A1-A1 Dc Block
PC Board Parts
Layout
(MS2601J OPT 05)

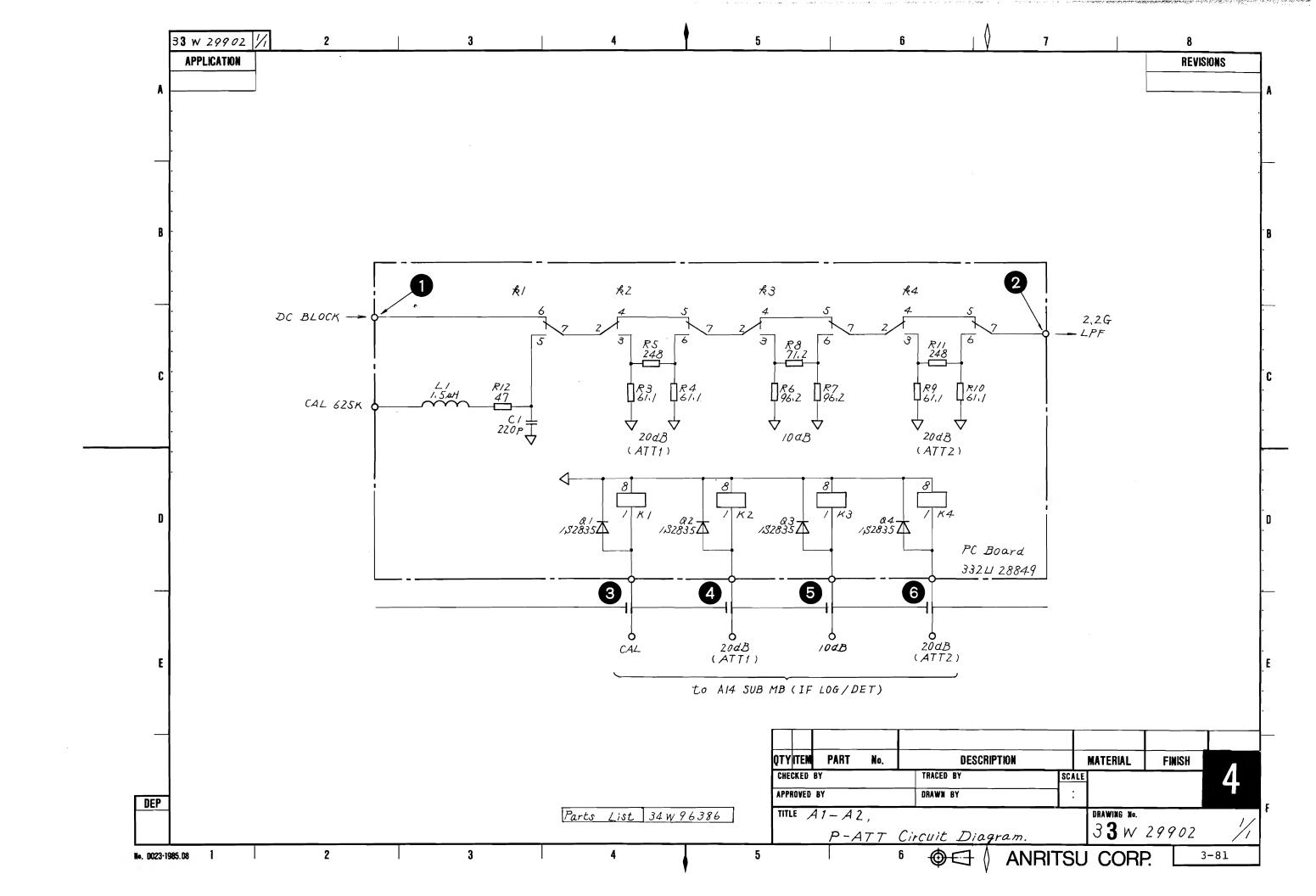








3-80



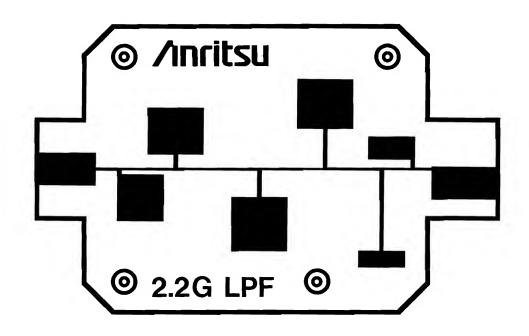
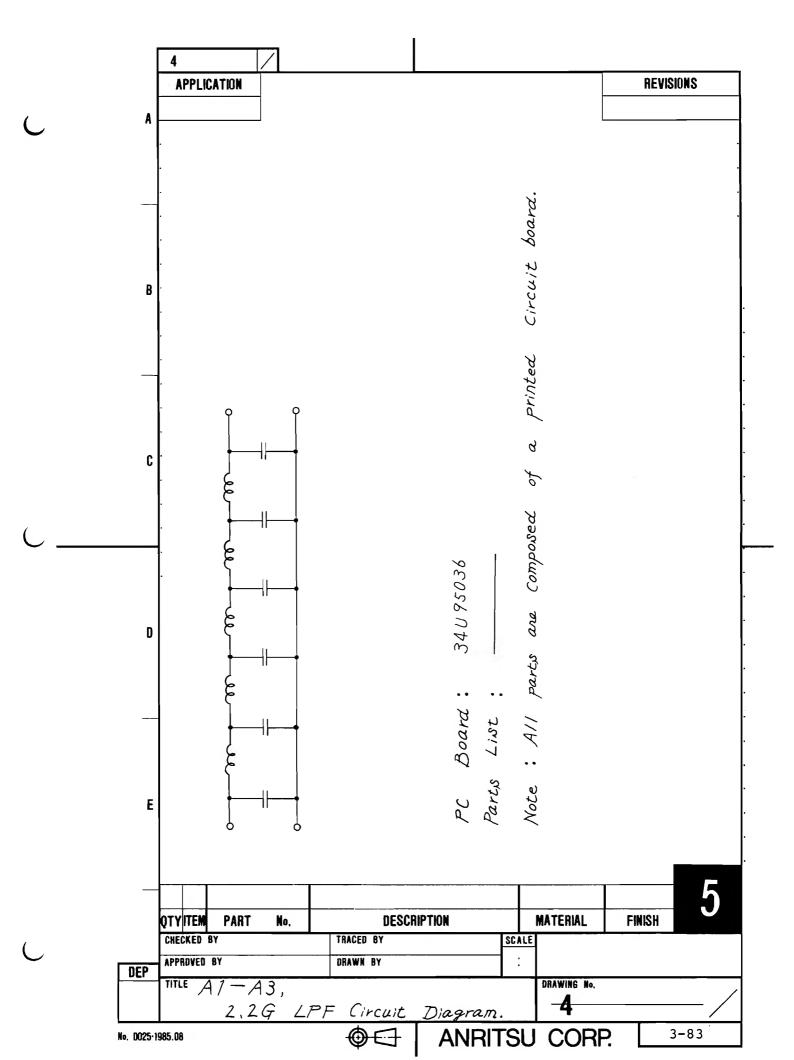


Fig. 3-13 Al-A3 2.2 G LPF
PC Board Layout 5



/inritsu

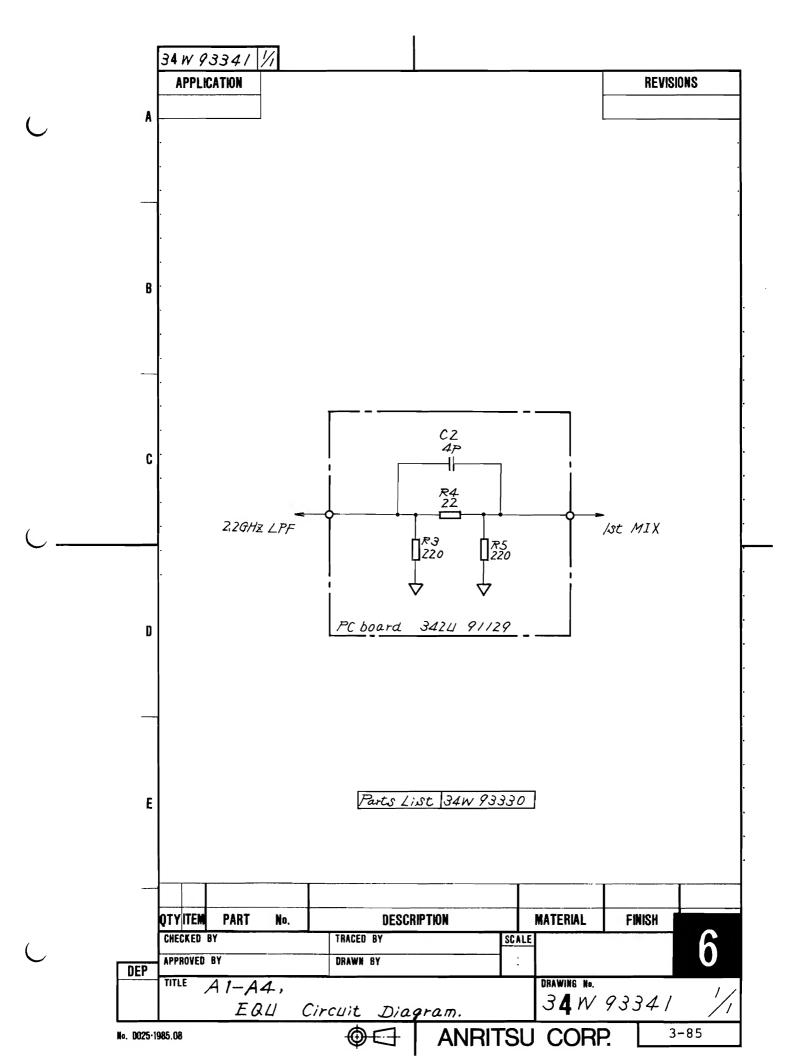
A4 EQU

C2

R4 - 9

342U 8 91129(Y1)

Fig. 3-14 A1-A4 EQU PC Board Parts Layout 6



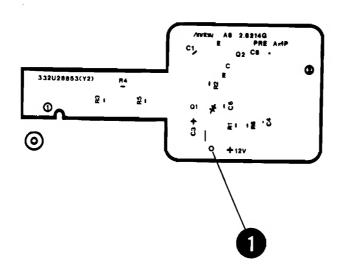
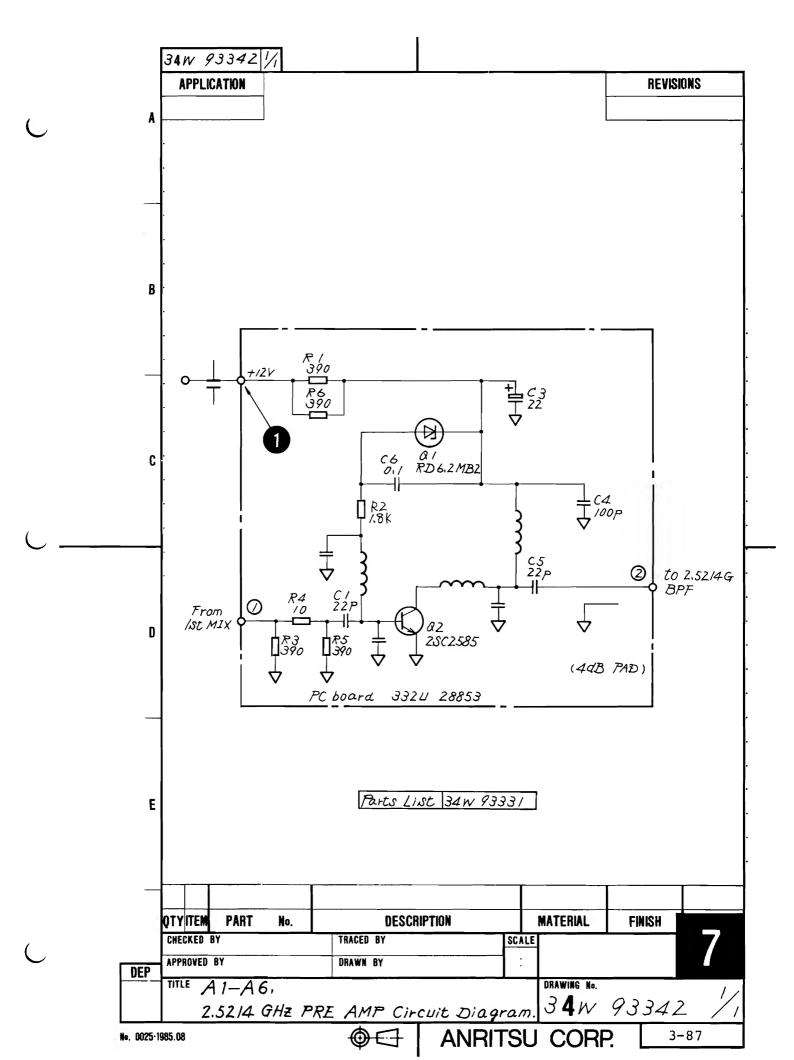


Fig. 3-15 Al-A6 2.5214 GHz PRE AMP
PC Board Parts Layout 7



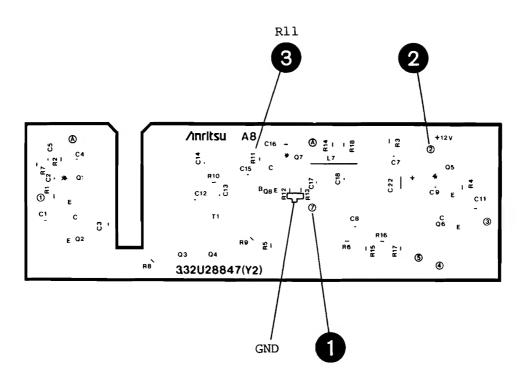


Fig. 3-16 Al-A8 2nd CONV PC Board
Parts Layout 8

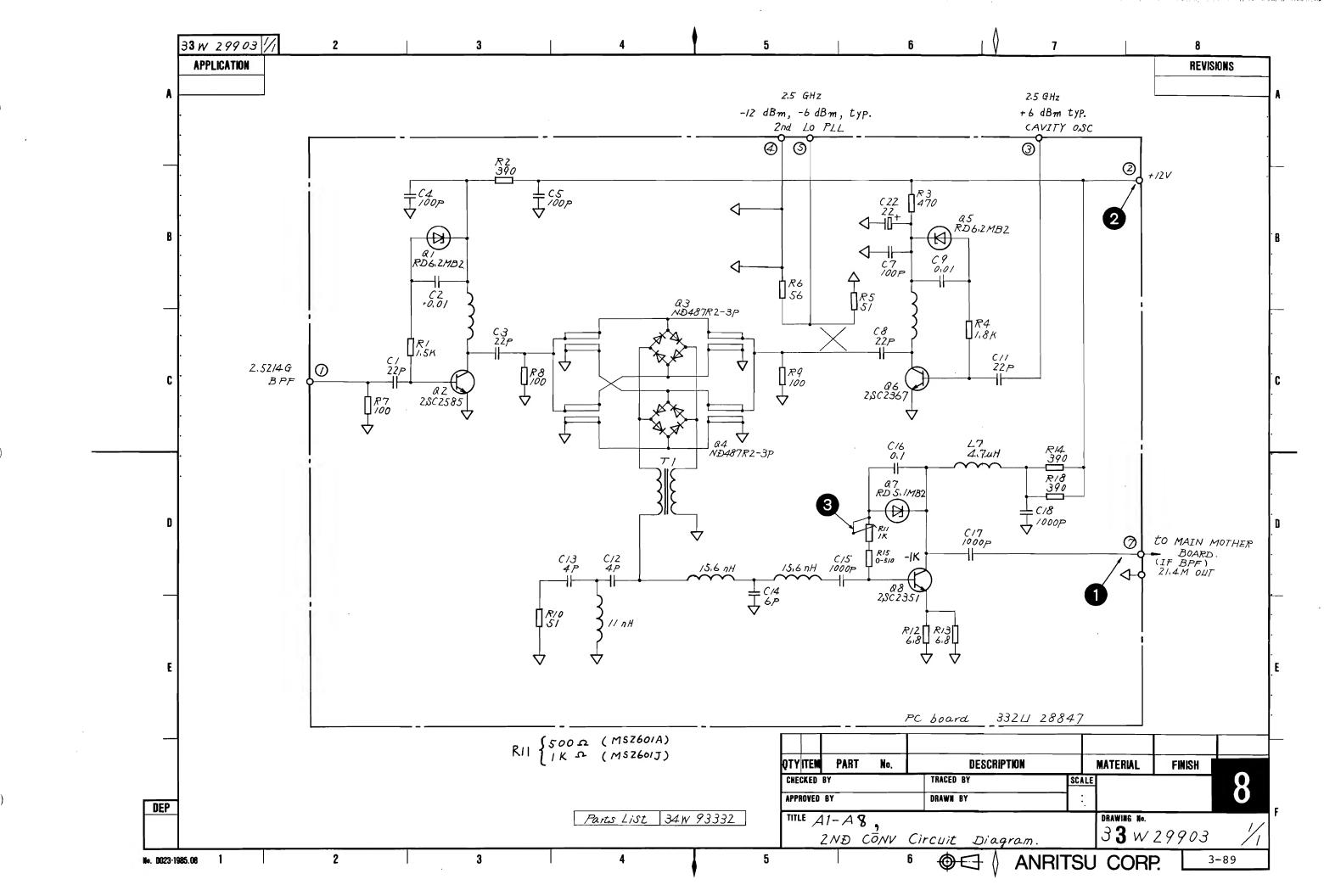
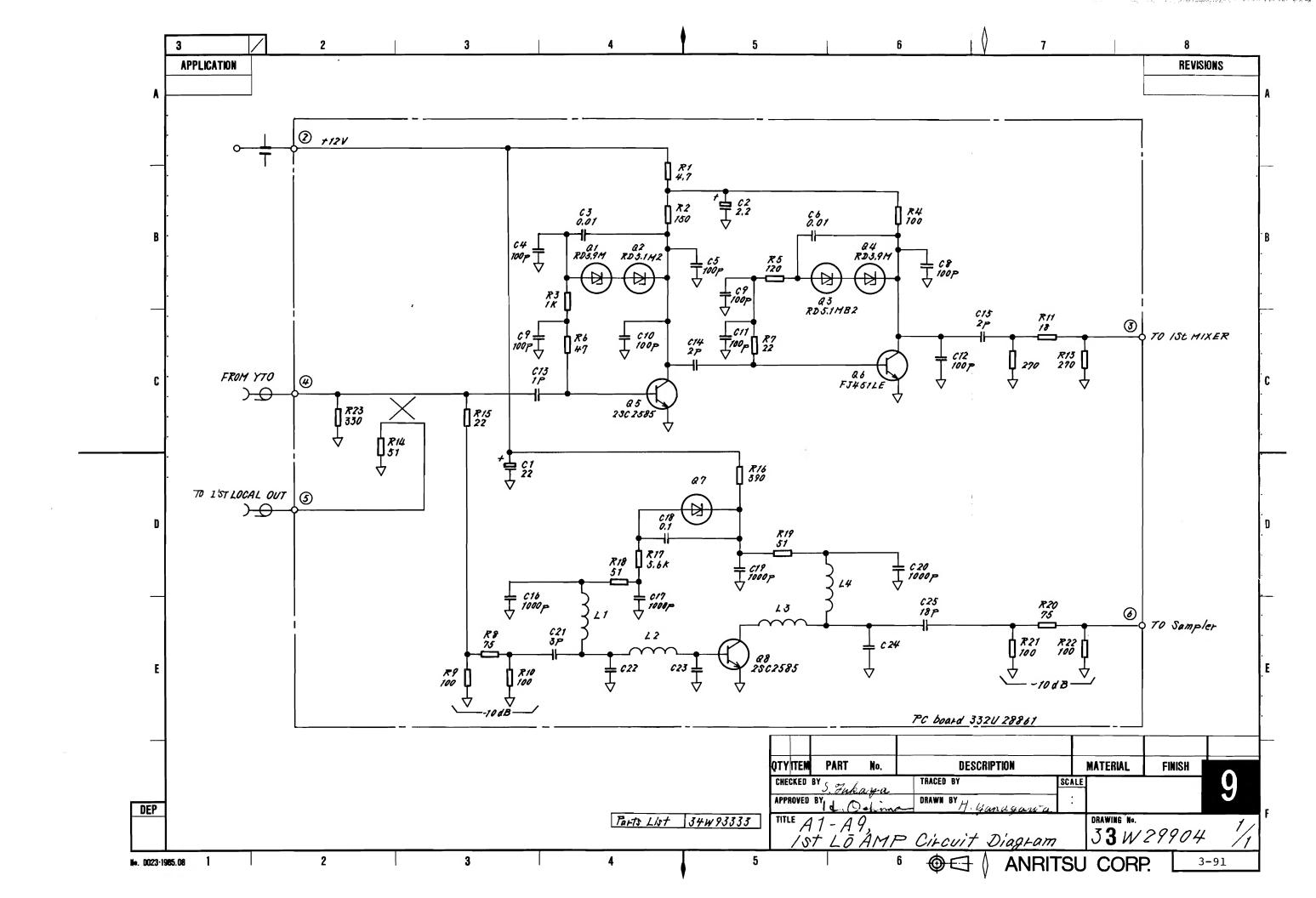


Fig. 3-17 Al-A9 1st LOCAL AMP PC Board
Parts Layout 9



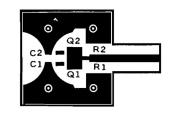
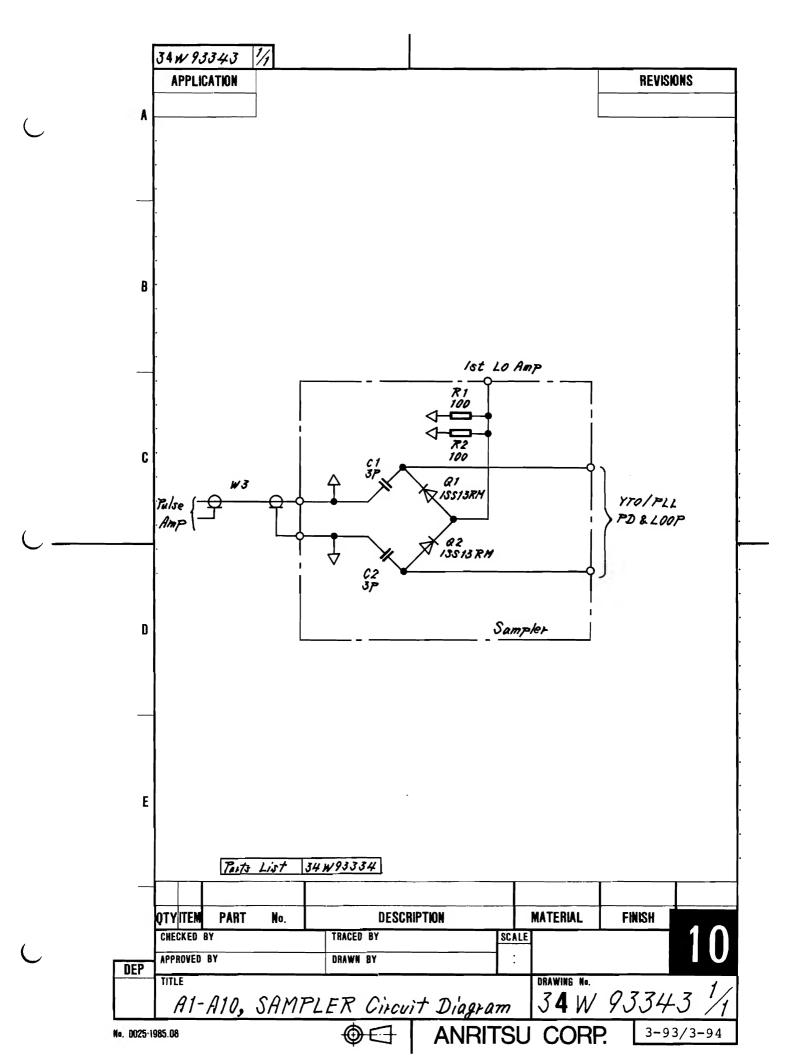


Fig. 3-18 A1-A10 SAMPLER PC Board Parts Layout 10



		<b>J</b>

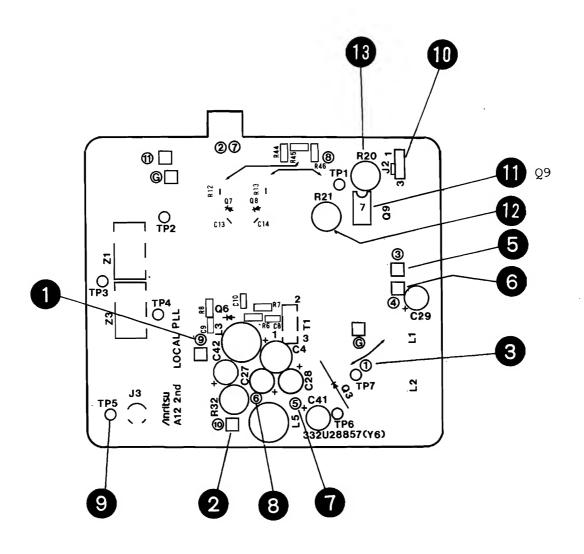


Fig. 3-19 (a) Al-Al2 2nd LOCAL PLL PC Board
Parts Layout (Parts Side)

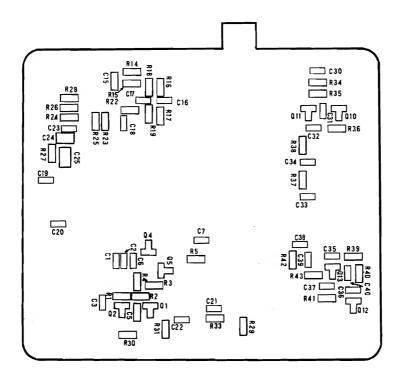
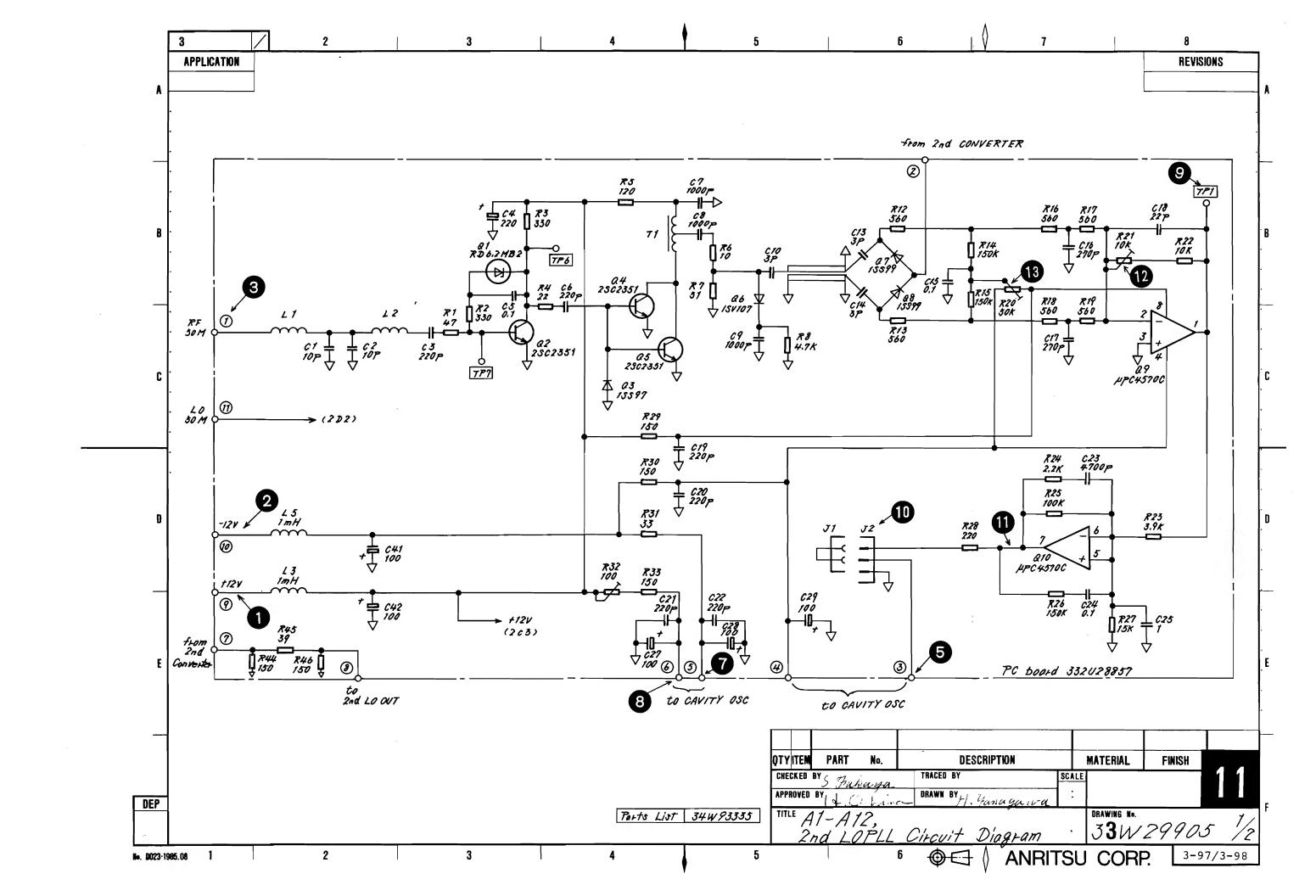
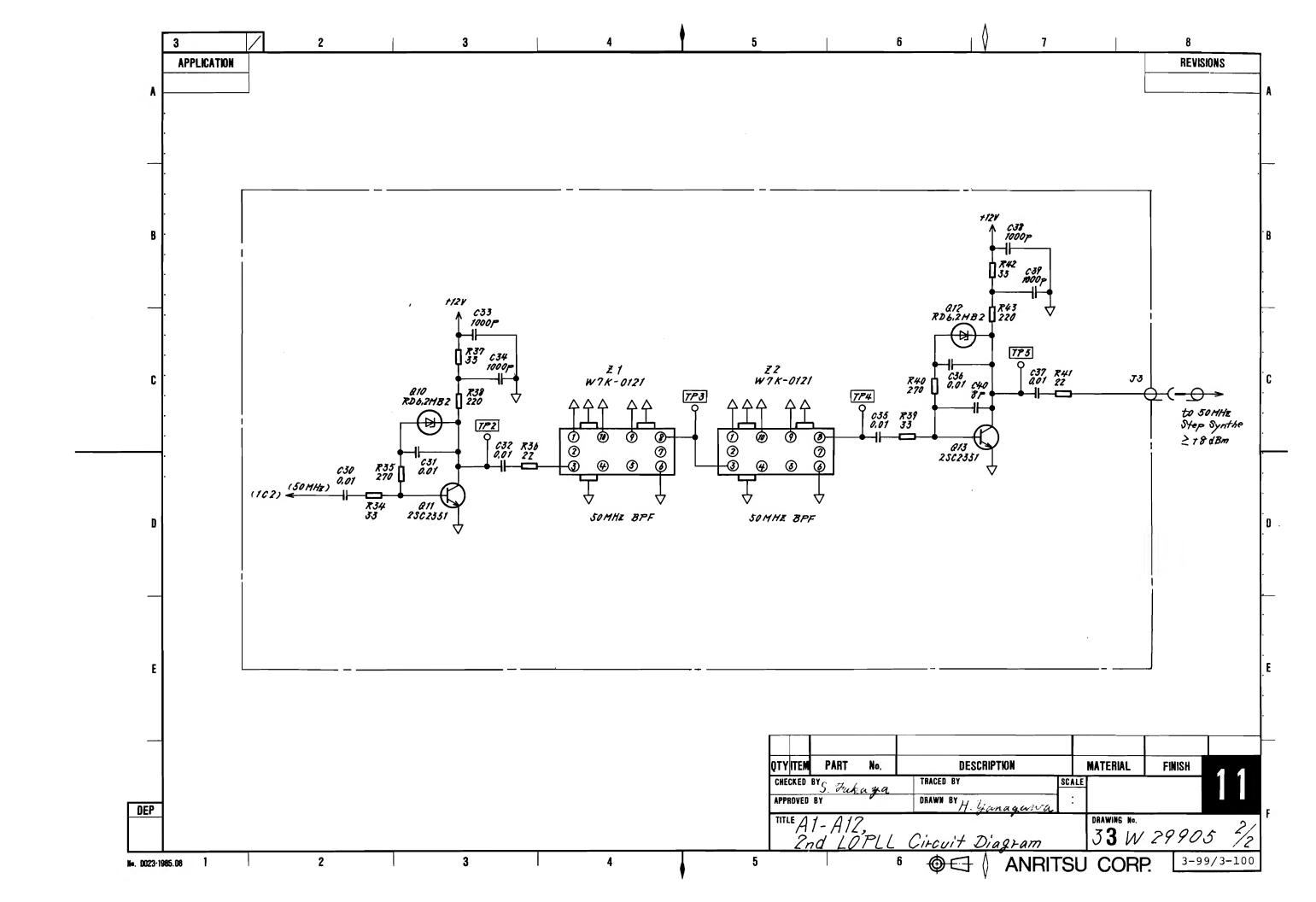


Fig. 3-19 (b) Al-Al2 2nd LOCAL PLL PC Board
Parts Layout (Pattern Side)



•

.



			)
	•		· <b>)</b>
			)

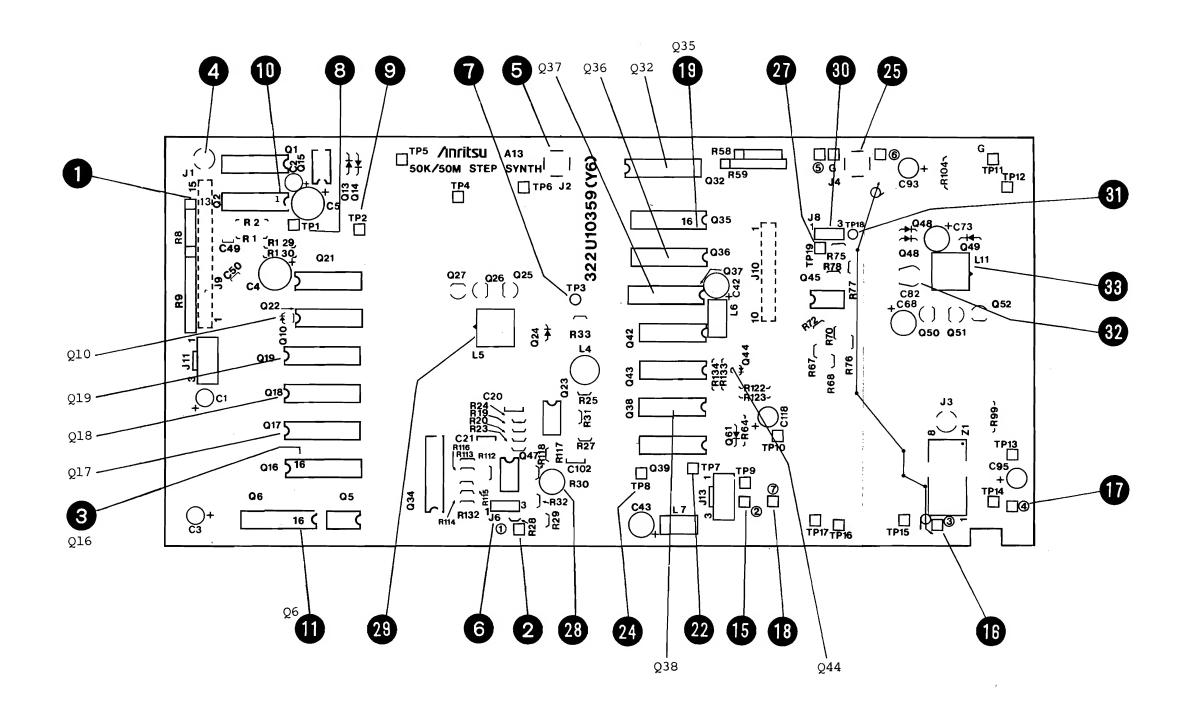


Fig. 3-20 (a) Al-Al3 50 k/50 M STEP SYNTH PC Board Parts Layout (Parts Side) 12

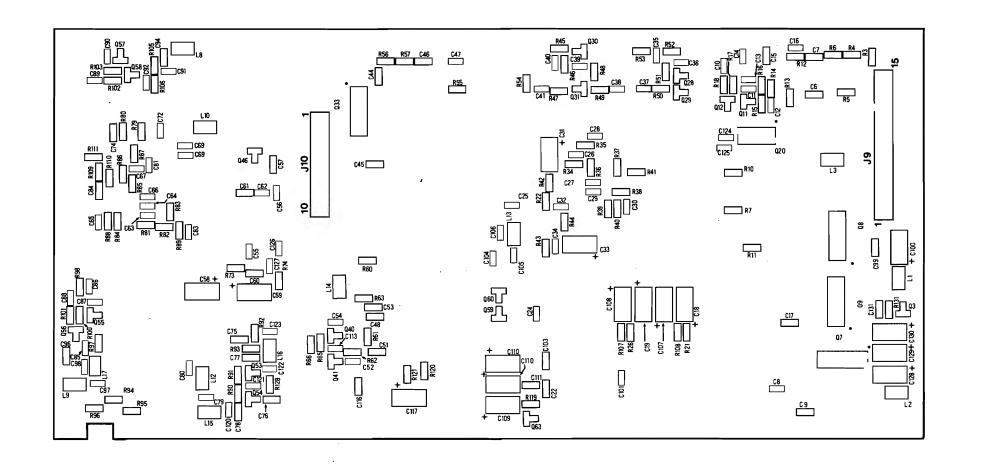
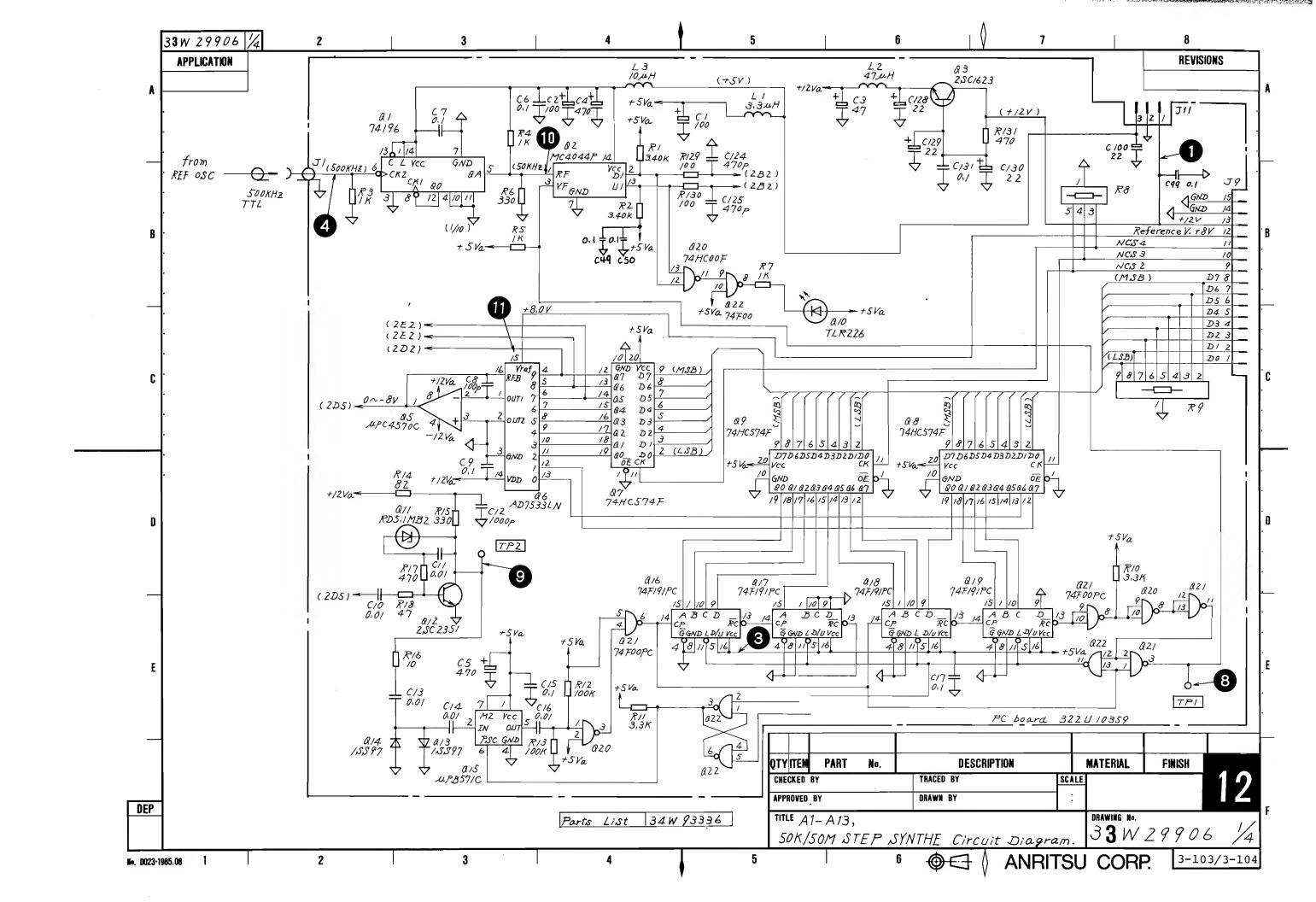
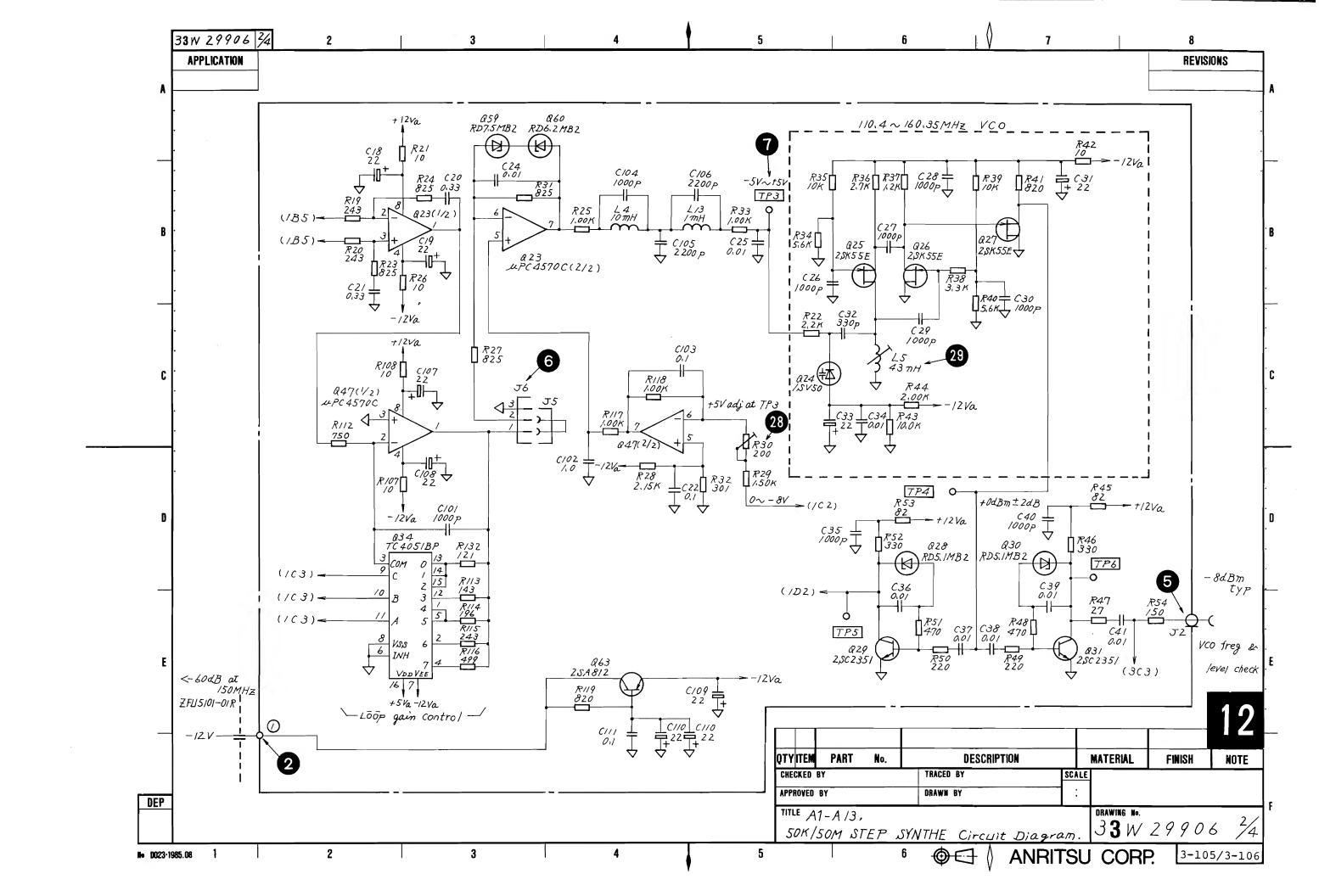


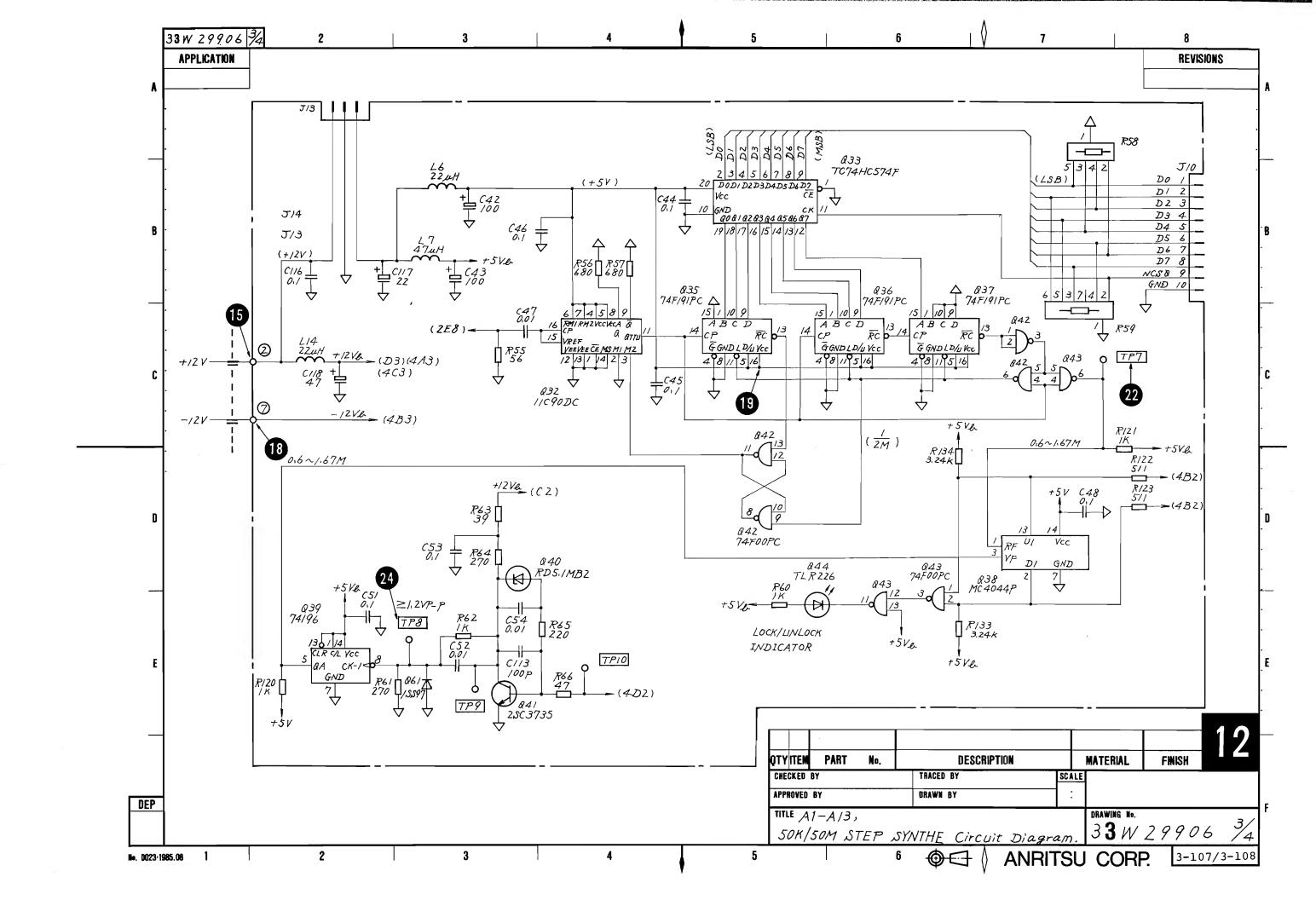
Fig. 3-20 (b) Al-Al3 50 k/50 M STEP SYNTH PC Board Parts Layout (Pattern Side)



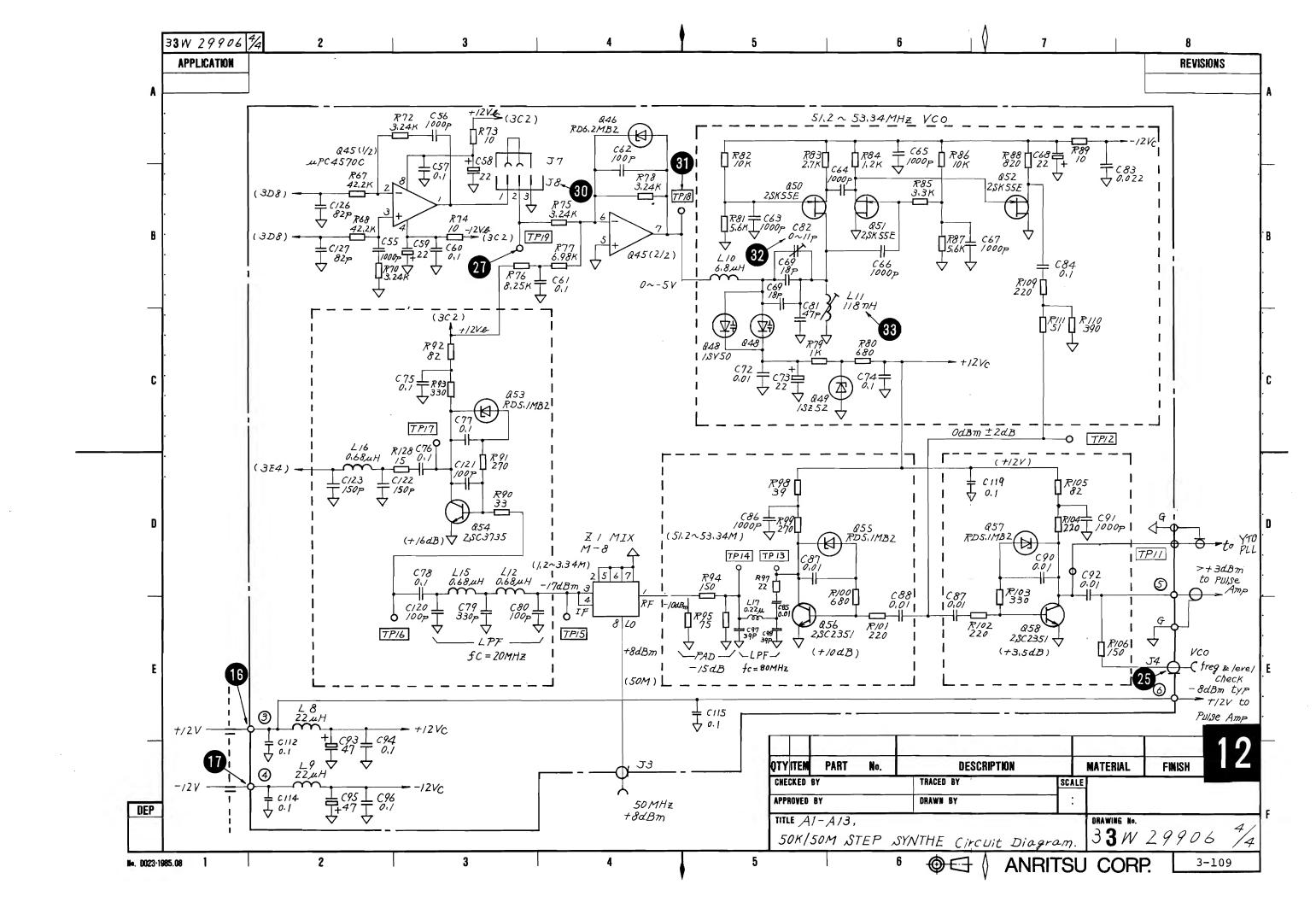
						)
,		,				
	•					
		•				
						)
					•	
						)



			)
			)



.



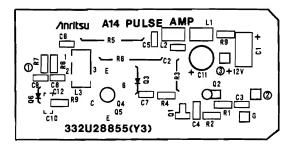
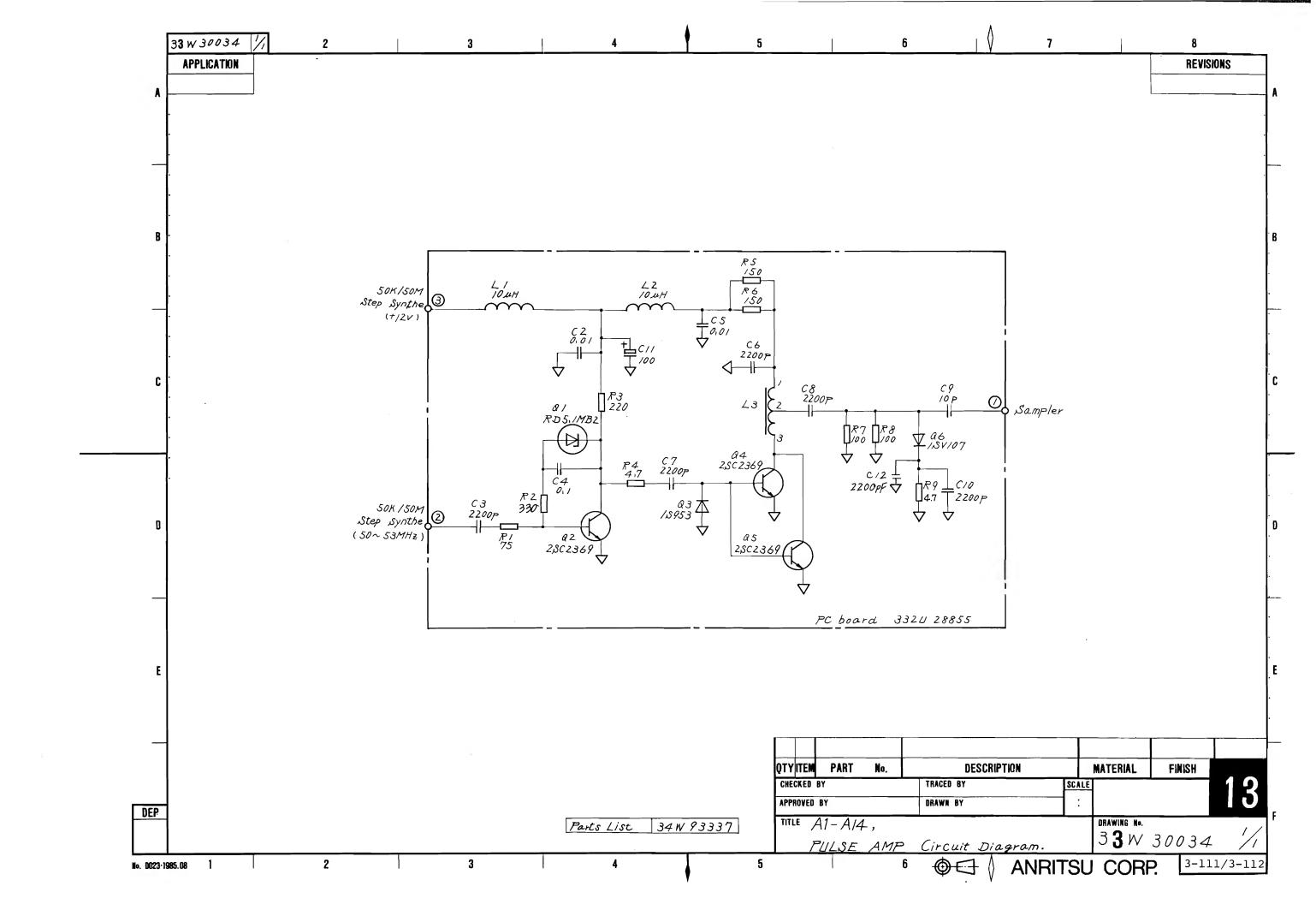


Fig. 3-21 Al-Al4 PULSE AMP PC Board
Parts Layout 13



		1		
				)
,	•			
				)
				)

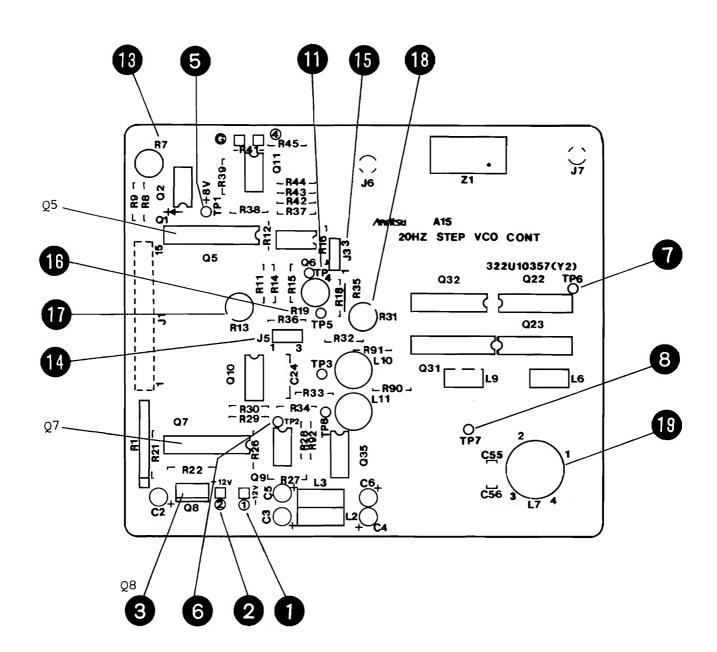


Fig. 3-22 (a) A1-A15 20 Hz STEP VCO CONT PC Board Parts Layout (Parts Side) 14

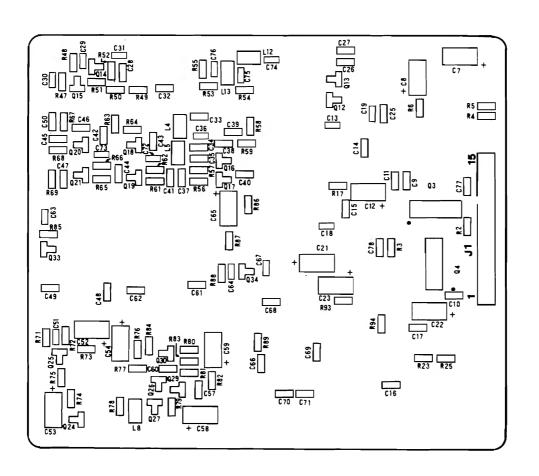
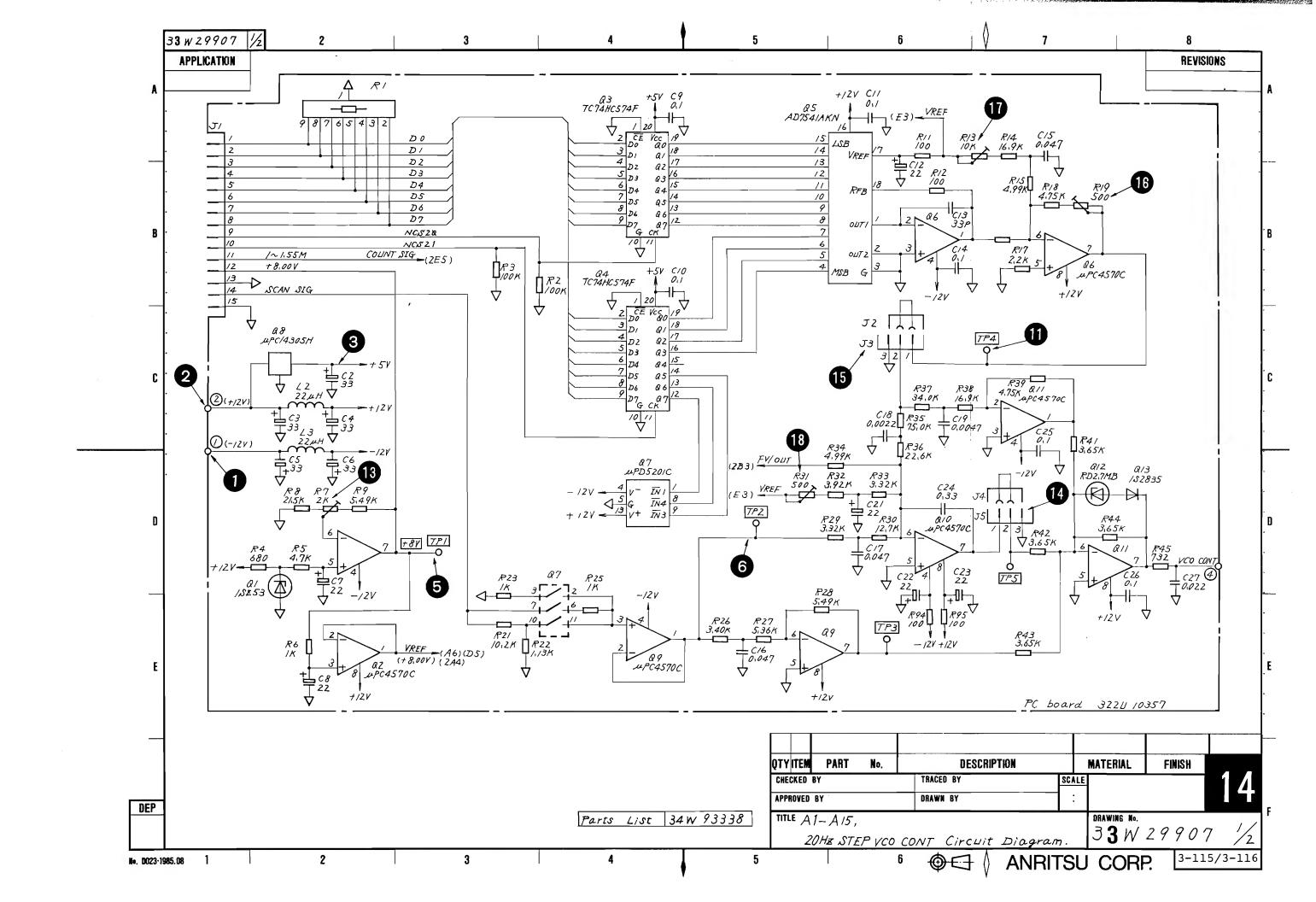


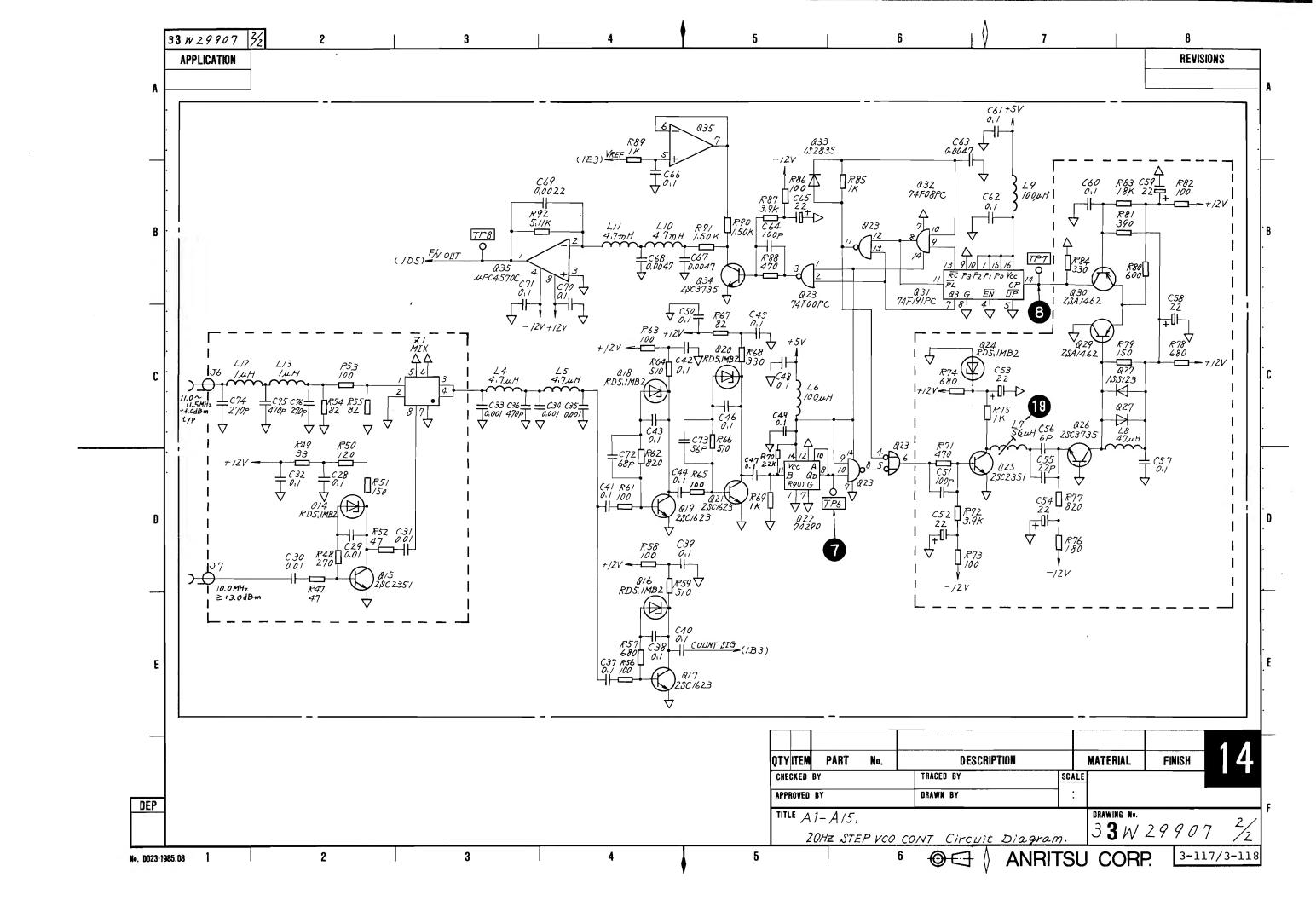
Fig. 3-22 (b) A1-A15 20 Hz STEP VCO CONT PC Board Parts Layout (Pattern Side) 14



.

•

40



·	•		
•			

)

)

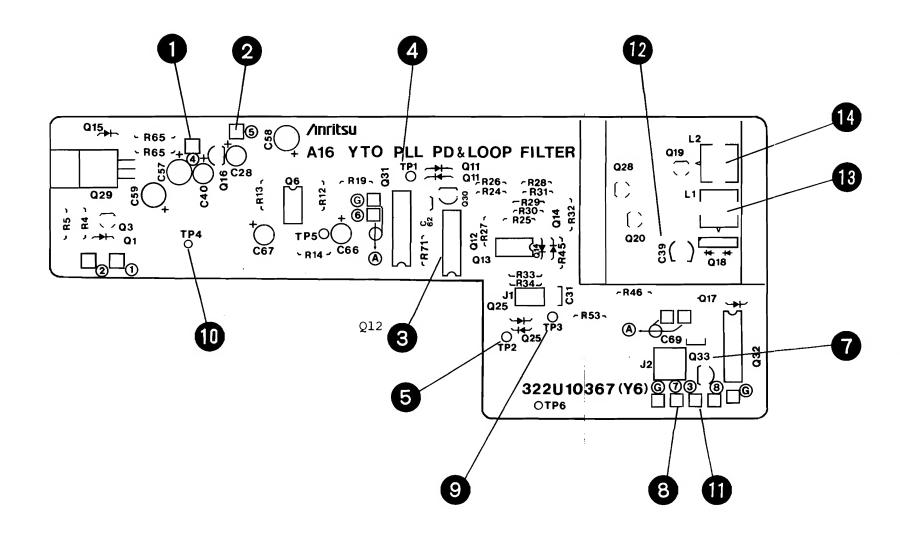


Fig. 3-23 (a) Al-Al6 YTO PLL PD & LOOP FILTER PC Board Parts Layout (Parts Side) 15

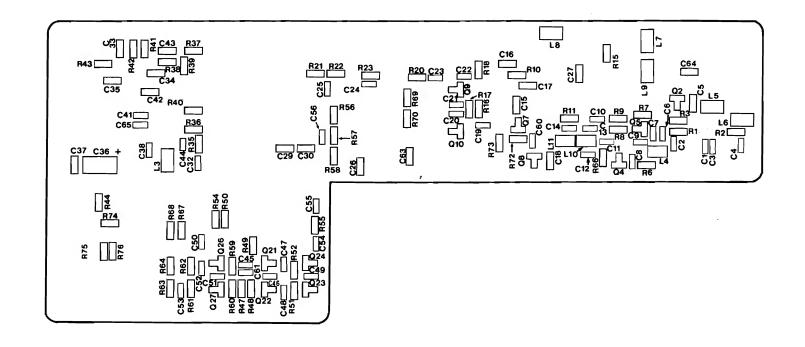
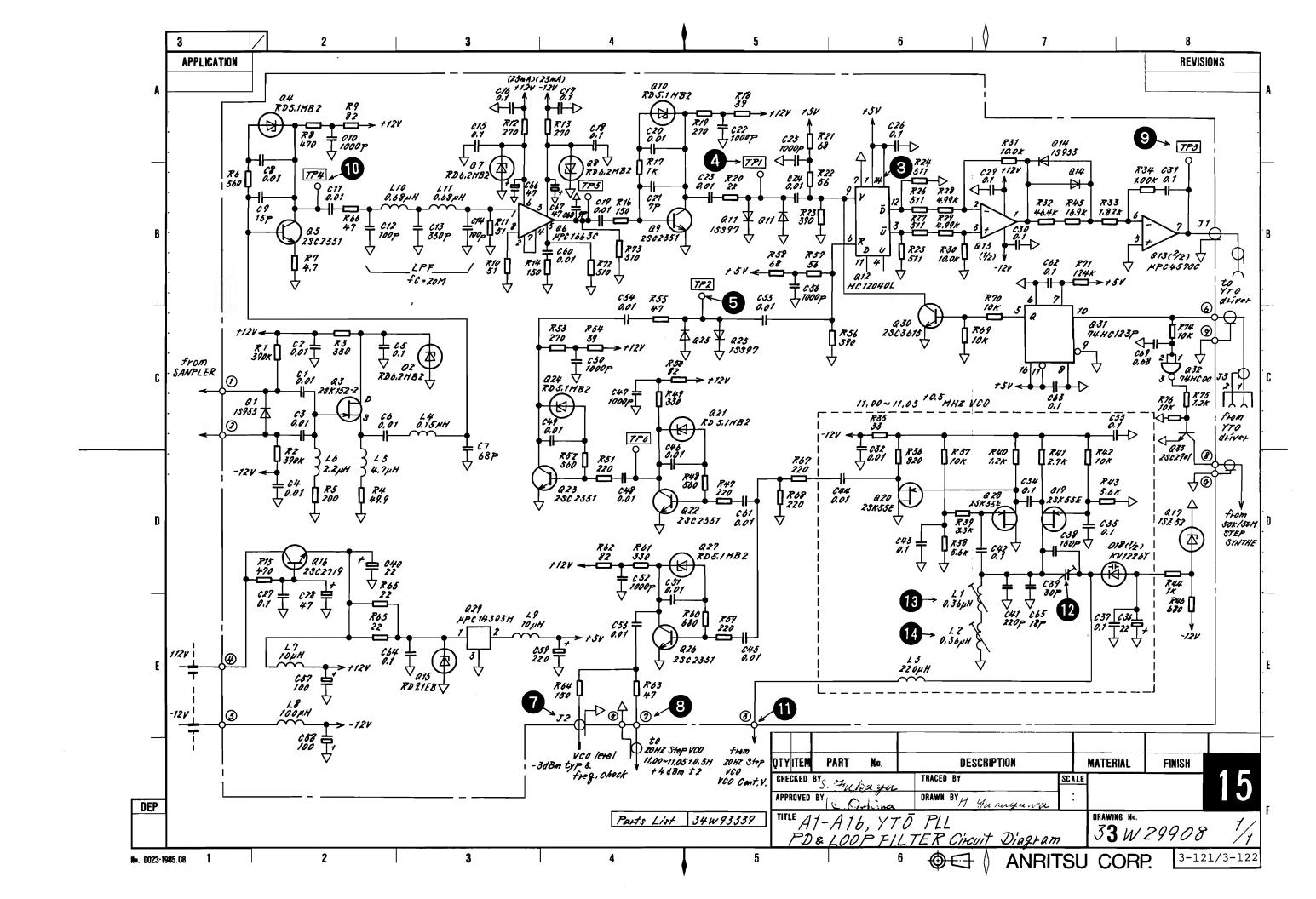


Fig. 3-23 (b) Al-Al6 YTO PLL PD & LOOP FILTER PC Board Parts Layout (Pattern Side) 15



			,
			,
			,

### (1) Circuit description

The 2nd IF signal (21.4 MHz) is converted to the 3rd IF signal (3.6 MHz) at A2 IF BPF. RBW and REF LEVEL are determined in this 3rd IF section.

The 21.4 MHz 2nd IF signal is output from A1-A8 2nd CONV in the A1 RF/PLL BLOCK. The A2 IF BPF is divided into 7 parts as shown in Fig. 3-26. The following paragraph describes the details of these circuits.

#### (a) 21.4 MHz BPF section

The 3rd IF 3.6 MHz image signal in the 21.4 MHz input signal is rejected using a band-pass filter which has a 3 dB bandwidth of approx. 2 MHz.

The front and rear stage buffer amplifiers use a transistors to match with the 21.4 MHz BPF impedance, and they have 50 ohm input impedance.

The overall gain is approx. 3 dB.

#### (b) Frequency converter section

This section uses a double-balanced mixer and the harmonic distortion is 70 dB or more. Furthermore, leakage of the local signal to the output is minimized.

### (c) BPF switching section

This section uses a capacitor-coupled resonance filter. It is inserted to prevent level saturation of the crystal filter during QP measurement. The 3 dB bandwidth is approx. 15 kHz.

- (d) 1st variable gain amplifier section

  This amplifier section is composed of two
  feedback amplifiers and a switch circuit, each of
  which is composed of hybrid ICs. The 1st-stage
  amplifier gain can be changed from 0 to 10 dB in
  2 dB steps in combination with the switch
  circuit. Also, the 2nd-stage amplifier gain can
  be changed from 0 to 20 dB in 10 dB steps.
- (e) 1st variable BPF section

After the signal has passed through the 1st variable gain amplifier, it enters the 1st variable BPF which sets the RBW from 30 Hz to 1 MHz. A crystal filter and an LC filter are used for the 30 Hz to 3 kHz RBWs and 10 kHz to 1 MHz RBWs, respectively.

The principle of the 10 kHz to 1 MHz LC filter is described below.

The signal V is supplied to the high-Q LC parallel resonance circuit via the variable resistance R as shown below.

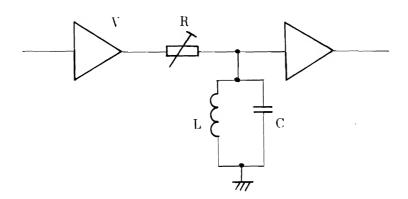


Fig. 3-24 Principle of LC Filter

The signal V is divided by the variable resistance R and the LC resonator because the input impedance of the buffer amplifier is high. If the L and C are ideal elements without any loss, the impedance of the LC resonator will be infinity at the resonance frequency, and the signal will be transmitted without any loss regardless of value R. When the frequency separates from the resonance frequency, the impedance of the resonator becomes small and the transmission loss becomes large because the signal V is divided by R. Therefore, when R becomes large, the BPF bandwidth becomes small and is controlled by the value R.

The principle of the 30 Hz to 3 kHz crystal filter is described below.

The crystal filter is composed of Cl, which cancels the parastic capacity such as the parallel capacity of crystal Xl and the output buffer amplifier, and the resonance circuits L and C2 as shown on the next page.

By this parastic capacity cancellation, the equivalent circuit becomes the LC series resonance circuit as shown on the next page.

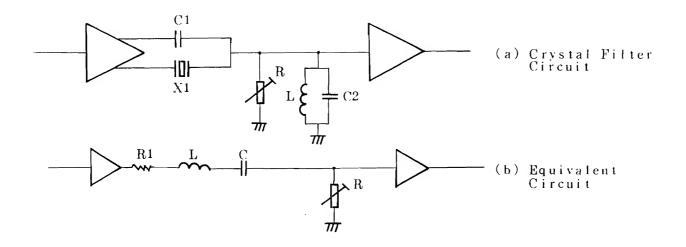


Fig. 3-25 Principle of Crystal Filter

If the crystal equivalent resistance is small enough and the buffer amplifier input impedance is high, the transmission loss is negligible. When the signal frequency separates from the resonance frequency, the impedance of the crystal resonator becomes high and the signal is divided by R so that the transmission loss becomes large. Therefore, when R becomes small, the bandpass filter bandwidth becomes small and the bandwidth is controlled by the value R.

In the actual circuit, hybrid ICs are used for the buffer amplifier and variable resistor. Furthermore, to simplify the circuit, the resonance circuit for crystal filter parastic capacity cancelling is the same as the LC filter resonance circuit.

Also, since neither the LC filter circuit nor the crystal filter circuit is an ideal resonance circuit, the loss changes when the bandwidth (RBW) is switched. The Z5 amplifier gain is changed by the Z6 switch circuit to reduce the deviation when the RBW is switched.

- (f) 2nd variable gain amplifier section This section has the same circuit configuration as the 1st variable gain amplifier section and is also composed of hybrid ICs. The 1st-stage amplifier is a compensation amplifier to reduce the deviation when the RBW is switched. The 2nd-stage amplifier gain changes from 0 to 30 dB in 10 dB steps.
- (g) This section has the same circuit configuration as the 1st variable BPF section. The specified RBW can be obtained by combining the 1st variable BPF section with this 2nd variable BPF section. One output of this 2nd variable BPF section becomes the IF OUTPUT via a buffer amplifier and

the other output enters A3 IF LOG/DET.

2nd variable BPF section

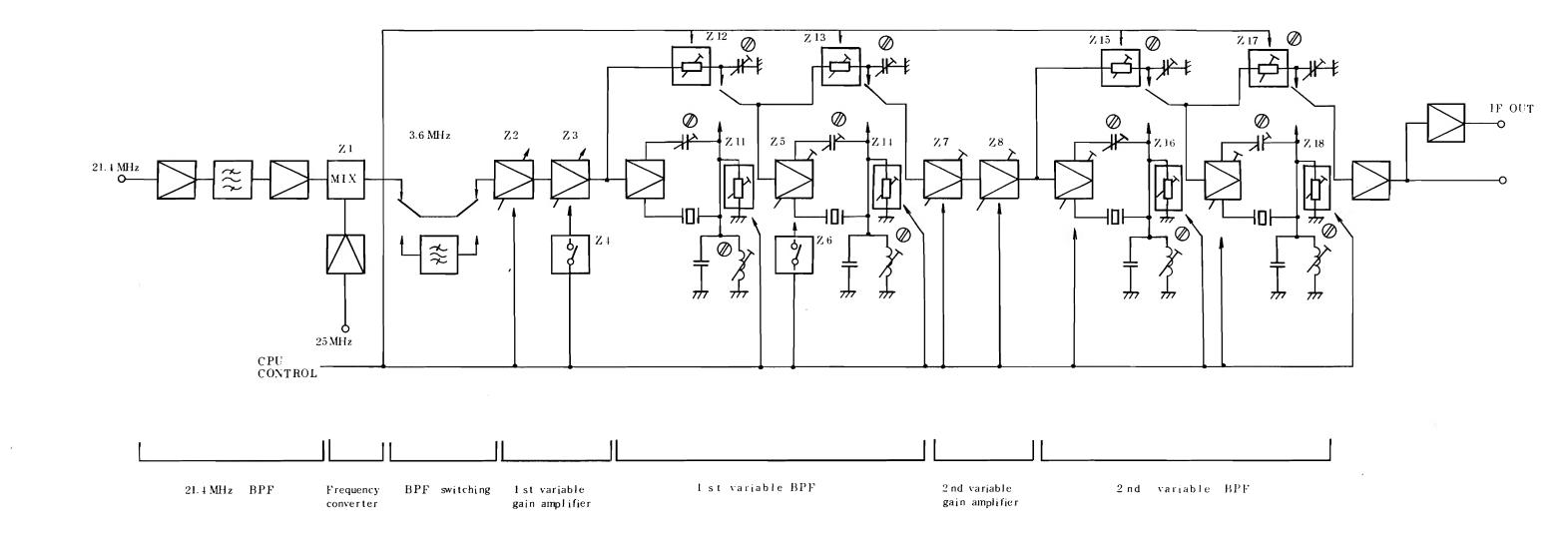


Fig. 3-26 A2 IF BPF Block Diagram

			)
	,		
			,

## (2) Symptom and cause

	Symptom	Cause
1.	No signal on CRT	Defective 2nd variable gain amplifier section or 2nd variable BPF section
2.	Absolute level value incorrect	Defective 21.4 MHz BPF section or 3.6 MHz stage amplifier
3.	Spurious generated due to 3.6 MHz image frequency	Defective 21.4 MHz BPF section
4.	Step change incorrect when REF LEVEL changed	Defective 1st and 2nd variable gain amplifiers
5.	RBW bandwidth incorrect	Defective 1st and 2nd variable BPF sections
6.	Level at 30 Hz to 3 kHz RBW incorrect	Defective BPF switching section
7.	Large level deviation at RBW switching	Defective 1st and 2nd variable BPF sections and defective Z6 changeover switch

# (3) Troubleshooting

(a) Required equipment

Signal generator: MG443B

Digital voltmeter

Oscilloscope

Network/spectrum Analyzer: MS420K

(b)	Pre	epar	ati	on
-----	-----	------	-----	----

C	70	TТ	m	т	$\overline{}$	ъT	

Turn off the power before disassembly.

Step	Procedure
1	Remove the bottom cover by referring to paragraph 2.2.
2	Remove the cover of A1-A8 2nd CONV by referring to Fig. 2-6.
3	Remove the coaxial cable connected to terminal 7 (21.4 MHz OUT) (Fig. 3-16, 8) of Al-A8.
4	Remove the A2 IF BPF by referring to paragraph 2.4 and then remove the shielding case (Fig. 2-3).
5	Reattach the A2 IF BPF using the extender board.

(c) Troubleshooting (Fig. 3-38, 16)

Step	Procedure
1	Check the power supply voltages according to the following table.
	Checkpoint Normal condition
	J2-17
	J2-12 <b>2</b> -14.3 to -15.7 V
	J2-15 3 +11.5 to +12.5 V
	J2-13 <b>4</b> -11.5 to -12.5 V
	J2-18 <b>6</b> +4.75 to +5.25 V
3	the other end of the cable (connector side) to a signal generator (SG).  Set the SG as follows:
	Output impedance: 50 ohm (for MG443B)  Output level: -8 dBm
	Output frequency: 21.4 MHz
4	Press the [INITIAL] key and set the MS2601A/J as follows:
	CENTER FREQ: 50 MHz
	REF LEVEL: 0 dBm
	SPAN: 0 kHz
	RBW: 3 kHz
	ATT: 10 dB

Step	Procedure
5	Decrease the SG output attenuator from 0 to -8 dB in 2 dB steps. At the same time, decrease the REF LEVEL setting in the same way according to the SG output attenuator.
	If the difference between the display level and REF LEVEL is within $\pm 0.5$ dB, the 1st variable gain amplifier Z3 is normal.
6	Decrease the SG output attenuator from 0 to $-60~\mathrm{dB}$ in 10 dB steps.
	At the same time, decrease the REF LEVEL setting value in the same way according to the SG output attenuator.
	If the difference between the display level and REF LEVEL is within $\pm 1.0$ dB, the 1st and 2nd variable gain amplifiers Z2 and Z8 are normal.
7	Remove the extender cable from J2-6 $\textcircled{8}$ and reconnect terminal $\textcircled{7}$ (21.4 MHz OUT) $\textcircled{1}$ of A1-A8.
8	Connect J1 10 to J1 19 (Fig. 3-43, 17) of A3 IF LOG/DET using the extender cable.
9	Apply a 20 MHz, 0 dBm signal to the RF INPUT.
10	Press the [INITIAL] key and set the MS2601A/J as follows:
	CENTER FREQ: 20 MHz
	REF LEVEL: 0 dBm
	SPAN: 5 MHz (at RBW 1 MHz)

Step	Procedure
11	Check that the RBW (3 dB bandwidth) is within $\pm 20\%$ of the specifications.
	Change the RBW setting down to 30 Hz and check that it is within $\pm 20\%$ of the specifications.
	When it is checked, the displayed waveform must be a single peak. (See paragraph 4.4.4 in the operation manual.)
12	Check the set value of the control signal shown in Tables 3-15 and 3-16.

Table 3-15 RBW Control Signal

RBW set	t value	19	Q1 18	13 p	oin 16	No.		Q12 pin No. 19
1	MHz	1	0	1	0	0	0	0
300	kHz	1	0	1	1	0	0	0
100	kHz	1	0	1	1	1	0	0
30	kHz	1	0	1	0	0	1	0
10	kHz	1	0	1	1	0	1	0
3	kHz	0	0	0	1	1	0	1
1	kHz	1	0	0	1	1	0	1
300	Ηz	0	1	0	1	1	0	1
100	Hz	0	0	1	1	1	0	1
30	Hz	1	0	1	1	1	0	1

<sup>1:</sup> Approx. 5 V 0: Approx. 0 V

Step

Procedure

12 (Cont.)

Table 3-16 IF GAIN Control Signal (at ATT 10 dB setting)

REF LEVEL set	Q11 pin No.								Q12 pin No.		
value (dBm)	19	18	17	16	15	14	13	14	13	12	
0 dBm	0	0	0	0	0	0	0	0	0	0	
-2	0	0	0	1	0	0	0	0	0	0	
-4	0	0	0	0	1	0	0	0	0	0	
<b>-</b> 6	0	0	0	0	0	1	0	0	0	0	
-8	0	0	0	0	0	0	1	0	0	0	
-10	1	0	0	0	0	0	0	0	0	0	
-20	0	1	0	0	0	0	0	0	0	0	
-30	0	1	0	0	0	0	0	0	0	1	
-40	0	1	0	0	0	0	0	0	1	0	
<b>-</b> 50	0	1	0	0	0	0	0	1	0	0	

1: Approx. 5 V

0: Approx. 0 V

# (4) Adjustment

- (a) 21.4 MHz BPF adjustment
  - (i) Setup

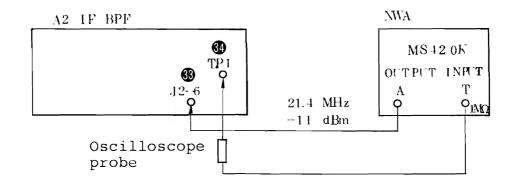


Fig. 3-27 21.4 MHz BPF Adjustment Setup

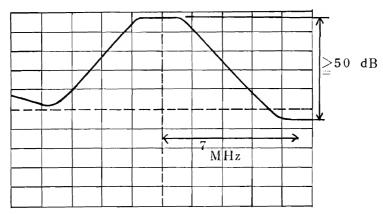
# (ii) Adjustment

Step	Procedure
1	Remove the coaxial cable connected to terminal 7 (21.4 MHz OUT) • on A1-A8 2nd CONV (Fig. 3-16,
2	Solder the extender cable directly to $J2-6$ $\textcircled{8}$ as shown in Fig. 3-27.
3	Adjust L2 6, L3 7 and L4 8 so that the characteristics shown in the figures on the next page are obtained.
	. Attenuation $\geq 50$ dB at 7 MHz from center frequency
	. Pass-band ripple <1 dB within center frequency ±500 kHz

Step

Procedure

3 (Cont.)

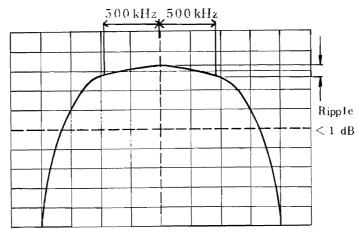


 $\begin{array}{lll} C\,F\,\,;\,\,21.\,100.000.00\,\,Hz & S\,PA\,N\,\,;\,\,15.000,000.00\,\,Hz \\ O\,U\,T\,(A)\,\,;\,-\,11.00\,\,dBm & I\,N\,P\,U\,T & T\,\,;\,\,1\,\,M\Omega \end{array}$ 

IRG:-10 dBm RBW: 3 kHz

10 dB/

## (1) Total Pass-band/Attenuation



 $\begin{array}{lll} C\,F\,\colon\,21,\,100,000.00\,\;Hz & S\,PA\,N\,\colon\,3,000,000.00\,\;Hz \\ O\,U\,T\,(A)\,\colon-\,11.00\,\;dBm & I\,N\,P\,U\,T & T\,\colon\,1\,\;M\Omega \end{array}$ 

IRG: -10 dBm RBW: 3 kHz

1/dB <

(2) Pass-band

Fig. 3-28 21.4 MHz BPF Characteristics

# (b) 3.6 MHz BPF adjustment

## (i) Setup

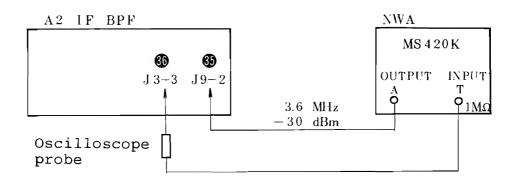


Fig. 3-29 3.6 MHz BPF Adjustment Setup

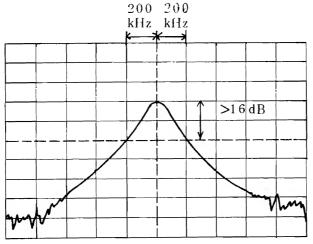
# (ii) Adjustment

Step	Procedure
1	Remove the shielding case (56) (Fig. 2-3) attached to the pattern side of the A2 PC board and solder the extender cable to J9 (50 -pin 2 on the pattern side (Pin 3 is ground pin).
2	Reattach the shielding case $66$ .
3	Remove J10 connected to J9 🚯 .
4	Set the MS2601A RBW to 3 kHz.
5	Adjust L8 <b>9</b> , L9 <b>0</b> and L10 <b>1</b> so that the characteristics shown on the next page are obtained.
	. Attenuation $\geq 16$ dB at $\pm 200$ kHz from center frequency
	. Peak frequency to 3.6 MHz

Step

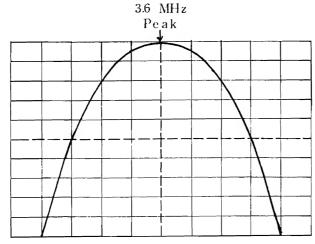
### Procedure

5 (Cont.)



10 dB.

### (1) Total Pass-band/Attenuation



 $\begin{array}{lll} C\,F:\,3,600,900.00\,\;Hz & S\,PA\,N:\,300,000.00\,\;Hz \\ O\,U\,T\,(A):\,-\,30.00\,\;dBm & I\,\,N\,P\,U\,T & T:\,1\,\,M\Omega \\ I\,R\,G:\,-\,40\,\;dBm & R\,B\,W:\,3\,\;kHz \end{array}$ 

1 dB.

### (2) Pass-band

Fig. 3-30 3.6 MHz BPF Characteristics

# (c) Crystal filter adjustment(i) Setup

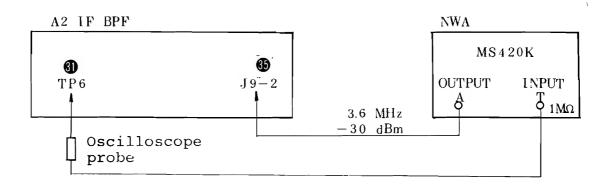
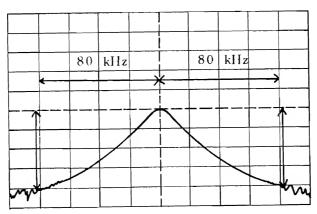


Fig. 3-31 Crystal Filter Adjustment Setup

# (ii) Adjustment

Step	Procedure
1	Press the MS2601A/J [INITIAL] key and set the RBW to 9 kHz.
	1st stage adjustment
2	Connect J6, J8, J12, and J14 to J5 $ $
	J6 $\rightarrow$ J5 $\bigcirc$ between pins 2 and 3 (normal connection)
	J8 $\rightarrow$ J7 $lackbox{1}{8}$ between pins 1 and 2
	J12 $\rightarrow$ J11 $lackbox{0}$ between pins 1 and 2
	J14 $\rightarrow$ J13 $\textcircled{\textbf{b}}$ between pins 1 and 2 Note:
	At normal connection, J6, J8, J12, and J14 are connected between pins 2 and 3 of J5, J7, J11, and J13, respectively.

	(continued)
Step	Procedure
3	Adjust C34
4	Set the SCALE of the MS420K to 1 dB/DIV and adjust L13  so that the peak frequency is 3.6 MHz as shown in Fig. 3-32 (2).
5	Repeat steps 3 and 4 two or three times to obtain both the characteristics simultaneously.



 $\begin{array}{lll} C\,F:\,3,\!600,\!000.00\,\,Hz & S\,PAN:\,200,\!000.00\,\,Hz \\ O\,U\,T\,(A):\,-\,30.00\,\,dBm & I\,N\,P\,U\,T & T:\,1\,\,M\Omega \end{array}$ 1RG: -20 dBm RBW: 3 kHz

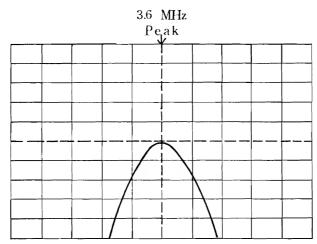
10 dB.

## (1) Total Pass-band/Attenuation

Fig. 3-32 Crystal Filter Adjustment

Step

Procedure



CF: 3,600,000.00 Hz SPAN: 50,000.00 Hz
OUT(A): -30.00 dBm INPUT T: 1 MΩ

 $I\,RG:-20~dBm - RBW: 3~kHz$ 

 $1 \, dB_2$ 

## (2) Pass-band

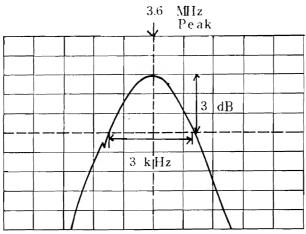
Fig. 3-32 Crystal Filter Adjustment (Cont'd)

Step	Procedure
	3rd stage adjustment
6	Connect J6, J8, J12, and J14 to J5  , J7  , J11  , and J13  , respectively, as follows:
	J6 → J5 ② between pins 1 and 2
	J8 $\rightarrow$ J7 (8) between pins 1 and 2 (same as step 2)
	J12 → J11
	J14 → J13
7	Perform steps 3, 4, and 5 described above.
	However, use C51 🚯 and L19 🔞 instead of C34 and
	L13 for adjustment.
	4th stage adjustment
8	Connect J6, J8, J12, and J14 to J5 $ lackbox{1}{0} $ , J7 $ lackbox{1}{0} $ ,
	J11 $lackbox{ beta}$ , and J13 $lackbox{ beta}$ , respectively, as follows:
	J6 $\rightarrow$ J5 $\bigcirc$ between pins 1 and 3 (same as step 6)
	J8 + J7
	J12 → J11
	J14 → J13
9	Perform steps 3, 4, and 5 described above.
	However, use C58 🐠 and L21 🐠 instead of C34 and
	L13 for adjustment.

Step	Procedure
	2nd stage adjustment
10	Connect J6, J8, J12, and J14 to J5 $( P )$ , J7 $( P )$ , J11 $( P )$ , and J13 $( P )$ , respectively, as follows:
	J6 $\rightarrow$ J5 $\bigcirc$ between pins 1 and 2 (same as steps 6 and 8)
	J8 + J7
	J12 + J11
	J14 + J13 <b>(b)</b> between pins 2 and 3 (normal connection)
11	Change the RBW of the MS2601A/J to 3 kHz.
12	Perform steps 3, 4, and 5 described above.  However, use C40  and L15  instead of C34 and L13 for adjustment.
13	Connect J6, J8, J12, and J14 between pins 2 and 3 of J5 10, J7 18, J11 11, and J13 15, respectively (normal connection).
	Check that the filter characteristic is as shown in the following figure.
	Center frequency: 3.6 MHz
	3 dB BW: 3 kHz ±20%

Step Procedure

13 (Cont.)



 $\begin{array}{lll} C\,F:\,3,\!600,\!000.00~Hz & S\,PA\,N:\,10,\!000.00~Hz \\ O\,U\,T\,(A):\,-\,30.00~dBm & I\,N\,P\,U\,T & T:\,1~M\Omega \end{array}$ 

IRG:-20 dBm RBW: 3 kHz

1 dB

Fig. 3-33 Crystal Filter Pass-band Characteristic

# (d) LC filter adjustment

## (i) Setup

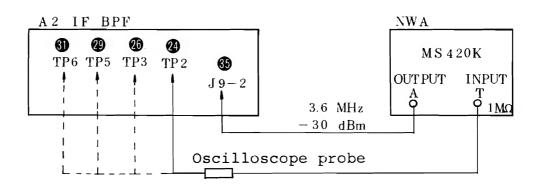
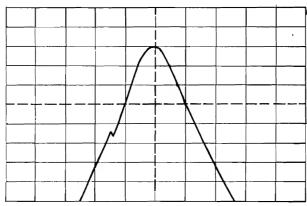


Fig. 3-34 LC-Filter Adjustment Setup

# (ii) Adjustment

Step	Procedure
1	Connect an oscilloscope probe to INPUT T (1 M $\Omega$ ) of the MS420K for use in the following steps.
2	Set the RBW of the MS2601A/J to 10 kHz.
3	Connect INPUT T of the MS420K to TP2 $^{f Q}$ .
4	Adjust C35 <b>6</b> so that the peak frequency is 3.6 MHz as shown in Fig. 3-35 (1).
5	Connect INPUT T of the MS420K to TP3 🔞 .
6	Adjust C50 $②$ so that the peak frequency is 3.6 MHz as shown in Fig. 3-35 (2).
7	Connect INPUT T of the MS420K to TP5 @ .
8	Adjust C52 $@$ so that the peak frequency is 3.6 MHz as shown in Fig. 3-35 (3).
9	Connect INPUT T of the MS420K to TP6 🚯 .
10	Adjust C62  so that the peak frequency is 3.6 MHz as shown in Fig. 3-35 (4).

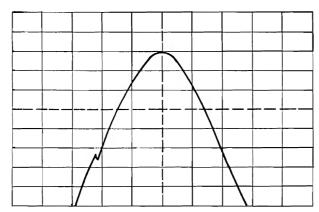


 $\begin{array}{lll} C\,F:\,3,600,000.00\;Hz & S\,P\,A\,N:\,100,000.00\;Hz \\ O\,U\,T\,(A):\,-\,30.00\;dB\,m & I\,N\,P\,U\,T\,\;T:\,1\;M\Omega \\ I\,R\,G:\,-\,30\;dB\,m & R\,B\,W:\,3\;kHz \end{array}$ 

1 dB/

MINAL 9 KIIS

## (1) TP2



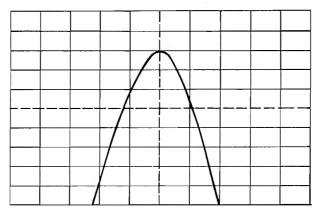
CF: 3,600,000.00 Hz SPAN: 50,000.00 Hz OUT (A): -30.00 dBm INPUT T: 1 MΩ

IRG: -30 dBm RBW: 3 kHz

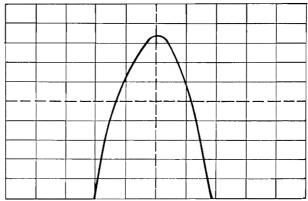
 $1 dB \times$ 

## (2) TP3

Fig. 3-35 LC Filter Adjustment



## (3) TP5



 $\begin{array}{lll} CF: 3,600,000.00\ Hz & SPAN: 50,000.00\ Hz \\ OUT(A): -30.00\ dBm & INPUT\ T: 1\ M\Omega \\ IRG: -30\ dBm & RBW: 3\ kHz \\ I\ dB & \end{array}$ 

## (4) TP6

Fig. 3-35 LC Filter Adjustment (Cont'd.)

# (e) Variable gain amplifier adjustment(i) Setup

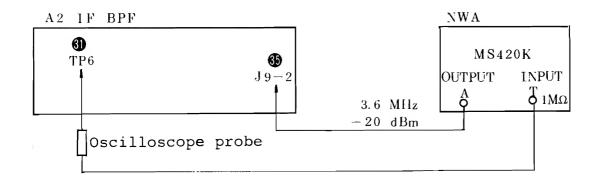


Fig. 3-36 Variable Gain Amplifier Adjustment Setup

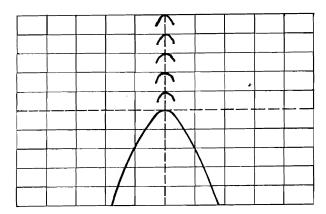
# (ii) Adjustment

Step	Procedure				
1	Press the MS2601A/J [INITIAL] key and set as shown below.				
	REF LEVEL: -10 dBm				
	RBW: 3 kHz				
	ATT: 0 dB				
2	Change the REF LEVEL of the MS2601A/J to -10, -12, -14, -16, -18, and -20 dBm and check that the MS420K display changes by 2 $\pm$ 0.5 dB each.				

(continued)

:e
•

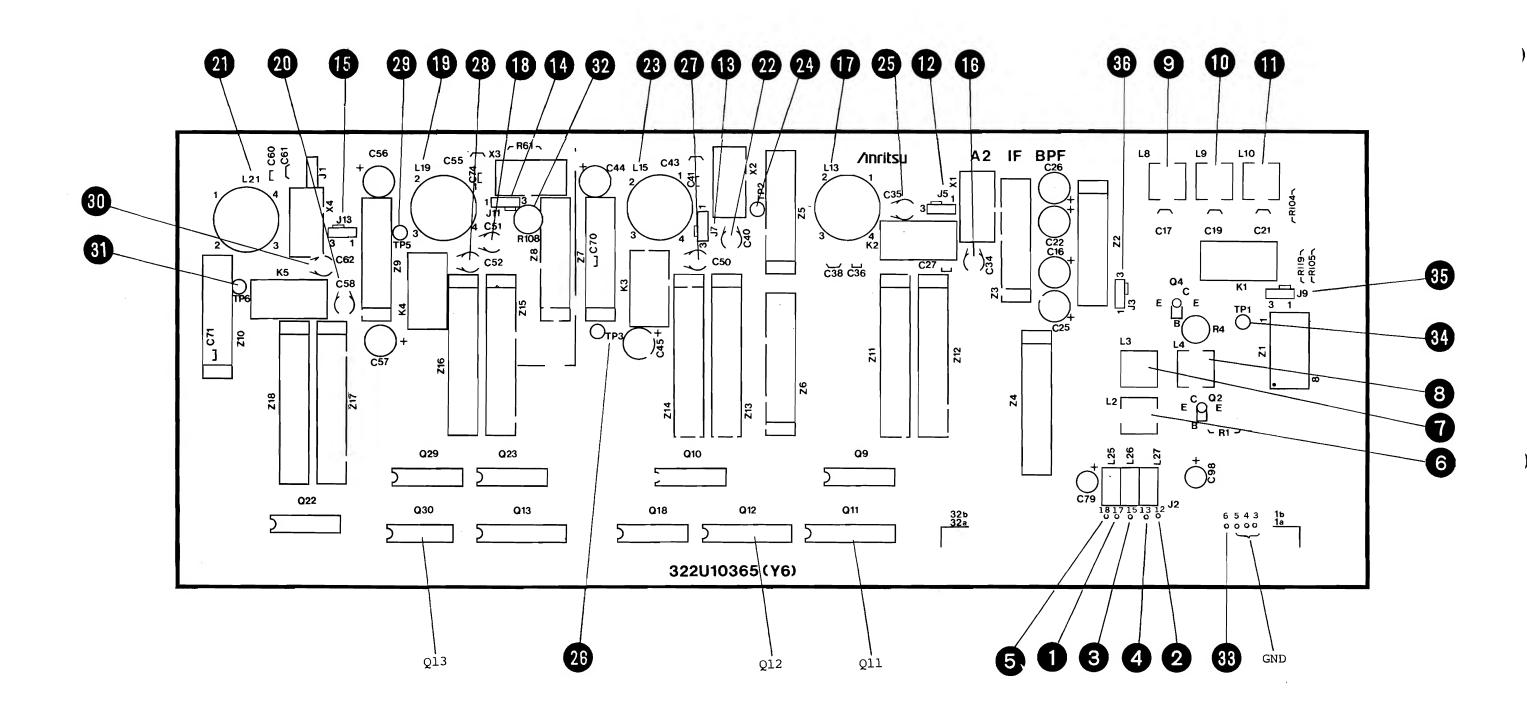
Also, read the MS420K displayed value when the REF LEVEL is -20 dBm. (This value is used in the next step.)



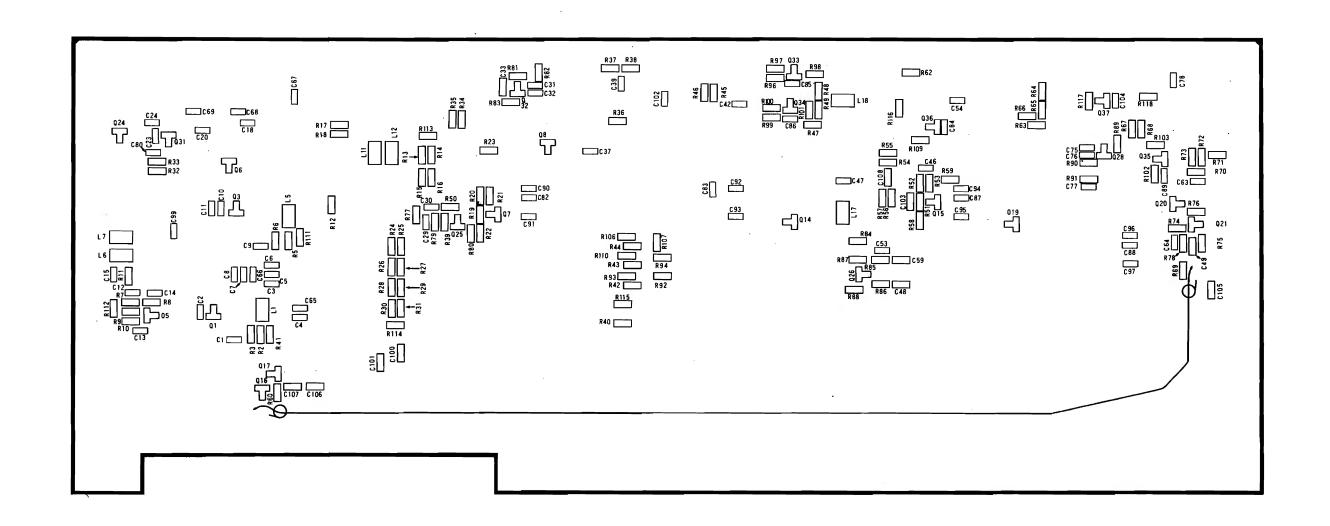
CF: 3,600,000.00 Hz SPAN: 20,000.00 Hz OUT (A): -20.00 dBm INPUT T: 1 M $\Omega$  IRG: -20 dBm RBW: 3 kHz 2 dB/

Fig. 3-37 Variable Gain Amplifier Adjustment

- Set the MS420K output level and the MS2601A/J REF LEVEL to -60 dBm.
- Adjust R108 so that the MS420K displayed value is the same as in step 2.



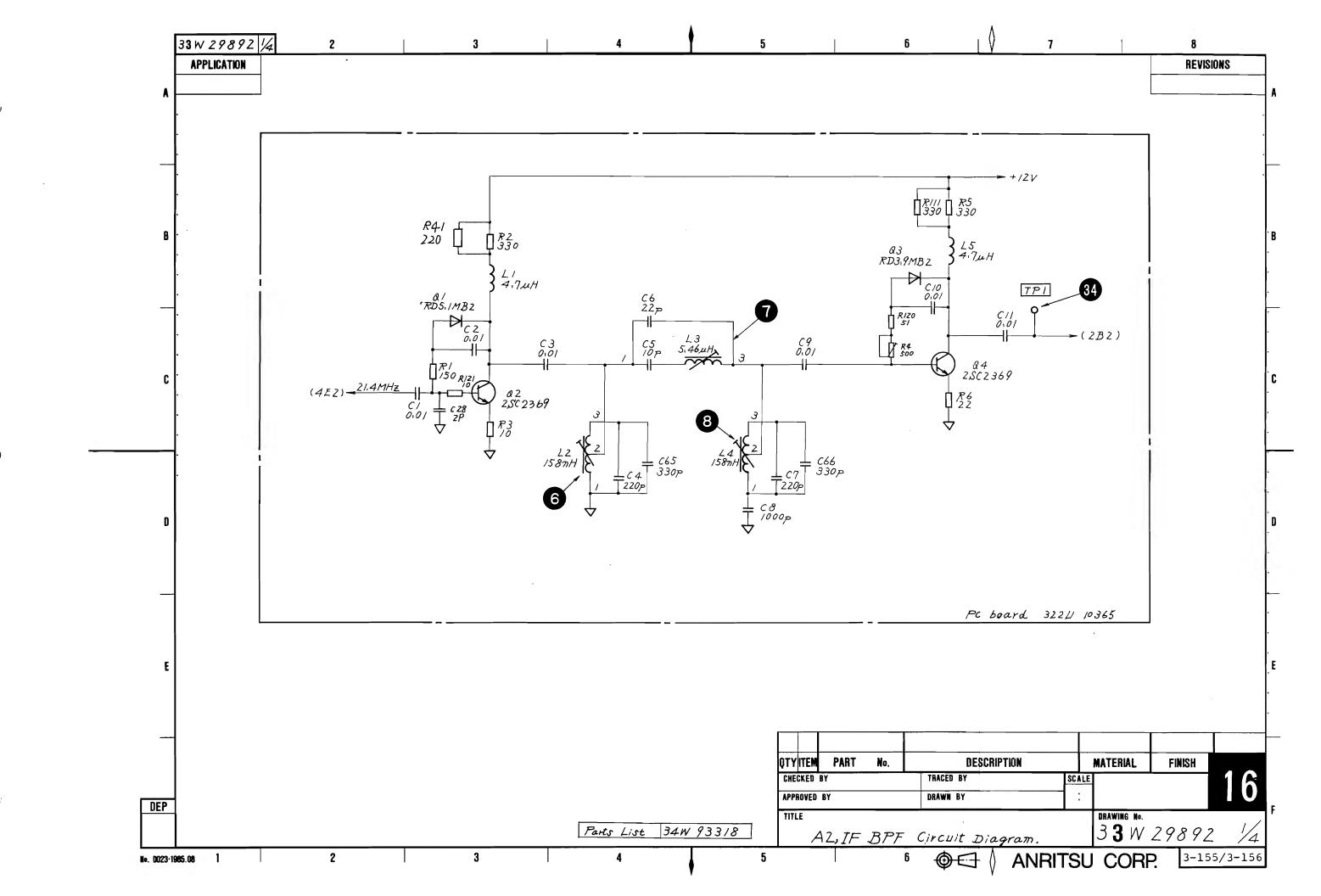
3-38 (a) A2 IF BPF PC Board
Parts Layout (Parts Side)



3-38 (b) A2 IF BPF PC Board Parts Layout (Fattern Side)

16

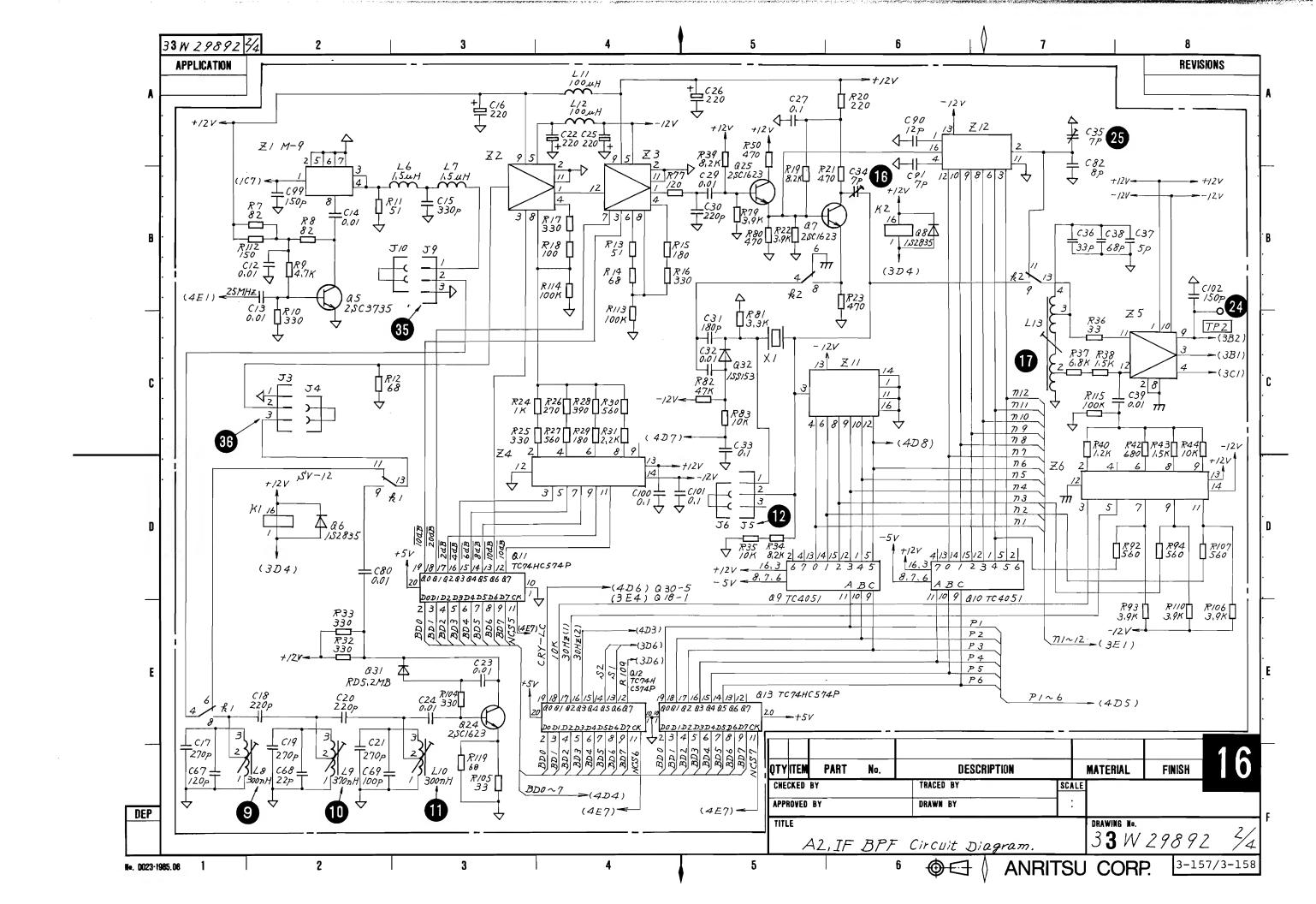
(3-153 blank)/3-154



j )

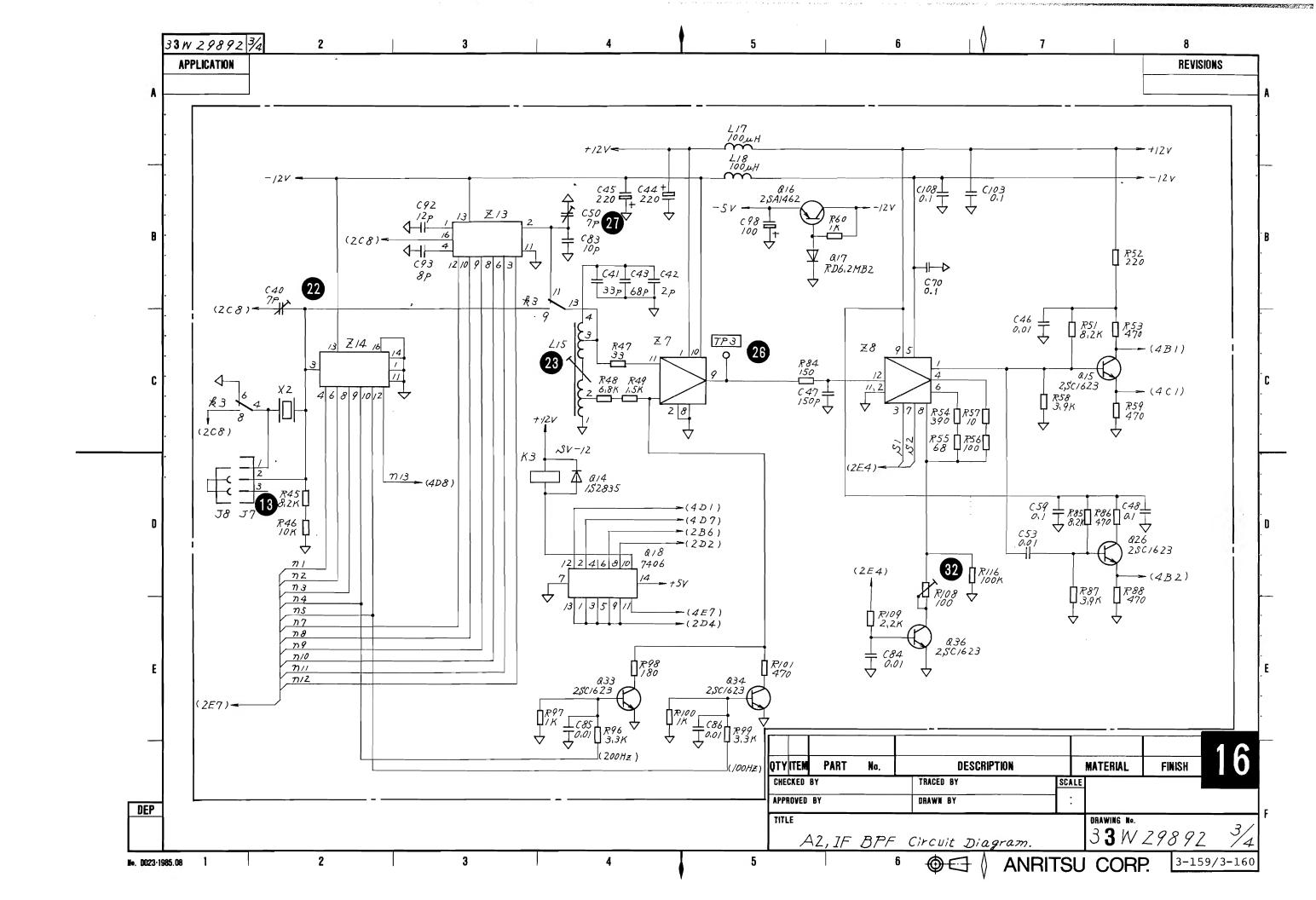
**(** )

. )

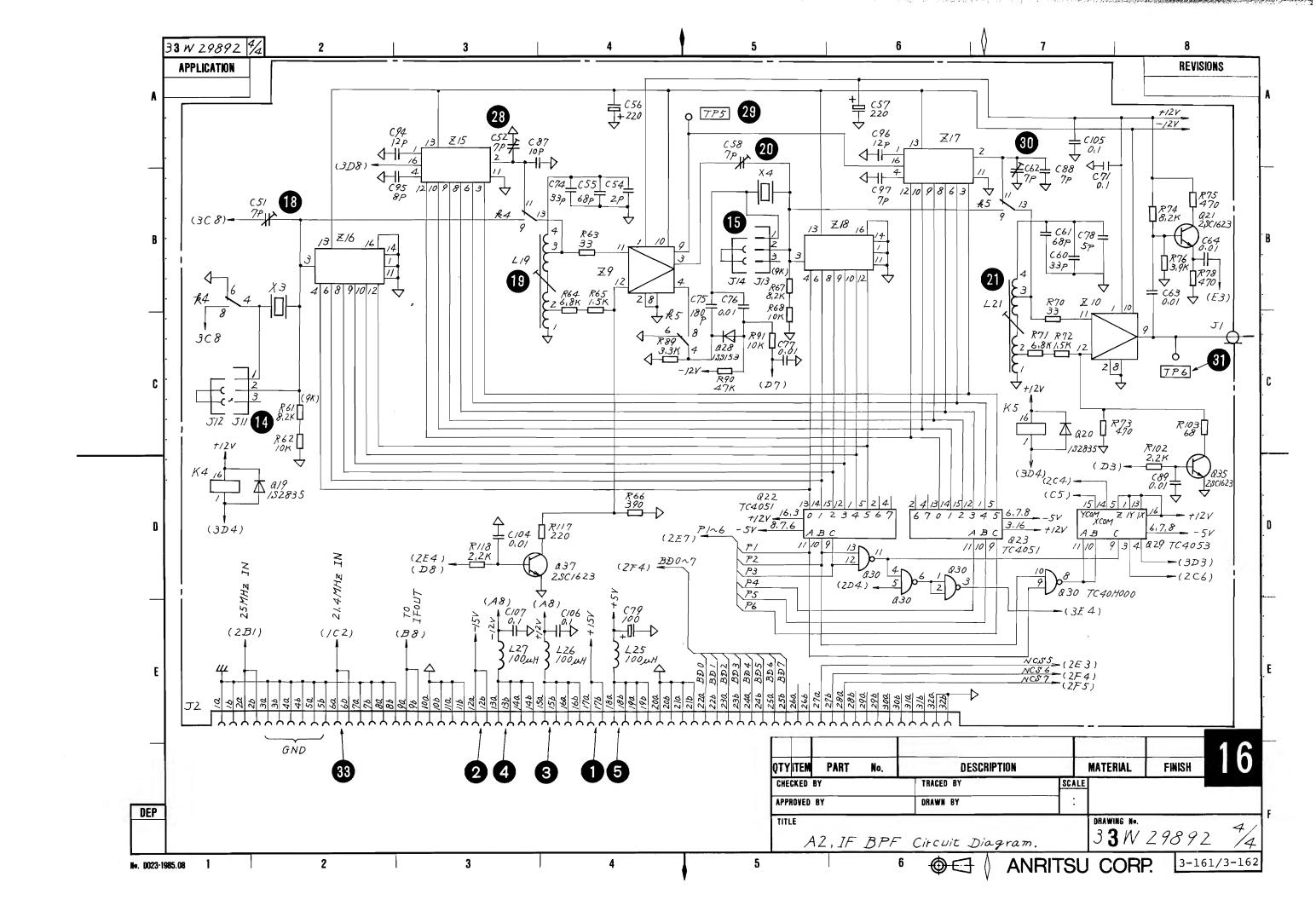


•

,



			)
	,		
			)
			)



)

# 3.3.6 A3 IF LOG/DET 17

## (1) Circuit description

The A3 IF LOG/DET section logarithmically compresses and detects the 3.6 MHz 3rd IF input signal. This detected signal is input to the video filter section. This dc output filtered signal is A/D converted and the digitallized signal is sent to the A8 MAIN CPU.

In the QP detection mode, a QP detector is inserted after the detector.

A3 IF LOG/DET has a frequency distributor for supplying the various reference frequency signals to each circuit.

A reference signal and reference variable attenuator used in automatic calibration are also provided. These circuits are described below in detail in Fig. 3-39 and 17.

#### (a) LOG amplifier

This LOG amplifier is a current addition type ac LOG compression circuit. A seven-stage differential amplifier is used. It has an 80 dB dynamic range. These consists of four hybrid ICs. Outputs of Q87-1 and Q87-7 are used as the reference power sources supplied to the hybrid ICs.

LIN/LOG mode switching is also performed in this section. In the LIN mode, the input signal is not passed through the LOG amplifier but is supplied to the Q2 transistor amplifier directly by switching K1 relay.

#### (b) Detector

The detector consists of a three-transistor dc amplifier and two-diode detector. It is a feedback type detection circuit.

Its detected output is amplified by the dc amplifier and supplied to a variable VIDEO FILTER, which has a dynamic range of 40 dB. In the QP detection mode, this detector is used as an envelop detector.

#### (c) QP detector

The input signal is detected by diode Q30. The electrical charge and discharge time-constants are switched by Q72 and Q37. These time-constants conform to CISPR standards. The dc output is LOG-compressed by pair transistor Q34, which has a dynamic range of 50 dB. The output also enters the filter circuit which determines the mechanical time-constant. This time-constant also conforms to CISPR standards.

#### (d) Video filter

The video filter consists of six low-pass filter circuits. These circuits are switched by switch ICs Q12 and Q13.

#### (e) Frequency counter

The frequency counter counts the Q2 output signal frequency. The receive signal frequency is 3.6 MHz. This signal waveform is shaped by transistor Q18, Q22 limiter circuit and the frequency is counted by the counter IC Q24.

#### (f) A/D converter

The A/D converter consists of a peak signal detection circuit, negative signal detection circuit, sample hold circuit, A/D conversion circuit, and a circuit which controls the timing of these circuits.

The peak signal detection circuit consists of diodes Q39 and Q40 with high impedance at reverse bias, charging capacitor C35, and high input impedance IC to detect the positive signal.

The C35 charged voltage is discharged instantly by the signal from the timing control circuit. At the negative signal detection circuit, the arrangement of diodes Q39 and Q40 is opposite to than of the peak signal detection circuit to detect the negative signal.

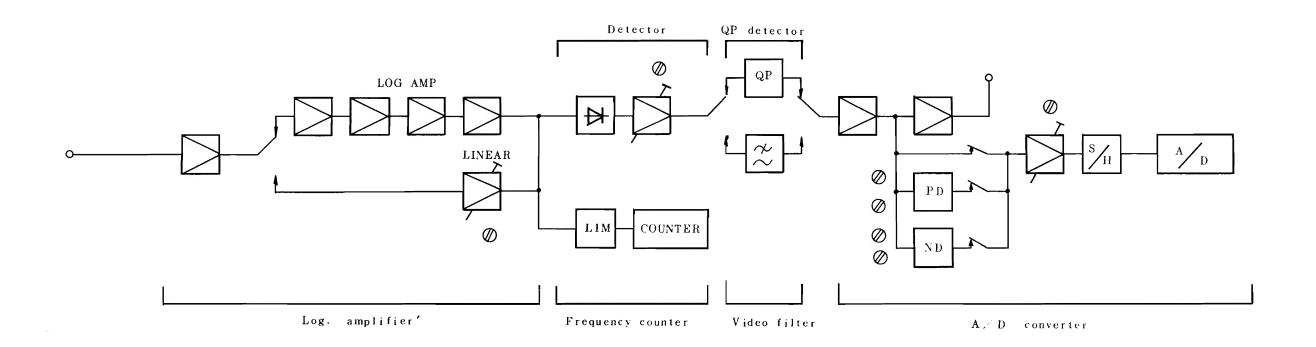
## (g) Frequency distributor

Frequency distribution is performed by digital ICs Q50, Q51, and Q52. The 50 MHz input signal from the REF OSC section is divided by 2 to obtain 25 MHz and becomes the A2 IF BPF 3rd local signal. This signal is further divided by 50 to obtain 500 kHz and becomes the counter circuit reference signal.

The 25 MHz signal is also divided by 40 to obtain 625 kHz and becomes the reference signal for automatic calibration.

#### (h) Reference variable attenuator

Because the power supply voltage of Q52 is highly stabilized, the output level of Q52 is very accurate. The Q56 switch circuit which attenuates the signal level from 0 to 3 dB in 1 dB steps, the Q57 switch circuit which attenuates the signal level from 0 to 12 dB in 4 dB steps, and the Q58 switch circuit which attenuates the signal level to 0, 32, and 36 dB; all of these are cascade-connected so that this Q52 output level can be attenuated from 0 to 52 dB in 1 dB steps. The Q84 IC amplifier output signal is passed through emitter-follower transistor Q85 and is supplied to the RF section in the A1 RF/PLL BLOCK.



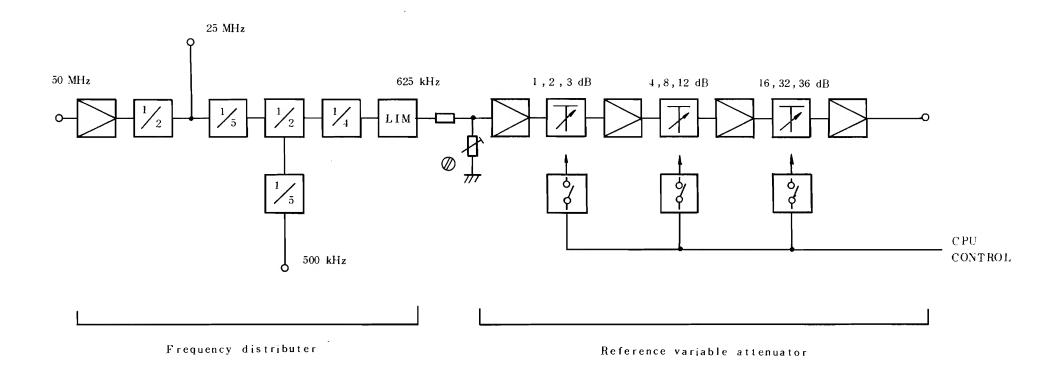


Fig. 3-39 A3 IF LOG/DET Block Diagram

•

# (2) Symptoms and causes

	Symptom	Cause						
1.	No signal on CRT.	LOG amplifier, detector, video filter faulty.						
2.	Linearity very poor when input signal varied key 10 dB.	LOG detector faulty.						
3.	Video filter not switched correctly.	Video filter faulty.						
4.	QP operation not switched correctly.	QP detector faulty.						
5.	Frequency counter	a) Frequency counter faulty.						
	does not count correctly.	b) Frequency distributor faulty.						
6.	Level change is large at line spectrum display.	A/D converter faulty						
7.	No sweep.	A/D converter faulty						
8.	FREQ CAL automatic calibration cannot be	a) Frequency distributor faulty.						
	performed.	b) Reference variable attenuator faulty.						
9.	LEVEL CAL 1 and LEVEL CAL 2 automatic calibration cannot be performed.	Reference variable attenuator faulty.						

(3) Troubleshooting
---------------------

(a) Required equipment
Digital voltmeter
Oscilloscope

Signal generator: MG443B

50  $\Omega$  terminator

Frequency counter: MF76A

(b) Preparations

CAUTION ----

Turn off the power before disassembly.

Step	Procedure							
1	Remove A3 IF LOG/DET by referring to paragraph 2.4.							
2	Reinstall A3 IF LOG/DET by using an extender board.							

(c) Troubleshooting

(Fig. 3-43, 17

Step	Procedure								
1	Check the power supply voltages according to the table below.								
	Checkpoint Normal condition								
	J2-12 <b>1</b> -14.3 to -15.7 V								
	J2-13 <b>2</b> -11.5 to -12.5 V								
	J2-15 <b>3</b> +11.5 to +12.5 V								
	J2-17 <b>4</b> +14.3 to +15.7 V								
	J2-18 <b>6</b> +4.75 to +5.25 V								

Check the LOG amplifier reference voltage according to the table below.

Checkpoint	Normal condition				
Z3-17 <b>6</b>	-11.5 to -12.5 V				
z3-14 <b>7</b>	-7.0 to -8.0 V				
z3-12 <b>8</b>	-3.0 to -4.0 V				

Step Procedure

3 Connect J1 9 to a signal generator (SG) through an extender cable and 50  $\Omega$  terminator as shown below.

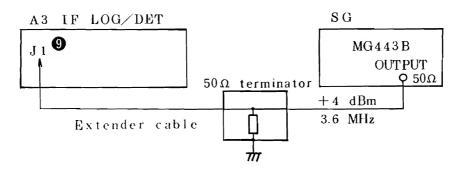


Fig. 3-40 A3 Troubleshooting Setup

4 Press the MS2601A/J [INITIAL] key, then set as follows:

SPAN: 0 kHz

VID BW: 1 Hz

- 5 Lower the SG output level from 0 to 70 dB in 10 dB steps. If the corresponding MS260lA/J display level at this time is within ±2 dB, LOG amplifier operation is normal.
- 6 Check the frequencies of the following points with a frequency counter:

Q51-8 **1** 500 kHz

TP6 (19 25 MHz

Q52-9 **1** 625 kHz

7 Connect J1 9 to J1 (Fig. 2-3) in A2 IF BPF with an extender cable.

	(00::21::404)
Step	Procedure
8	Check the automatic calibration function as follows:
	Press the [LEVEL CAL 1], [LEVEL CAL 2], or [FREQ CAL] keys and check if the operating time becomes:
	LEVEL CAL 1 Approx. 30 s
	LEVEL CAL 2 Approx. 45 s
	FREQ CAL Approx. 7 s
	If not OK, the frequency distributor or reference variable attenuator is faulty.
9	Check the A3 IF LOG/DET control signal set values shown in Tables 3-17 to 3-21.

Table 3-17 VBW Control Signals

VBW se	et value	19	Q14 p:	Q15 pin No.			
				16	15	12	13
100	kHz	0	0	1	0	0	0
10	kHz	1	1	1	0	0	0
1	kHz	1	0	1	0	0	0
100	Hz	0	0	1	0	1	0
10	Hz	1	1	1	0	· 1	0
1	Hz	0	1	1	0	1	0
OFF		0	1	1	1	0	0

<sup>1 ...</sup> Approx. 5 V 0 ... Approx. 0 V

				(continued)
Step	Pro	cedure		
9 (Cont.)	Table 3-18 QP	Control	Signals	
	QP set value	Q14 16	pin No.	13
	QP 120 k	0	0	0
	QP 9 k	0	1	0
	QP 200 Hz	0	0	1
	OFF	1	*	*
	1 Approx. 5 V 0 Approx. 0 V * Don't care Table 3-19 LOG/	•	rol Signa	als
	Q14	pin No. 17	Q15 pin 12	n No.
	LOG	1	0	<del></del>

0

1

LIN

Step		Pı	roced	dure			
9 Tal	ole 3-20	RF A	ATT (	Conti	rol s	Signa	ls
RF	ATT set	value	e (dI	3) —	Q60 12	pin 13	No.
	0				0	0	0
	10				0	1	0
	20				0	0	1
	30				0	1	1
	40				1	0	1
	50				1	1	1
		ox. 5					
Tal	ole 3-21	CAL	Conf	trol	Sig	nals	
		Q15	pin 19	No.	Q	60 pi 15	
CA	L ON		0			1	
1 0		ox. 5					

### (4) Adjustment

- (a) LOG detector adjustment
  - (i) Setup

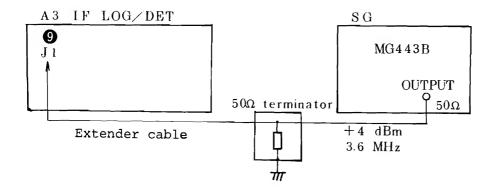


Fig. 3-41 A3 Adjustment Setup

### (ii) Adjustment

Step	Procedure							
1	Apply a 3.6 MHz, +4 dBm signal from a signal generator (SG) to Jl $oldsymbol{9}$ .							
2	Adjust R22 $ lacktrianum{1}{0}$ to obtain a voltage of 4.00 V at TP2 $ lacktrianum{1}{0}$ .							

- (b) DET mode adjustment
  - (i) Setup

(Same as Fig. 3-41)

# (ii) Adjustment

Step	Procedure
1	Connect J4 (connected to J3 (2)) to between J3 (2) pins 2 and 3.
2	Press the [INITIAL][SHIFT] and [5] keys in this sequence to set the DET mode (menu display: SUB TRACE).
3	Press the [F3] key to set the SMP mode.
4	Measure the TP5 (8) voltage. Assume this voltage to be the reference voltage (Approx. 0 V), which is used later for adjustment.
5	Press the [F3] key to set the PEAK mode.
6	Adjust R84 $ extbf{@}$ to set TP5 $ extbf{@}$ voltage to the reference voltage in step 4.
7	Press the [F3] key to set the DIP mode.
8	Adjust R150 $\textcircled{\textbf{f}}$ to set TP5 $\textcircled{\textbf{f}}$ voltage to the reference voltage in step 4.
9	Connect J4 (connected to J3 10) to J3 10 pins 1 and 2. (Return to original state.)
10	Set the SMP mode.
11	Measure the TP5 🔞 voltage.
	Assume this voltage to be the reference voltage (Approx. 2 V), which is used later for adjustment.
12	Set the PEAK mode.
13	Adjust R86 <b>6</b> to set TP5 <b>8</b> voltage to the reference voltage in step ll.

4	,								-	
- 4		$\overline{}$	n	+	٦.	n	11	$\sim$	~	1
•	C	u	11	٠.	1	11	u	⊏:	u	

Step	Procedure
14	Set the DIP mode.
15	Adjust R153 <b>1</b> to set TP5 <b>1</b> voltage to the reference voltage in step 11.

- (c) Overall adjustment
  - (i) Setup
     (Same as Fig. 3-14)
  - (ii) Adjustment

Step	Procedure
1	Apply a 3.6 MHz, +4 dBm signal from a signal generator (SG) to J1 $oldsymbol{9}$ .
2	After pressing the MS2601A/J [INITIAL] key, set the DET mode to PEAK.
3	Adjust R98 $②$ to set the display level to 0.00 dBm $\pm 0.02$ dB.
4	Press the keys in [SHIFT][8][F5] order to change the MS260lA/J setting from the LOG mode to the LIN mode.
5	Adjust R5 $ extbf{Q}$ to set the display voltage to 224 ±1 mV.

### (d) QP function adjustment

### (i) Setup

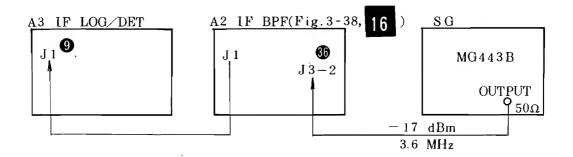


Fig. 3-42 QP Function Adjustment

### (ii) Adjustment

Step	Procedure
1	Setup as follows:
	. By referring to paragraph 2.4, remove A2 IF BPF and also remove the shield cases (55) and (56) (Fig. 2-3).
	. Disconnect J4 (connected to J3  in A2 IF BPF) and solder an extender cable to J3  pin 2 on the pattern side. (Pin 1 is a ground pin.)
	. Next, reinstall the shield case $66$ and A2 IF BPF in the chassis.
2	Connect J1 $\textcircled{9}$ to J1 (Fig. 2-3) in A2 IF BPF with an extender cable and apply a 3.6 MHz, -17 dBm signal from the SG to A2 J3-2 $\textcircled{6}$ .

After pressing the MS2601A/J [INITIAL] key, set as follows:  SPAN: 0 Hz  REF LEVEL: -10 dBm  RBW: 1 kHz  SCALE: LOG 1 dB  4 Change the SG frequency in 100 Hz steps to set it to the frequency at which the MS2601A/J display level is maximum.  5 Change the SG output level so that the marker level is at the top of the MS2601A/J CRT scale.  6 Change the MS2601A/J SCALE to the LIN mode and check if the level value is at the top of the scale.  If not OK, adjust R5 to set the level value at the top of the scale.  Adjustment when 6 dB bandwidth = 120 kHz  7 Set the MS2601A/J RBW to 6 dB bandwidth 120 kHz.  8 Change the SG output level so that the MS2601A/J level value is at the top of the CRT scale.  9 Connect J4 (connected to J3 to ) to J3 to pins 2 and 3.  Adjust R43 to set the Q70-1 to voltage to 0.00 ±0.05 mV.	<del></del>	(continued)
follows:  SPAN: 0 Hz  REF LEVEL: -10 dBm  RBW: 1 kHz  SCALE: LOG 1 dB  4 Change the SG frequency in 100 Hz steps to set it to the frequency at which the MS2601A/J display level is maximum.  5 Change the SG output level so that the marker level is at the top of the MS2601A/J CRT scale.  6 Change the MS2601A/J SCALE to the LIN mode and check if the level value is at the top of the scale.  If not OK, adjust R5 to set the level value at the top of the scale.  Adjustment when 6 dB bandwidth = 120 kHz  7 Set the MS2601A/J RBW to 6 dB bandwidth 120 kHz.  8 Change the SG output level so that the MS2601A/J level value is at the top of the CRT scale.  9 Connect J4 (connected to J3 to J3 pins 2 and 3.  Adjust R43 to set the Q70-1 voltage to 0.00	Step	Procedure
REF LEVEL: -10 dBm  RBW: 1 kHz  SCALE: LOG 1 dB  4 Change the SG frequency in 100 Hz steps to set it to the frequency at which the MS2601A/J display level is maximum.  5 Change the SG output level so that the marker level is at the top of the MS2601A/J CRT scale.  6 Change the MS2601A/J SCALE to the LIN mode and check if the level value is at the top of the scale.  If not OK, adjust R5  to set the level value at the top of the scale.  Adjustment when 6 dB bandwidth = 120 kHz  7 Set the MS2601A/J RBW to 6 dB bandwidth 120 kHz.  8 Change the SG output level so that the MS2601A/J level value is at the top of the CRT scale.  9 Connect J4 (connected to J3  to J3 pins 2 and 3.  Adjust R43  to set the Q70-1  voltage to 0.00	3	
RBW: 1 kHz  SCALE: LOG 1 dB  4 Change the SG frequency in 100 Hz steps to set it to the frequency at which the MS2601A/J display level is maximum.  5 Change the SG output level so that the marker level is at the top of the MS2601A/J CRT scale.  6 Change the MS2601A/J SCALE to the LIN mode and check if the level value is at the top of the scale.  If not OK, adjust R5 to set the level value at the top of the scale.  Adjustment when 6 dB bandwidth = 120 kHz  7 Set the MS2601A/J RBW to 6 dB bandwidth 120 kHz.  8 Change the SG output level so that the MS2601A/J level value is at the top of the CRT scale.  9 Connect J4 (connected to J3 to J3 pins 2 and 3.  Adjust R43 to set the Q70-1 voltage to 0.00		SPAN: 0 Hz
SCALE: LOG 1 dB  4 Change the SG frequency in 100 Hz steps to set it to the frequency at which the MS2601A/J display level is maximum.  5 Change the SG output level so that the marker level is at the top of the MS2601A/J CRT scale.  6 Change the MS2601A/J SCALE to the LIN mode and check if the level value is at the top of the scale.  If not OK, adjust R5 to set the level value at the top of the scale.  Adjustment when 6 dB bandwidth = 120 kHz  7 Set the MS2601A/J RBW to 6 dB bandwidth 120 kHz.  8 Change the SG output level so that the MS2601A/J level value is at the top of the CRT scale.  9 Connect J4 (connected to J3 to J3 pins 2 and 3.  Adjust R43 to set the Q70-1 voltage to 0.00		REF LEVEL: -10 dBm
Change the SG frequency in 100 Hz steps to set it to the frequency at which the MS2601A/J display level is maximum.  Change the SG output level so that the marker level is at the top of the MS2601A/J CRT scale.  Change the MS2601A/J SCALE to the LIN mode and check if the level value is at the top of the scale.  If not OK, adjust R5  to set the level value at the top of the scale.  Adjustment when 6 dB bandwidth = 120 kHz  Set the MS2601A/J RBW to 6 dB bandwidth 120 kHz.  Change the SG output level so that the MS2601A/J level value is at the top of the CRT scale.  Connect J4 (connected to J3  to J3  pins 2 and 3.  Adjust R43  to set the Q70-1  voltage to 0.00		RBW: 1 kHz
the frequency at which the MS2601A/J display level is maximum.  Change the SG output level so that the marker level is at the top of the MS2601A/J CRT scale.  Change the MS2601A/J SCALE to the LIN mode and check if the level value is at the top of the scale.  If not OK, adjust R5 to set the level value at the top of the scale.  Adjustment when 6 dB bandwidth = 120 kHz  Set the MS2601A/J RBW to 6 dB bandwidth 120 kHz.  Change the SG output level so that the MS2601A/J level value is at the top of the CRT scale.  Connect J4 (connected to J3 to J3 pins 2 and 3.  Adjust R43 to set the Q70-1 voltage to 0.00		SCALE: LOG 1 dB
is at the top of the MS2601A/J CRT scale.  6 Change the MS2601A/J SCALE to the LIN mode and check if the level value is at the top of the scale.  If not OK, adjust R5 to set the level value at the top of the scale.  Adjustment when 6 dB bandwidth = 120 kHz  7 Set the MS2601A/J RBW to 6 dB bandwidth 120 kHz.  8 Change the SG output level so that the MS2601A/J level value is at the top of the CRT scale.  9 Connect J4 (connected to J3 to J3 pins 2 and 3.  Adjust R43 to set the Q70-1 voltage to 0.00	4	the frequency at which the MS2601A/J display level
if the level value is at the top of the scale.  If not OK, adjust R5  to set the level value at the top of the scale.  Adjustment when 6 dB bandwidth = 120 kHz  7 Set the MS2601A/J RBW to 6 dB bandwidth 120 kHz.  8 Change the SG output level so that the MS2601A/J level value is at the top of the CRT scale.  9 Connect J4 (connected to J3  to J3  pins 2 and 3.  Adjust R43  to set the Q70-1  voltage to 0.00	5	
the top of the scale.  Adjustment when 6 dB bandwidth = 120 kHz  7 Set the MS2601A/J RBW to 6 dB bandwidth 120 kHz.  8 Change the SG output level so that the MS2601A/J level value is at the top of the CRT scale.  9 Connect J4 (connected to J3 ② ) to J3 ② pins 2 and 3.  Adjust R43 ③ to set the Q70-1 ③ voltage to 0.00	6	_
Set the MS2601A/J RBW to 6 dB bandwidth 120 kHz.  Change the SG output level so that the MS2601A/J level value is at the top of the CRT scale.  Connect J4 (connected to J3 1 ) to J3 1 pins 2 and 3.  Adjust R43 4 to set the Q70-1 3 voltage to 0.00		
Change the SG output level so that the MS2601A/J level value is at the top of the CRT scale.  Connect J4 (connected to J3 1 ) to J3 1 pins 2 and 3.  Adjust R43 4 to set the Q70-1 3 voltage to 0.00		Adjustment when 6 dB bandwidth = 120 kHz
level value is at the top of the CRT scale.  9 Connect J4 (connected to J3 12 ) to J3 12 pins 2 and 3.  Adjust R43 24 to set the Q70-1 28 voltage to 0.00	7	Set the MS2601A/J RBW to 6 dB bandwidth 120 kHz.
and 3. Adjust R43 4 to set the Q70-1 4 voltage to 0.00	8	•
	9	-

Step	Procedure
10	Connect J4 (connected to J3 1 ) to J3 1 pins 1 and 2. (Return to original state.)
	Adjust R47 $\textcircled{9}$ to set the Q70-1 $\textcircled{3}$ voltage to 10.00 $\pm 0.05$ V.
11	Set the QP mode to ON.
12	Set the $\Delta$ marker to ON to set the level display to 0.00 dB.
13	Lower the SG output level by 10 dB.
14	Adjust R74 0 to display the level value to -10.1 dB.
15	Return the SG output level to its original value.
16	Press the [ $\Delta$ ] key (F2) to set the marker level display to 0.00 dB again.
17	Lower the SG output level by 10 dB.
18	Check if the displayed value is -10.1 ±0.05 dB.
19	When the displayed value is not -10.1 ±0.05 dB, repeat steps 14 through 18.
20	Return the SG output level to its original value and adjust R68 ② so that the level value at this time is at the top of the CRT scale.
21	Lower the SG output level by 40 dB.
22	Adjust R63 $\textcircled{8}$ so that the level value is at the 40 dB line (indicated by $\blacktriangleright$ —) display position.

Step	Procedure
	Adjustment when 6 dB bandwidth = 9 kHz
23	Set the 6 dB bandwidth to 9 kHz.
24	Change the SG frequency in 10 Hz steps to set it to the frequency at which the MS2601A/J display level becomes maximum.
25	Change the SG output level so that the marker level is at the top of the MS2601A/J CRT scale.
26	Lower the SG output level by 40 dB.
27	Adust R62 $②$ so that the level value is at the 40 dB line (indicated by $\triangleright$ ——) display position.
	Adjustment when 6 dB bandwidth = 200 Hz
28	Set the 6 dB bandwidth to 200 Hz.
29	Change the SG frequency in 1 Hz steps to set it to the frequency at which the MS2601A/J display level is maximum.
30	Change the SG output level so that the marker level is at the top of the MS2601A/J CRT.
31	Lower the SG output level by 40 dB.
32	Check if the level value is at the 40 dB line (indicated by $\triangleright$ —) display position.
	If not OK, recheck from step 23.

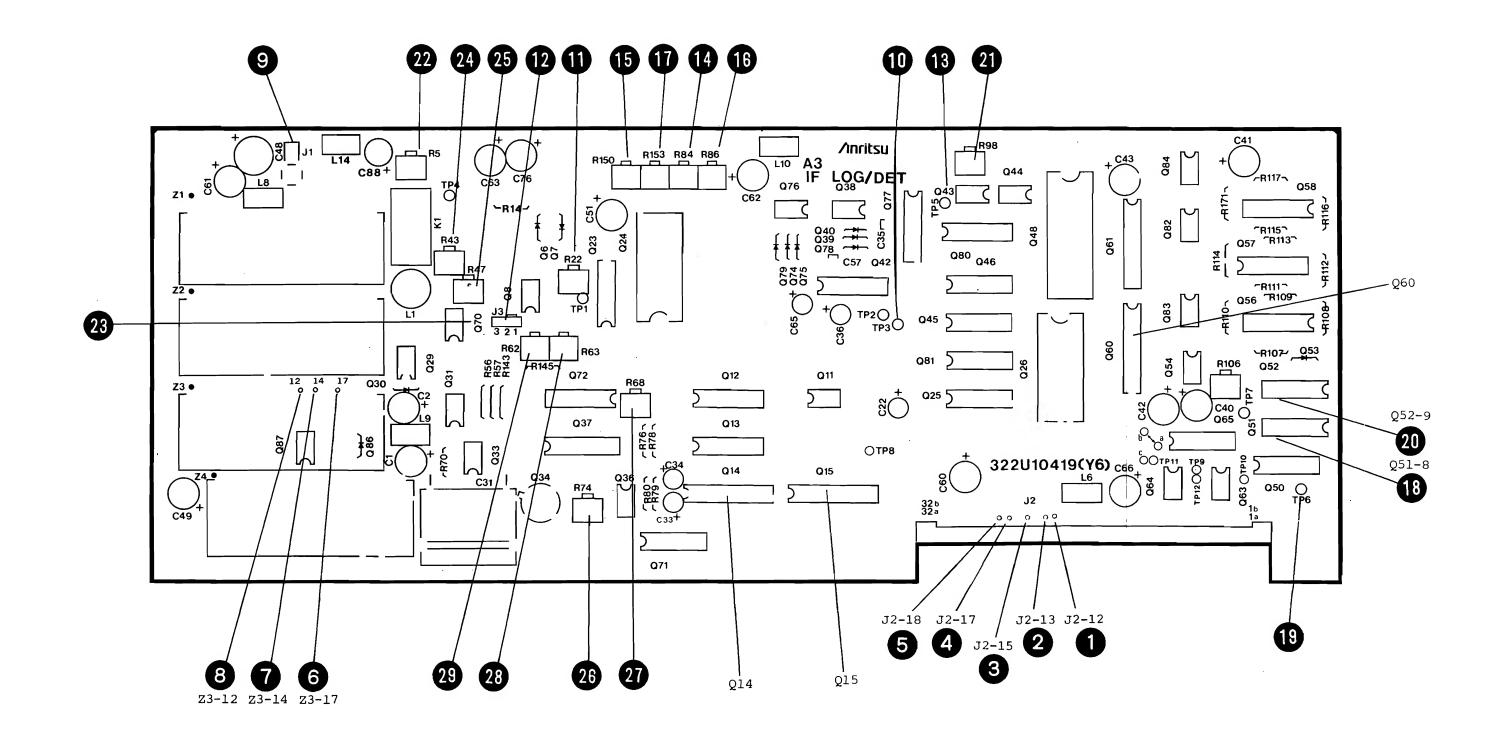


Fig. 3-43 (a) A3 IF LOG/DET PC Board Parts Layout (Parts Side) 17

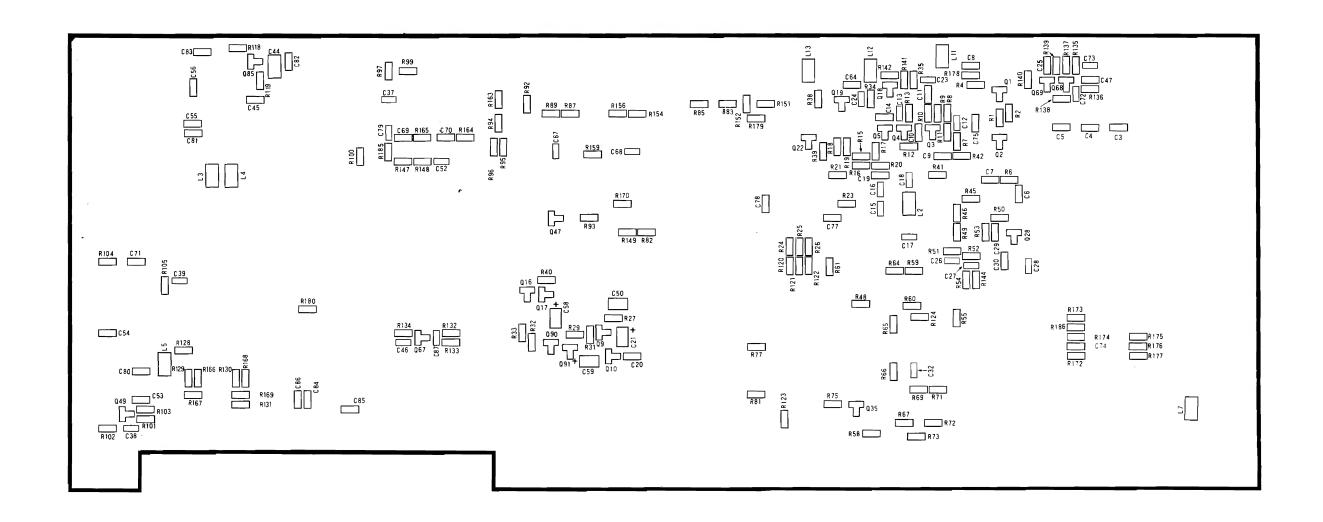
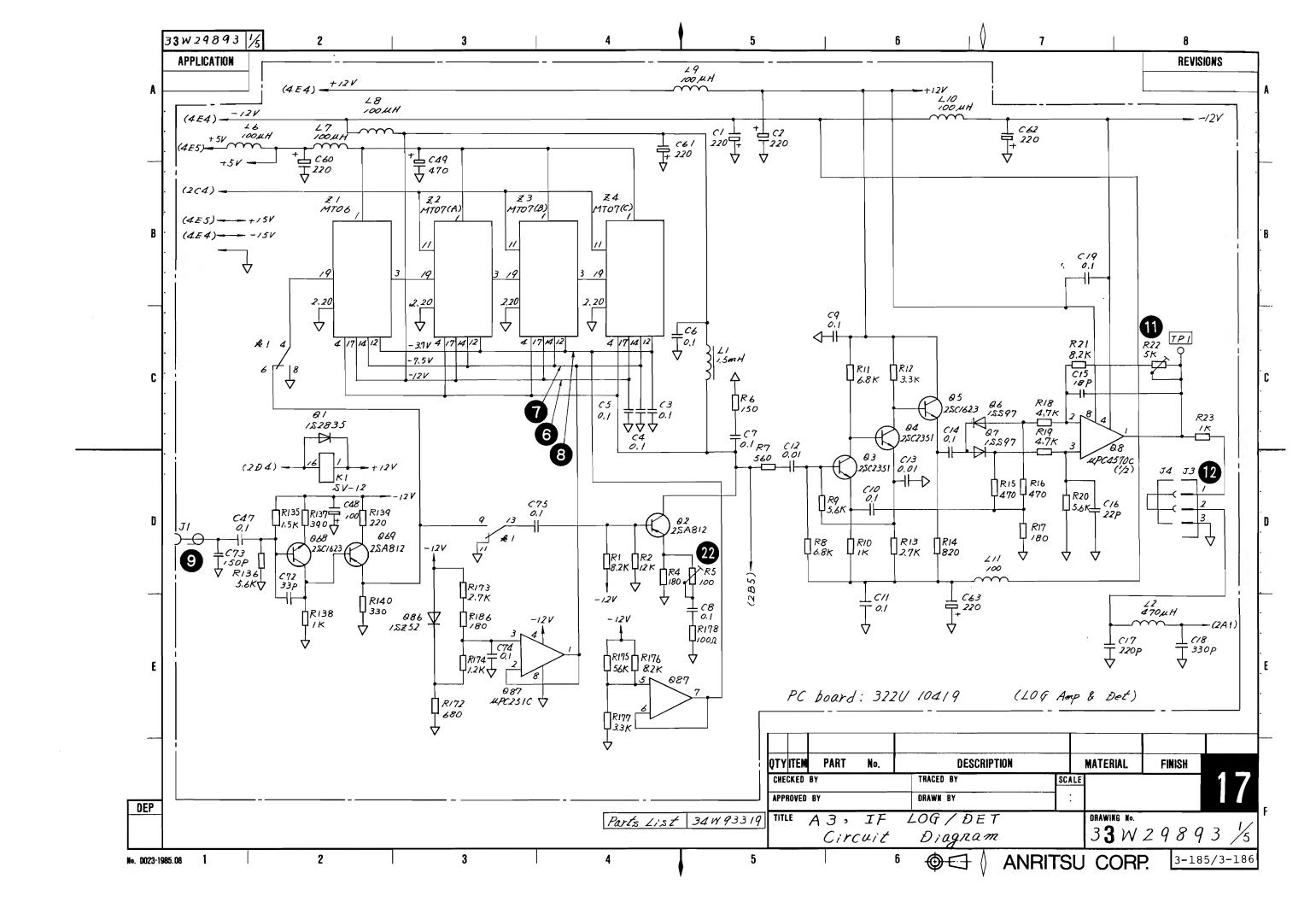
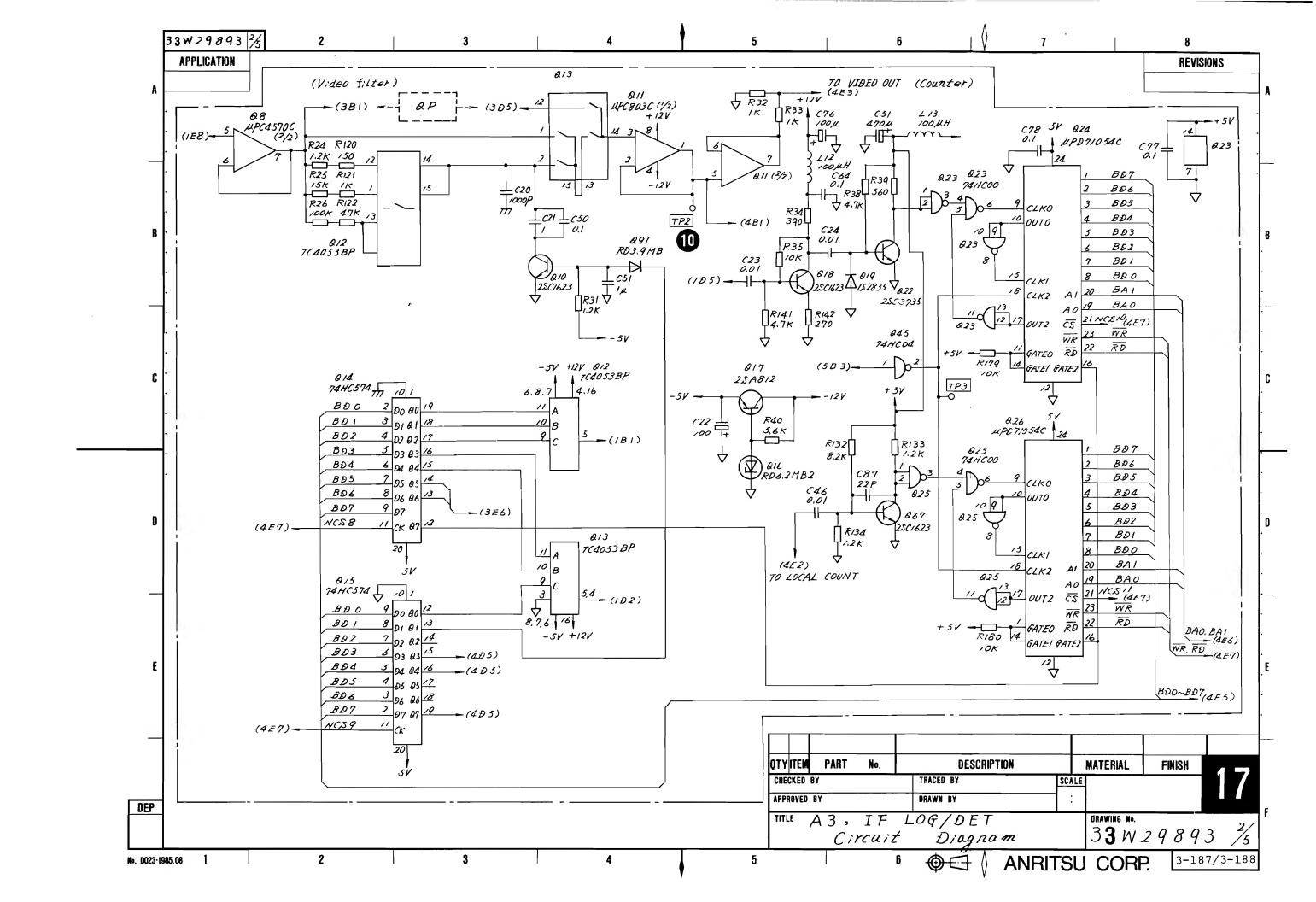
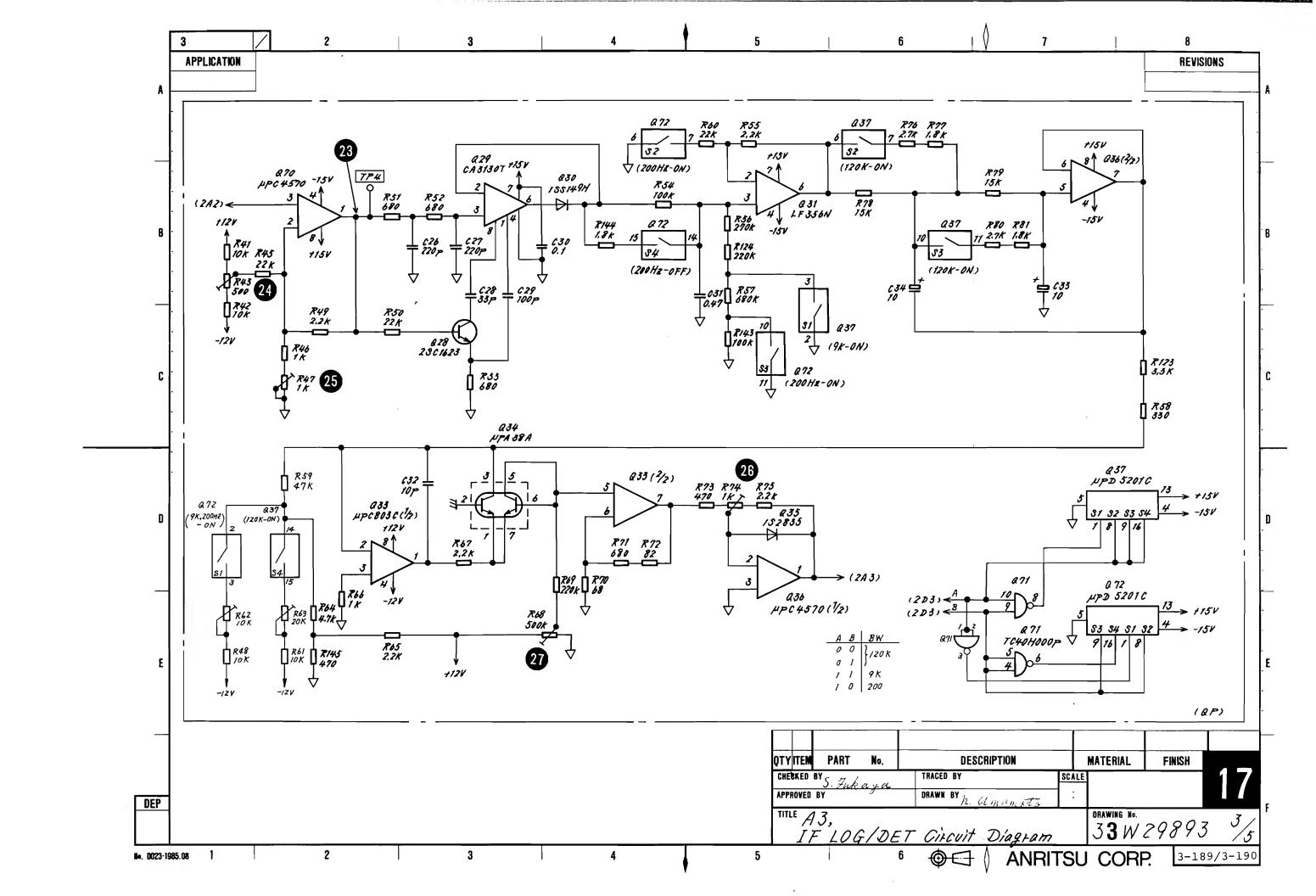


Fig. 3-43 (b) A3 IF LOG/DET PC Board Parts Layout (Pattern Side)

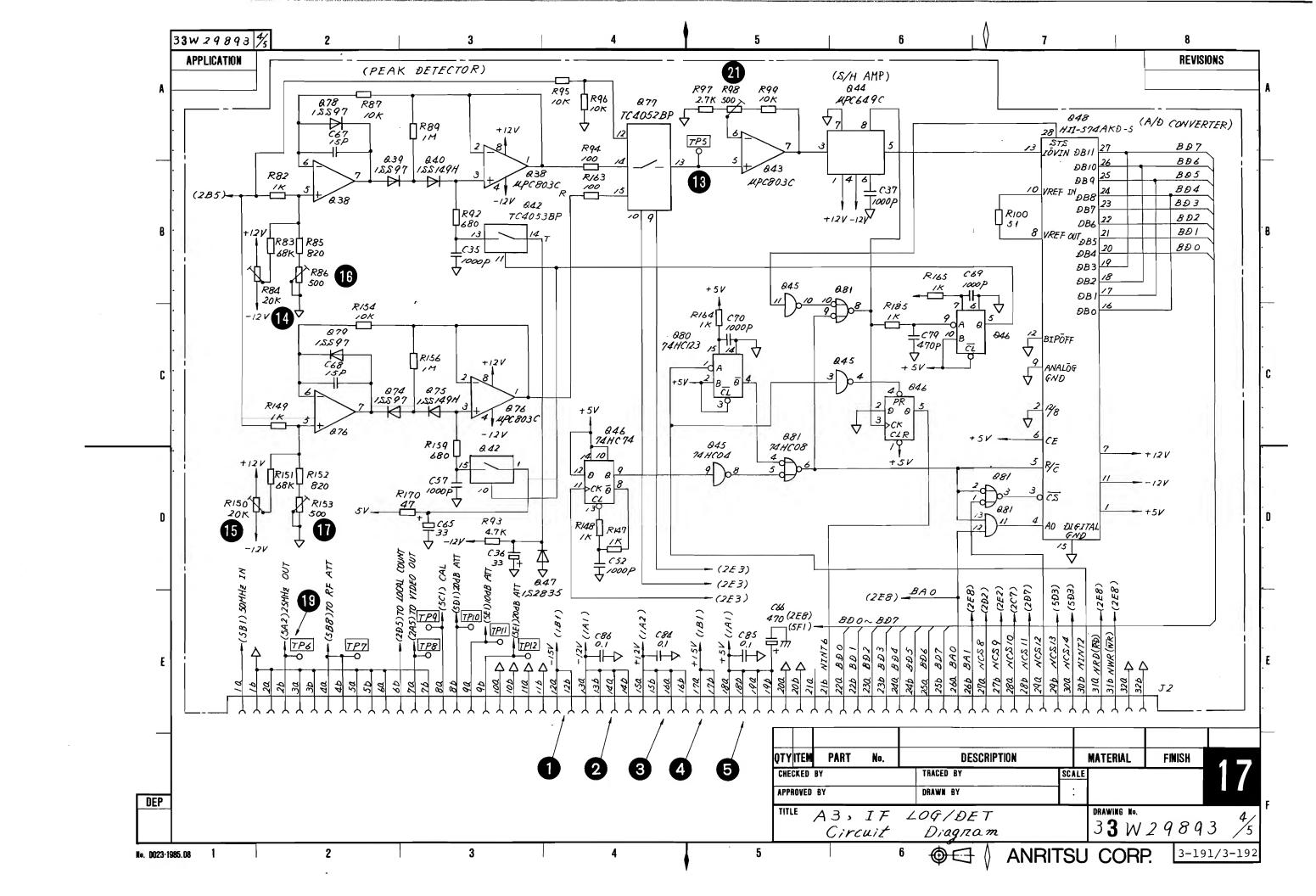




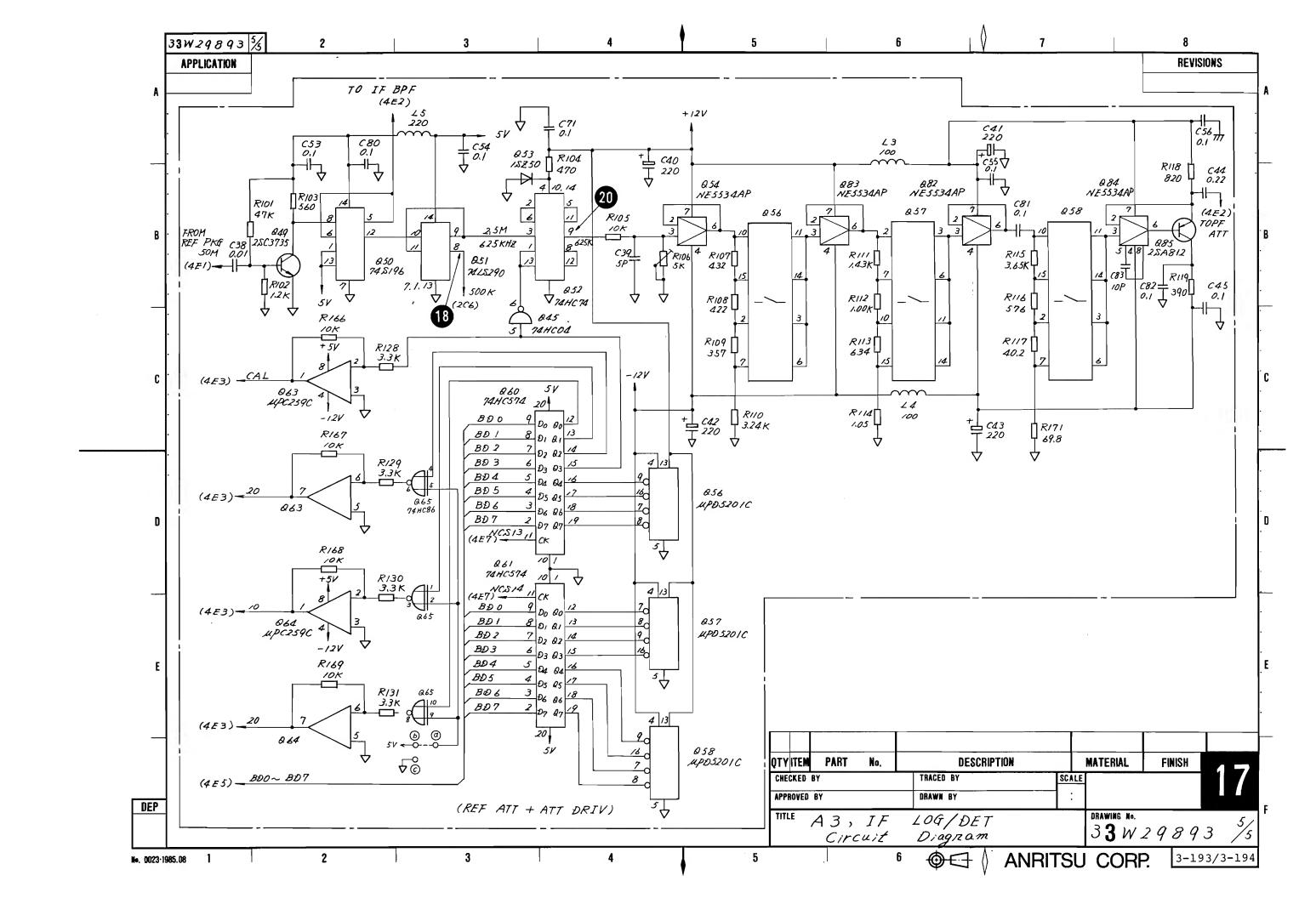
				)
				)
				)



		,
		,
		)
		)



j



				,
	•			
				)
				•

## 3.3.7 A5 FRONT BOARD 18

(1) Circuit description

A5 FRONT BOARD includes key switches, key encoder, rotary encoder, buzzer, etc. Figure 3-44 shows the block diagram.

#### (2) Symptom

- 1. When a specific key is defective, only that key function is not accepted
- When the key encoder is defective, all keys of the key matrix or all keys in a specific row or column cease operation
- 3. When the rotary encoder or pulse detection section is defective, data entry becomes impossible with the data knob, or the value changes in a reverse direction to the knob turning
- When the buzzer is defective, the buzzer does not sound at wrong key entry (For example, when unit key is pressed without entering a numeric key)

#### (3) Troubleshooting

- (a) Required equipment digital voltmeter Oscilloscope
- (b) Preparation

	CAUTION	
Turn off	the power before disassembly.	

Remove the front panel as described in paragraph 2.3. However, do not remove the W1 connector.

#### (c) Troubleshooting

Check each checkpoint by referring to the following table.

Signal name	Ch	eckpoint	Normal condition
+5 V	0	(Q1-40)	+5 ±0.25 V
CPU8MZ	0	(Q2-11)	8 MHz pulse wave
			Approx. 0.05 ms
SLO	6	(Q3 <b>-</b> 1)	$\overrightarrow{\uparrow}$ $\square$ $\square$ $\square$
SL1	4	(Q3-2)	
SL2	6	(Q3-3)	
			2 to 10 µs
IRQ	6	(Q1-4)	When key pressed
(Rotary	0	(Q5-2)	When encoder turned clockwise
encoder)			
(Rotary encoder)	8	(Q5-11)	<b>8</b>
			When encoder turned counterclockwise
			3
			<b>3</b>

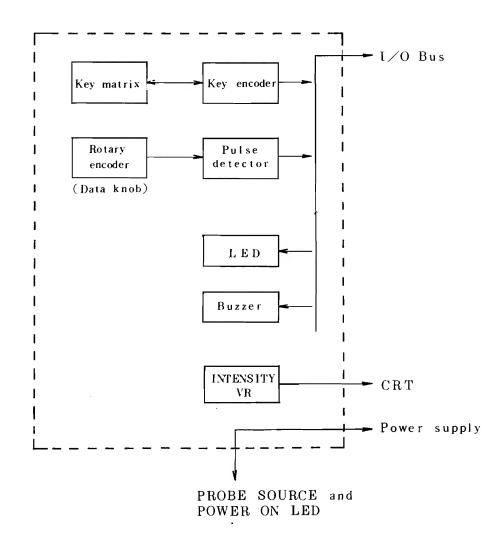


Fig. 3-44 A5 FRONT BOARD Block Diagram

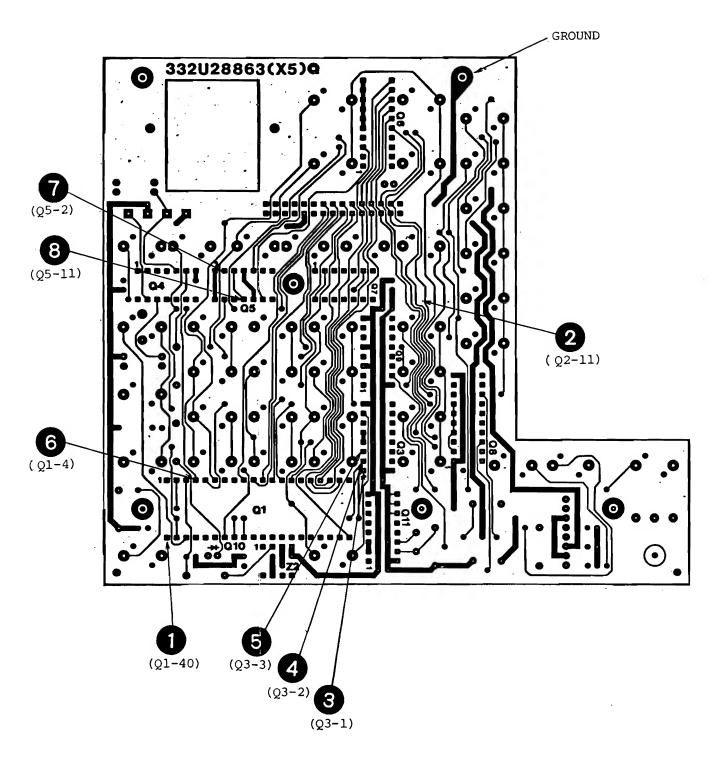


Fig. 3-45 (a) A5 FRONT BOARD PC Board Parts Layout (Pattern Side) 18

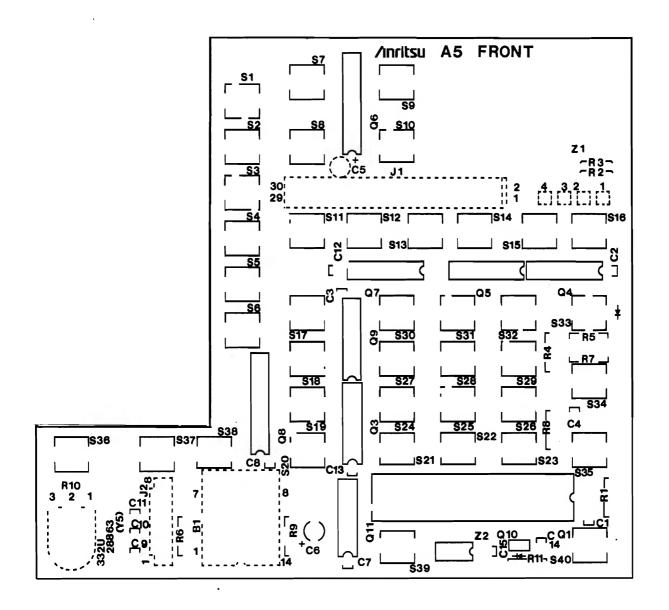
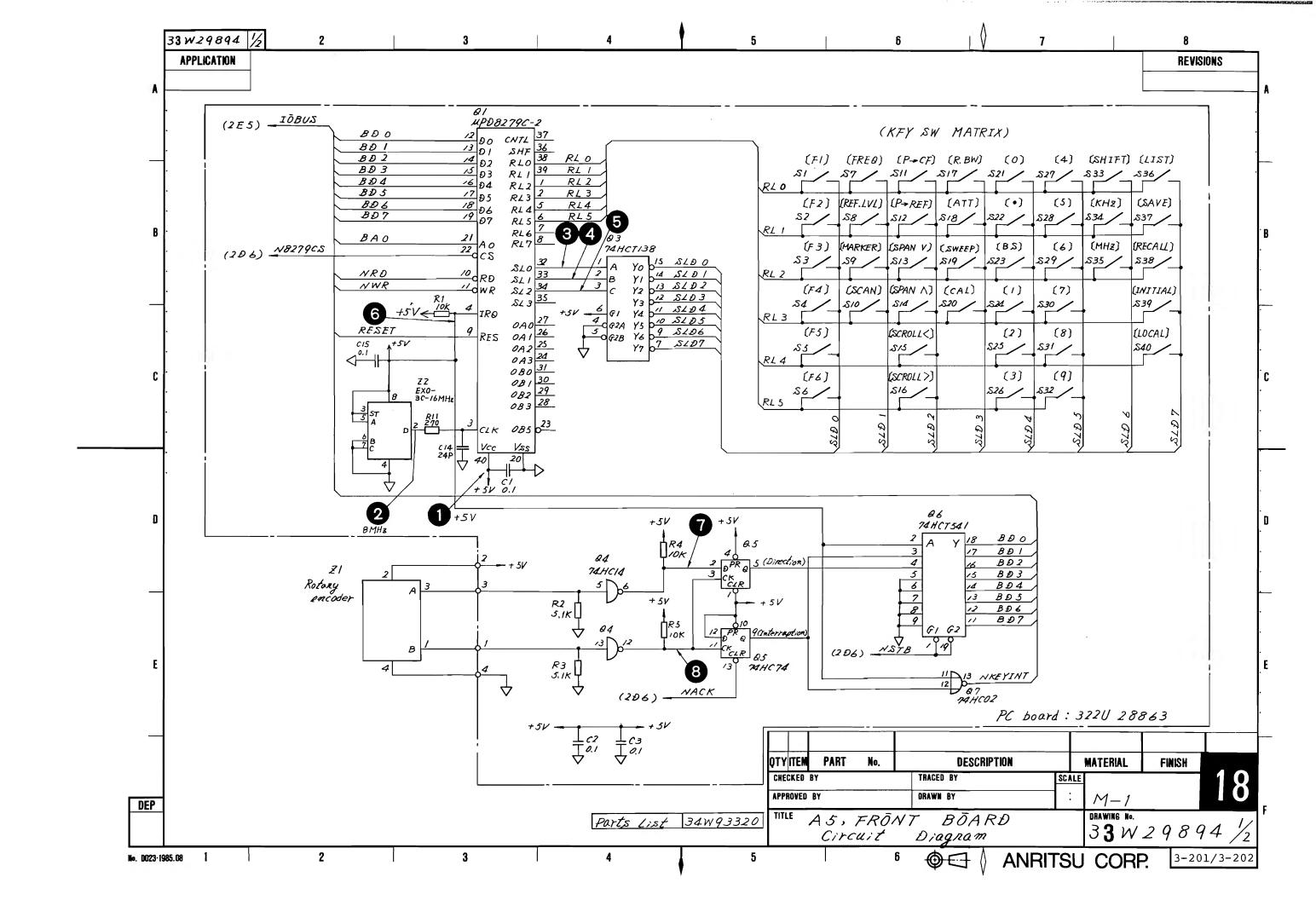
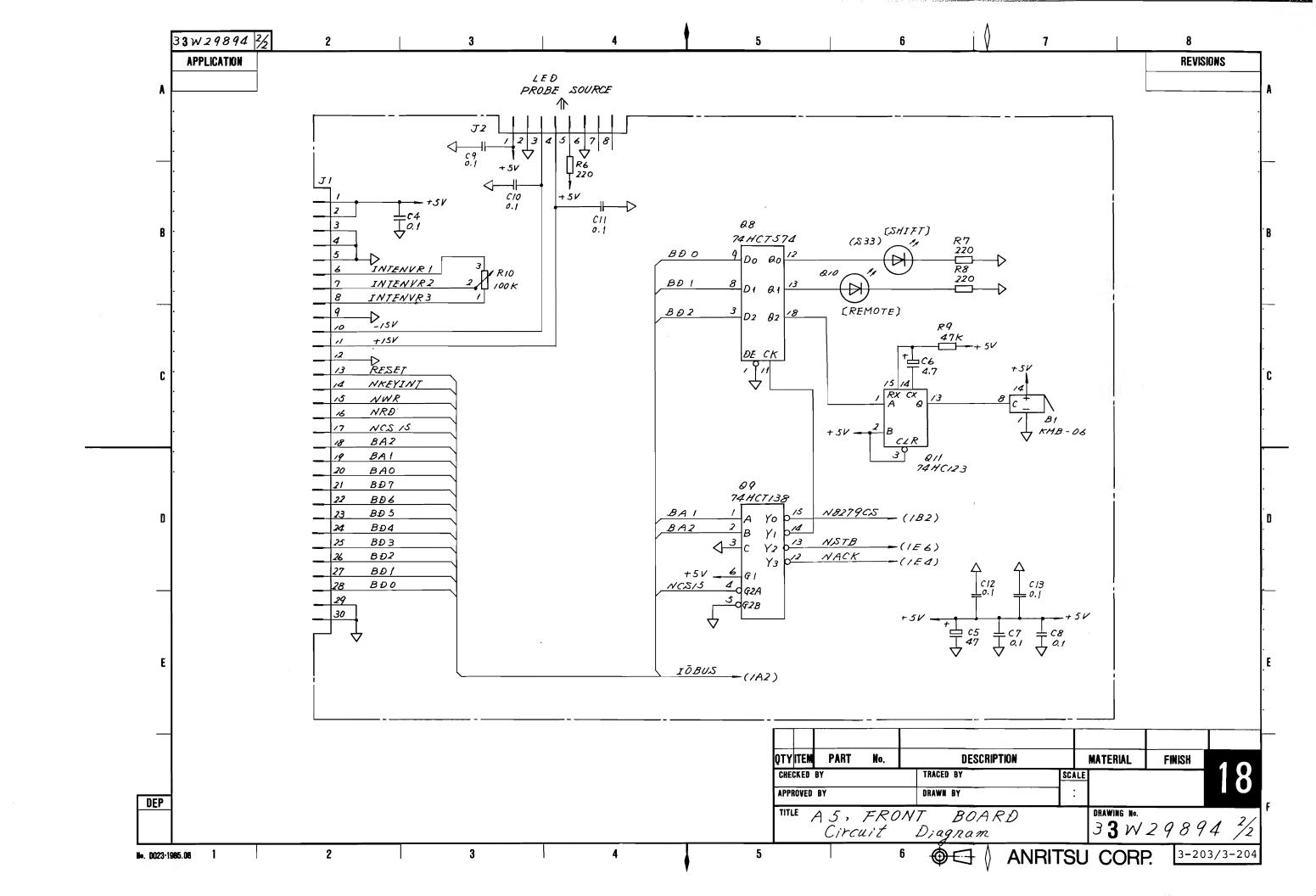


Fig. 3-45 (b) A5 FRONT BOARD PC Board
Parts Layout (Parts Side) 18



				)
,	,			
				•
				,
			*	
				,
				,



## 3.3.8 A6 SCAN/YTO DRIVE, Z1 YTO

## (1) Circuit description

Refer to the A6 block diagram shown in Fig. 3-46.

#### (a) A6 SCAN/YTO DRIVE

This part is composed of two circuits: a SCAN GENERATOR circuit and YTO DRIVE circuit.

#### (i) SCAN GENERATOR

This generator produces a sweep voltage (ramp voltage), which is applied to A1-A15 20 Hz STEP VCO CONT and A6 YTO driver, that varies the frequency sweep according to the frequency span setting. A8 MAIN CPU controls the sweep time, trigger mode, sweep start/stop, etc.

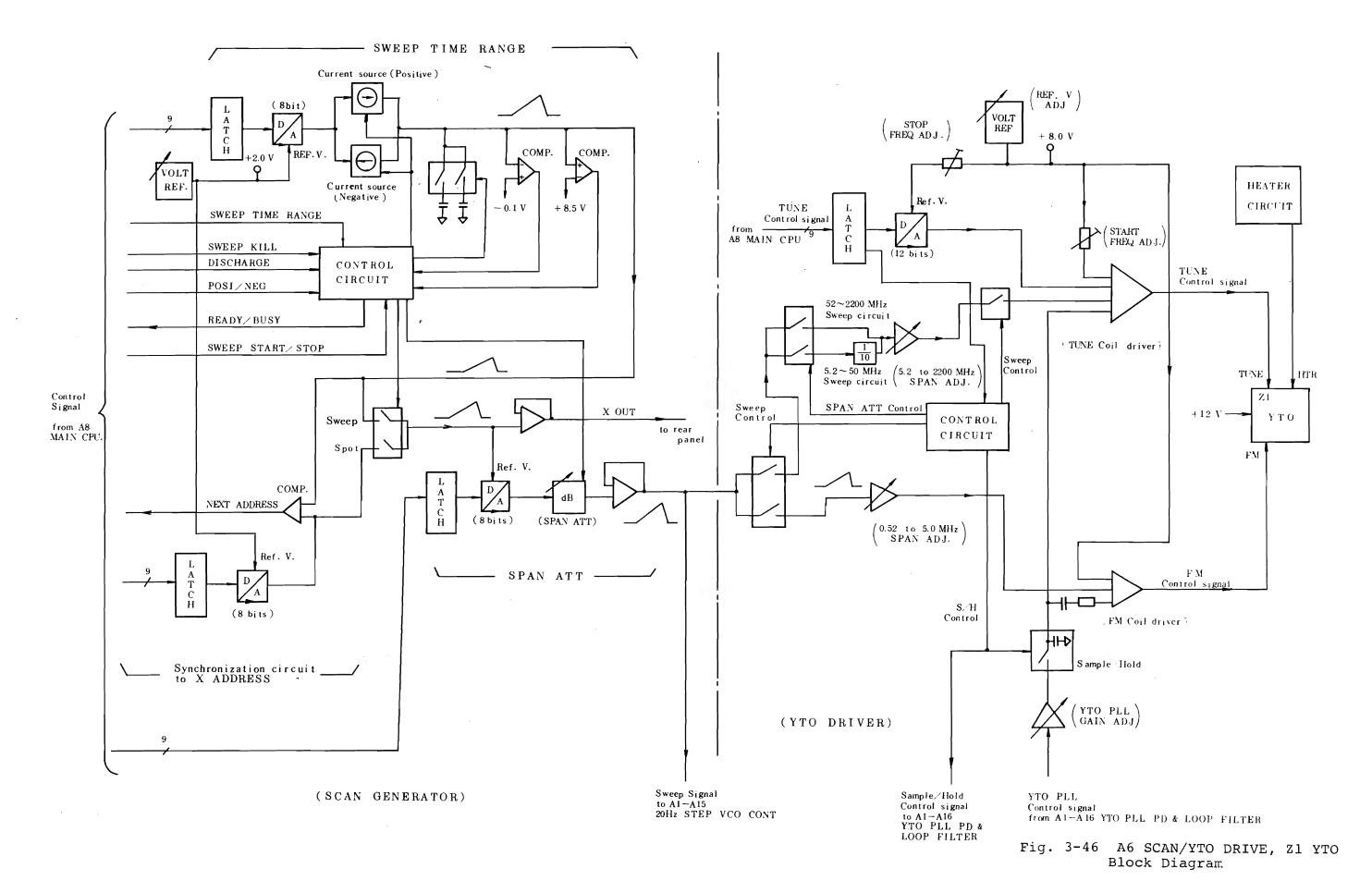
#### (ii) YTO DRIVE

This part drives the Z1 YTO. The sweep voltage for a SPAN exceeding 5.2 MHz is applied to the TUNE coil driver. The YTO PLL control voltage from A1-A16 YTO PLL PD & LOOP FILTER and the sweep voltage for a SPAN (520 kHz to 5.0 MHz) are applied to the FM coil driver. Moreover, the tuning voltage is applied to the TUNE coil driver by the D/A converter controlled by the A8 MAIN CPU according to the START FREQ change in 1 MHz step.

#### (b) Zl YTO

The YTO contains a TUNE coil and an FM coil which are driven by current.

The YTO is a YIG-tuned oscillator which generates a 2.5214 to 4.7214 GHz signal as the 1st local OSC.



3-207/(3-208 blank)

		)
		,
		,
		)

# (2) Symptom and cause

	Symptom		Cause	Unit to be checked
1.	Frequency drifts by 10 MHz or more	(a)	YTO PLL unlocked	A6 SCAN/YTO DRIVE Z1 YTO
2.	Does not sweep properly when SPAN set to	(a)	Sweep signal not output	A6 SCAN/YTO DRIVE (SCAN GENERATOR)
	500 kHz or less	(b)	Sweep start opera- tion not functioning normally	
3.	Does not sweep properly when SPAN set to 501 kHz or more	(a)	Defective YTO Driver (Sweep control)	A6 SCAN/YTO DRIVE (YTO DRIVER) Z1 YTO
4.	Entire waveform swings left and right	(a)	YTO PLL unlocked	A6 SCAN/YTO DRIVE

# (3) Troubleshooting A6 SCAN/YTO DRIVE

(a) Required equipment

Digital voltmeter

Frequency counter: MF76A

Oscilloscope

Spectrum analyzer: MS612A

(b) Preparation

Turn off the power before disassembly.

Step	Procedure
1	Remove the top cover (paragraph 2.2).
2	Remove the A6 SCAN/YTO DRIVE unit. (paragraph 2.4, Fig. 2-3).
3	Reconnect the A6 SCAN/YTO DRIVE unit again using a extender board and extender cable.

# (c) A6 SCAN/YTO DRIVE troubleshooting

The A6 SCAN/YTO DRIVE unit is composed of two circuits: a SCAN GENERATOR circuit and YTO DRIVER circuit.

The troublehsooting procedures for the two circuits are explained separately in steps 2 to 3 and 4 to 9.

Step	Procedure
1	Check the following voltages:
	<ul> <li>Voltage vetween J1-13 (a, b)  and J1-1 (a, b)</li> <li>(GND) is within -11.5 to -12.5 V</li> </ul>
	<ul> <li>Voltage between J1-15 (a, b) 3 and J1-1 (a, b)</li> <li>(GND) is within +11.5 to +12.5 V</li> </ul>
	<ul> <li>Voltage between J1-18 (a, b) 4 and J1-1 (a, b)</li> <li>(GND) is within +4.75 to +5.25 V</li> </ul>
	If the above-mentioned voltages are abnormal, check Z4 REGULATOR section (paragraph 3.3.3).

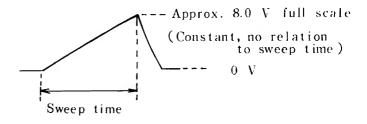
Step	Procedure
Step	Procedure

----- SCAN GENERATOR troubleshooting -----

2 Check the signal at each checkpoint according to the following table.

Checkpoint	Normal condition					
TP4 (V REF) <b>5</b>	+2.00	V ±0.1 V				
TP1 <b>6</b> (Reference voltage for sweep time:	Sweep time set value	TPl 6 (Const. Voltage)				
$[\frac{N}{256}] \times 2 \times 1.21 \text{ Vdc}$ typ. [Table 3-22])	50 ms 200 ms 2 s 20 s 100 s	0.756 V typ. 1.89 V typ. 1.89 V typ. 1.89 V typ. 0.378 V typ.				

TP3 (Sweep time range setting circuit output)



TP5 **8**(X-address data synchronous with sweep on CRT)

Same as TP3 waveform

Q41-7 pin **9** (SPAN ATT output signal)



SPAN	Q41-7 pin <b>9</b>
set value	Y Vp-p
50 kHz	Approx. 8.0
2.0 MHz	Approx. 3.20
100 MHz	Approx. 1.60

Step Procedure

Check the control signals of the SCAN GENERATOR circuit shown in Table 3-22 to 3-24.

Table 3-22 D/A Converter (Q2) Control Signal for Setting Sweep Time

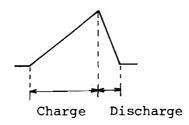
Sweep Time x 10	( M	SB)	Q	2 p	in	No.	(T.	SB)	-
(s)	5	6	7	8	9	10	11	12	N
2	1	1	0	0	1	0	0	0	200
3	1	0	0	0	0	1	0	1	133
5	0	1	0	1	0	0	0	0	80
7	0	0	1	1	1	0	0	1	57
10	Ò	0	1	0	1	0	0	0	40
15	0	0	0	1	1	0	1	1	27

#### Note:

TTL level (Positive logic) n = -2 to +1

TP1 6 voltage =  $\frac{N}{256}$  x 2 x 1.21 [Vdc] typ.

Step	Procedure								
3 (Cont.)	Tab	Chang .nga1	ge-over						
		Sweep Time Range	K1 Control Signal (ST4)						
		50 to 150 ms	0	1	0	1	1		
	Charge	02 to 1.5 s	1	1	0	1	1		
		2 to 15 s	0	1	1	1	0		
		20 to 100 s	1	1	1	1	0		
		50 to 150 ms	0	0	0	0	1		
Dis-		0.2 to 1.5 s	0	1	0	0	1		
	charge	2 to 15 s	0	0	0	0	0		
		20 to 100 s	0	0	1	0	0		



Note:

TTL level (Positive logic)

Step

Procedure

3 Table 3-24 D/A Converter (Q40) Control Signal (cont.) for Setting SPAN ATT

SPAN				Q40	) pi	n No	•		N
$\times 10^{n}$	(MSB)							(LSB)	
(kHz)	5	6	7	8	9	10	11	12	
52	0	0	0	1	1	0	1	0	25
54	0	0	0	1	1	0	1	1	26
56	0	0	0	1	1	1	0	0	27
•					•				:
•					•				:
198	0	1	1	0	0	0	1	1	99
200	0	1	1	0	0	1	0	0	100
202	0	1	1	0	0	1	0	1	101
204	0	1	1	0	0	1	1	0	102
:					•				:
490	1	1	1	1	0	1	0	1	245
•					•				:
500	1	1	1	1	1	0	1	0	250

Note:

TTL level (Positive logic)

$$n = -2 to +4$$

TP7 voltage =

 $\frac{N}{256}$  x TP6 voltage Vp-p value x 0.93 [Vp-p] typ.



Step	Procedure

----- YTO DRIVER troubleshooting -----

4 Check the signal at each checkpoint according to the following table.

Normal condition
+8.00 V ±0.1 V
<pre>&lt;±8.0 V at 0° to 50°C when START FREQ is from 0 to 2200 MHz</pre>
START FREQ TP12 (V)
0 Approx. +0.195 100 Approx. +0.39 500 Approx. +1.17 1000 Approx. +2.15 1500 Approx. +3.12 2000 Approx. +4.10 2200 Approx. +4.49

If the voltages at TP8, TP9, and TP12 are abnormal, YTO PLL may become unlocked. If these voltages are abnormal, the YTO DRIVER must be readjusted (paragraph 3.3.8(4)(b)).

- 5 Check the D/A converter (Q63) control signal for setting the tuning voltage shown in Table 3-47.
- 6 Check the YTO DRIVER sweep control signal shown in Table 3-48.
- 7 Check the TUNE coil driver control signal shown in Table 3-49.

Step	Procedure

8 Check the heater voltage applied to Z1 YTO according to the following table.

Checkpoint			Level
J4-3	pin	(HTR1)	-3.5 V typ.
J4-2	pin	(HTR2)	GND
J4-1	pin	(HTR3)	-5.3 V typ.

9 Check the relationship between the START FREQ and the 1st local output frequency shown in Table 3-50.

Table 3-47 D/A Converter (Q63) Control Signal for Setting Tuning Voltage

START FREQ	1st local output	(M	SB)				ç	 263	pir	n No	o,		(LSB)	N
(MHz)	frequency (MHz)	4	5	6	7	8	9	10	11	12	13	14	15	
0	2521.4	0	0	0	0	0	1	1	0	0	1	0	0	100
1	2522.4	0	0	0	0	0	1	1	0	0	1	0	1	101
2	2523.4	0	0	0	0	0	1	1	0	0	1	1	0	102
3	2524.4	0	0	0	0	0	1	1	0	0	1	1	1	103
4	2525.4	0	0	0	0	0	1	: 1	0	1	0	0	0	104 :
100	2621.4	0	0	0	0	1	1	. 0	0	1	0	0	0	200
500	3021.4	0	0	1	0	0	1	.0	1	1	0	0	0	600
1000	3521.4	0	1	0	0	0	1	. 0	0	1	1	0	0	1100
1500 •	4021.4	0	1	1	0	0	1	. 0	0	0	0	0	0	1600
2000	4521.4	1	0	0	0	0	0	. 1	1	0	1	0	0	2100
2200	4721.4	1	0	0	0	1	1	1	1	1	1	0	0	2300

#### Note:

TTL level (Positive logic)

TP12 tuning voltage =  $\frac{N}{4096}$  x (-ref. voltage at Q63-17 pin) [V] typ.

Table 3-48 YTO DRIVE Sweep Control Signal

			SPAN set va	alue				
Q62 pin No.		FM coil		TUNE coil				
	0 Hz	0.52 to	5.2 to	52 to	520 to			
		5.0 MHz	50 MHz	500 MHz	2200 MHz			
(DO) 19	0	0	1	1	1			
(D1) 18	0	1	1	1	1			
(D2) 17	1	1	0	1	1			
(D3) 16	1	0	0	0	0			

#### Note:

DO: Selects FM or TUNE coil

1: TUNE coil

2: FM coil

D1: Selects whether the YTO DRIVER sweep is on or off

1: YTO DRIVER sweep

0: A1-A15 20 Hz STEP VCO CONT. sweep

D2: Controls SPAN ATT chargeover switch (Q65)

1: Selects 52 to 2200 MHz sweep circuit

0: Selects 5.2 to 50 MHz sweep circuit

D3: Selects sample or Hold

1: Sample

0: Hold

Table 3-49 TUNE Coil Driver Control Signal

		s	PAN set value	e	
Relay	FM coil		TUNE coil		0 Hz and
	0.52 to 5.0 MHz	5.2 to 50 MHz	52 to 500 MHz	520 to 2200 MHz	1 to 500 kHz
К2	ON	OFF	OFF	OFF	ON
к3	ON	OFF	OFF	OFF	OFF

#### Note:

Switch between pin Nos. 3 and 4 of Q65 are ON only at sampling when the TUNE coil is selected

Table 3-50 Relationship between the START FREQ and 1st Local Output Frequency

START FREQ (MHz)	lst Local Output Frequencies (MHz)
0	2521.4
100	2621.4
500	3021.4
1000	3521.4
1500	4021.4
2000	4521.4
2200	4721.4

- (4) A6 SCAN/YTO DRIVE Adjustment
  - (a) SCAN GENERATOR adjustment

This circuit must be adjusted before the following adjustments.

- 1. A1-A15 20 Hz STEP VCO CONT. 1 kHz to 500 kHz SPAN linear adjustment
- 2. YTO DRIVER 520 kHz to 2200 MHz SPAN
  linearity adjustment (paragraph 3.3.8 (4)
  (b)(iii) and (iv))
- (i) Reference voltage (TP4 6 , +2.00 V) adjustment

Step	Procedure
1	Connect a digital voltmeter to TP4 5.
2	Adjust R22 $lackbox{18}$ so that +2.00 ±0.01 V is obtained.

# (ii) SCAN GENERATOR level adjustment

Step	Procedure
1.	Press the [INITIAL] key.
2	Press the [SHIFT] [TRIG] keys and then [F5] SINGLE key on the CRT menu to stop sweep.
3	Press [SHIFT] [CAL] keys and then [F3] SCAN ADJ1 soft key on the CRT menu.
4	Connect a digital voltmeter to Q41-pin 7 9.
5	Adjust R40 1 so that 9 voltage is +8.00 ±0.01 V.

(b) YTO DRIVER adjustment

Make this adjustment 15 minutes or more after power-on. (After the Z1 YTO oscillation frequency has stabilized.)

YTO DRIVER 520 kHz to 2200 MHz SPAN linearity adjustments (paragraphs 3.3.8(4) (b)(iii) and (iv) must be performed after SCAN GENERATOR adjustment (paragraph 3.3.8(4)(a)).

(i) Reference voltage (TP8 (0 , +8.00 V) adjustment

Step	Procedure
1	Connect a digital voltmeter to TP8 $ $
2	Adjust R88 $\bullet$ so that +8.00 ±0.01 V is obtained.

(ii) START FREQ (2521.4 MHz) and STOP FREQ (4721.4 MHz) adjustment

Step	Procedure
1	Press the [INITIAL] key.
2	Set as follows:
	START FREQ: 0 Hz
	SPAN: 0 Hz
3	Connect a frequency counter to the FIRST LOCAL OUTPUT on the rear panel.
4	Adjust R99 <b>6</b> so that the FIRST LOCAL OUTPUT frequency is 2521.4 ±1 MHz.

	(continued)
Step	Procedure
5	Set as follows:
	START FREQUENCY: 2200 MHz
	SPAN: 0 Hz
6	Adjust R82 $m{0}$ so that the FIRST LOCAL OUTPUT frequency is 4721.4 $\pm 1$ MHz.

(iii) 0.52 to 5.0 MHz SPAN linearity adjustment

Step	Procedure
1	Set the SPAN to 1.0 MHz.
2	Set the CENTER FREQ properly and input a signal equal to that frequency from the RF INPUT.
3	Adjust R121 $\ lackbox{1}{f B}$ so that the signal trace is at the center.
4	Change the input signal frequency in 100 kHz steps and check the SPAN accuracy.

(iv) 5.2 to 2200 MHz SPAN linearity adjustment

Step	Procedure
1	Set the SPAN to 10 MHz.
2	Set the CENTER FREQ properly and input a signal equal to that frequency from the RF INPUT.
3	Adjust R117 (9) so that the signal trace is at the center.
4	Change the input signal frequency in 1 MHz steps and check the SPAN accuracy

3-221

	•		

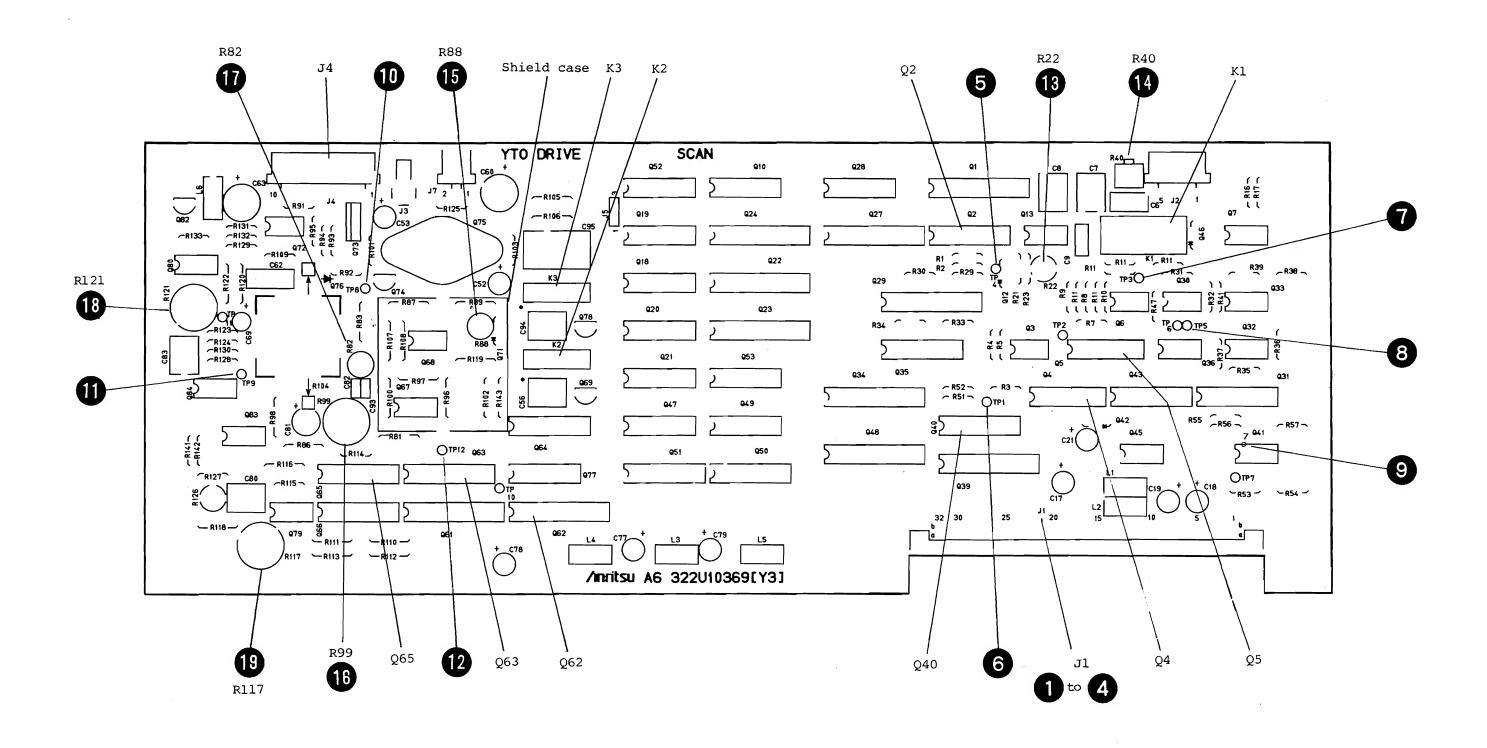


Fig. 3-51 (a) A6 SCAN/YTO DRIVE PC Board Parts Layout (Parts Side) 19

	•		
			•

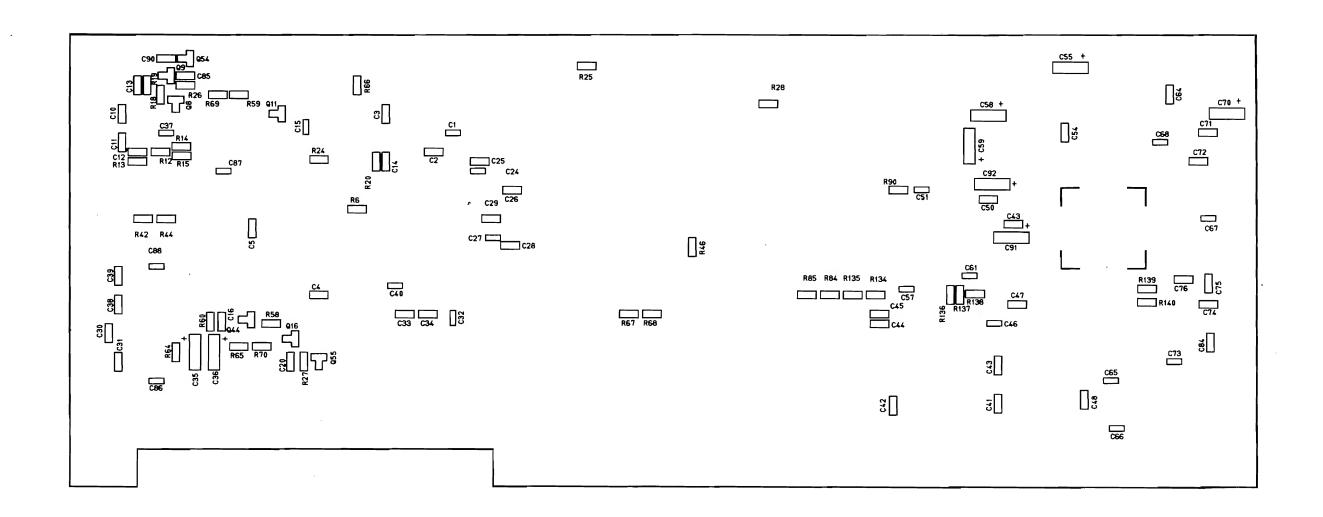
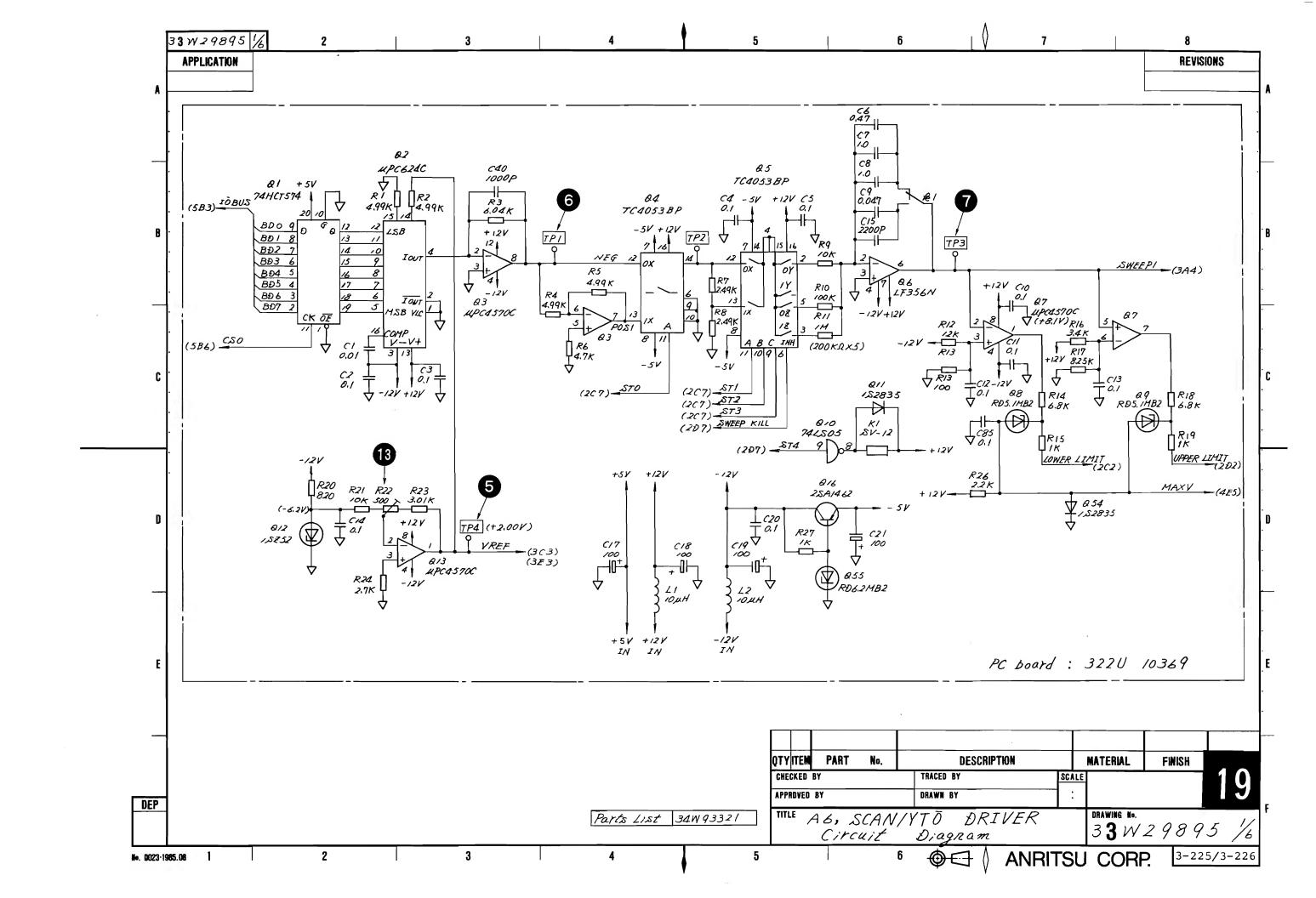
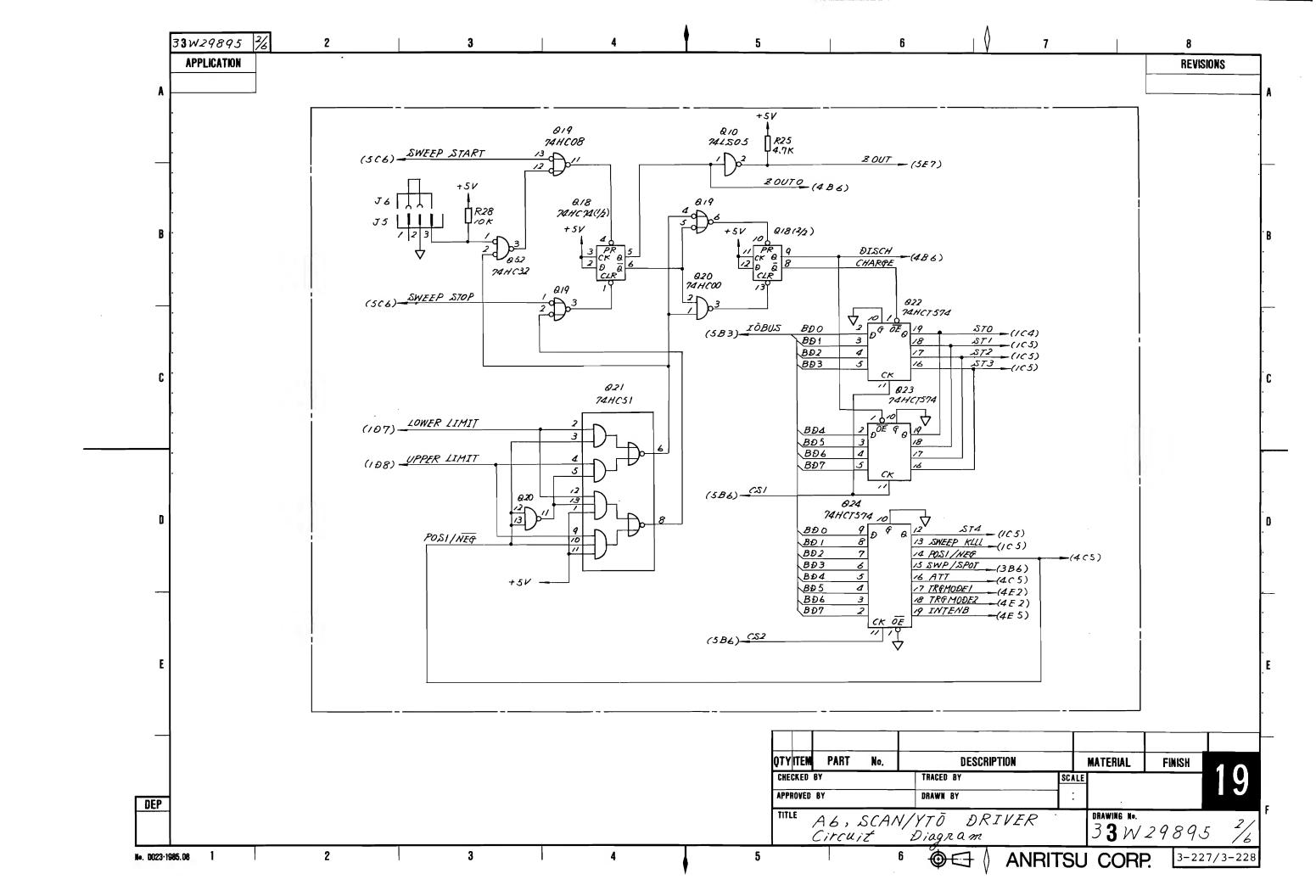


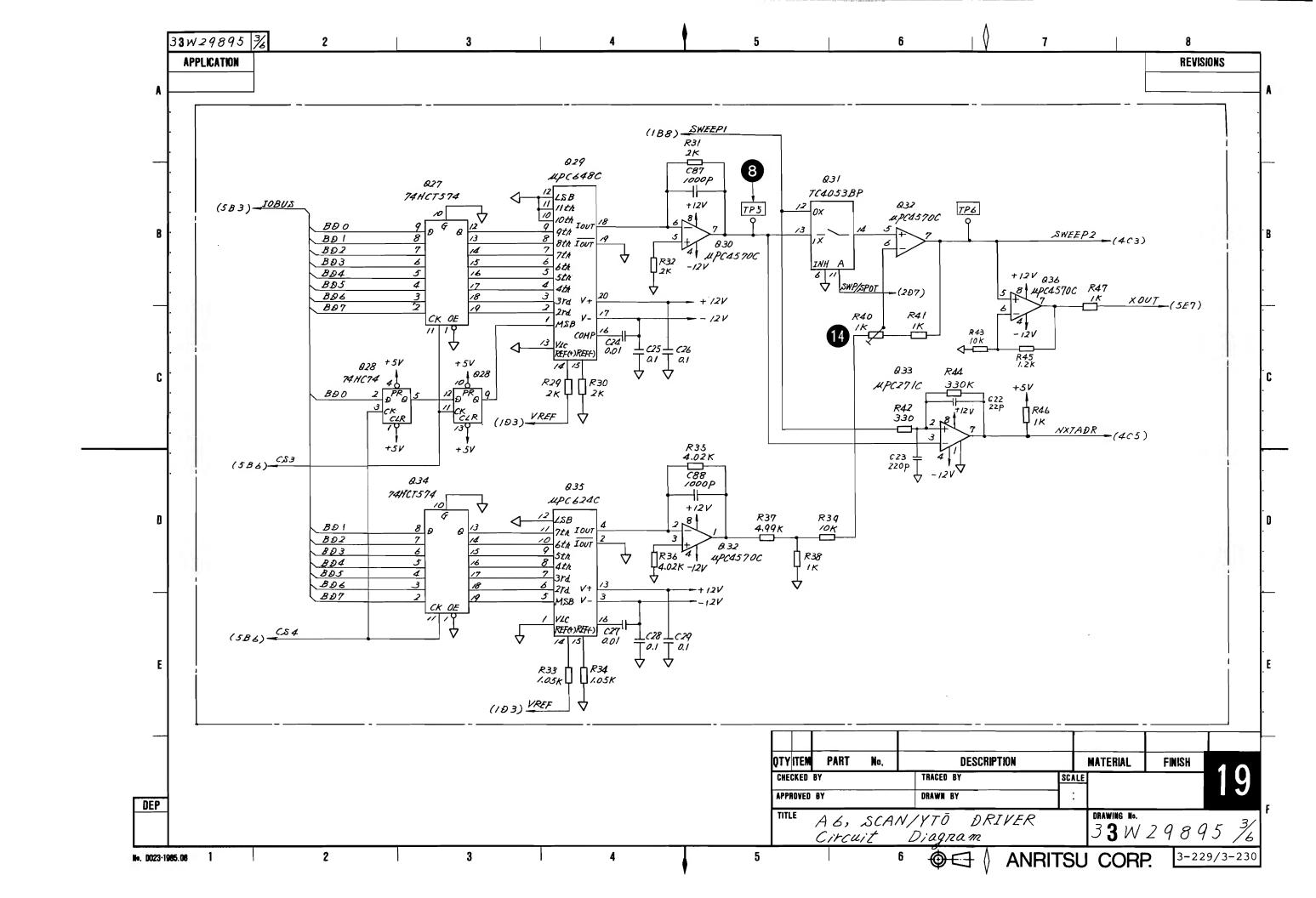
Fig. 3-51 (b) A6 SCAN/YTO DRIVE PC Board Parts Layout (Pattern Side) 19

(3-223 blank)/3-224

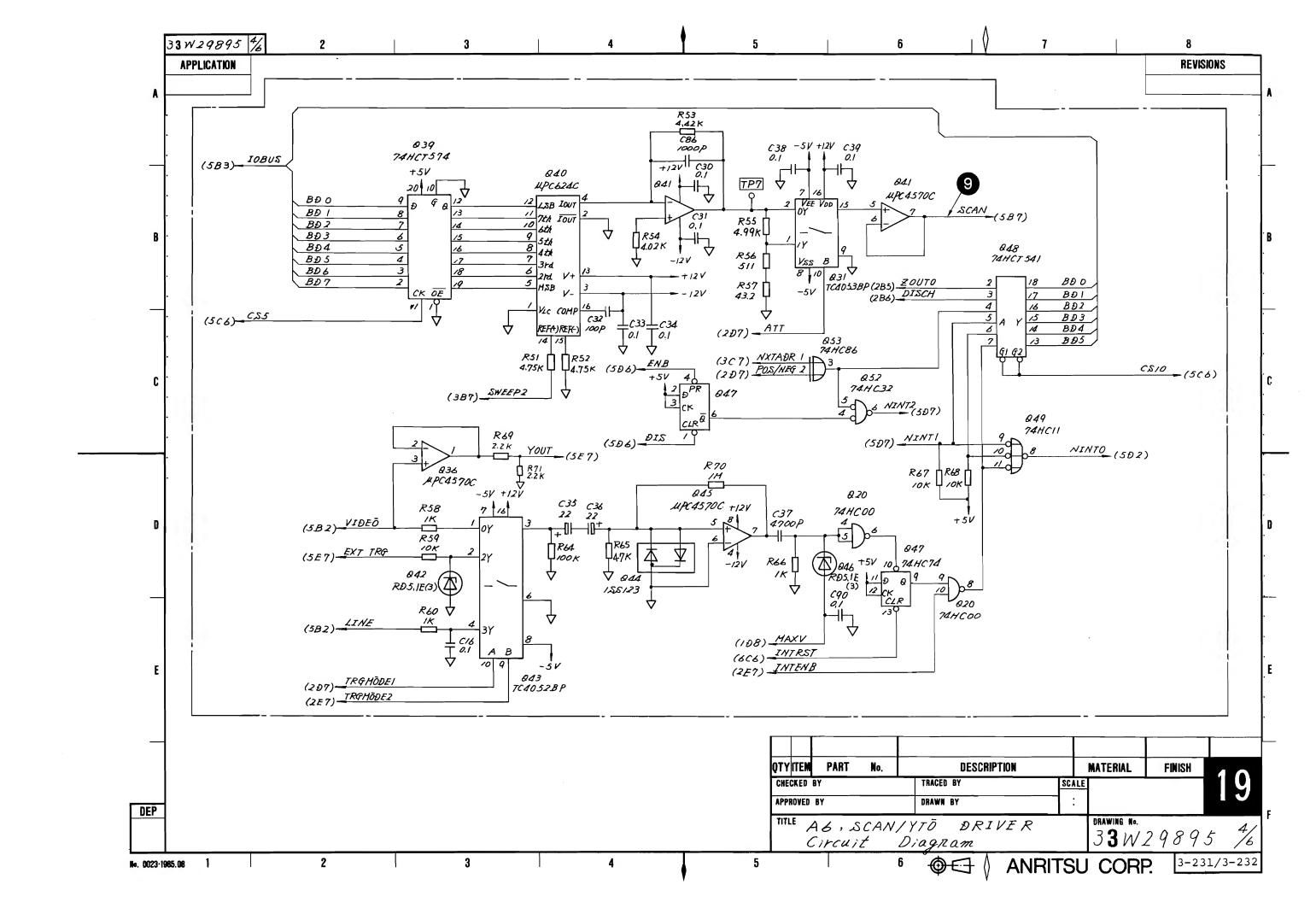




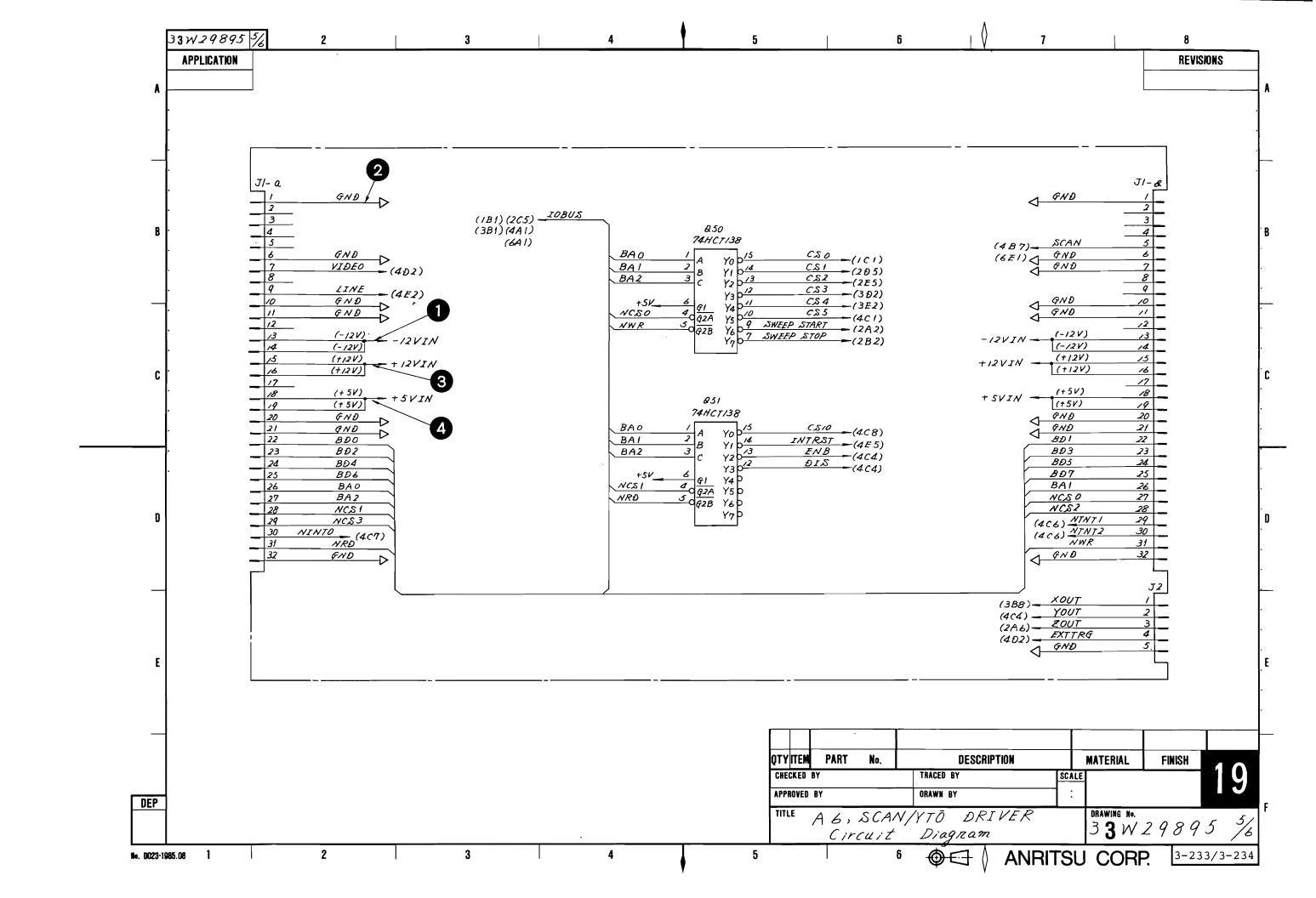
				)
				,
,				
				)
				)



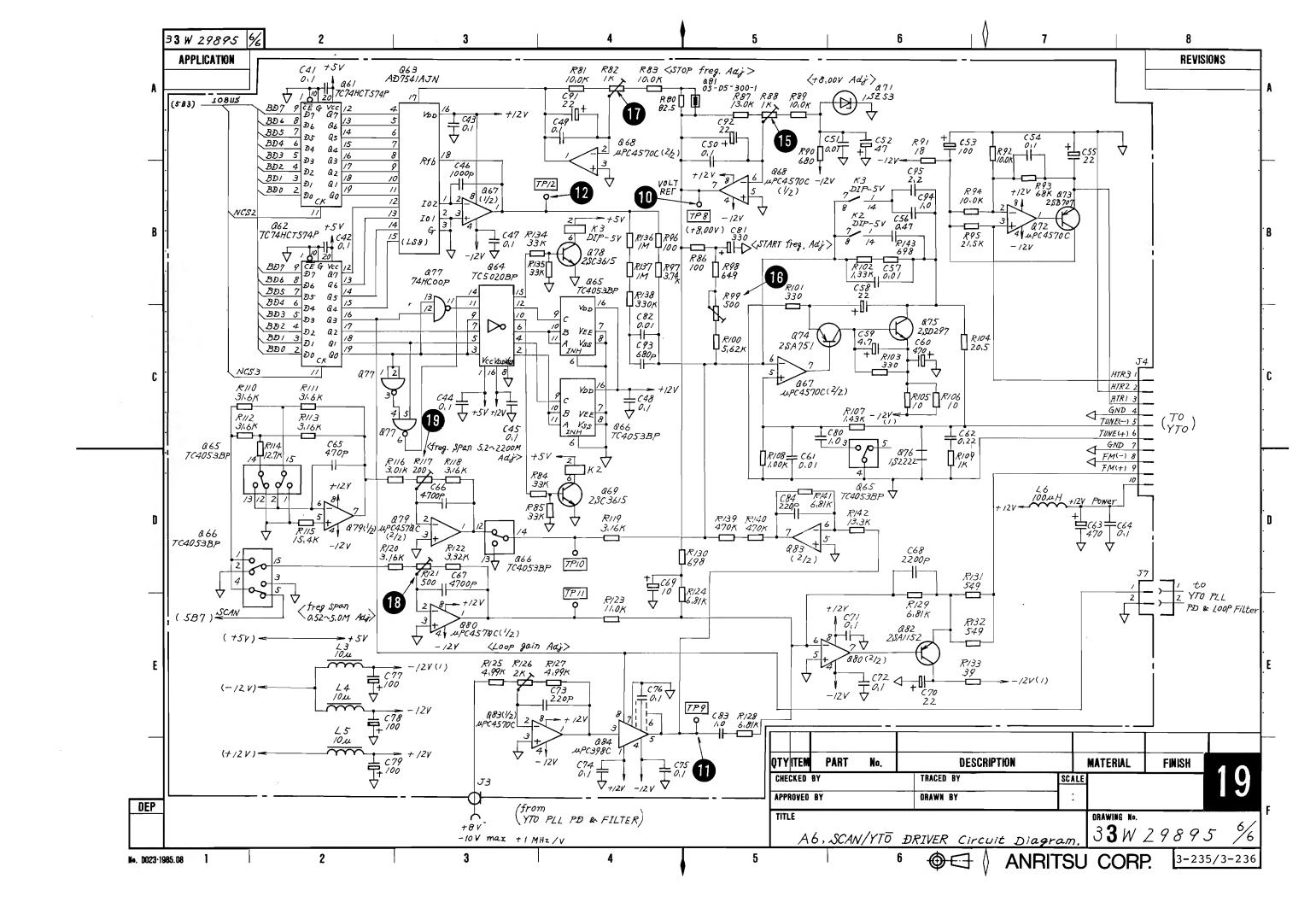
			)
			· )
			)



		)
,		
		•
		)



		)
,		
		)
		)



			)
			,
			)

# 3.3.9 A7 REF OSC 20

## (1) Circuit description

Refer to the A7 block diagram shown in Fig. 3-52.

This circuit supplies the reference signal, etc. to each synthesizer of the 1st local oscillator and the 2nd local oscillator. This circuit configures a PLL circuit with a 50 MHz VCXO, 1/5 divider, phase detector (PD), 10 MHz crystal oscillator and generates high purity 50 MHz signals. This circuit supplies the 50 MHz signals to other units as well as the 500 kHz signal (divided by 100) to A1-A13 to 50 kHz/50 MHz STEP SYNTH and the 10 MHz signal to A1-A15 20 Hz STEP VCO CONT.

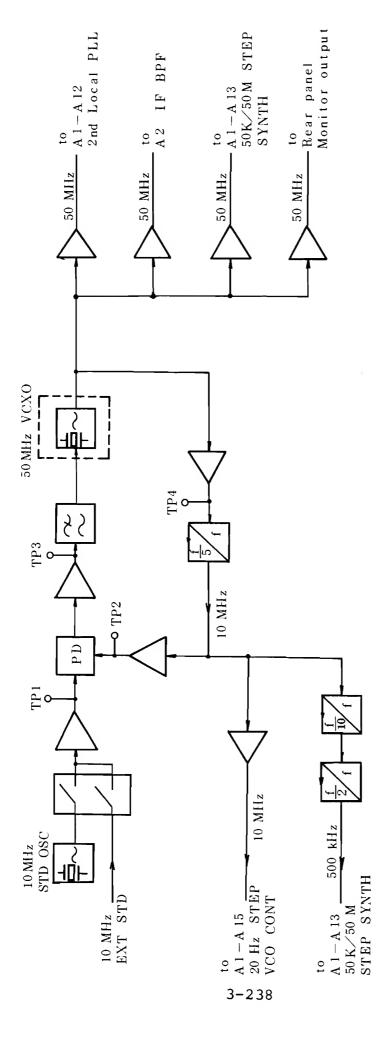


Fig. 3-52 A7 REF OSC Block Diagram

## (2) Symptoms

When A7 REF OSC is abnormal, the following two symptoms occur frequently.

- 1. Frequency uniformally drifts by about 100 Hz to  $10\ \mathrm{kHz}$
- 2. Frequency display error is large in same error ratio to frequency regardless of the frequency

# (3) Troubleshooting

(a) Required equipment

Digital voltmeter

Frequency counter: MF76A

Oscilloscope

Spectrum analyzer with high-impedance probe: MS612A

(b) Preparation

CAUTION —

Turn off the power before disassembly.

Step	Procedure
1	Remove the top cover (paragraph 2.2).
2	Remove the top cover of the A7 REF OSC shield case (paragraph 2.6, Fig. 2-4).
3	Remove the A7 REF OSC unit from the shield case.
4	Reattach the A7 REF OSC unit to the shield case using a extender board.

Step	Procedure
1	Check the following voltages:
	. Voltage between J1-14 $①$ and J1-15 $②$ (GND) is within -11.5 to -12.5 V.
	. Voltage between J1-18 $3$ and J1-15 $2$ (GND) is within +11.5 to +12.5 V.
	If these voltages are abnormal, check the Z4 REGULATOR section (paragraph 3.3.3).
	. Voltage between Q22-pin 16 and Q22-pin 14 (GND) is within $\pm 4.75$ to $\pm 5.25$ V.
	If this voltage is abnormal, check the Q36 three-terminal regulator IC.
_	

2 Check the signal at each checkpoint according to the following table.

Checkpoint	Normal condition
TP4 <b>4</b> (1/5 divider drive signal)	50 MHz TTL level
TP2 <b>5</b> (PD drive signal)	10 MHz <u>&gt;</u> 8 Vp-p
TP1 <b>6</b> (PD input RF signal)	10 MHz <u>&gt;</u> 6 Vp-p
Note: The voltage difference between must be 2 V or more.	ween TP2 and TP1

TP3 

(50 MHz VCXO Control Voltage)

EXT REF Signal
Input level J1-20 

(50 MHz VCXO Control Younger of the second of the seco

	(continued)
Step	Procedure
2 (Cont.)	If these values are abnormal, the A7 REF OSC PLL is unlocked.
3	Check each output level with a high-impedance probe.
	J1-8 (to rear panel)
	J1-6 (to A1-A13 50 k/50 M STEP SYNTH)  (At 50 Ω
	J1-4 (to A2 IF BPF) termination)
	J1-2 (to A1-A12
	J1-10 (to A1-A15 10 MHz, 20 Hz STEP VCO CONT) 10 MHz, +3 dBm or more (At 50 $\Omega$ termination)
	J1-12 (to A1-A13

# (4) Adjustment

Make this adjustment 15 minutes or more after power-on.

(After the 10 MHz STD OSC oscillation frequency has stabilized).

(a) 50 MHz VCXO oscillation frequency adjustment

Step	Procedure
1	Connect a digital voltmeter to TP3 7 .
2	Adjust L3 and R30 through the adjustment holes in the shield case so that the TP3 7 voltage is approx. 0 V.

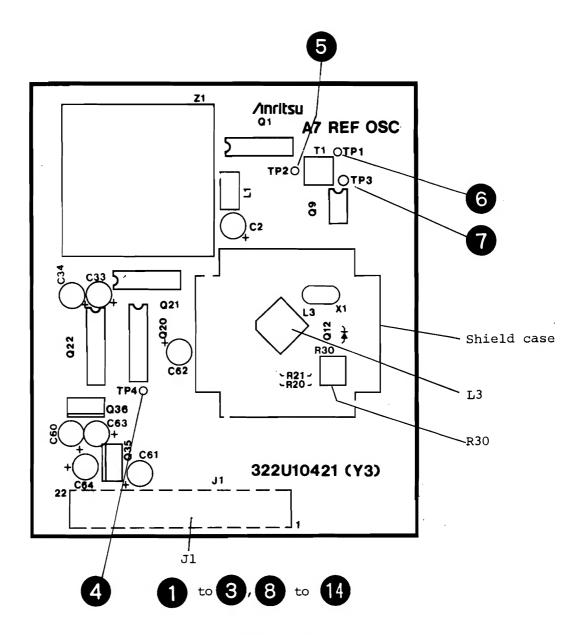


Fig. 3-53 (a) A7 REF OSC PC Board Parts Layout (Parts Side) 20

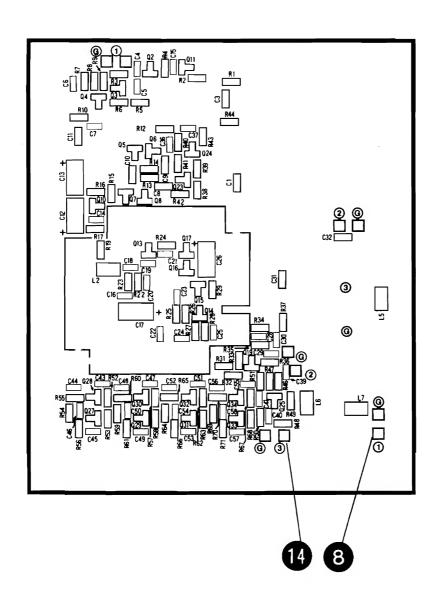
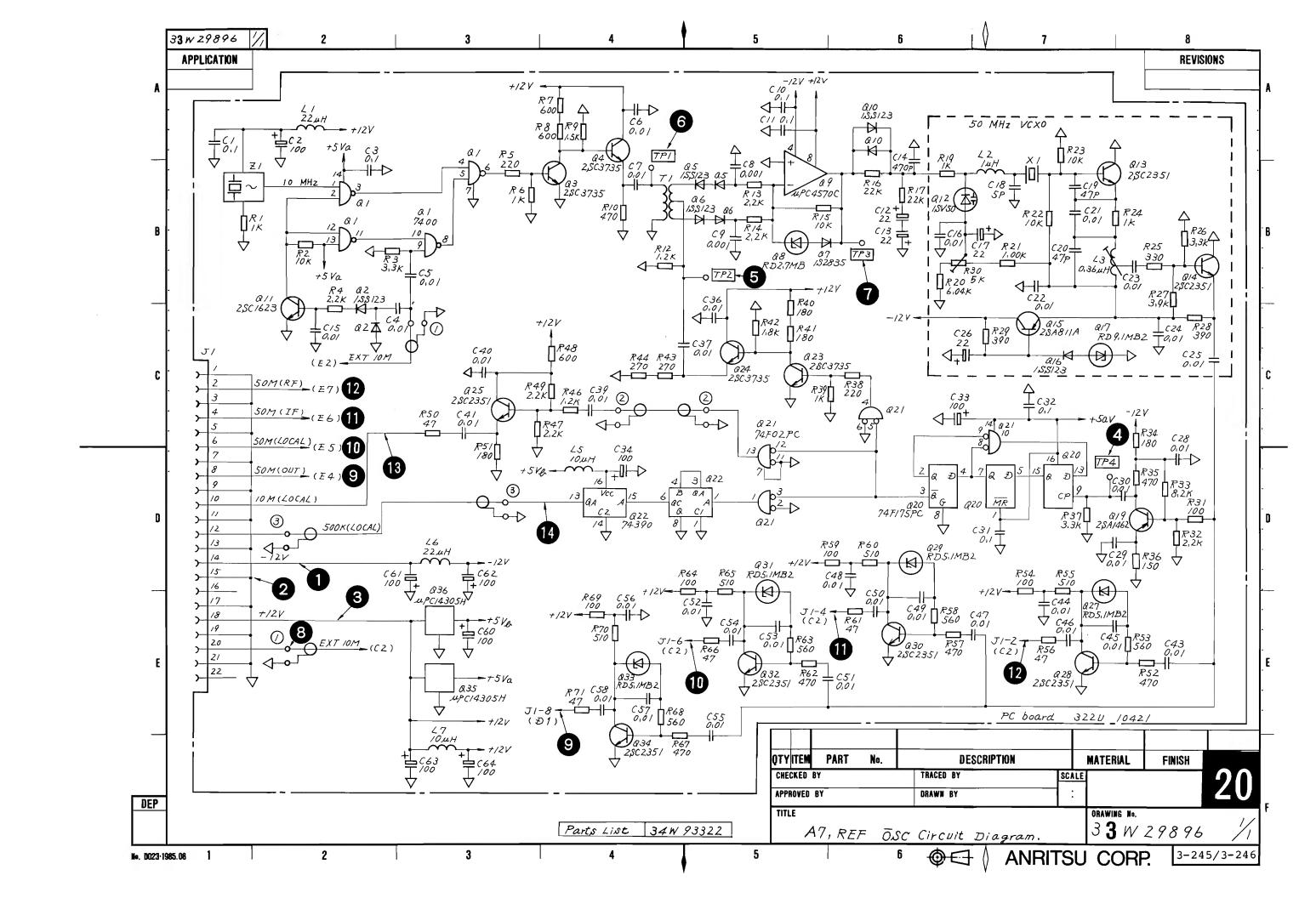


Fig. 3-53 (b) A7 REF OSC PC Board Parts Layout (Pattern Side) 20



	4				
					)
		,			
					)
-4					
				•	
					)

# (1) Circuit description

The MAIN CPU controls the A9 GP-IB (or A11 RS-232C), PMC, and common RAM as well as the entry from the A5 FRONT BOARD and each part of the hardware. (Fig. 3-3 (2/2)).

Figure 3-55 shows the interrupt system diagram. Note that the interrupt signal from A5 FRONT BOARD is applied to MAIN CPU through A6 SCAN/YTO DRIVER.

### (2) Symptoms

- If the MAIN CPU is not operating normally, all the MS2601A/J functions do not operate.
- When the life of the battery on the A9 GP-IB PC board (or A11 RS-232C PC board) has expired, the set parameters are not backed-up when the power is turned off.

#### (3) Troubleshooting

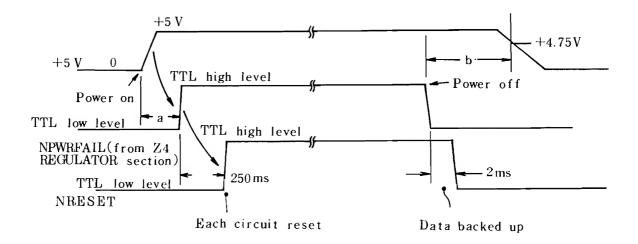
(a) Required equipment
Digital voltmeter
Oscilloscope

		Oscilloscope
	(b)	Preparation
	<del></del>	CAUTION —
	Turn	off the power before disassembly.
_		

Step	Procedure						
1	Remove the A8 MAIN CPU along with A9 GP-IB as described in paragraph 2.4.						
2	Reattach them using an extender board.						

# (c) Troubleshooting Check each checkpoint by referring to the following table.

Signal name	Checkpoint	Normal condition
+5 V	① (Q26-16)	+5 ±0.25 V
CPU8MZ	<b>2</b> (Q15-15)	8 MHz pulse wave
+5 V	0	The waveforms at
NPWRFAIL	<b>3</b> (Q23-21)	<pre>power-on and power-off are shown in Fig.</pre>



+5 V : LOGIC section power supply

NPWRFAIL: Power fail signal, output to each CPU from the Z4

REGULATOR section.

NRESET : Generated by Q23 using internal timing when it is

received from the NPWRFAIL signal.

### Fig. 3-54 RESET TIMING CHART

#### Note:

The value of "a" and "b" may differ somewhat depending on whether the A4 PTA PC board (option 01) is installed and not installed.

The waveforms shown in the above figure are examples when the A4 PTA is not installed. In either case, the following two conditions must be satisfied.

- NPWRFAIL goes TTL low level → TTL high level after +5 V is raised.
- 2. +5 V held for at least 3 ms after NPWRFAIL goes TTL high level \* TTL low level.

When condition 1 is not satisfied, the MS2601A does not operate normally at power-on.

When condition 2 is not satisfied, the panel setting data is not backed up into the internally memory at power-off.

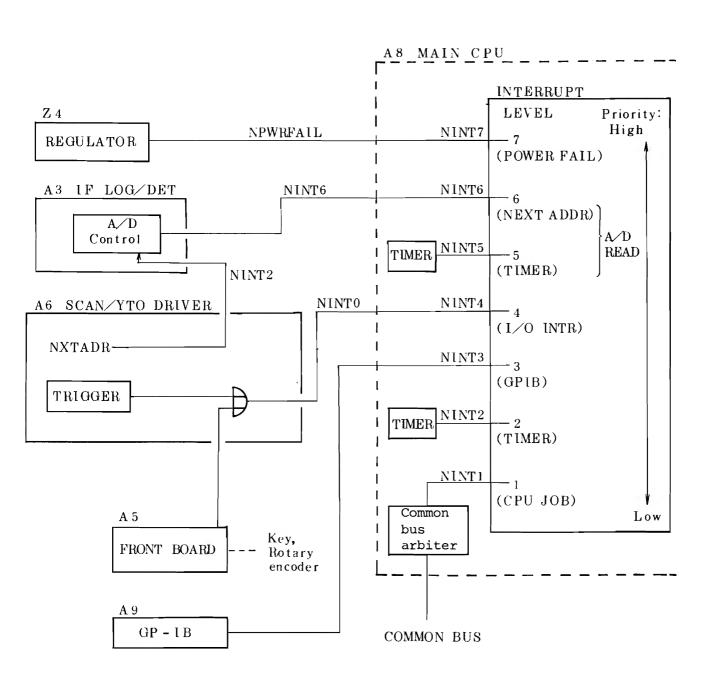


Fig. 3-55 A8 MAIN CPU Interrupt System Diagram

•		

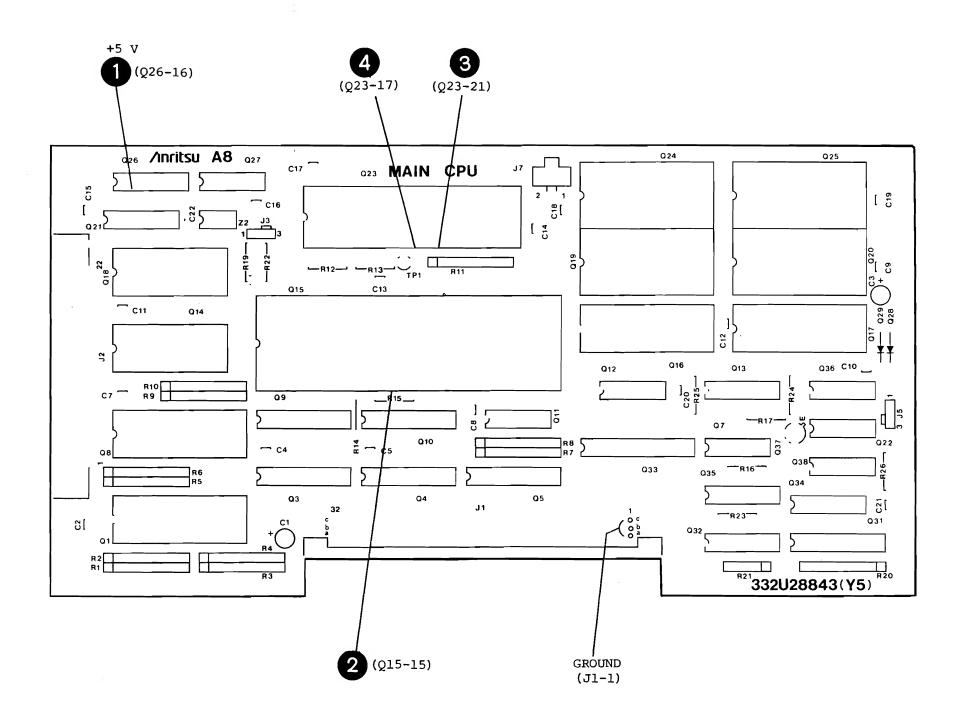
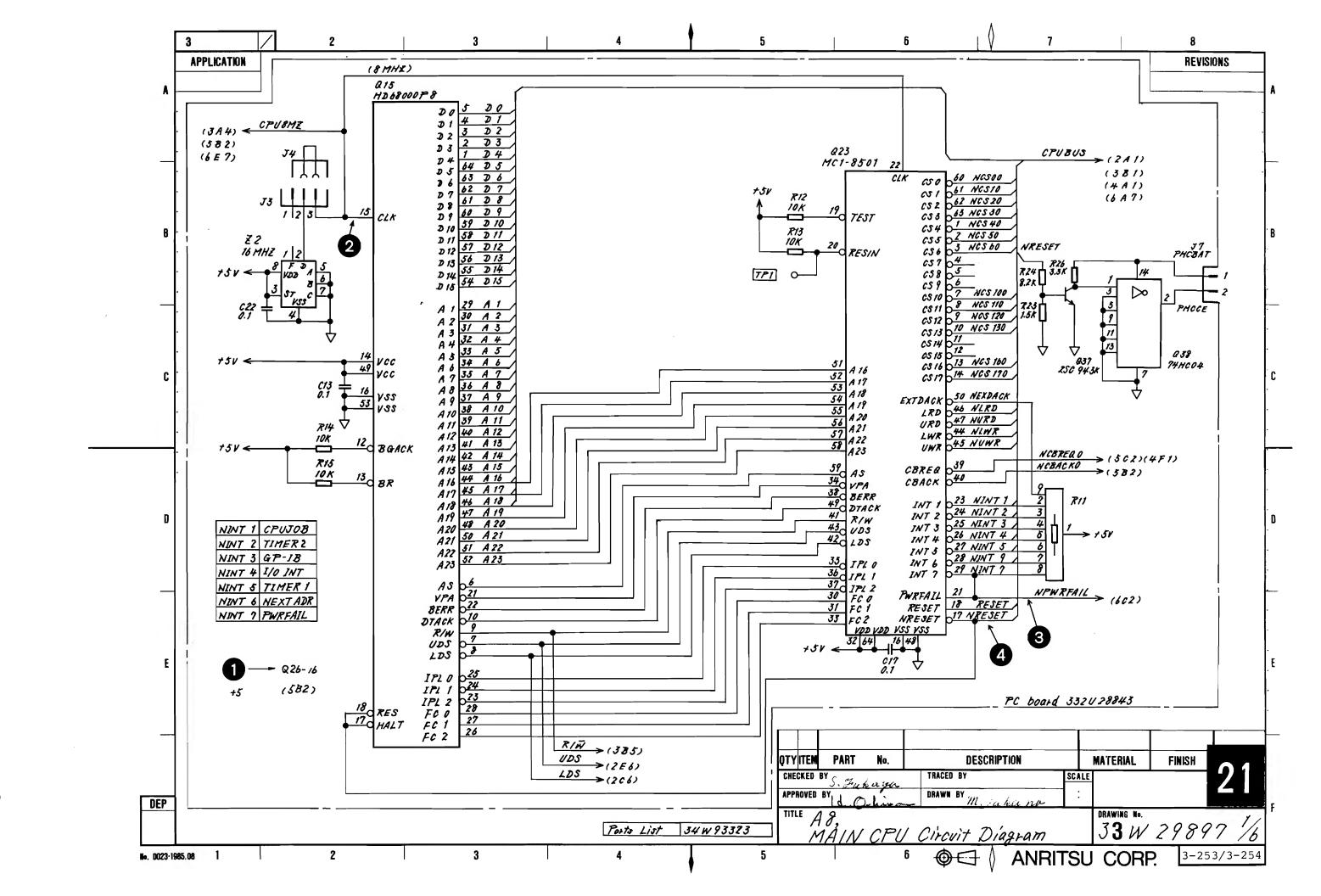


Fig. 3-56 A8 MAIN CPU PC Board
Parts Layout 21

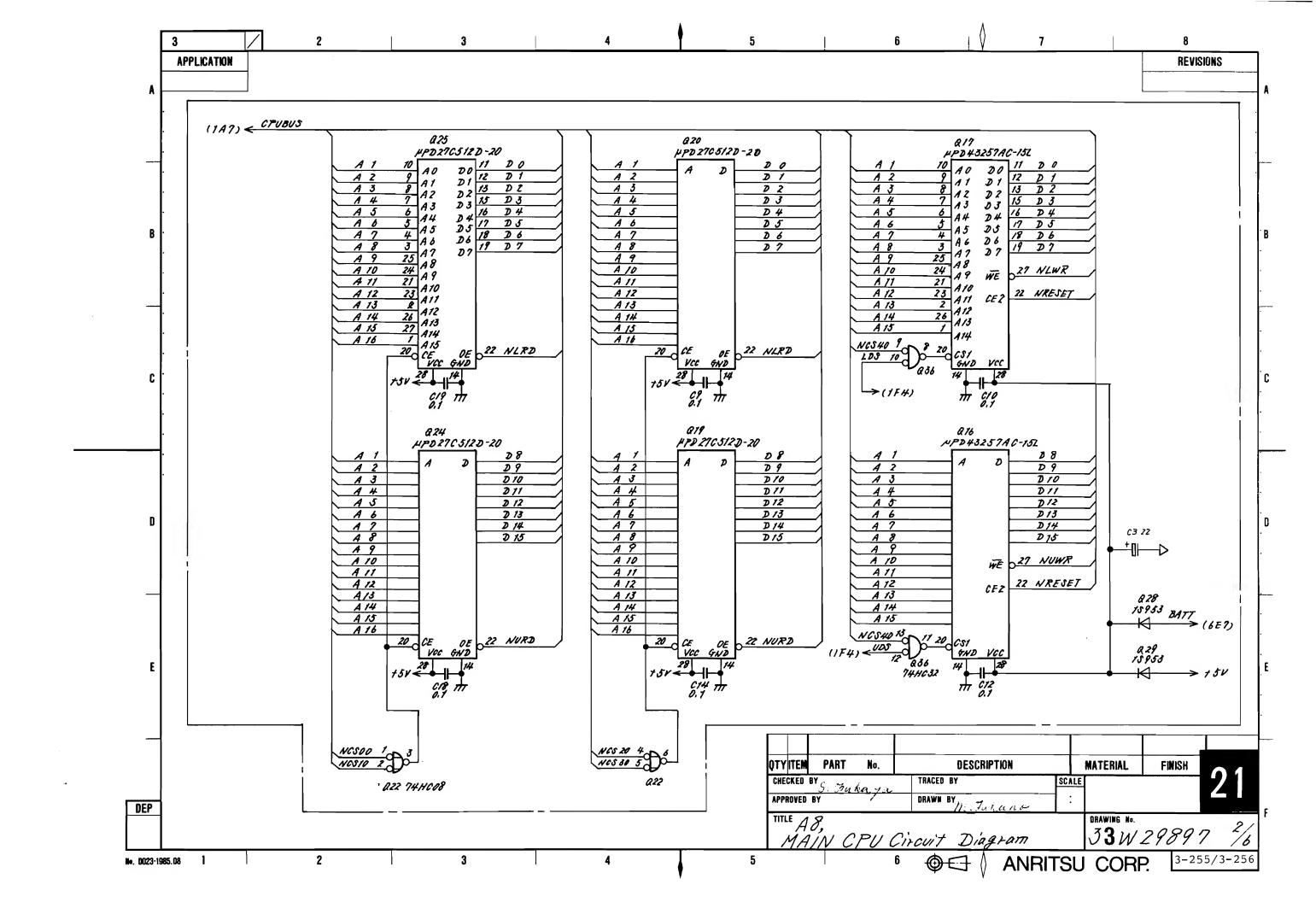
(3-251 blank)/3-252

,

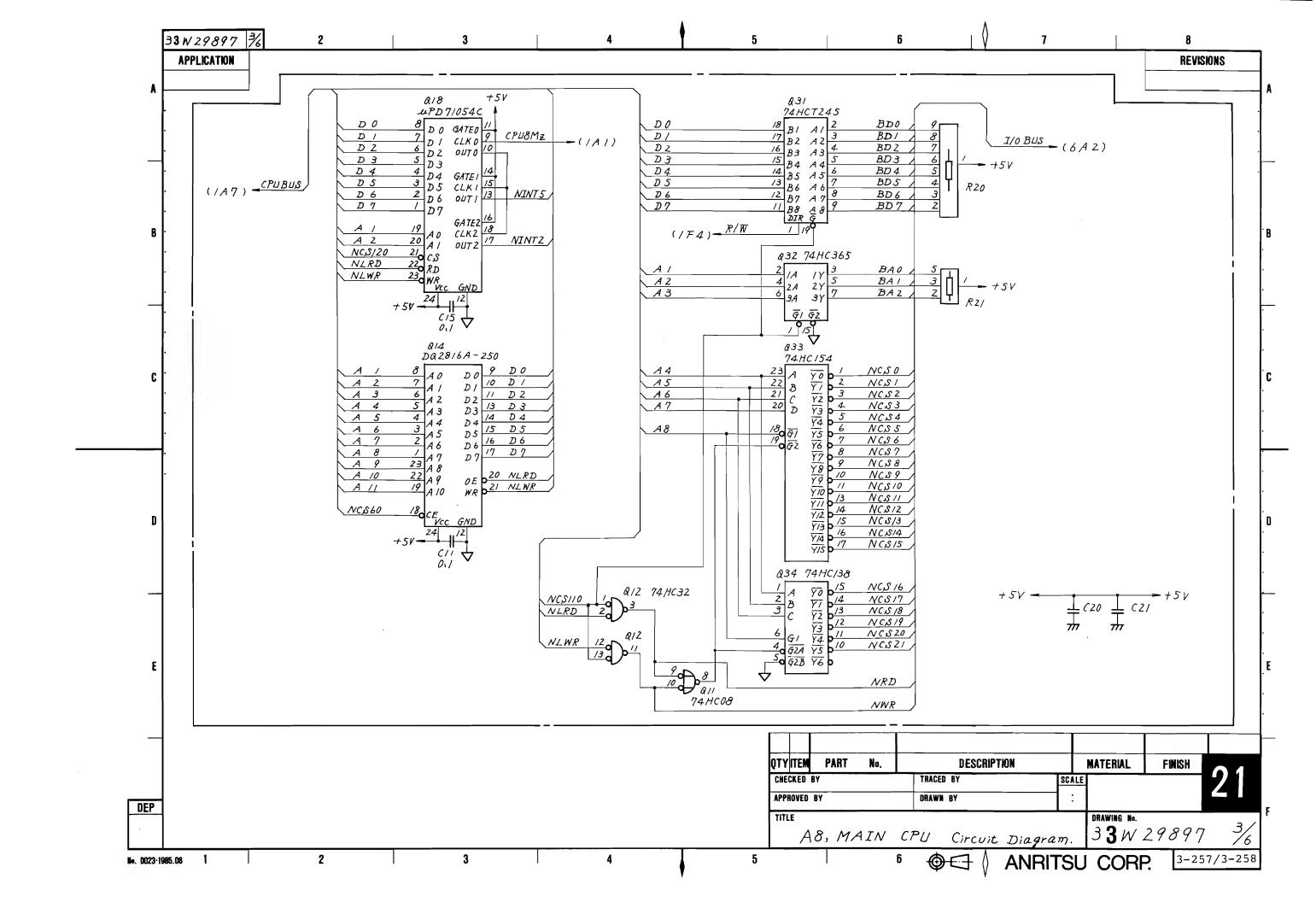
)



			)
	•		
			)
			)

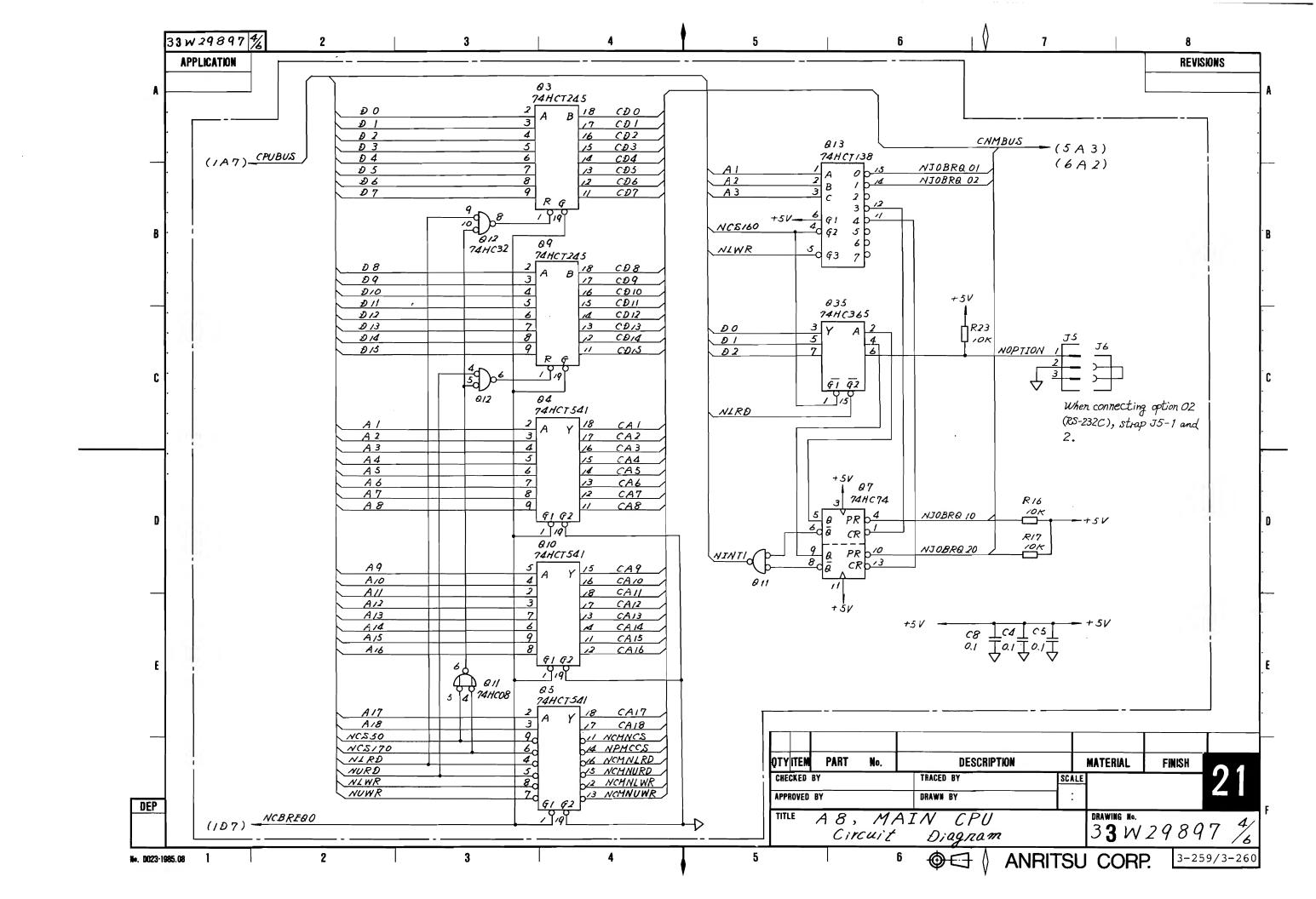


			,
	,		
			)
			,

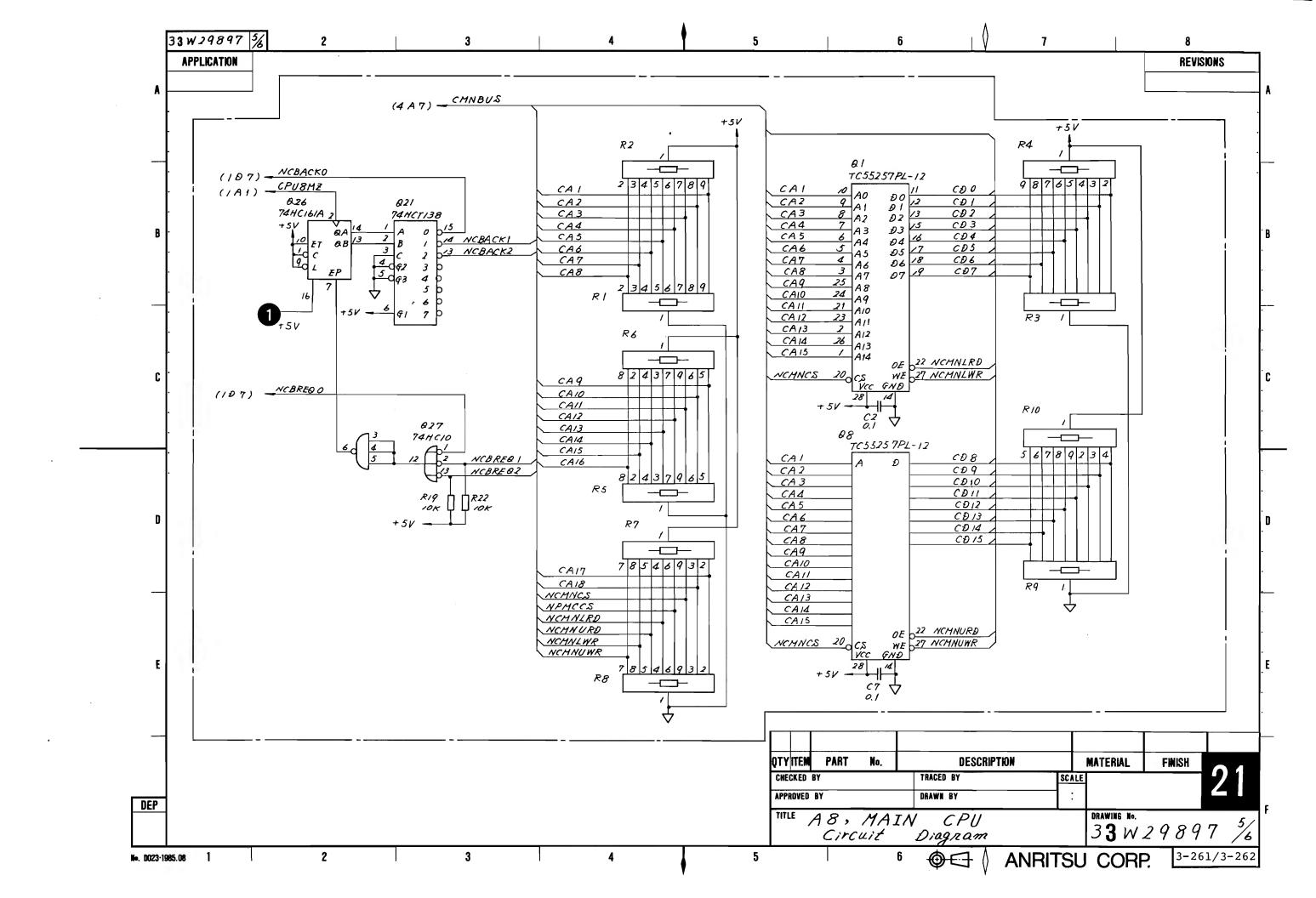


r

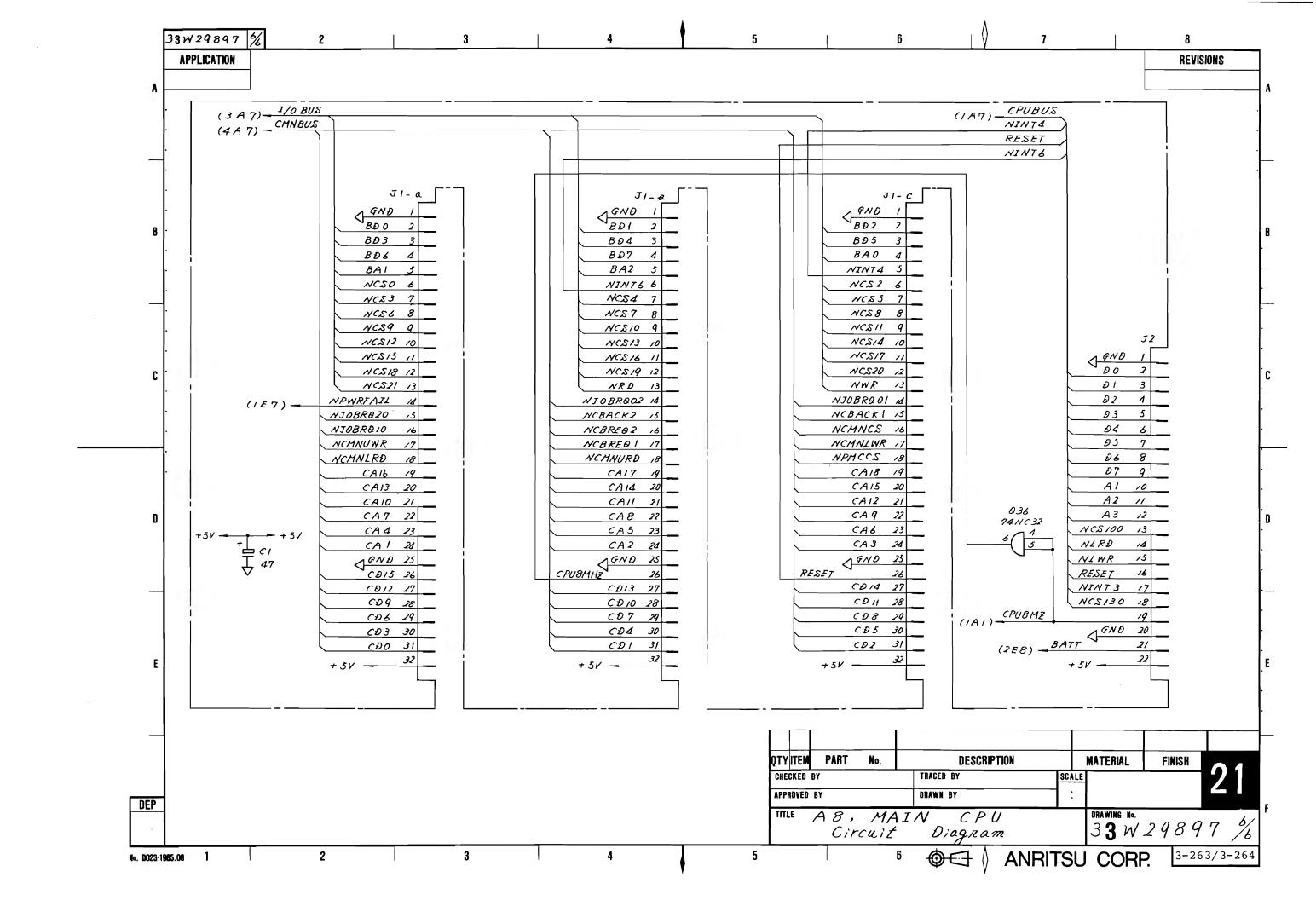
. .



*y* 



			,



			)
			,
			,
			)

# 3.3.11 A9 GP-IB 22

(1) Circuit description

GP-IB adapter LSI, GP-IB bus driver/receiver and RAM back-up battery of the MAIN CPU are include in this section.

(2) Symptom

When the A9 GP-IB board is defective, GP-IB control is impossible.

- (3) Troubleshooting
  - (a) Required equipment
     Digital voltmeter
     Oscilloscope
  - (b) Preparation

Turn off the power before disassembly.

Step	Procedure
1	Remove A8 MAIN CPU along with A9 GP-IB as described in paragraph 2.4.
2	Reattach them using an extender board.

# (c) Troubleshooting Check each checkpoint by referring to the following table.

Signal name	Checkpoint		Normal condition
+5 V	0	(Q1-40)	+5 ±0.25 V
CPU 8MZ	2	(Q1-3)	8 MHz pulse wave
Battery voltage	8	(R3)	≧3 Vdc

	•	

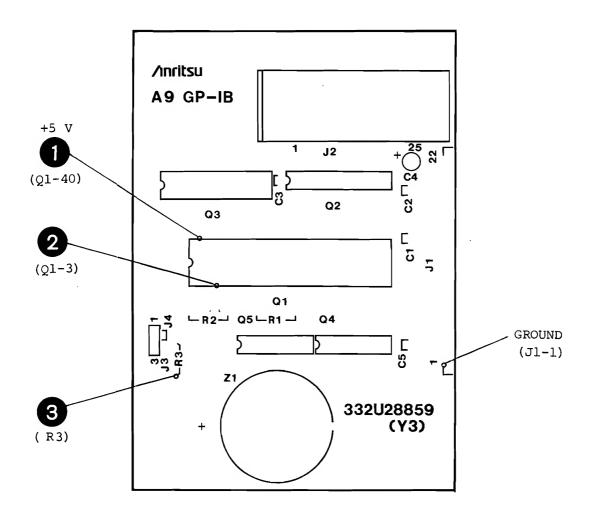
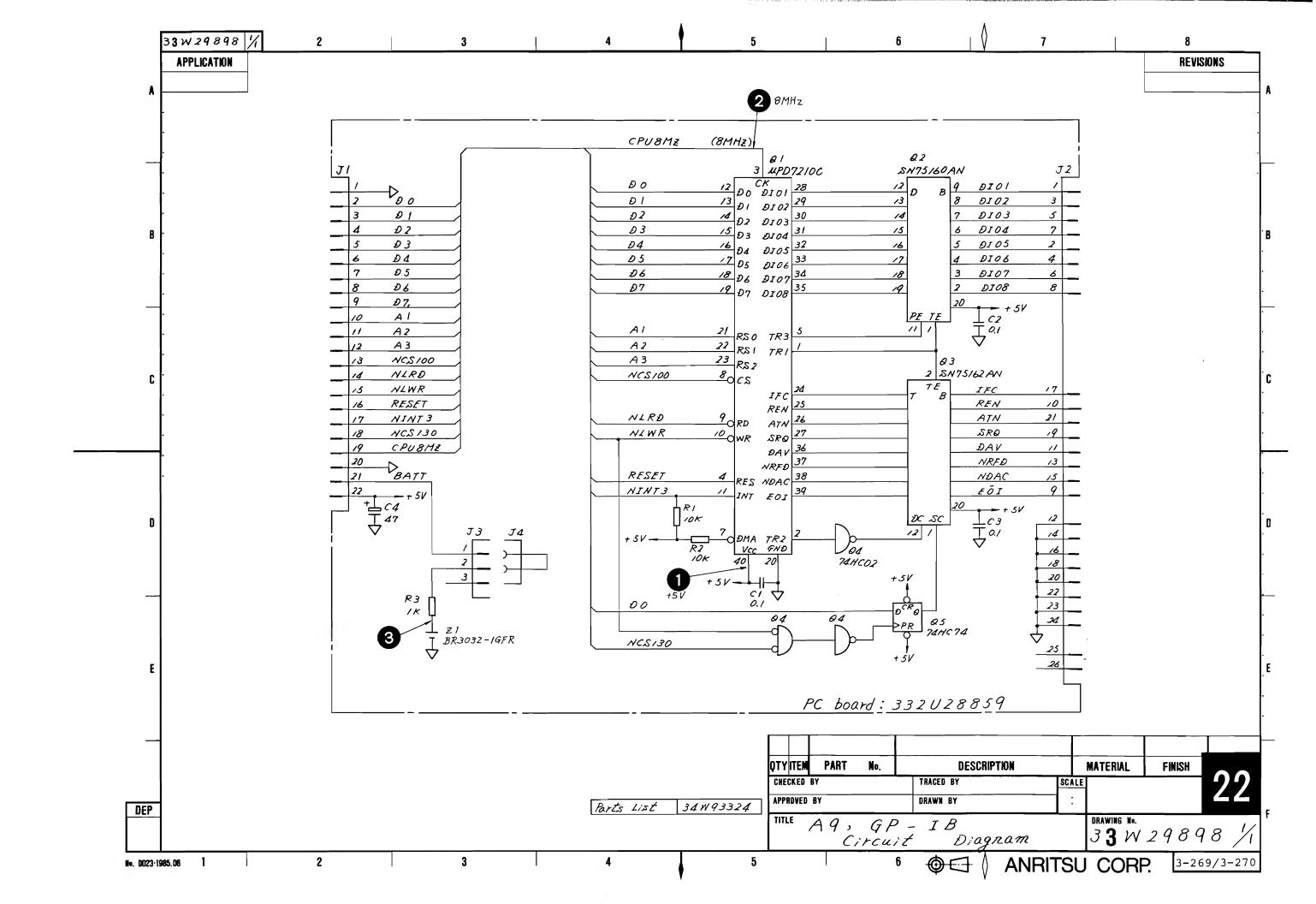


Fig. 3-57 A9 GP-IB PC Board Parts Layout



			,
			)
			)
			)

# 3.3.12 A10 DISP CPU

## (1) Circuit description

This circuit displays on the CRT the display data sent from the A8 MAIN CPU via a common RAM. Figure 3-58 shows the block diagram of the CRT controller section.

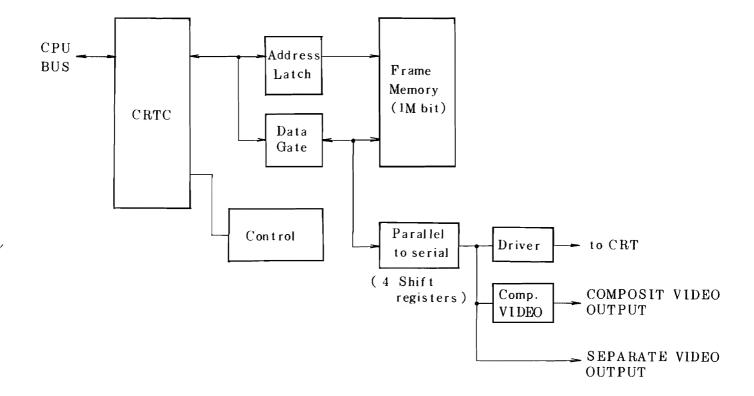


Fig. 3-58 A10 DISP CPU-CRT Controller Block Diagram

## (2) Symptoms

- 1. If A10 DISP CPU is not operating normally, the CRT does not display anything.
- 2. If the DISP CPU is operating, but the CRT controller section is defective, part or all of the graduation lines and characters may be dislocated or distorted, or unnecessary dots and lines may be displayed.

## (3) Troubleshooting

- (a) Required equipment

  Digital voltmeter

  Oscilloscope
- (b) Preparation

 CAUTION						
Turn	off	the	power	before	disassembly.	

Step	Procedure				
1	Remove A10 DISP CPU as described in paragraph 2.4.				
2	Reattach it using an extender board.				

(c) Troubleshooting
 Check each checkpoint by referring to the
 following table.

Signal name	Checkpoint	Normal condition
+5 V	① (Q5-20)	+5 ±0.25 V
CPU Clock	<b>2</b> (Q7-15)	8 MHz Pulse wave (τ ≒ 125 ns)
CRTC Clock (1)	<b>3</b> (Q4-50)	6.4 MHz Pulse wave ( $\tau = 156 \text{ ns}$ )
CRTC Clock (2)	<b>4</b> (Q9-15)	12.8 MHz Pulse wave (T ≒ 78 ns)
+5 V	0	Same as A8 MAIN CPU
NPWRFAIL	<b>5</b> (Q1-21)	(See Fig. 3-54, paragraph 3.3.10)
NRESET	<b>6</b> (Q1-17)	
CRTHSYNC	<b>7</b> (Q39-12)	(τ ≒ 63 μs)
CRTVSYNC	<b>8</b> (Q39-10)	(τ ≒ 16.7 ms)

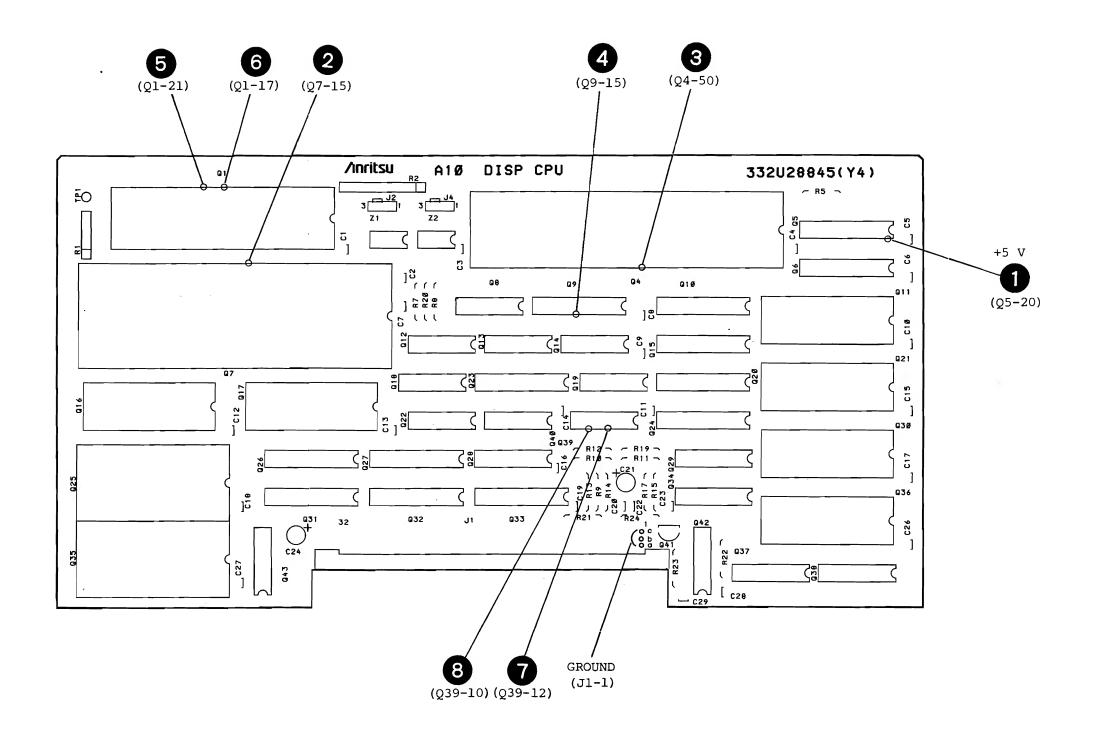
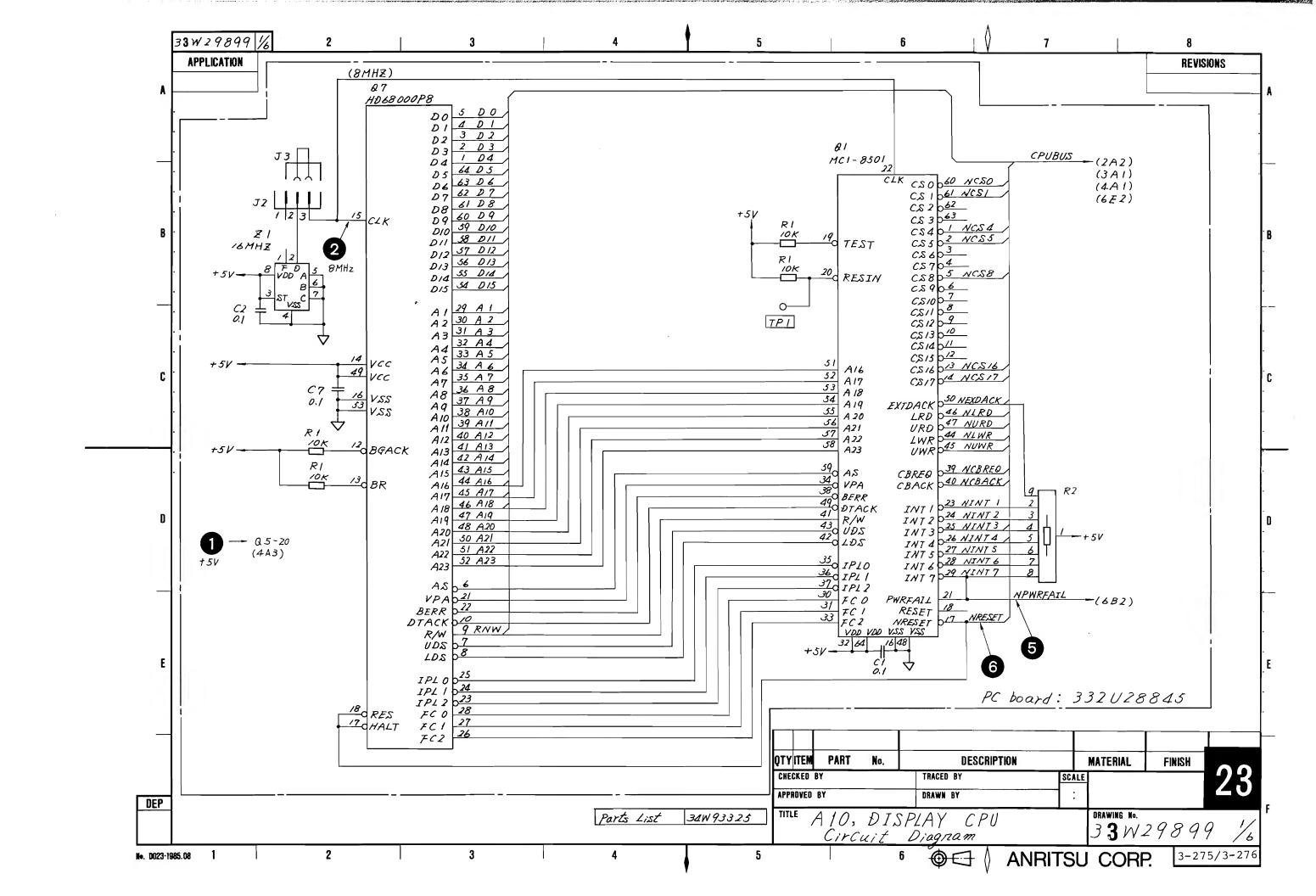
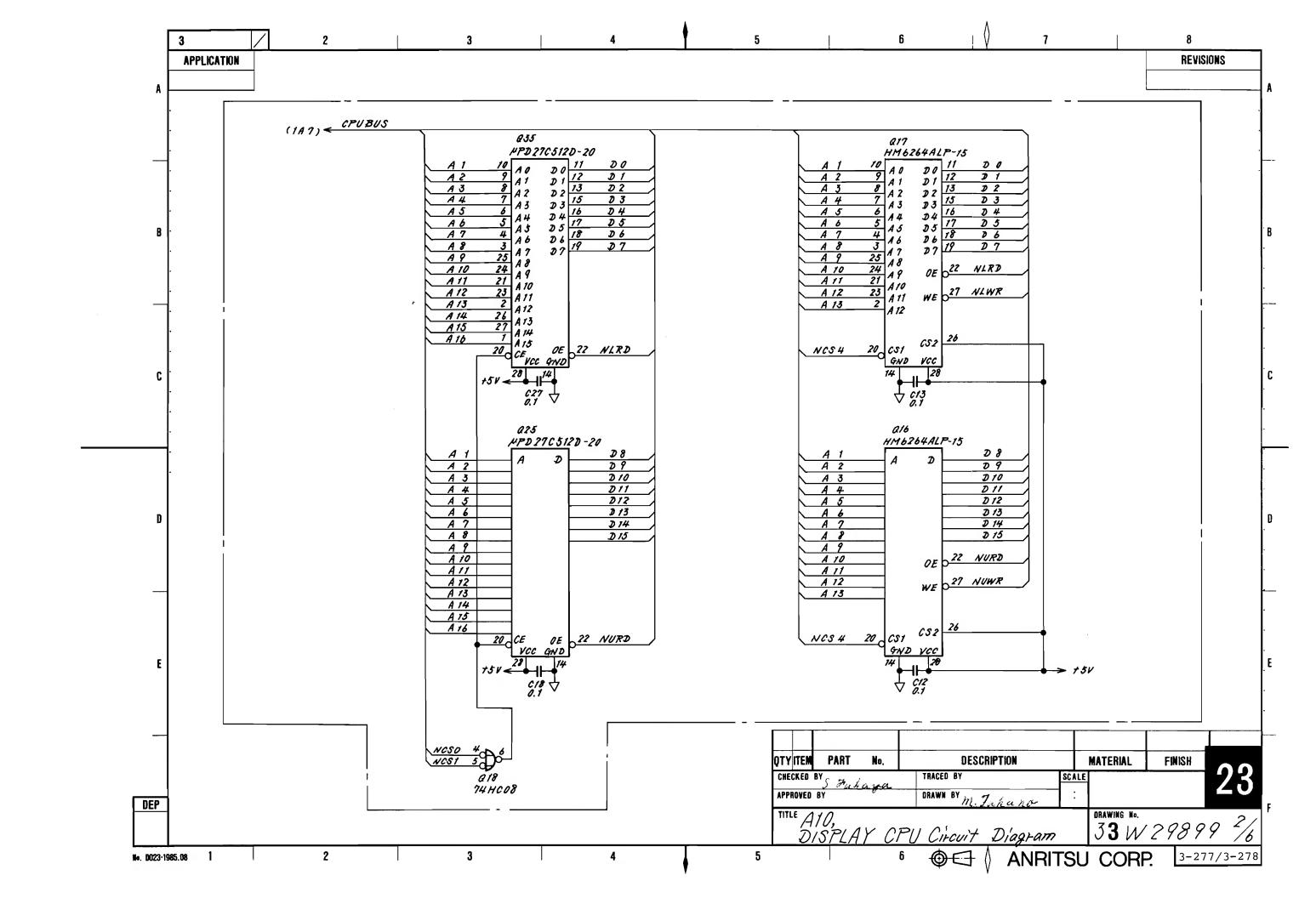


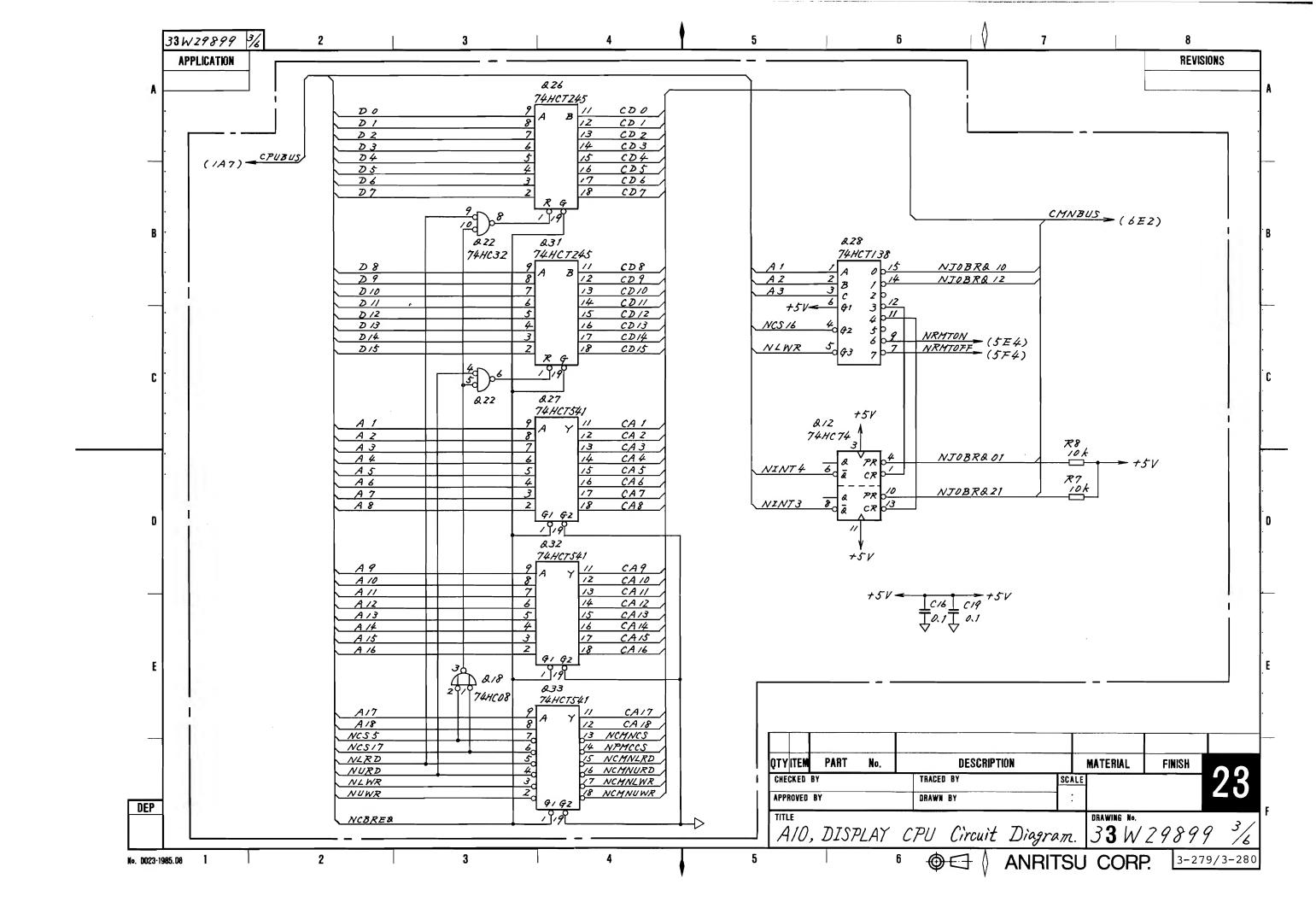
Fig. 3-59 AlO DISP CPU PC Board
Parts Layout 23

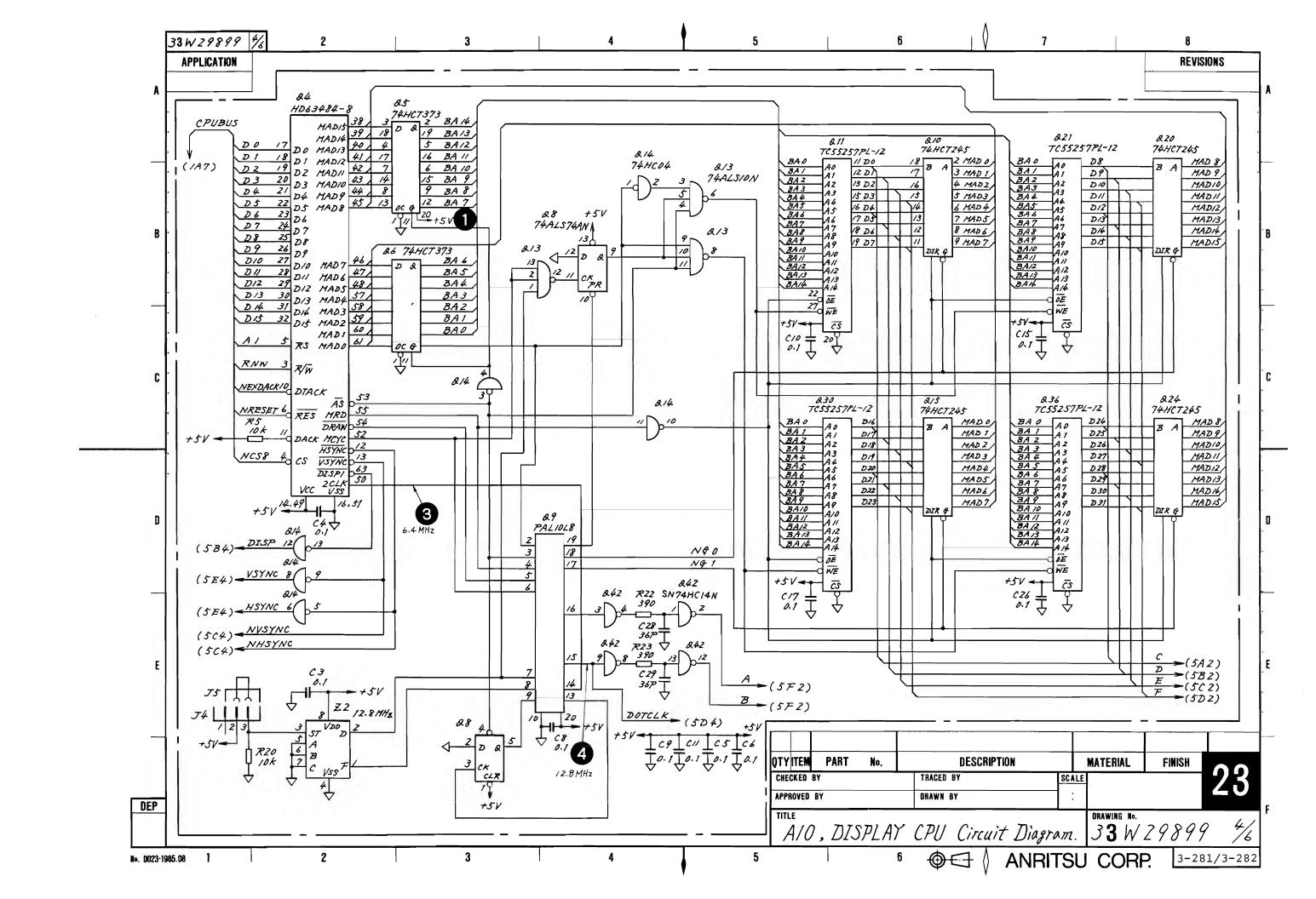


i

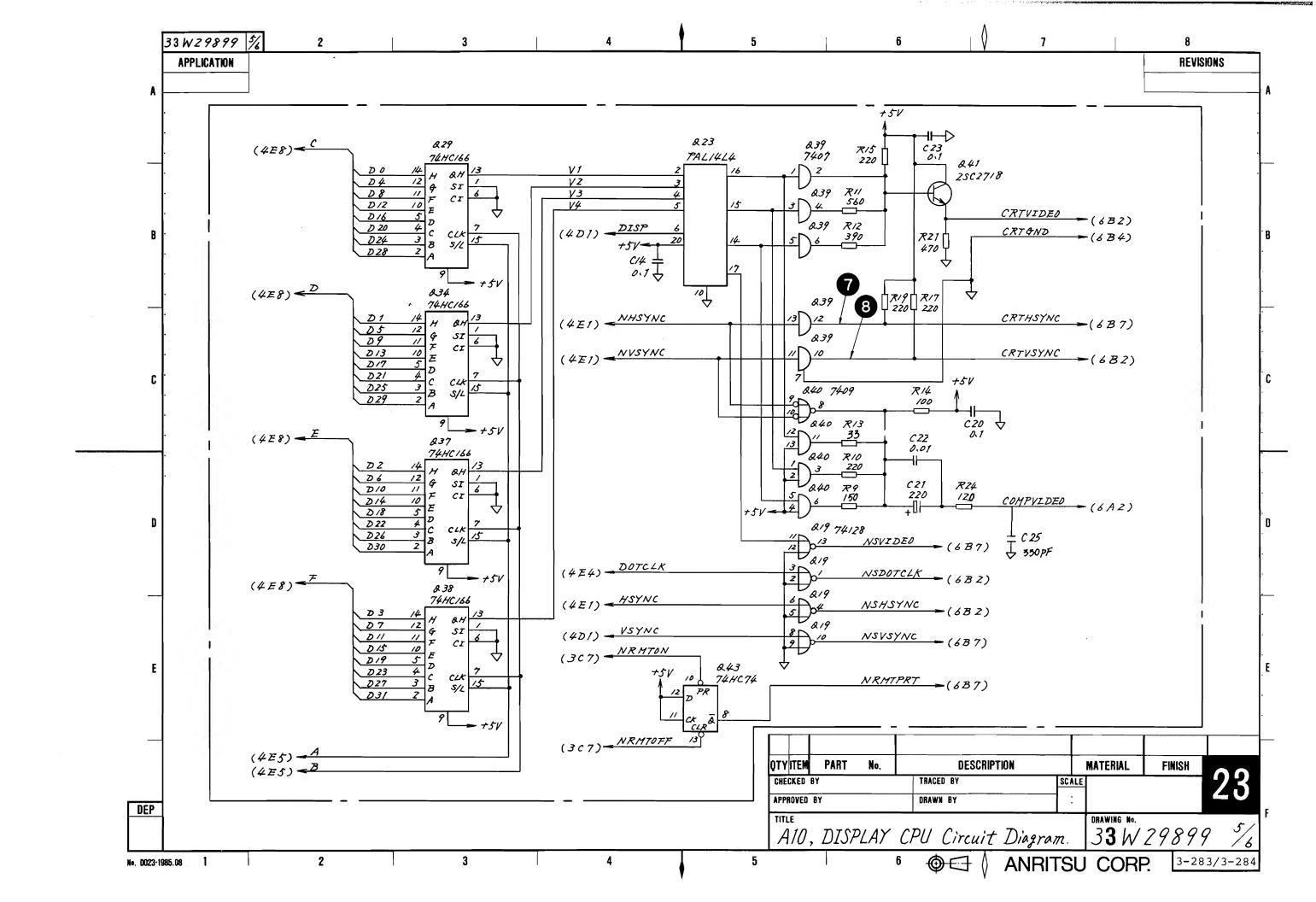


			)
			, )



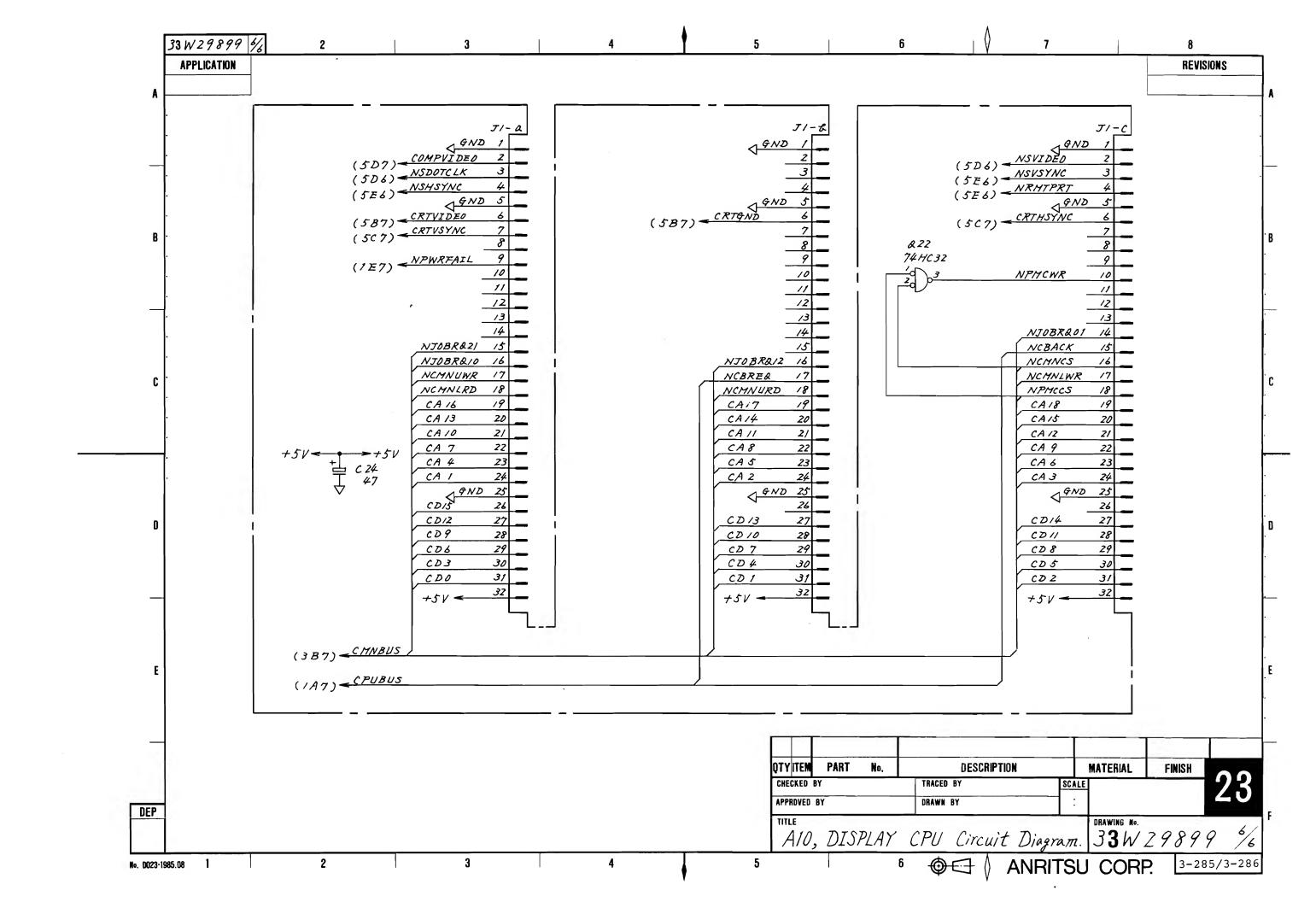


			)
			)
			,



.

.



. ...

\*

•

- 3.3.13 A13 MAIN MOTHERBOARD 24 , A14 SUB MOTHERBOARD 25 and A15 LED 26
  - 1. A13 MAIN MOTHERBOARD (Fig. 3-60, 24)
  - 2. A14 SUB MOTHERBOARD (Fig. 3-61 , 25

These are junction boards that supply dc voltages from the Z4 REGULATOR to each unit, send the control signal from A8 MAIN CPU to each unit, and send and receive other signals.

3. A15 LED (Fig. 3-62, 26 )

When the MS2601A/J is operating, the LED mounted on this board comes on.

4. A16 FILTER (Fig. 3-63, 28)

This board has a PROBE SOURCE (power supply for high impedance probe) noise filter.

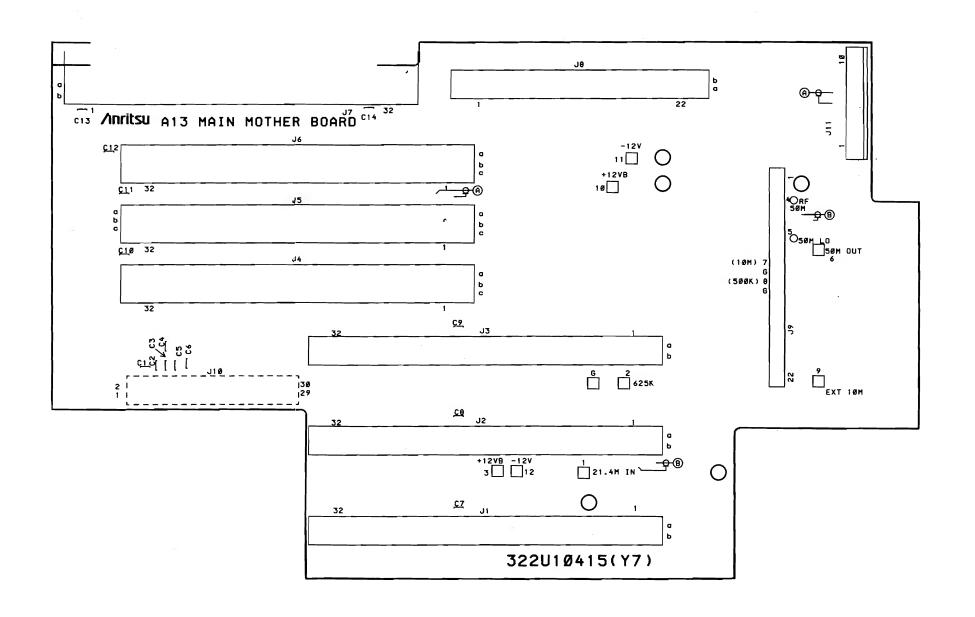


Fig. 3-60 Al3 MAIN MOTHERBOARD PC Board Parts Layout 24

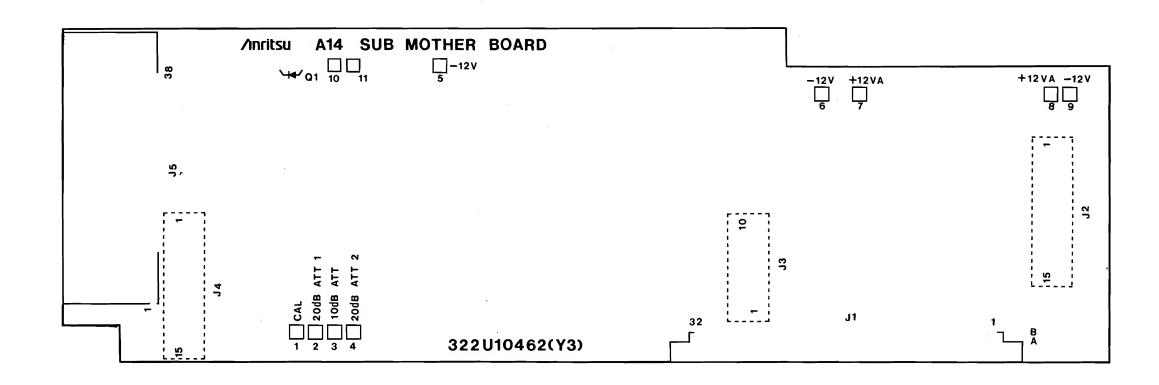


Fig. 3-61 Al4 SUB MOTHERBOARD PC Board Parts Layout 25

012 5 6 342U91135

Fig. 3-62 A15 LED PC Board Parts Layout 26

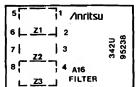
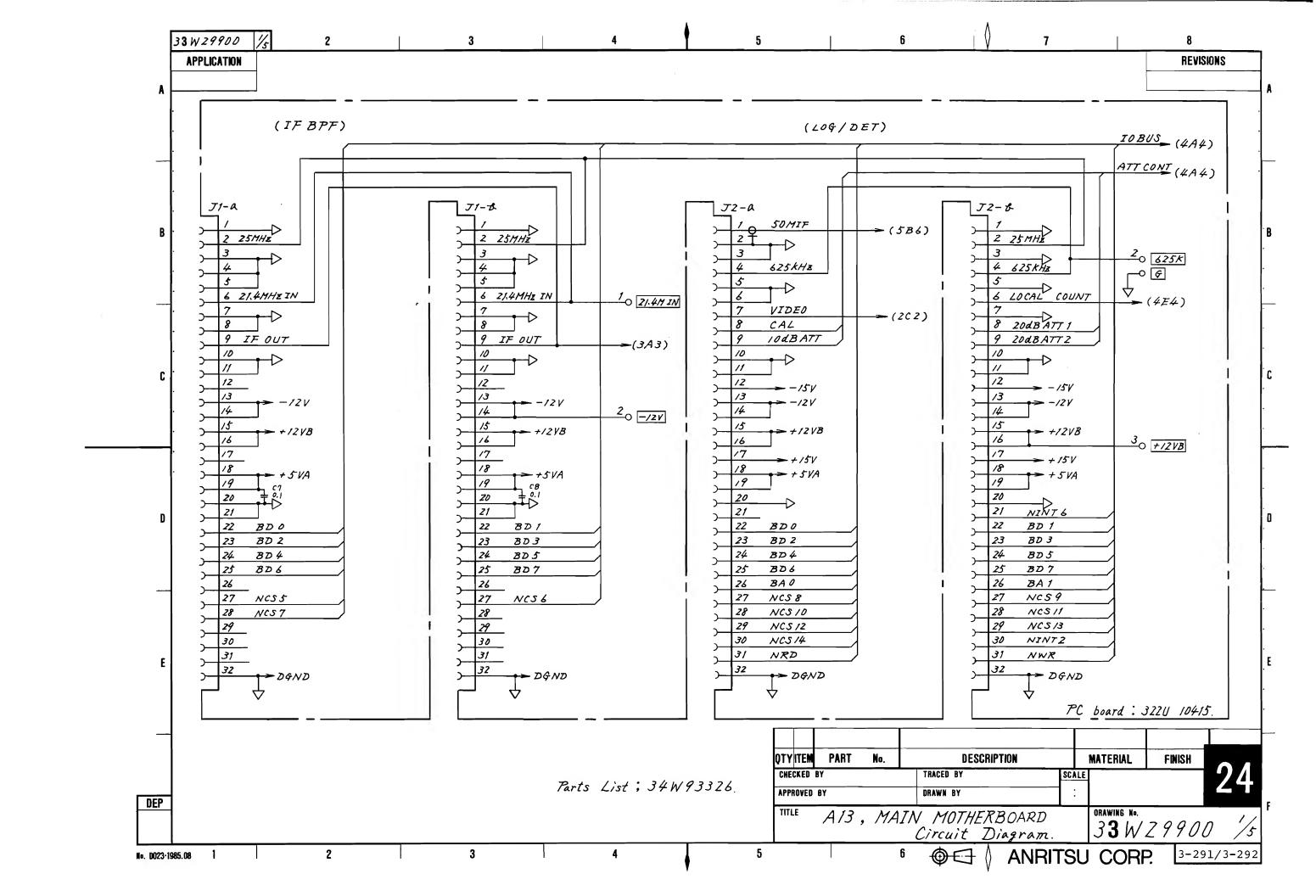
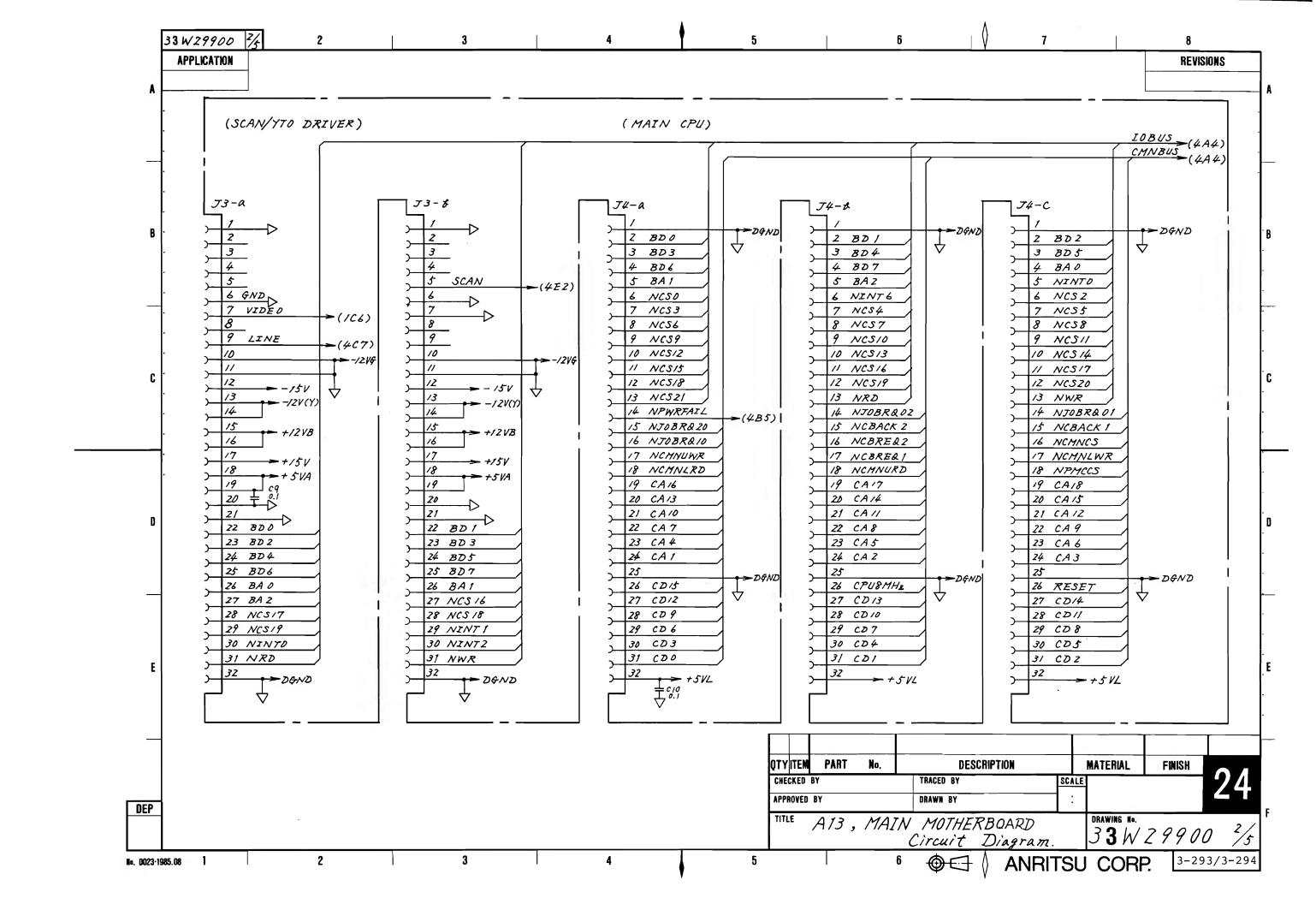
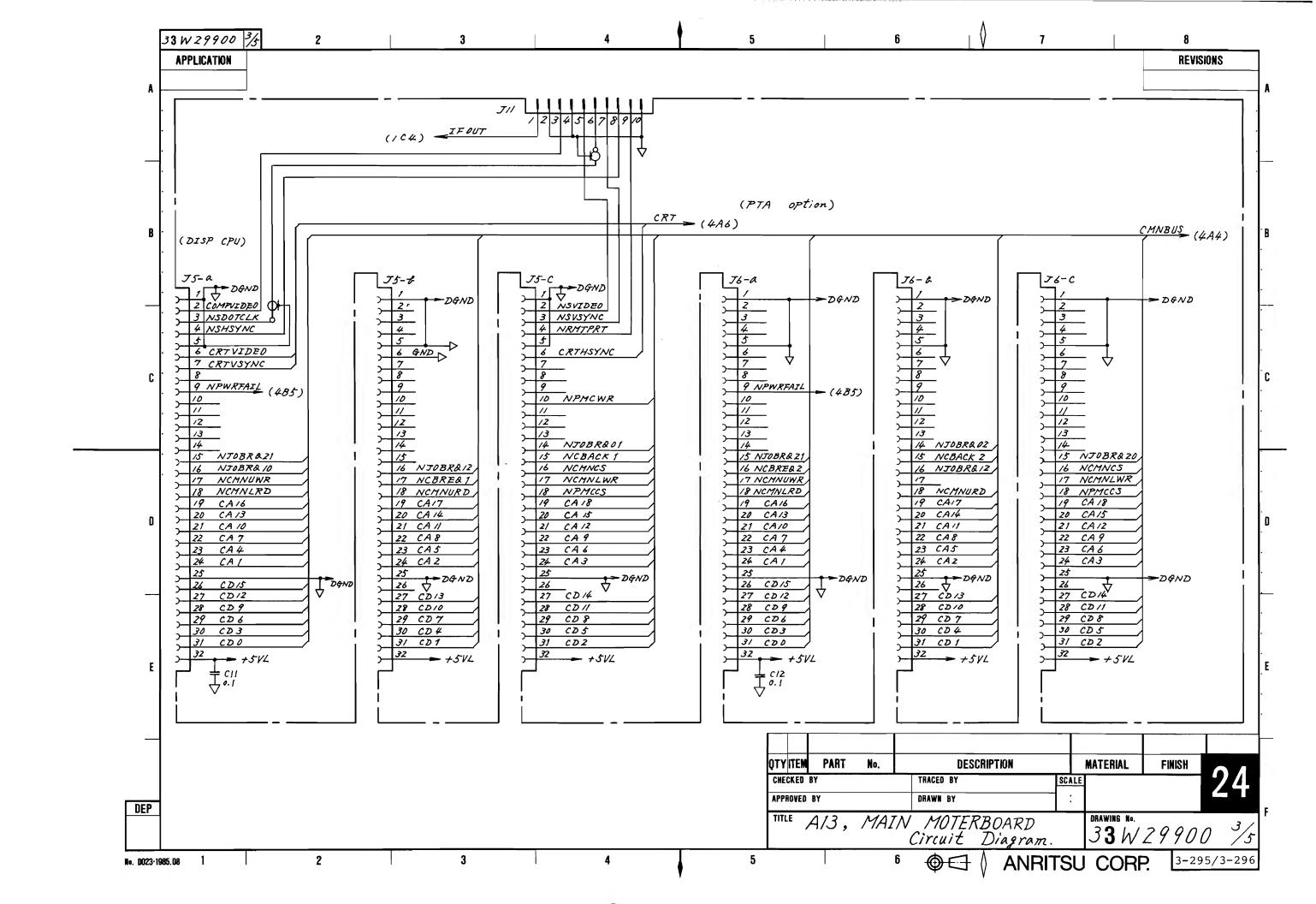


Fig. 3-63 A16 FILTER PC Board Parts Layout 28

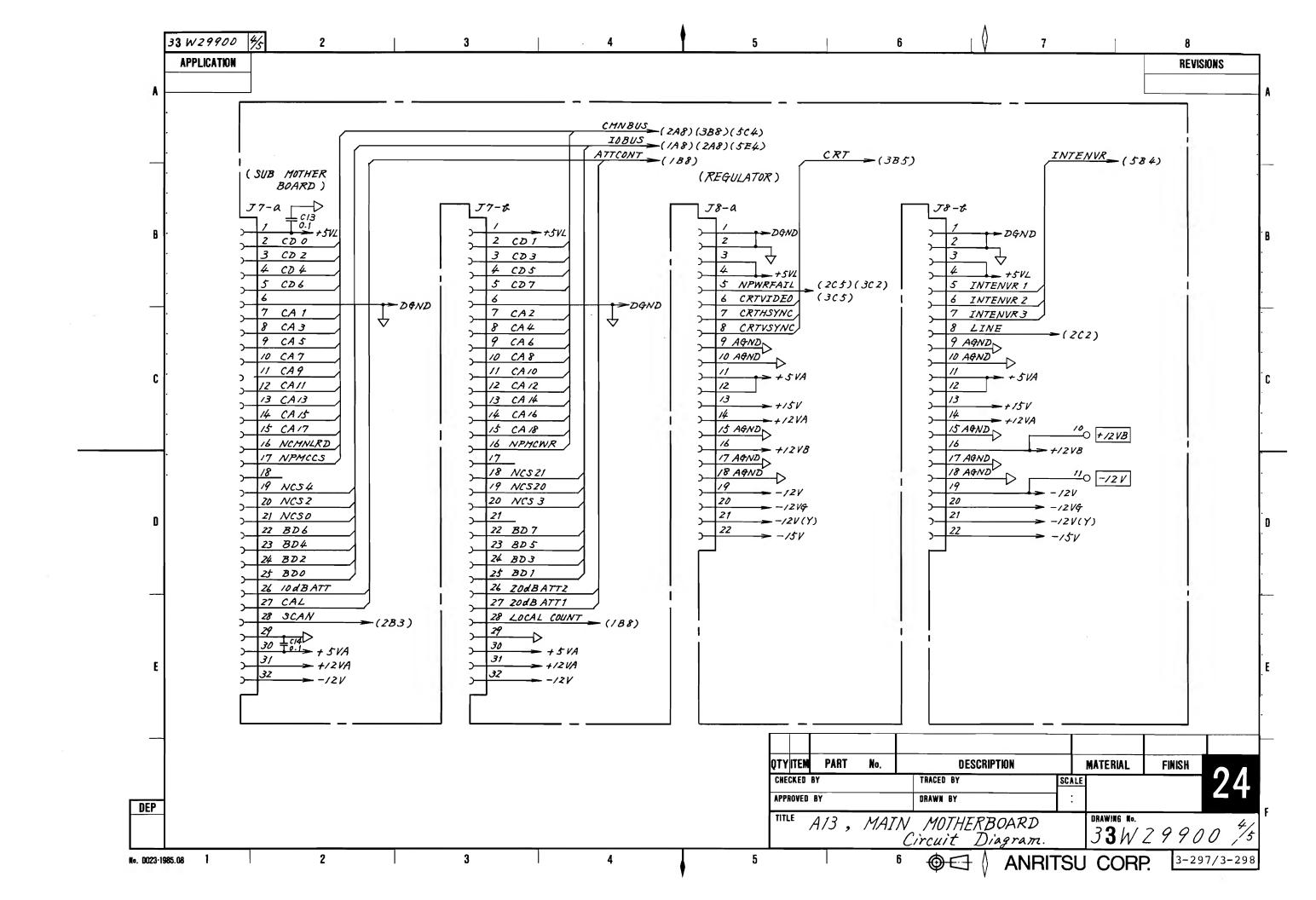




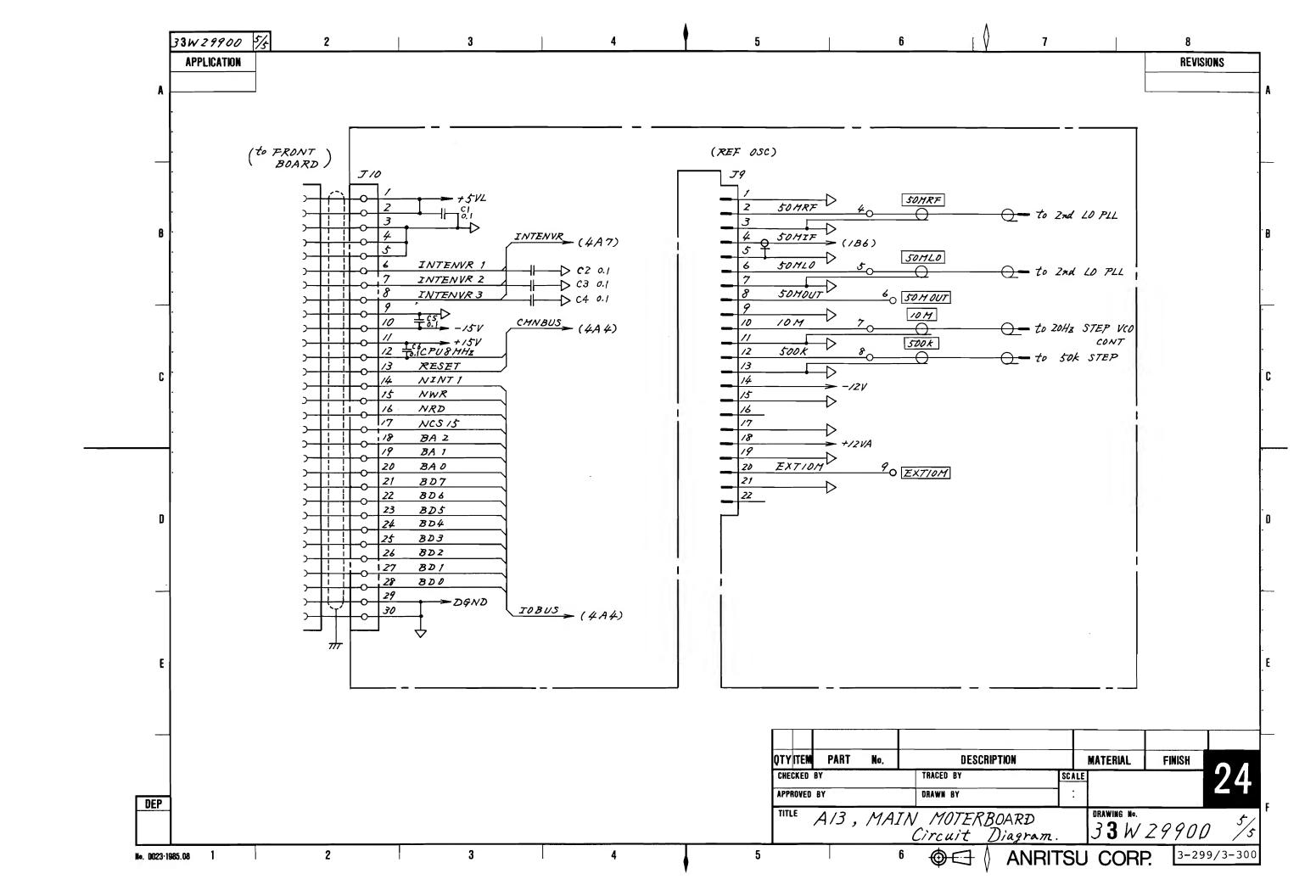
		,
		)
		)



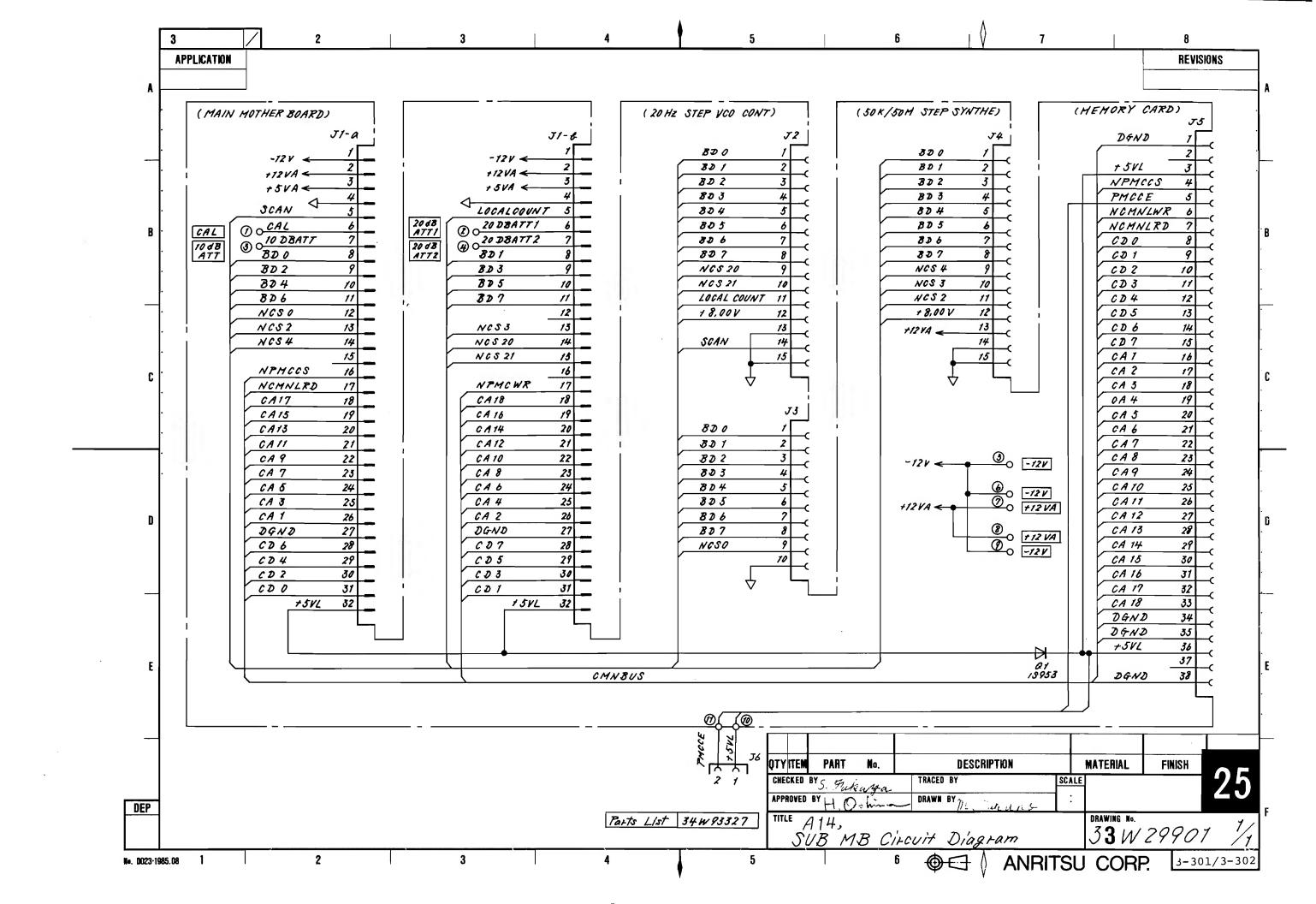
			,
			)



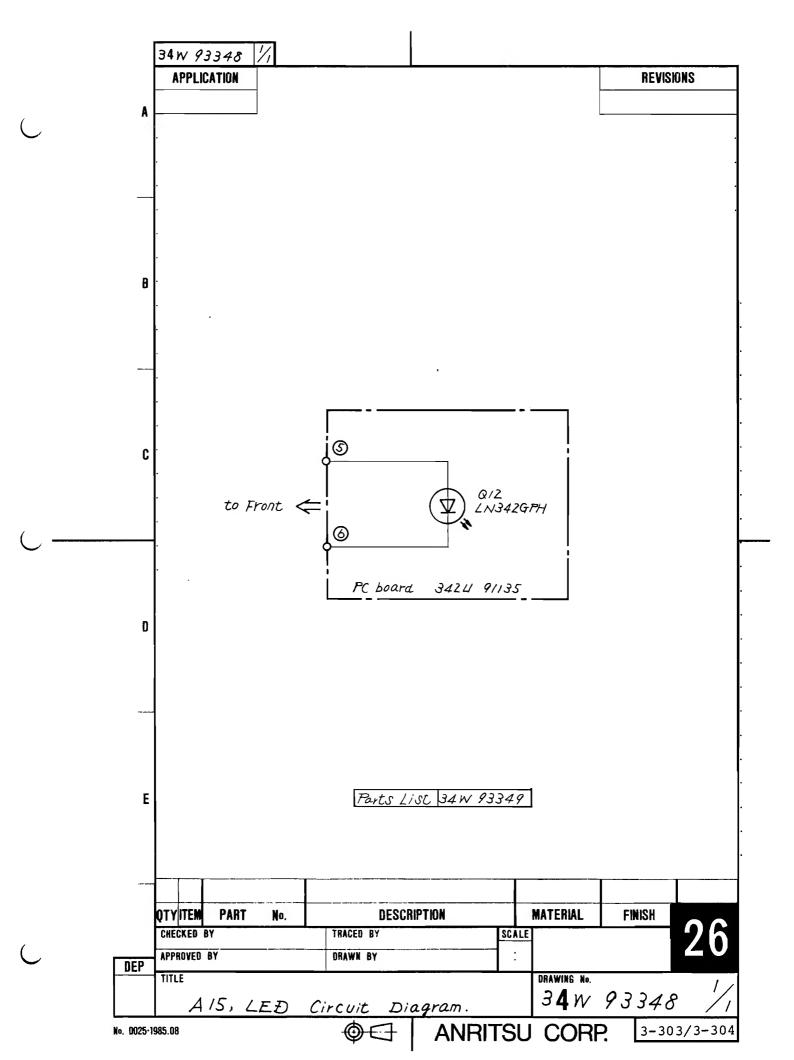
			,
			)
			,
			,



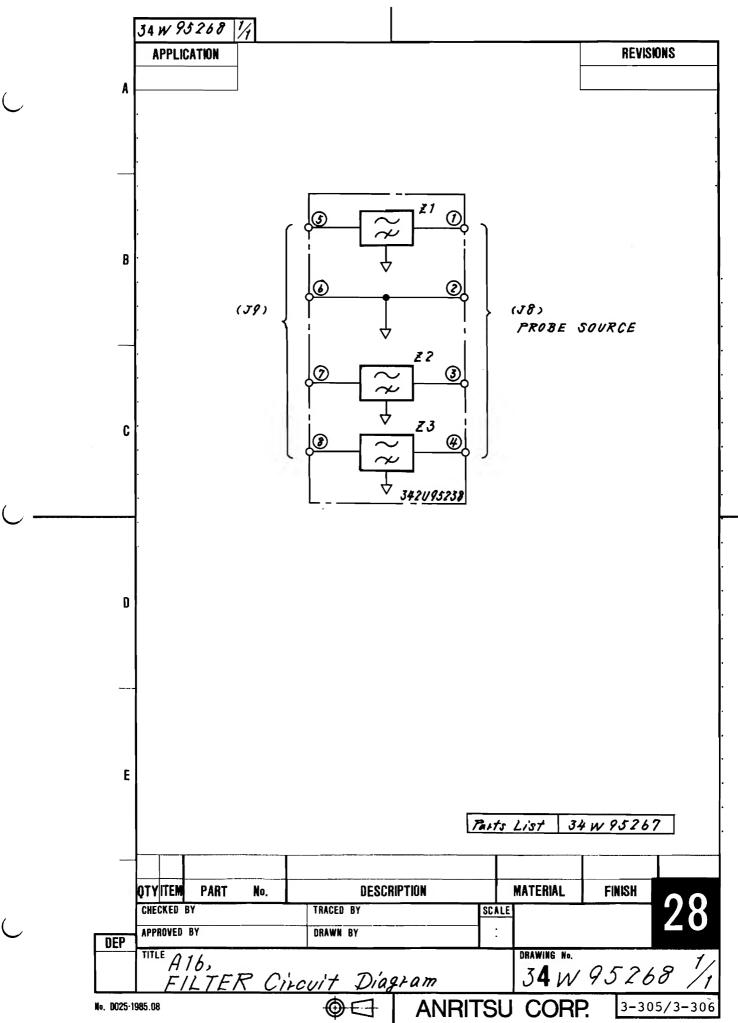
					)
	•				
					)
		,			
					)



		•	
		)	



		<b>)</b>



		•
		•

# 3.3.14 A4 PTA BOARD (Option 01, 04) 29

### (1) Circuit description

The PTA executes the PTA program created by the user. An external keyboard can be connected via the keyboard interface. Parallel data is input/output to external equipment via the I/O port interface. is exchanged between the MAIN CPU and DISP CPU through a common RAM.

This board has a calendar clock IC. It is backed up by a battery.

### (2) Symptoms

- If A4 PTA is not operating normally, a PTA menu is not displayed.
- If the external keyboard or the keyboard 2. interface is faulty, characters input at the external keyboard are not displayed on the PTA menu screen.
- If the battery is dead, the contents of the 3. calendar clock are not normally maintained when power is turned OFF.

#### (3) Troubleshooting

(a) Required equipment Digital voltmeter Oscilloscope

# (b) Preparation

----- CAUTION -----

Turn off the power before disassembly.

Step	Procedure
1	Remove A4 PTA as described in paragraph 2.4.
2	Reattach it using an extender board

# (c) Troubleshooting

Check each checkpoint by referring to the following table.

Signal name	Checkpoing	Normal condition
+5 V	① (Q4-24)	+5 ±0.25 V
CPU Clock	<b>2</b> (Q5-15)	8 MHz pulse wave
+5 V	0	O WATE COM
NPWRF AIL	<b>3</b> (Q2-21)	Same as A8 MAIN CPU (See Fig. 3-54, paragraph
NRESET	<b>4</b> (Q2-17)	3.3.10)
Battery Voltage	<b>5</b> (R7, R8)	≥+2 V

• 

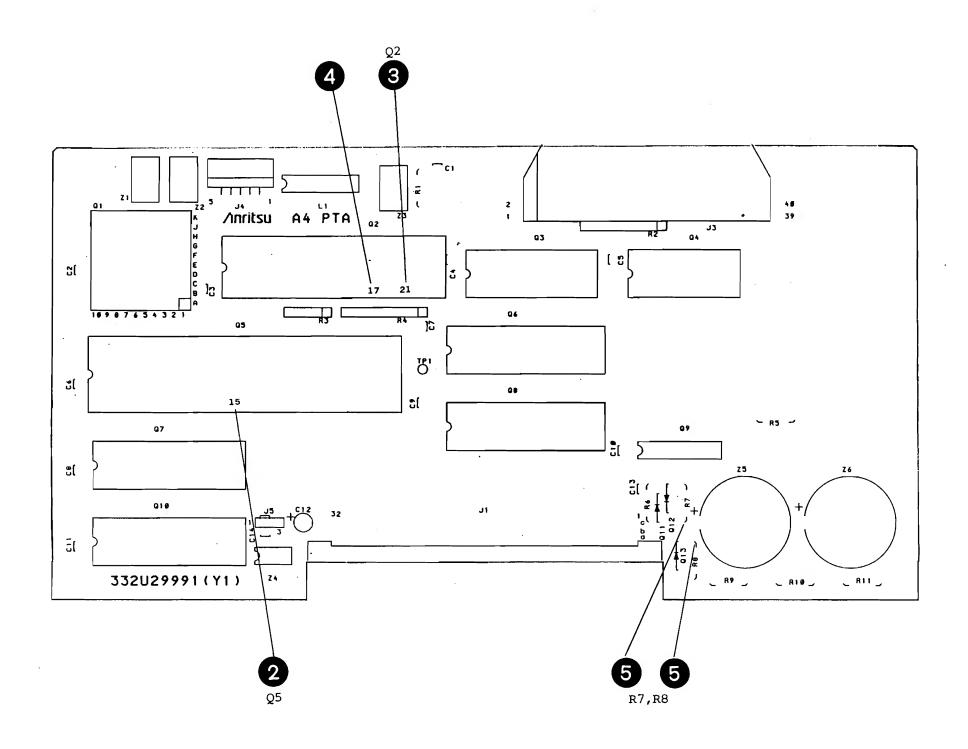


Fig. 3-64 (a) A4 PTA (OPTION 01)
PC Board Parts Layout
(Parts Side) 29

(3-309 blank)/3-310

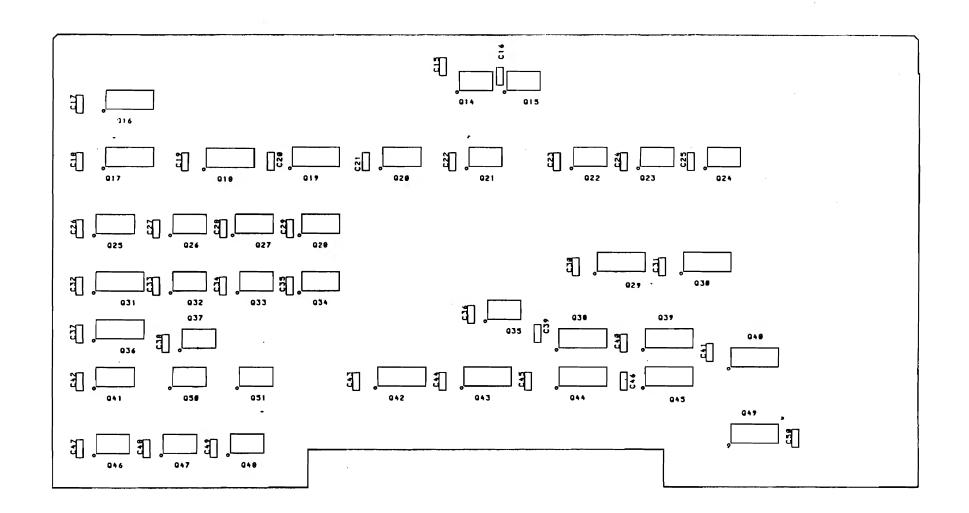
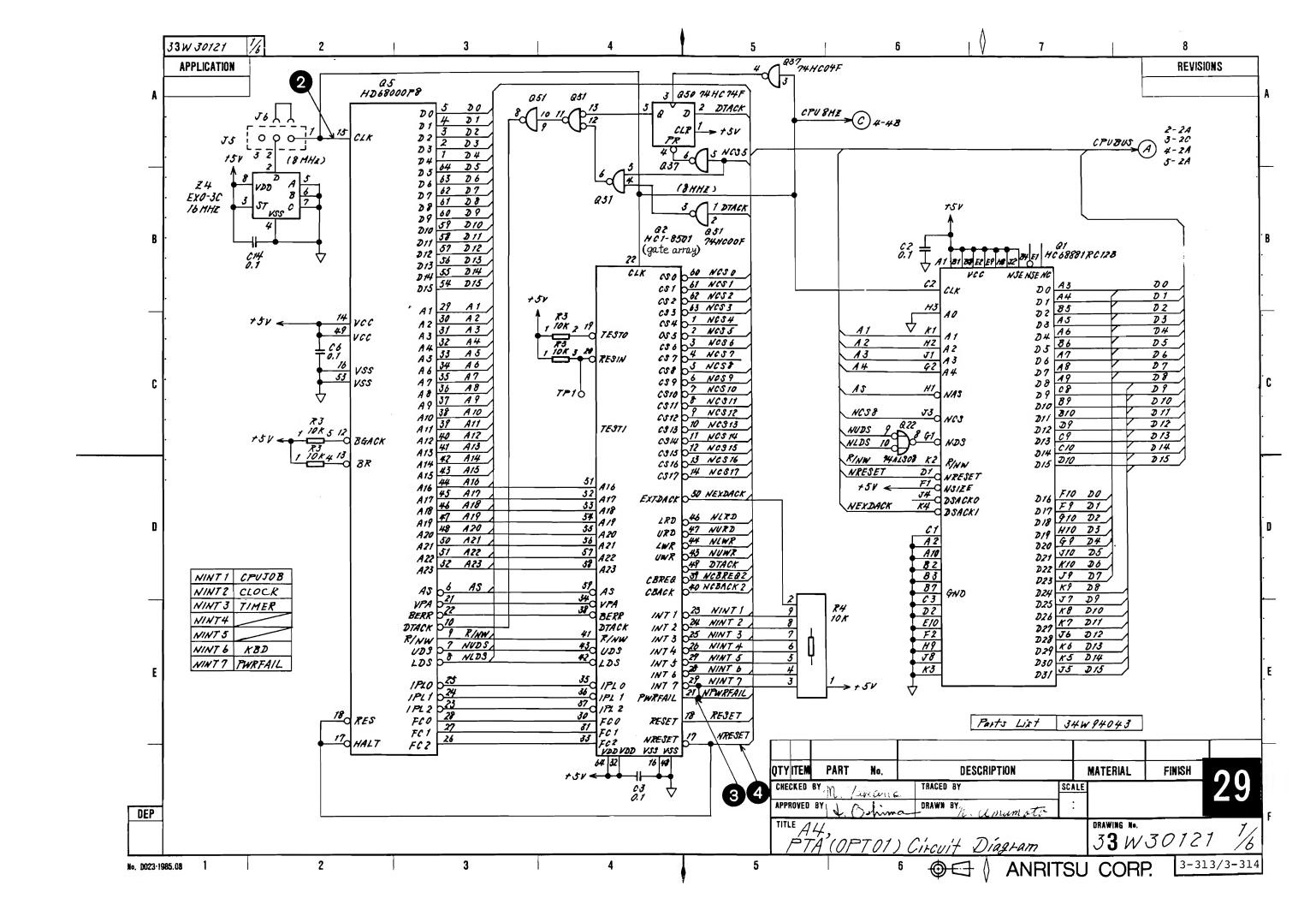
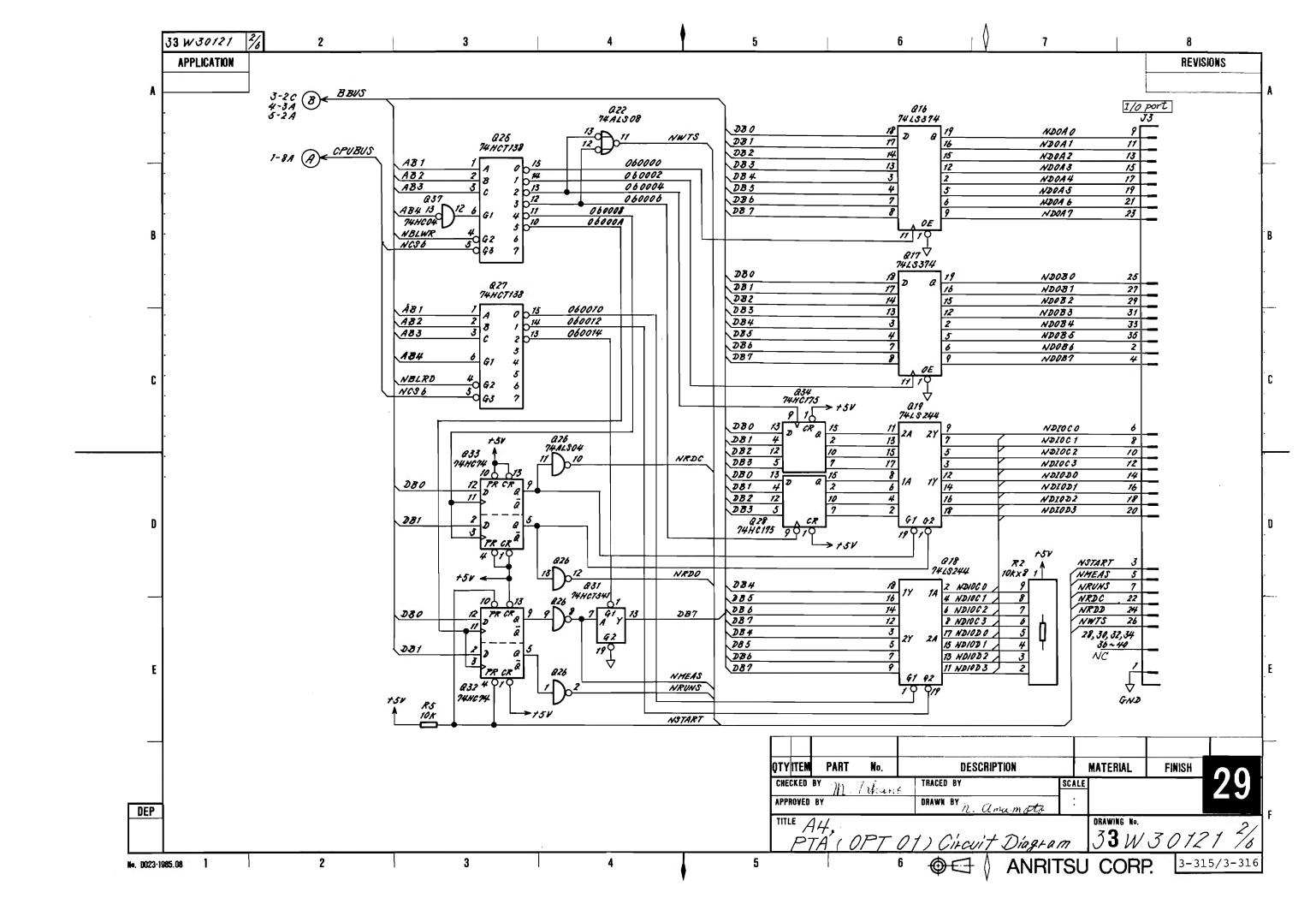


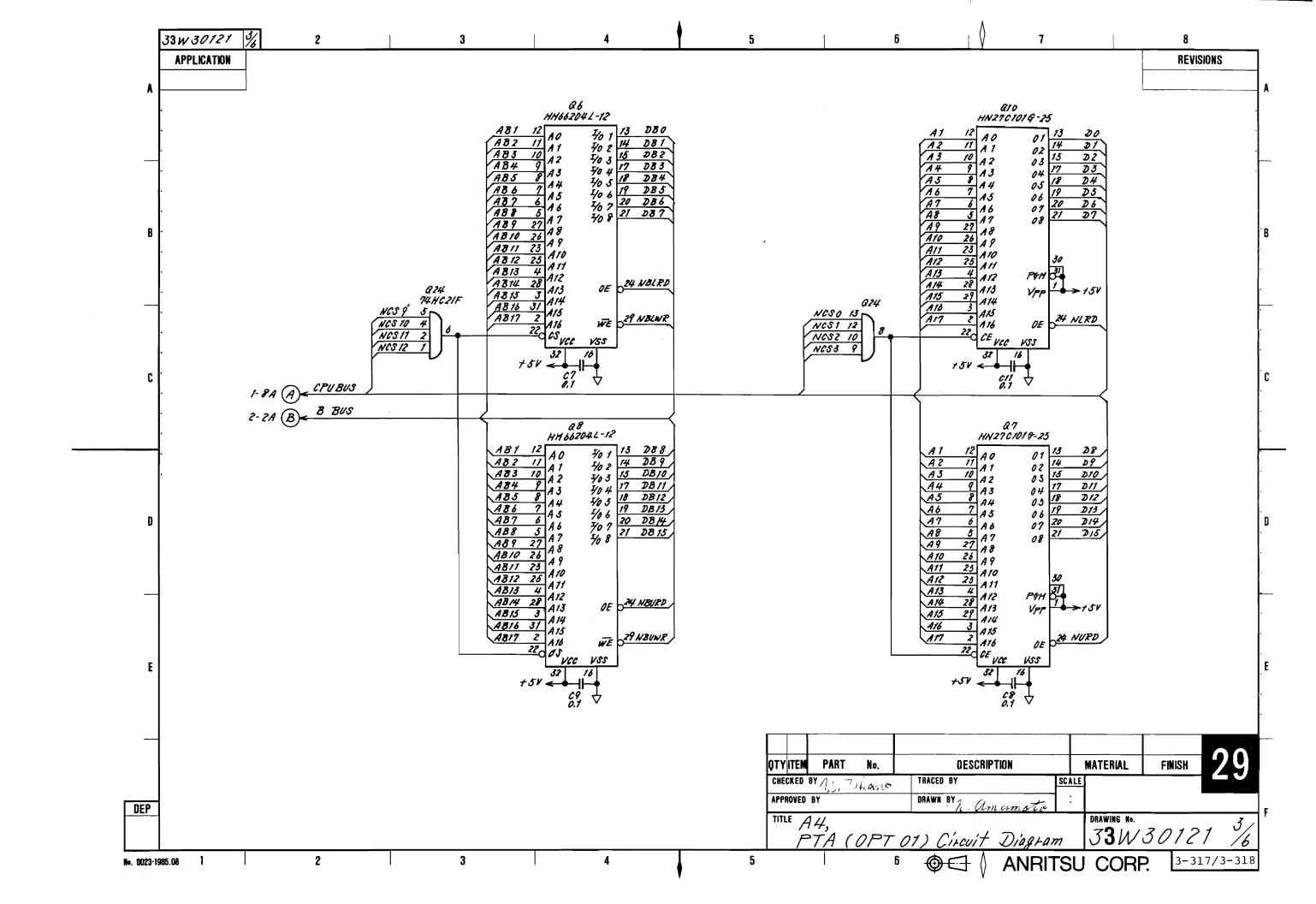
Fig. 3-64 (b) A4 PTA (OPTION 01)
PC Board Parts Layout
(Pattern Side) 29

(3-311 blank)/3-312



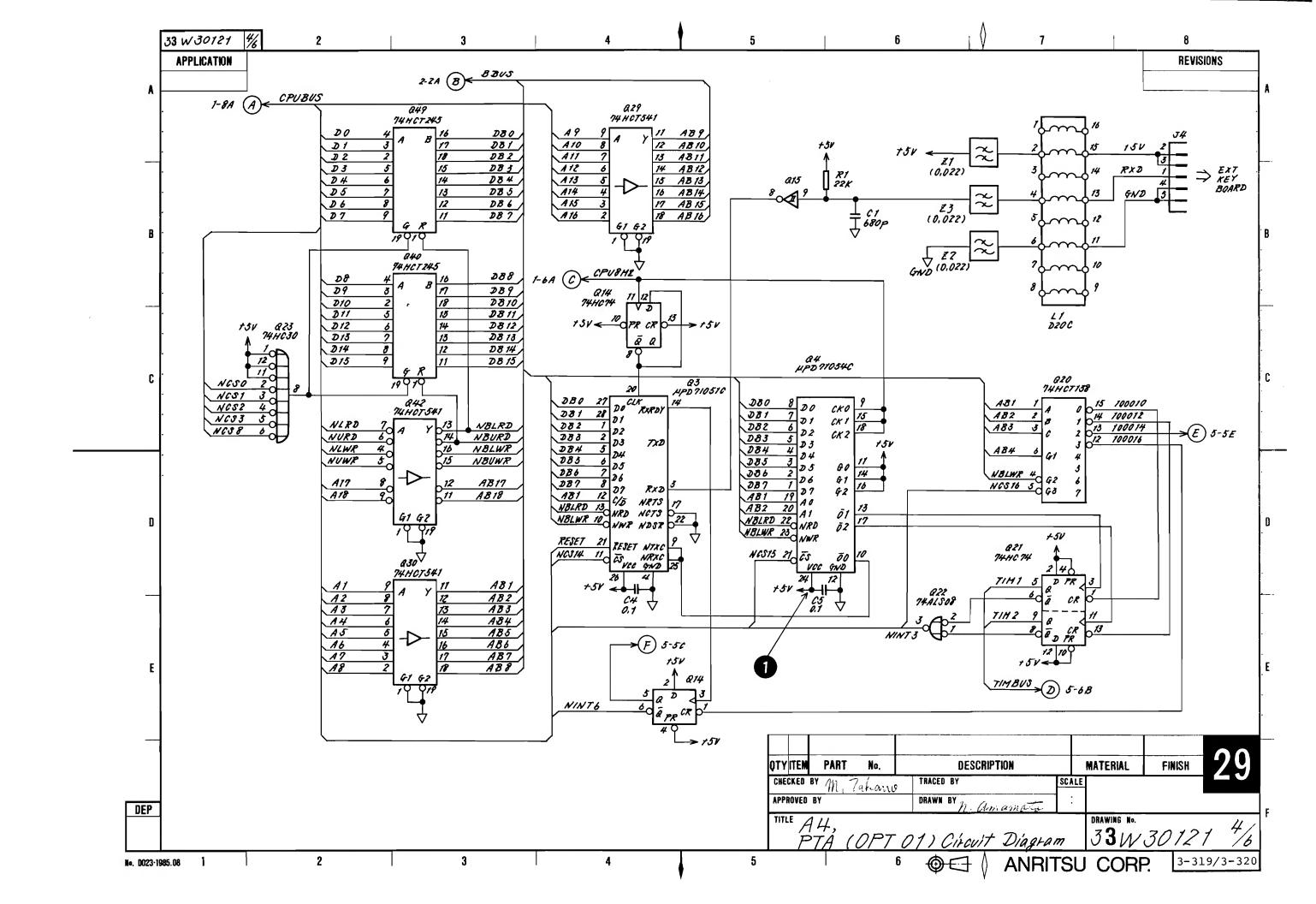


				)
				)
•				
				,

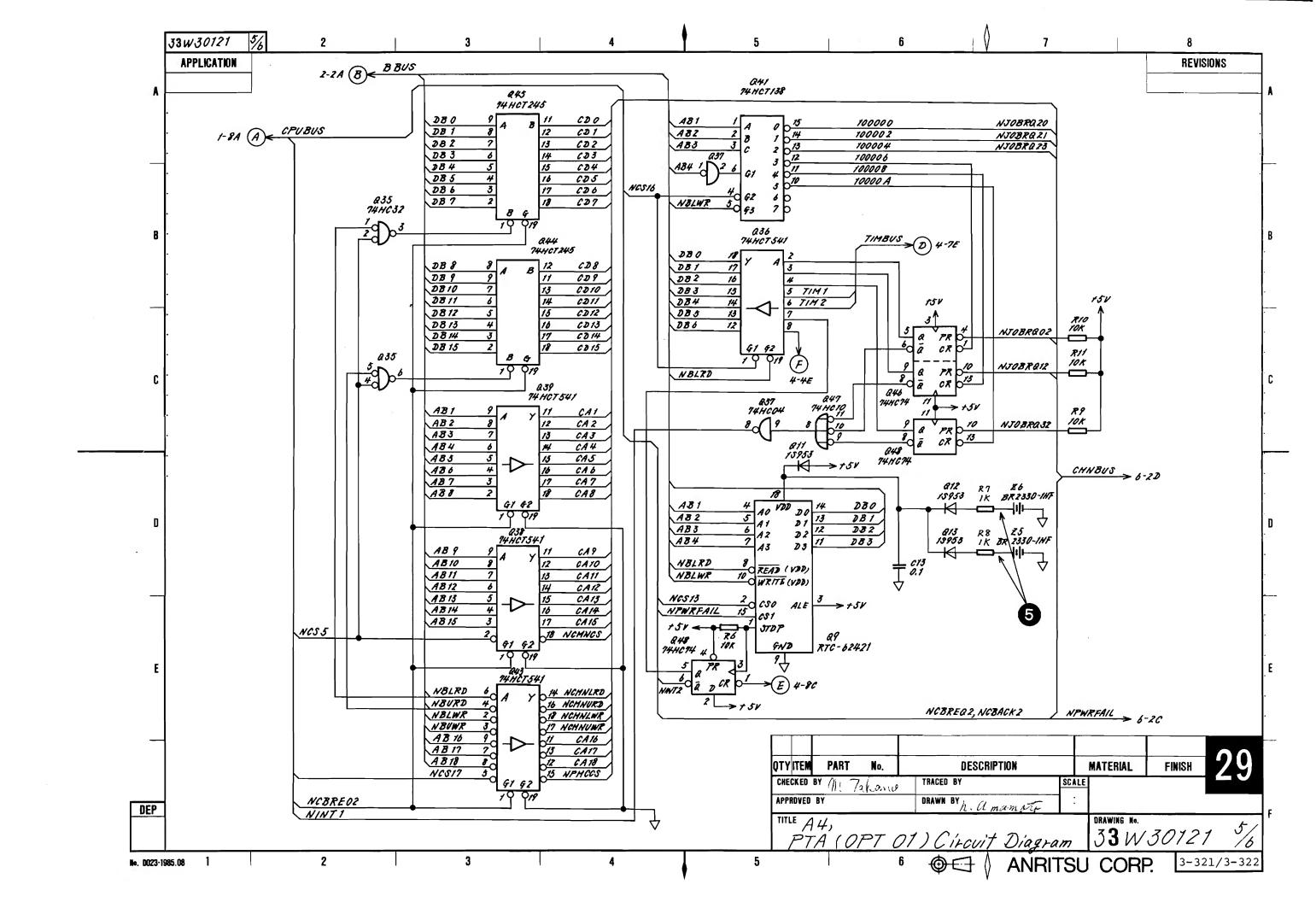


t r at at any and analysis analysis and anal

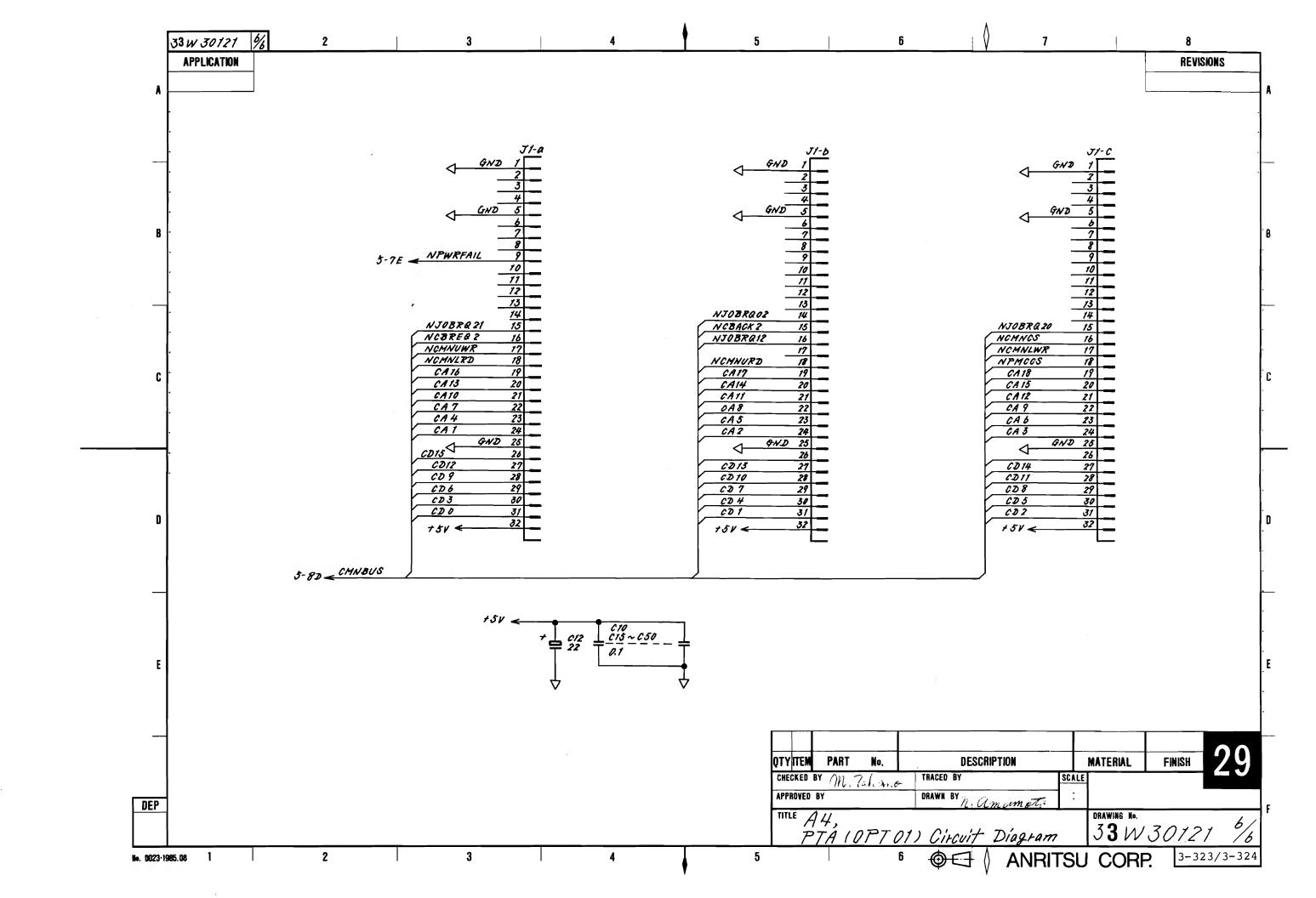
•



)
· •



		)
•		
		)
		)



	•		,
			,
			)
			)

(1) Circuit description

This section includes the serial interface LSI, timer LSI for baud rate generator, RS-232C driver/ receiver (with built-in dc-dc converter), and RAM backup battery for the main CPU.

(2) Symptom

> If All RS-232C boards are faulty, the RS-232C cannot be controlled.

- (3) Troubleshooting
  - (a) Required equipment Digital voltmeter Oscilloscope
  - (b) Preparation

---- CAUTION ----

Turn off the power before disassembly.

Step	Procedure
1	Remove A8 MAIN CPU along with A11 RS-232C as described in paragraph 2.4.
2	Reattach them using an extender board

(c) Troubleshooting
 Check each checkpoint by referring to the
 following table.

Signal name	Checkpoint	Normal condition
+5 V	① (Q2-26)	+5 ±0.25 V
CPU 8 MHz	<b>2</b> (Q1-9)	8 MHz Pulse wave
Baud Rate Clock	<b>3</b> (Q1-10)	Pulse wave
	Baud Rate Cloc	k Frequency
	Baud Rate	Frequency
	300	4.8 kHz
	600 1200	9.6 kHz 19.2 kHz
	2400	38.4 kHz

768.8 kHz

Battery Voltage **4** (R1) ≥+3 V

4800

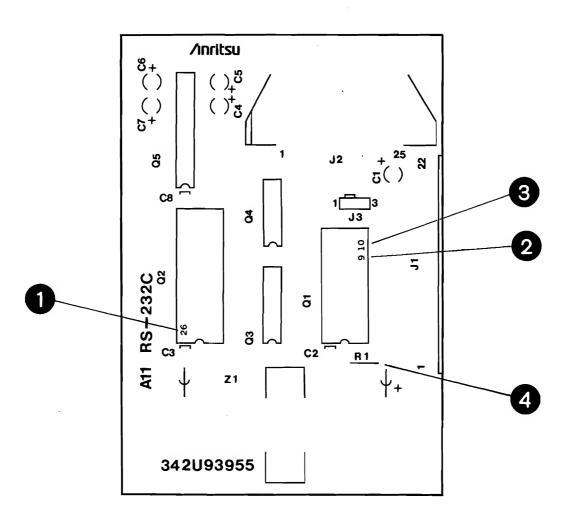
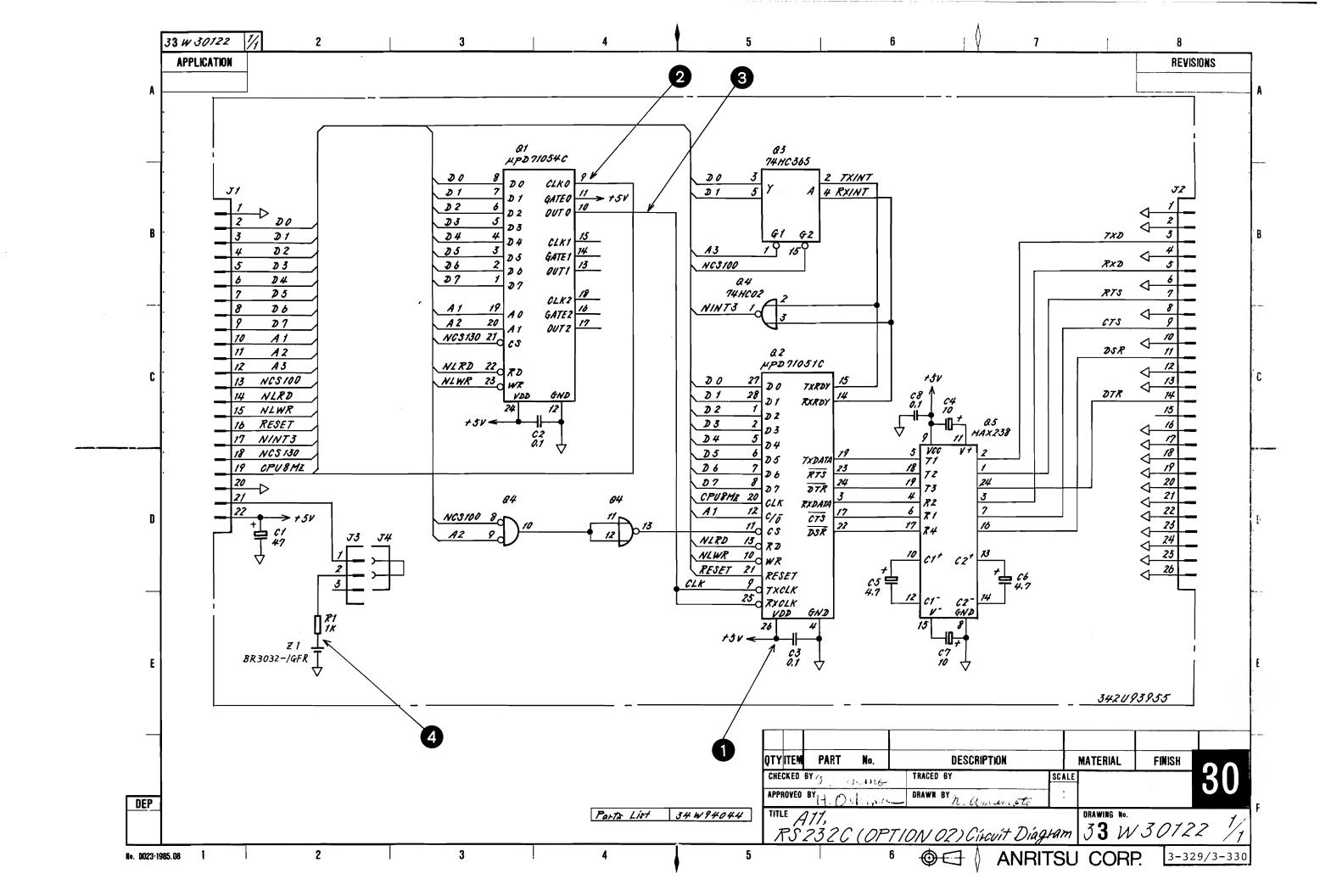
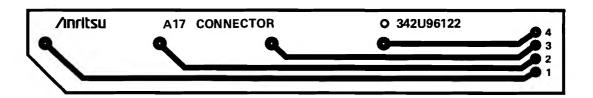


Fig. 3-65 All RS-232C (OPTION 02)
PC Board Parts Layout 30



			)
			)



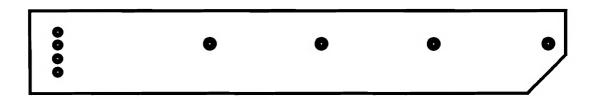


Fig. 3-66 A17 CONNECTOR PC Board
Parts Layout 31

		J
·		
		)
		)

#### SECTION 4

#### CALIBRATION OF COMPENSATION DATA

The MS2601A/J measuring accuracy can be improved by entering the compensation data shown below in the built-in memory.

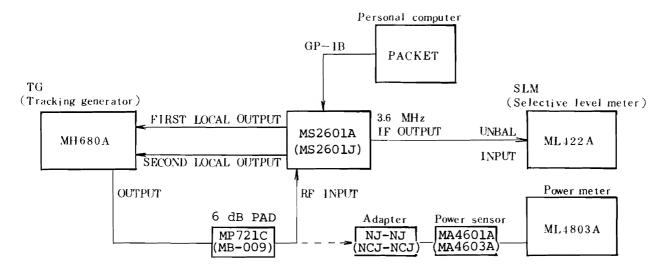
- 1. Frequency response compensation value
- 2. CAL level compensation value

If the specifications are not met for the performance test described in paragraph 4.4 of the operation manual after the circuit related to these compensation data has been repaired, the compensation data must be reentered. The input method is described below.

### 4.1 Frequency Response Calibration

If the specifications are not met for the performance test of the frequency response (paragraph 4.4.8 in the operation manual) after the circuit between the RF INPUT and 1st MIXER has been repaired, calibrate the compensation data according to the procedures described below.

### (1) Setup



\* The units in parenthesis indicate the composition of the MS260lJ.

Fig. 4-1 Frequency Response Calibration

### (2) Calibration

Step	Procedure
1	Press the MS2601A/J [INITIAL] key, and set as follows:
	CENTER FREQ: 625 kHz  REF LEVEL: -10 dBm  SPAN: 0 kHz  RBW: 10 kHz  ATTEN: 20 dB
2	Set the Selective Level Meter (SLM) as follows: IMPEDANCE: 75 $\Omega$ UNBAL BW: 1.74 kHz LEVEL: AUTO FREQUENCY: 3.6 MHz AFC: ON

Step	Procedure
3	Adjust the Tracking Generator (TG) output level so that the SLM measured value is $4 \pm 1 \text{ dBm}$ .
4	Set the SLM to the relative value measuring mode to set the measurement value to 0.00 dB. Press the [RELATIVE (R)] key and then the [MEMORY] key.
	Press the [MODE] key to set dB (X-R) display mode.
5	Change the MS2601A/J CENTER FREQ from 5 MHz to 2000 MHz in 5 MHz steps and read the SLM measured value each time.
	Frequency Measurement value
	5 MHz X(1) dB 10 MHz X(2) dB
	\(\)\(\)\(\)\(\)
	2000 MHz X (400) dB
6	Set the MS2601A/J CENTER FREQ to 625 kHz.
7	Connect the output side of the 10 dB PAD shown in Fig. 4-1 to the power sensor.
8	Press the [dB (REL)] key of the power meter to set the relative value measuring mode and set the measurement value to 0.00 dB.

9 Change the MS2601A/J CENTER FREQ from 5 MHz to 2000 MHz in 5 MHz steps and read the value measured at

Procedure

the power meter each time.

Step

Frequency	Measurement value
5 MHz 10 MHz	R(1) dB R(2) dB
50 MHz 2000 MHz	R(10) dB ( ) R(400) dB

10 Find the frequency response data D(N) from the values measured in steps 5 and 9 from:

$$D(N) = X(N) - R(N) dB$$

where N = 1 to 400

Calculate the following equation but omit figures after the decimal point to give integer CD(N).

$$CD(N) = (D(N) \times 100 + 2)/5$$

### Example:

D(N) CD(N)  

$$-1.01 \rightarrow -20.6 \rightarrow -20$$
  
 $-1.02 \rightarrow -20.8 \rightarrow -20$   
 $-1.03 \rightarrow -21 \rightarrow -21$ 

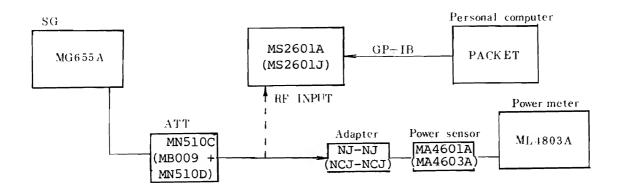
u	C	u	11	_	L	11	v	C	١,

Step	Procedure							
11	Enter the CD(N) values to the MS2601A/J via GP-IB using a personal computer using the following procedures.							
	WRITE @101:"CD2,0" Enter the frequency response input condition.							
	WRITE @101:0 Enter data 0 in address 0.							
	WRITE @101:CD(N) Enter the CD(N) data at 400 points from N=1 to 400 sequentially.							
	FOR I=1 to 40  WRITE @101:CD(400)  NEXT I  Enter the CD(400) data at 2000 MHz in address 401 to 440.							

### 4.2 CAL Level Calibration

If the specification is not met for the performance test of the CRT display amplitude scale linearity (paragraph 4.4.7 in the operation manual) after the CAL circuit has been repaired, calibrate the compensation data using the following procedures.

### (1) Setup



\* The units in parenthesis indicate the composition of the MS2601J.

Fig. 4-2 CAL Level Calibration

### (2) Calibration

Step	Procedure
1	Set the SG as follows:
	Level: +2 dBm (MS2601A is used) +8 dBm (MS2601J is used)
	Frequency: 625 kHz
	Set the ATT to 0 dB.
2	Adjust the SG output level so that the value measured at the power meter is $\pm 2$ $\pm 0.2$ dBm. This measured value is L(1) dBm.
3	Calculate the output level at each ATT attenuation of 1 to 51 dB (1 dB steps) as shown below.

ATT (dB)	Attenuation (calibration value)	ATT output level (dBm)
0	AT(1) dB (= 0 dB)	L(1)
1	AT(2) dB	L(2) = L(1) - AT(2)
<sup>2</sup>	AT(3) dB	L(3) = L(1) - AT(3)
50	AT (51) dB	L(51) = L(1) - AT(51)
51	AT(52) dB	L(52) = L(1) - AT(52)

- 4 Connect the ATT output side to the MS2601A/J RF INPUT.
- 5 Set the ATT to 5 dB.
- 6 Set the MS2601A/J in the following order.

Press the [INITIAL] key

CENTER FREQ: 625 kHz

REF LEVEL: +2 dBm

Step		Procedure
6	SPAN:	5 kHz
(cont.)	RBW:	3 kHz
	ATTEN:	20 dB
	VBW:	10 Hz
	Press the	[PEAK+CF] key to more the waveform peak to
	the cente	r of the screen.
_		

7 Change the ATT from 0 to 51 dB in 1 dB steps and read the MS2601A/J marker level each time.

ATT (dB)	Marker level (dBm)
0	R(1) R(2)
2 \ \	R(3)
50 51	R(51) R(52)

8 Set the MS2601A/J in the following order without changing the ATT setting (51 dB).

Press the [SHIFT] key.

Press the [CAL] key.

Press the  $\lceil F1 \rceil$  key. (RF\*  $\rightarrow$  CAL\*)

Press the 「F5] key (♠) several times until the marker level indicates the maximum value.

(When pressing the 「F5] key several times, the marker level falls suddenly. Next, when the 「F6] key (♥) is pressed, the marker level reaches the maximum.) At this time, this maximum marker level value is X(1) dBm. (CAL ATT = 0 dB).

10	Press the [F5] key ( $>>$ ) 51 times and read the
	marker level each time. (Every time the key is
	pressed, CAL ATT increases towards 51 dB in 1 dB
	steps.)

Procedure

CAL ATT	(dB)	Marker level (dBm)
0		X(1)
1		X(2)
2		X(3)
5		5
50 51		X (51) X (52)

11 Calculate the CAL level D(N) from the values measured in steps 3, 7 and 10 as shown below.

$$D(N) = X(N) - R(N) + L(N) dBm$$

where N = 1 to 52

Step

Also, calculate the following equation but omit the figures after the decimal point to give integer values.

 $CD(N) = D(N) \times 100$ 

•			•				-	
- 1	$\sim$	nt	- 7	n	וו	Δ	$\boldsymbol{\alpha}$	1
١,	CO	111	- 1	11	u	C	u	,

Step	Procedure						
11 (cont.)	Example:						
(331120)	D(N)						
	+0.03 → 3						
	$-10.05 \rightarrow -1005$						
12	Enter the CD(N) values to the MS2601A/J via GP-IB						
	using a personal computer using the following						
	procedures.						
	WRITE @101:"CD1,0" Enter the CAL data input condition.						
	WRITE @101:CD(N) Enter the CD (N) values at the 52 points from N = 1 to 52 sequentially.						

#### SECTION 5

#### REPLACEABLE PARTS

#### 5.1 Introduction

This section contains information relative to ordering replacement parts.

The following table shows circuit reference (hereinafter CKT REF) and abbreviations used for parts given in the Parts List.

In the Parts List, the quantity of each part is one if no quantitative description is given in the "NOTE" column.

### 5.2 Ordering Information

When ordering parts, please give the following descriptions by referring to the PARTS LIST.

	Item	Example			
(1).	Name of instrument	Spectrum Analyzer MS2601A/J			
(2)	Name of parts list	Parts of MS2601A/J OVERALL CIRCUIT			
(3)	CKT REF	z 1			
(4)	Name of part	YTO, (MP657A)			
		Note:			
		Parts name is given in parentheses () in the Parts List. Parts with asterisk* are those that require factory adjustment upon repairing. When ordering a part or parts with asterisk, give full description of the part.			
(5)	Quantity	1			
(6)	Serial No. of instrument	Serial No. M31257			

When ordering PC boards with parts mounted, please include the A-number under item (2) above instead of items (3) and (4). (See Table 3-1 for PC board number.)

# (1) Circuit references

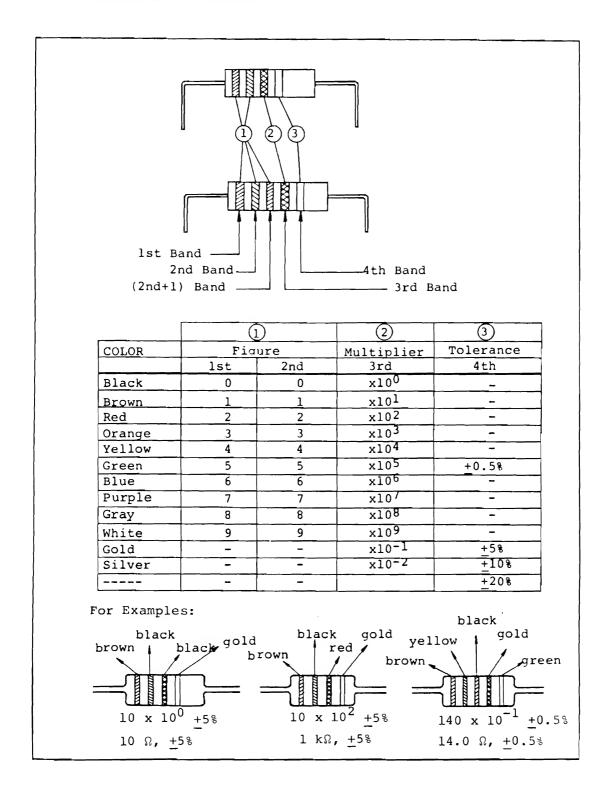
A: AT: B: C:	Unit (PCB) Attenuator Speaker, Bell Capacitor	J: K: L:	Jack, plug, connector Relay Coil, microconductor	Q: R: S:	Transistor, diode, IC, rectifier Resistor Switch	V: W: X: Z:	Vacuum tube Connector with cable Crystal OSC
F:	Fuse	M:	Meter, timer	T:	Transformer	4.	OHIC
G:	Fan	P:	Lamp				

### (2) Abbreviations

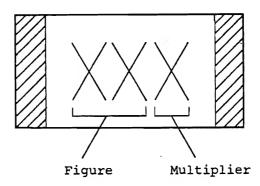
A:	amperes	Multi:	multiplying
Att, R var:	variable attenuator using film	N-ch:	N-channel
K val:	elements	non-lin:	non-linear taper
BL:	boundary layer	Non-pol:	non polarity
Cer:	ceramic	NPN:	negative-positive-negative
CF:	carbon film	Ω:	ohms
Comp:	composition	p:	pico (x 10 <sup>-12</sup> )
CRT:	cathode-ray tube	Plast:	plastic film
Di:	diode	PMTR:	potentiometer
DIP:	dual in-line package	PNP:	positive-negative-positive
Elect:	electrolytic aluminum	p-p:	peak-to-peak value
F:	farad	RFC:	RF choke
FET:	field-effect transistor	R-lamp:	resistor lamp
G:	ground	rms:	effective value (root-mean-square)
Ge:	germanium	SBD:	Schottky barrier diode
Н:	henry	SCR:	silicon-controlled rectifier
Hz:	hertz	Si:	silicon
IC:	integrated circuit	SRD:	step-recovery diode
IEC:	Conforms to IEC Safety Standards.	Tant:	tantalum
J-FET:	junction FET	TM:	time-lag
k:	kilo (x 10 <sup>3</sup> )	Tr:	transistor
LED:	light-emitting diode	Trans:	transformer
M:	mega (x 10 <sup>6</sup> )	μ:	micro (x 10 <sup>-6</sup> )
m:	milli (x 10 <sup>-3</sup> )	V:	volt
MF:	metallized film	Var:	variable
MOS-FET:	metal-oxide semiconductor FET	ww:	wire-wound
M paper:	metallized paper	XTAL:	crystal
M plast:	metallized plastic film		

### 5.3 Reading Capacitance and Resistance

### (1) Reading resistance



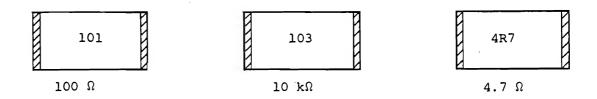
### (2) Reading chip resistance



The first two characters are significant digits and the last numeric character indicates the number of zeroes that follow the first two characters.

A decimal point is represented by the character R, and numeric characters are all significant digits in the R representation.

For Examples:



## (3) Reading capacitance

CAPACITANCE -

- MULTIPLIER

Value in Picofarads (pF)



Number of zeros following value

EXAMPLES:

 $103 = 10,000 \text{ pF} = 10^{-8} \text{ F or } 0.01 \text{ } \mu\text{F}$ 

 $302 = 3,000 \text{ pF} = 3x10^{-9} \text{ F or } 0.003 \text{ } \mu\text{F}$ 

 $676 = 67,000,000 \text{ pF} = 67 \times 10^{-6} \text{ F or } 67 \text{ } \mu\text{F}$ 

(a) Ceramic and polyester capacitors

Indication	0.5	1	10	101	102	103	104
Capacity	0.5 pF	l pF	10 pF	100 pF	1000 pF	0.01 µF	0.1 µF

Example:

Ceramic Capacitor











Capacity values are always underlined.

Polyester Capacitor



(b) Tantalum, metallized, and electrolytic capacitors

Indication	OR47	010	100	101	
Capacity	0.47 μF	l μF	10 μF	100 μF	

(c) Chip tantalum capacitance

Indication	0.47	4.7	47
Capacity	0.47 µF	4.7 µF	47 μF

## (4) Reading chip ceramic capacitance

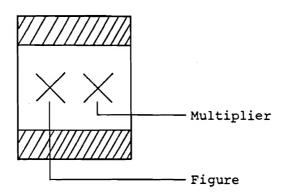
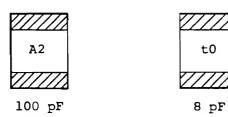
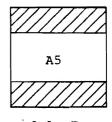


Figure					Mult	imeter	
Indicated alphabetic character	Corre- sponding value	Indicated alphabetic character	Corre- sponding value	Indicated alphabetic character	Corre- sponding value	Indicated value	Corresponding multiplier
	1.0	М	3.0	Y	8.2	0	100
В	1.1	N	3.3	z	9.1	1	10 <sup>1</sup>
С	1.2	P	3.6	a	2.5	2	10 <sup>2</sup>
D	1.3	Q	3.9	b	3.5	3	103
E	1.5	R	4.3	đ	4.0	4	104
F	1.6	s	4.7	е	4.5	5	10 <sup>5</sup>
G	1.8	т	5.1	f	5.0	6	10 <sup>6</sup>
H	2.0	ט	5.6	m	6.0	7	107
J	2.2	v	6.2	n	7.0	8	108
ĸ	2.4	W	6.8	t	8.0	9	10 <sup>-1</sup>
L	2.7	x	7.5	У	9.0	·	<del></del>

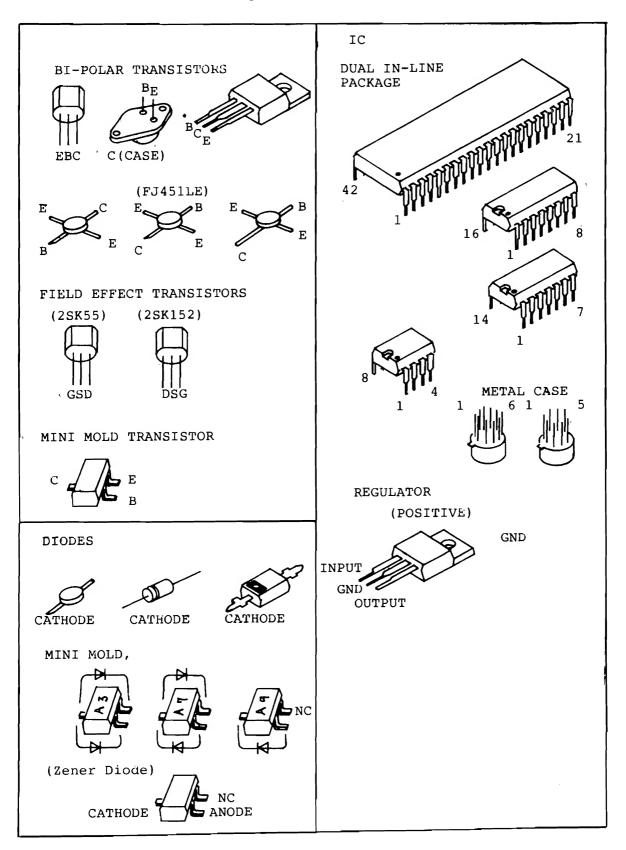
Examples:





0.1 µF

## 5.4 Semiconductor Markings



## 5.5 Parts List

Note:

For the PC board number, see Table 3-1.

		)

Parts List: MS2601A

	Parts Dist: M32001X			
CKT REF	DESCRIPTION	RATING	NOTE	
A 1 A 2 A 3 A 4 A 5	RF/PLL BLOCK IF BPF IF LOG/DET PTA FRONT	_	OPT 01 only	
A 6 A 7 A 8 A 9	SCAN/YTO DRIVE REF OSC MAIN CPU GP-IB		Not assigned for OPT	
A 10 A 11 A 12 A 13 A 14	DISP CPU RS 232C Not absigned MAIN MOTHER BOARD SUB MOTHER BOARD		OPT 02 only	
A 15	LED			
G 1	Fan, (FBH-08A12H)			
J 1 J 2 J 3 J 4 J 5	Not assigned Connector, (BNC-071) Not assigned Not assigned Connector, (57-40360)		OPT 01 only	
<i>ū</i> 6	Connector, (TCS0254-01-0101)		OPT 01 only	
J 7 J 8	Connector, (CNF3-40D-2.54R) Connector,(RA0304NAG)		OPT 01 only	
J 9	Connector,			
J 10 J 11	(DF1-8S-2.5R24) Not assigned Connector, (DF1B-10S-2.5R)			
J 12 J 13 J 14 J 15 J 16	Connector, (BNC-071) Connector, (BNC-071) Connector, (BNC-071) Connector, (BNC-071) Connector, (DC-071) Connector, (DF1-5S2.5R24)			
J 17 J 18 J 19 J 20	Connector, (3CR) Connector, (3CR) Not assigned Not assigned			

Parts List: MS2601A

		LISC: MS2001A	
CKT REF	DESCRIPTION	RATING	NOTE
J 21 J 22 J 23 J 24	Connector, (TCS0284-01-0101) Connector,(BNC-071) Connector,(F-1306-DB) Connector, (DF1-1052.5R24)		
J 25 J 26 J 27	Ground terminal Inlet, (NC-165) Jack, (DF1-10S2.5R24)		Attached to CRT UNIT
J 28 J 29 J 30 J 31	Jack, (DF1-8S2.5R24) Connector, (1625-02P1) Connector, (DF1-10S2.5R24) Connector, (1625-03R1)		
J 32 J 33	Connector, (1625-03P1) Connector, (1625-02R1)		Attached to REGULA- TOR UNIT
R 1	CF, (ARD25T105J)	1.0MΩ, ±5%,1/4W	
<b>s</b> 1	Switch, (SDU3P2106)		
<b>T</b> 1	Power transformer		
W 1 W 2 W 3	Not assigned Not assigned Cable, (57FE-450-GP-IB)		
Z 1 Z 2	YTO, (MP657A) Noise filter, (ZMB 2203-13)		
Z 3 Z 4	CRT unit, (DDC-V6ND) Regulator unit		

( ): Manufacturer's part number

\* : Selected at factory

34W93351 1/2

( ): Manufacturer's part number
\* : Selected at factory

34W93351 2/2

Parta List: Al, RF/PLL BLOCK

NOTE  34W93328 34W93329 34W93330 34W93332 34W93333 34W93333 34W93333 34W93336 34W93336 34W93336 34W93336 34W93337 34W93338
34W93329 34W93330 34W93331 34W93333 34W93333 34W93336 34W93336 34W93336 34W93336 34W93336 34W93336 34W93336
34W93329 34W93331 34W93332 34W93333 34W93333 34W93336 34W93336 34W93336 34W93336 34W93336 34W93336 34W93336
34W93331 34W93333 34W93333 34W93335 34W93337 34W93337 34W93339
34w93331 34w93333 34w93334 34w93337 34w93337 34w93337 34w93338 34w93339
34w93334 34w93333 34w93334 34w93336 34w93337 34w93339 34w93339
34w93334 34w93333 34w93334 34w93336 34w93337 34w93339 34w93339
34W93333 34W93335 34W93337 34W93337 34W93339
34W93334 34W93335 34W93337 34W93338 34W93339
34w93336 34w93337 34w93338 34w93339 ***
34w93336 34w93337 34w93338 34w93339 ***
34w93336 34w93339 34w93339 
34W93337 34W93339 34W93339 *********************************
34W93339 34W93339 34W93339 ***
34W93339 34W93339 ** *
34W91578 34W91578 34W91578
34W91578 34W91578 34W91578
34W91578 34W91578
34W91578
34W91578

Parts List: Al, RF/PLL BLOCK

CKT REF	DESCRIPTION	RATING	NOTE
R 6	MF, (RN14K2E1001D)	1.00kΩ,±0.5%,1/4W	
W 1	Semi-rigid cable, (34J92577)		
₩ 2	Semi-rigid cable,		
W 3	(34J92578) Semi-rigid cable, (34J95262)		
W 4	Coaxial cable, (34J91082K)		
W 5	Coaxial cable, (34J91082G)		
W 6	Coaxial cable, (34J91082G)		
<b>W</b> 7	Coaxial cable, (34J91082E)		
Z 17	Noise filter,		
z 18	(ZFN5101-01R-A) Noise filter,		
Z 19	(ZFN5101-01R-A) Noise filter, (ZFN5101-01R-A)		
Z 20	Noise filter, (ZFN5101-01R-A)		
z 21			
Z 25	Noise filter, (ZFN5101-01R-A)		
Z 26	Noise filter, (ZFN5101-01R-A)		
			-

( ): Manufacturer's part number
\* : Selected at factory

34W93317 1/2

( ): Manufacturer's part number
\* : Selected at factory

34W93317 2/2

Parts List: A1-A1, DC BLOCK (MS2601A)

		er ni ni, se sacen	3
CKT REF	DESCRIPTION	RATING	NOTE
C 1 C 2	Cer, (GR44-1W5R224K100) Cer, (GR44-1W5R224K100)	0.22µF,±20%,100V 0.22µF,±20%,100V	

Parts List: A1-A1 DC BLOCK (MS2601J)

	Parts List:	AT-AT DC BLOCK (MS26013)	3
CKT REF	DESCRIPTION	RATING	NOTE
C 1 C 2	Cer, (GR44-1W5R224Z100) Cer, (GR44-1W5R224Z100)	0.22μF,+80/-20%,100V 0.22μF,+80/-20%,100V	
R 1 R 2	CM, (RM73B2B470JD) CM, (RM73B2B820JD)	47Ω,±5%,1/8W 82Ω,±5%,1/8W	
	·		

( ): Manufacturer's part number
\* : Selected at factory

34W93328 1/1

( ): Manufacturer's part number

\* : Selected at factory

34W94374 1/1

Parts List: A1-A1 DC BLOCK (MS2601J OPT 05)

	Falts Dist. A	I-MI DC BLOCK (M32001	3
CKT REF	DESCRIPTION	RATING	NOTE
R 1 R 2	CM, (RM73B2B470JD) CM, (RM73B2B820JD)	47Ω,±5%,1/8W 82Ω,±5%,1/8W	
			4.
			T'

Parts List: A1-A2, P-ATT

CKT REF	DESCRIPTION	RATING	NOTE
C 1	Cer,(CC732CH1H221J(J2))	220pF,±5%,50V	
K 1 K 2 K 3 K 4	Relay, (UH-12) Relay, (UH-12) Relay, (UH-12) Relay, (UH-12)	+12V +12V +12V +12V	
L 1	Coil, (NL453232-1R5K)	1.5µH,±10%	
2 1 2 2 2 3 2 4	Di,(152835(A3)) Di,(152835(A3)) Di,(152835(A3)) Di,(152835(A3))		V
R 1	CM, (RM73B2B470JD)	47Ω,±5%,1/8W	
Z 1 Z 2 Z 3	Att,(20DB) Att,(10DB) Att,(20DB)		

( ): Manufacturer's part number
\* : Selected at factory

34W96453 1/1

( ): Manufacturer's part number
\* : Selected at factory

34W96386 1/1

Parts List: Al-A4, EQU

CRT REF         DESCRIPTION         RATING         NO           C 1 Not assigned Cer, (CC732CH1040D)         4pF, ±0.5pF,50V         *           R 1 Not assigned R 2 Not assigned CM, (RW73B2B22JJD)         2200, ±5%,1/8W         2200, ±5%,1/8W           R 4 CM, (RW73B2B22JJD)         2200, ±5%,1/8W         2200, ±5%,1/8W		Parts List: Al-A4, EQU			
C 2   Cer, (CC732CH1H040D)   4pF,:0.5pF,50V   *		DESCRIPTION	RATING	NOTE	
R 2 Not assigned R 3 CH,(RM73B2B22JJD) 2200,;5%,1/8W R 4 CH,(RM73B2B22OJD) 220,:5%,1/8W	C 1	Not assigned Cer, (CC732CH1H040D)	4pF, ±0.5pF, 50V		
	R 2 R 3 R 4	Not assigned CM, (RM73B2B221JD) CM, (RM73B2B220JD)	22Ω,±5%,1/8W		

Parts List: A1-A6, 2.5214 GHZ PRE AMP

CKT	DESCRIPTION	RATING	NOTE
REF	DESCRIPTION	RATING	NOTE
c 1	Cer, (CC732CH1H220J(J1))	22pF,±5%,50V	
č 2	Not assigned	p: /:50/500	
c 3	Tant, (CS734E1C226M)	22µF, ±20%, 16V	
C 2 C 3 C 4 C 5	Cer, (CC732CH1H101J(A2))	100pF,±5%,50V	
C 5	Cer, (CC732CH1H220J(J1))	22pF, ±5%,50V	
C 6	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
Q 1	Di,breakdown,	6.0 to 6.39V,200mW	
Ç 2	(RD6.2MB2(622)) Tr,(2SC2585)		
R 1	CM, (RM73B2B391JD)	390Ω,±5%,1/8W	
R 2	CM, (RM73B2B182JD)	1.8kΩ,±5%,1/8₩	
R 3	CM, (RM73B2B391JD) CM, (RM73B2B100JD)	390Ω,±5%,1/8W 10Ω,±5%,1/8W	1
R 5	CM, (RM73B2B391JD)	390Ω,±5%,1/8W	
R 6	CM, (RM73B2B391JD)	390Ω,±5%,1/8W	
		l J	
	Ĭ		
		1	
		1	
		I	
		I	
		I	
	1	I	1
		I	
		I	
		I	
		I	
		<b> </b>	
		<b> </b>	
		}	

( ): Manufacturer's part number

\* : Selected at factory

34W93330 1/1

( ): Manufacturer's part number
\* : Selected at factory

34W93331 1/1

Parts List: A1-A8, 2ND CONV

	_		8
CKT REF	DESCRIPTION	RATING	NOTE
C 1 C 2 C 3 C 4 C 5	Cer, (CC732CH1H220J(J1)) Cer, (CK732B1H103K(A4)) Cer, (CC732CH1H220J(J1)) Cer, (CC732CH1H101J(A2)) Cer, (CC732CH1H101J(A2))	0.01µF,±10%,50V 22pF,±5%,50V 100pF,±5%,50V	
C 6 C 7 C 8 C 9 C 10	Cer, (CK924F1H104z) Cer, (CC732CH1H101J(A2)) Cer, (CC732CH1H220J(J1)) Cer, (CK732B1H103K(A4)) Not assigned		
C 11 C 12 C 13 C 14 C 15	Cer, (CC732CH1H220J(J1)) Cer, (CC732CH1H040D(d0)) Cer, (CC732CH1H040D(d0)) Cer, (CC732CH1H060D(m0)) Cer, (CK732B1H102K(A3))	4pF,±0.5pF,50V 4pF,±0.5pF,50V	
C 16 C 17 C 18 C 19 C 20	Cer,(CK733F1H1042(A5)) Cer,(CK732B1H102K(A3)) Cer,(CK732B1H102K(A3)) Not assigned Not assigned	0.1uF,+80/-20%,50V 1000pF,±10%,50V 1000pF,±10%,50V	į
C 21 C 22	Not assigned Tant, (CS734E1C226M)	22μF,±20%,16V	
L 1 L 2 L 3 L 4 L 5	Not assigned Not assigned Not assigned Not assigned Not assigned		
L 6 L 7	Not assigned Coil,(SP0408-4R7K)	4.7μH	
Q 1 Q 2 Q 3 Q 4 Q 5	Di,breakdown, (RD6.2MB2(622)) Tr.(2SC2585) Di, (ND487R2-3P) Di,(ND487R2-3P) Di,breakdown (RD6.2MB2(622))	6.0 to 6.39V,200mW	
Q 6 Q 7 Q 8	Tr,(2SC2367) Di,breakdown, (RD5.1MB2(512)) Tr,(2SC2351(R2 OR R3))	4.97 to 5.24V,200mW	

Parts List: A1-A8, 2ND CONV

CKT REF	DESCRIPTION	RATING	NOTE
R 1 R 2 R 3	CM, (RM73B2B152JD) CM, (RM73B2B391JD) CM, (RM73B2B471JD)	1.5kΩ,±5%,1/8W 390Ω,±5%,1/8W 470Ω,±5%,1/8W	
R 4 R 5	CM, (RM73B2B182JD) CM, (RM73B2B510JD)	1.8kΩ,±5%,1/8W 51Ω,±5%,1/8W	
R 6 R 7 R 8 R 9	CM, (RM73B2B560JD) CM, (RM73B2B101JD) CM, (RM73B2B101JD) CM, (RM73B2B101JD)	56Ω,±5%,1/8W 100Ω,±5%,1/8W 100Ω,±5%,1/8W 100Ω,±5%,1/8W	
R 10	CM, (RM73B2B510JD)  Ver, MF, (RJ-6P 1KΩ)	51Ω, ±5%, 1/8W  1kΩ, 1/2W	
R 12 R 13 R 14 R 15	CM, (RM73B2B6R8JD) CM, (RM73B2B6R8JD) CM, (RM73B2B6R8JD) CM, (RM73B2B391JD) CM, (RM73B2B511JD)	6.8Ω, 15%, 1/8W 6.8Ω, 25%, 1/8W 390Ω, 15%, 1/8W 510Ω, 15%, 1/8W	
R 16 R 17 R 18	CM, (RM73B2B390JD) CM, (RM73B2B151JD) CM, (RM73B2B391JD)	39Ω,±5%,1/8W 150Ω,±5%,1/8W 390Ω,±5%,1/8W	
т 1	Trans, (342T74443)		

( ): Manufacturer's part number
\* : Selected at factory

34W93332 1/2

( ): Manufacturer's part number

\* : Selected at factory

34W93332 2/2

Parts List: A1-A9, 1ST LO AMP

Parts List: Al-A9, 1ST LO AMP

RATING

6.0 to 6.39V,200mW

4.7Ω, ±5%, 1/8W 150Ω, ±5%, 1/8W 1kΩ, ±5%, 1/8W 100Ω, ±5%, 1/8W 120Ω, ±5%, 1/8W

47Ω,±5%,1/8W 22Ω,±5%,1/8W 75Ω,±5%,1/8W 100Ω,±5%,1/8W 100Ω,±5%,1/8W

18Ω,±5%,1/8W 270Ω,±5%,1/8W 270Ω,±5%,1/8W 51Ω,±5%,1/8W 22Ω,±5%,1/8W

390Ω,±5%,1/8W 5.6kΩ,±5%,1/8W 51Ω,±5%,1/8W 51Ω,±5%,1/8W 75Ω,±5%,1/8W

100Ω,±5%,1/8W 100Ω,±5%,1/8W 330Ω,±5%,1/8W

NOTE

CKT			9
RÉF	DESCRIPTION	RATING	NOTE
C 1 C 2 C 3 C 4 C 5	Elect, (CE04C1H220A) Elect, (CE04C1H220A) Cer, (CK732B1H103K(A4)) Cer, (CC732CH1H101J(A2)) Cer, (CC732CH1H101J(A2))		
C 6 C 7 C 8 C 9 C 10	Cer,(CK732B1H103K(A4)) Cer,(CK732CH1H101J(A2)) Cer,(CC732CH1H101J(A2)) Cer,(CC732CH1H101J(A2)) Cer,(CC732CH1H101J(A2))	100pF,±5%,50V 100pF,±5%,50V	
C 11 C 12 C 13 C 14 C 15	Cer,(CC732CH1H101J(A2)) Cer,(CC732CH1H101J(A2)) Cer,(CC732CK1H010C(A0)) Cer,(CC732CK1H020C(H0)) Cer,(CC732CK1H020C(H0))	100pF, ±5%,50V 100pF, ±5%,50V 1pF, ±0.25pF,50V 2pF, ±0.25pF,50V 2pF, ±0.25pF,50V	
C 16 C 17 C 18 C 19 C 20	Cer,(CK732B1H102K(A3)) Cer,(CK732B1H102K(A3)) Cer,(CK733F1H104Z(A5)) Cer,(CK732B1H102K(A3)) Cer,(CK732B1H102K(A3))	1000pF,±10%,50V 1000pF,±10%,50V 0.1µF,+80/-20%,50V 1000pF,±10%,50V 1000pF,±10%,50V	
C 21 C 22 C 23 C 24 C 25	Cer,(CC732CJ1H030C(M0)) Not assigned Not assigned Not assigned Cer,(CC732CH1H180J(G1))		
L 1	Coil		Printed
L 2	Coil		pattern Printed
L 3	Coil		Printed pattern
L 4	Co11		Printed pattern
Q 1	Di,breakdown, (RD3.9MB(39))	3.7 to 4.1V,200mW	
Q 2	Di,breakdown, (RD5.1MB2(512))	4.97 to 5.24V,200mW	
Q 3	Di,breakdown, (RD5.1MB2(512))	4.97 to 5.24V,200mW	
Q 4	Di,breakdown,	3.7 to 4.1V,200mW	
Q 5 Q 6	(RD3.9MB(39 )) Tr,(2SC2585) Tr,(FJ451LE)		

١:	Manufactur	er's part number	34W93333	1/2	
5)					

: Selected at factory Parts List: A1-A10, SAMPLER

10

REF

CKT

REF

Q 7

Q B

R 1 R 2 R 3 R 4 R 5

R 11 R 12 R 13 R 14 R 15

R 16 R 17 R 18 R 19 R 20

DESCRIPTION

Di,breakdown, (RD6.2MB2(622)) Tr,(2SC2585)

CM, (RM73B2B4R7JD) CM, (RM73B2B151JD) CM, (RM73B2B102JD) CM, (RM73B2B101JD) CM, (RM73B2B121JD)

CM, (RM73B2B470JD) CM, (RM73B2B220JD) CM, (RM73B2B750JD) CM, (RM73B2B101JD) CM, (RM73B2B101JD)

CM, (RM73B2B180JD) CM, (RM73B2B271JD) CM, (RM73B2B271JD) CM, (RM73B2B271JD) CM, (RM73B2B510JD) CM, (RM73B2B220JD)

CM, (RM73B2B391JD) CM, (RM73B2B562JD) CM, (RM73B2B510JD) CM, (RM73B2B510JD) CM, (RM73B2B510JD)

CM, (RM73B2B101JD) CM, (RM73B2B101JD) CM, (RM73B2B331JD)

CKT REF	DESCRIPTION	RATING		NOTE
C 1 C 2	Cer, (CC732CJ1H030C(M0)) Cer, (CC732CJ1H030C(M0))	3pF,±0.25pF,50V 3pF,±0.25pF,50V	1	
Q 1 Q 2	Di,(1SS13RM) Di,(1SS13RM)			
R 1 R 2	CM, (RM73B2B101JD) CM, (RM73B2B101JD)	100Ω,±5%,1/BW 100Ω,±5%,1/BW		
w 3	Semi-rigid cable, (34J92579)			

( ): Manufacturer's part number 34W93334 1/1 : Selected at factory

Cer,(CC732CH1H100D(A1)) 10pF,:0.5pF,50V Cer,(CC732CH1H100D(A1)) 10pF,:0.5pF,50V Cer,(CC732CH1H221J(JZ)) 220pF,:55,50V Elect,(CE04C1E221A) 220pF,:20%,25V Cer,(CK733F1H104Z(A5)) 0.1µF,+80/-20%,50V

( ): Manufacturer's part number

Parts List: A1-A12, 2ND LO PLL

RATING

: Selected at factory

DESCRIPTION

Cer,(CC732CH1H221J(J2)) 220pF,:5%,50V Cer,(CK732B1H102K(A3)) 1000pF,:10%,50V Cer,(CK732B1H102K(A3)) 1000pF,:10%,50V Cer,(CK732B1H102K(A3)) 1000pF,:10%,50V Cer,(CC732CJ1H030C(M0)) 3pF,:0:25pF,50V C 6 C 7 C 8 C 9 C 10 Not assigned Not assigned Cer, (CC45CJ1H030CY) Cer, (CC45CJ1H030CY) Cer, (CK733F1H104Z(A5)) Oliuf,+80/-20%,50V C 11 C 12 C 13 C 14 C 15 C 16 C 17 C 18 C 19 C 20 Cer,(CC732CH1H271J(L2))
Cer,(CC732CH1H271J(L2))
Cer,(CC732CH1H270J(J1))
Cer,(CC732CH1H221J(J2))
Cer,(CC732CH1H221J(J2)) 270pF, ±5%,50V 270pF, ±5%,50V 22pF, ±5%,50V 220pF, ±5%,50V 220pF, ±5%,50V Cer, (CC732CH1H221J(J2)) Cer, (CC732CH1H221J(J2)) Cer, (CK732B1H472K(S3)) Cer, (CK734B1H104K(1A5)) Tant, (CS732E1V105M) 220pF, ±5%,50V 220pF, ±5%,50V 4700pF, ±10%,50V 0.1µF, ±10%,50V 1µF, ±20%,35V C 21 C 22 C 23 C 24 C 25 Not assigned Elect, (CE04C1E101A) Elect, (CE04C1E101A) Elect, (CE04C1E101A) Cer, (CK732B1H103K(A4)) C 26 C 27 C 28 C 29 C 30 100µF, ±20%,25V 100µF, ±20%,25V 100µF, ±20%,25V 0.01µF, ±10%,50V Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4)) Cer, (CK732B1H102K(A3)) Cer, (CK732B1H102K(A3)) Cer, (CK732B1H103K(A4)) 0.01µF, ±10%,50V 0.01µF, ±10%,50V 1000pF, ±10%,50V 1000pF, ±10%,50V 0.01µF, ±10%,50V C 31 C 32 C 33 C 34 C 35 Cer,(CK732B1H103K(A4)) Cer,(CK732B1H103K(A4)) Cer,(CK732B1H102K(A3)) Cer,(CK732B1H102K(A3)) Cer,(CC732CH1H080D(t0)) 0.01µF,±10%,50V 0.01µF,±10%,50V 1000pF,±10%,50V 1000pF,±10%,50V 8pF,±0.5pF,50V C 36 C 37 C 38 C 39 C 40 Elect, (CE04C1E101A) Elect, (CE04C1E101A) 100µF, ±20%, 25V 100µF, ±20%, 25V Connector, (008261-024200-870)

( ): Manufacturer's part number

: Selected at factory

34W93335 1/3

34W93333 2/2

NOTE

CKT				
REF	DESCRIPTION	RATING	NOTE	
J 2	Connector,			
	(008261-033311-852)		1	
J 3	Receptacle, (FL-R-PC(2))			
		ľ		
L 1	Coil		Printed	
<b>,</b>			pattern	
L 2	Coil		Printed pattern	
L 3	Coil, (ELF1010SKI-102K)	1mH	1	
L 4	Not assigned			
L 5	Coil, (ELF1010SKI-102K)	1mH		
Q 1	Di,breakdown,	6.0 to 6.39V,200mW		
ļ	(RD6.2MB2(622))			
Q 2 Q 3	Tr,(2SC2351(R2 OR R3)) Di,(1SS97)			
Q 4	Tr, (2SC2351 (R2 OR R3))			
Q 5	Tr,(2SC2351(R2 OR R3))			
Q 6	Di,(1SV107)	ļ		
Q 7	Di,(18899) Di,(18899)			
0 9	Di, (µPC4570C)			
Q 10	Di,breakdown,	6.0 to 6.39V,200mW		
, , ,	(RD6.2MB2(622))			
Q 11 Q 12	Tr,(2SC2351(R2 OR R3)) Di,breakdown,	6.0 to 6.39V,200mW		
"	(RD6.2MB2(622))			
Q 13	Tr, (2SC2351 (R2 OR R3))		1	
R 1 R 2	CM, (RM73B2B470JD) CM, (RM73B2B331JD)	47Ω,±5%,1/8W 330Ω,±5%,1/8W		
R 3	CM, (RM73B2B331JD)	330Ω, ±5%, 1/8W		
R 4	CM, (RM73B2B220JD)	22Ω, ±5%, 1/8W		
R 5	CM, (RM73B2B121JD)	120Ω,±5%,1/8W		
R 6	CM, (RM73B2B100JD)	10Ω,±5%,1/8W 51Ω,±5%,1/8W		
R 7	CM, (RM73B2B510JD) CM, (RM73B2B472JD)	5111,±5%,1/8W 4.7kΩ,±5%,1/8W		
R 9	Not assigned	7.		
R 10	Not assigned			
R 11	Not assigned	2 220 .50 1/00		
R 12	CM, (RM73B2B222JD) CM, (RM73B2B222JD)	2.2kΩ,±5%,1/8W 2.2kΩ,±5%,1/8W		
R 14	CM, (RM73B2B154JD)	150kΩ, ±5%, 1/8W		
R 15	CM, (RM73B2B154JD)	150kil, ±5%,1/8W		

CKT	, DESCRIPTION	RATING	NOTE
		5500 -50 3700	
R 16	CM, (RM73B2B561JD)	560Ω,±5%,1/8W	
R 17	CM, (RM73B2B561JD)	560Ω,±5%,1/8W	
R 18	CM, (RM73B2B561JD)	560Ω,±5%,1/BW	
R 19	CM, (RM73B2B561JD)	560Ω,±5%,1/8W	
R 20	Var,MF, (RJ-6P 50KΩ)	50kΩ,1/2W	
R 21	Var,MF, (RJ-6P 10KΩ)	10kΩ,1/2W	
R 22	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
R 23	CM, (RM73B2B392JD)	3.9kΩ,±5%,1/8W	
R 24	CM, (RM73B2B222JD)	2.2kΩ,±5%,1/8W	
R 25	CM, (RM73B2B104JD)	100kΩ,±5%,1/8W	
R 26	CM, (RM73B2B154JD)	150kΩ, ±5%, 1/8W	
R 27	CM, (RM73B2B153JD)	15kΩ,±5%,1/8W	
R 28	CM, (RM73B2B221JD)	220Ω, ±5%, 1/8W	
R 29	CM, (RM73B2B151JD)	150Ω,±5%,1/8W	
R 30	CM, (RM73B2B151JD)	150Ω,±5%,1/8W	
1 ~ 30	CH, (MI/3BZBI32BB)	13011,130,1,04	
R 31	CM, (RM73B2B330JD)	33Ω,±5%,1/8W	[
R 32	Var,MF, (RJ-6P 100Ω)	1000,1/2W	1
R 33	CM, (RM73B2B151JD)	150Ω,±5%,1/8W	
R 34	CM, (RM73B2B330JD)	33Ω,±5%,1/8W	
R 35	CM, (RM73B2B271JD)	270Ω,±5%,1/8W	
R 36	CM, (RM73B2B220JD)	22Ω,±5%,1/8W	
R 37	CM, (RM73B2B330JD)	33Ω,±5%,1/8W	1
R 38	CM, (RM73B2B221JD)	220Ω,±5%,1/8W	1
R 39	CM, (RM73B2B330JD)	33Ω,±5%,1/8W	
R 40	CM, (RM73B2B271JD)	270Ω,±5%,1/8W	
R 41	CM, (RM73B2B220JD)	22Ω,15%,1/8W	
R 42	CM, (RM73B2B330JD)	33Ω.±5%.1/8W	
R 43	CM, (RM73B2B221JD)	220Ω, 15%, 1/8W	
R 44	CM, (RM73B2B151JD)	150Ω, ±5%, 1/8W	
R 45	CM, (RM73B2B390JD)	390.±5%,1/8W	
` '	CA, (Idi) 3525390057	394,130,170	ľ
R 46	CM, (RM73B2B151JD)	150Ω,±5%,1/8W	
	1		
l			
T 1	Trans, (342T60521B)		
	4-47		
2 1	BPF, (AKW-50M)	50MHz	34292892
2 2	BPF, (AKW-50M)	50MHz	34292892

DESCRIPTION

34W93335 2/3

12

NOTE

( ): Manufacturer's part number

\* : Selected at factory

34W93335 3/3

Parts List: A1-A13, 50K/50M STEP SYNTHE

RATING

		Elect, (CEO4C1ElO1A)	100µF, ±20%,25V		
	C 1		100µF, ±20%,10V		
	C 2	Elect, (CE04ClA101A)	47µF, ±20%, 25V		
	C 3	Elect, (CE04C1E470A)		1	
1	C 4	Elect, (CEO4ClA471A)	470µF, ±20%, 10V		
	C 5	Elect, (CE04ClA47lA)	470µF,±20%,10V		
	C 6	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V		
	C 7	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V		
	C 8	Cer, (CC732CH1H101J(A2))			
	C 9	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	í	
	C 10	Cer, (CK732B1H103K(A4))	0.01µF, :10%,50V		
		001, (11			
	C 11	Cer, (CK732B1H103K(A4))	0.01µF,:10%,50V		
	C 12	Cer, (CK732B1H102K(A3))	1000pF, ±10%, 50V	1	
	C 13	Cer, (CK732B1H103K(A4))	0.01µF,:10%,50V		
			0.01µF, 110%,50V		
	C 14	Cer, (CK732B1H103K(A4))	0.1µF,+80/-20%,50V		
	C 15	Cer, (CK733F1H104Z(A5))	U.1µF,+8U/-2U8,3UV	l	
			a 01 E 100 FOU	1	
	C 16	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V		
	C 17	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V		
	C 18	Tant, (CS734E1C226M)	22µF, ±20%,16V		
	C 19	Tant, (CS734E1C226M)	22µF,±20%,16V	,	
	C 20	Plast, (ECQ-VIH334JW)	0.33µF,±5%,50V		
	C 21	Plast, (ECQ-V1H334JW)	0.33µF,±5%,50V		
	C 22	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V		Į.
	C 23	Not assigned		Į	l
	C 24	Cer, (CK73281H103K(A4))	0.01µF, +10%,50V		
	C 25	Cer, (CK732B1H103K(A4))	0.01µF, 10%, 50V		
	l -				
	C 26	Cer, (CK732B1H102K(A3))	1000pF, :10%,50V		
	C 27	Cer, (CK732B1H102K(A3))	1000pF, 10%,50V		ì
	C 28	Cer, (CK73281H102K(A3))	1000pF,:10%,50V		
	C 29	Cer, (CK732B1H102K(A3))	1000pF, . 10%, 50V	ì	
	C 10	Cer, (CK732B1H102K(AJ))	1000pr, 10%,50V		
	I " '"			1	1
	C 31	Tant, (CS734E1C226M)	22ur. •20%,16V		
	0 32	Cer, (CC732CH1H331J (N2))			Į.
		Tant , (CS734E1C226M)	22uF. 208,16V	l	
	C 33	Cer, (CK732B111103K(A4))	0.01pr, 10%,50V	1	
	C 34		1000pF, 10%,50V		
	C 35	Cor, (CK732B131302K(A3))	1000br, 10k, 30v		
	l		0 01 11 . 100 600	1	1
	C. 36	Cer, (CK732B1H103K(A4))	0.01µF, +10%,50V	ſ	{
	C 37	Cor, (CK732B1H103K(A4))	0.01ar, 10%,50V	Į.	ĺ
	C 38	Cor, (CK732H1H103K(A4))	0.01pF, -10%,50V		l
	C 39	Cer, (CK732B1H103K(A4))	0.01nF, 10%,50V		l
	C 40	Cer, (CK/1/BIH102K(A4))	1000pF,+10%,50V		l
	1	1		1	I

Parts List: A1-A13, 50K/50M STEP SYNTHE

CKT REF	DESCRIPTION	RATING	NOTE
C 4B	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 49	Cer, (CK924F1H104Z)	0.1µF,+80/-20%,50V	
C 50	Cer, (CK924F1H104Z)	0.1µF,+80/-20%,50V	i
C 51	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 52	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 53	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 54	Cer, (CK732B1H103K(A4))	0.01µF,:10%,50V	
C 55	Cer, (CK732B1H102K(A3))	1000pF, ±10%,50V	
C 56	Cer, (CK732B1H102K(A3))	1000pF, ±10%,50V	
C 57	Cer, (CK733F1H1042(A5))	0.1µF,+80/-20%,50V	
C 58	Tant, (CS734E1C226M)	22µF,±20%,16V	1
C 59	Tant, (CS734E1C226M)	22µF, ±20%, 16V	
C 60	Cer, (CK733F1H1042(A5))	0.1µF,+80/-20%,50V	
C 61	Cer, (CK733F1H1042(A5))	0.1µF,+80/-20%,50V	
C 62	Cer, (CC732CH1H101J(A2))		
C 62	Cer, (cc /32cminiois (A2))	100pr, 134,304	
C 63	Cer, (CK732B1H102K(A3))	1000pF,±10%,50V	
C 64	Cer,(CK732B1H102K(A3))	1000pF,±10%,50V	1
C 65	Cer, (CK732B1H102K(A3))	1000pF,:10%,50V	
C 66	Cer, (CK732B1H102K(A3))	1000pF, ±10%,50V	
C 67	Cer, (CK732B1H102K(A3))	1000pF, ±10%,50V	
C 68	Elect, (CE04C1H220A)	22µF,±20%,50V	1
C 69	Cer, (CC732CH1H180J(G1))		Q'ty 2
C 70	Not assigned		
C 71	Not assigned	1	
C 72	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 73	21 (CD04G1#2201)	22µF, ±20%,50V	
	£lect, (CE04C1H220A)	0.1µF,+80/-20%,50V	
C 74	Cer, (CK7)3F1H104Z(A5))		
C 75	Cer, (CK733F1H1042(A5))	0.1µF,+80/-20%,50V	
C 76	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 77	Cer, (CK733F1H1042(A5))	0.1µF,+80/-20%,50V	
C 78	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	1
C 79	Cer, (CC732CH1H331J(N2))	330pF, ±5%,50V	
C 80	Cer, (CC732CH1H101J(A2))	100pF, ±5%, 50V	
C 81	Cer, (CC7)2CH1H470J(S1))	47pF,±5%,50V	
C 82	Var, Cer, (TZ03T110A)	11pF,100V	
C 83	Cer, (CK732B1H223K)	0.022µF,±10%,50V	
C 84	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 85	Cer, (CK732B1H103K(A4))	0.01µF, ±10%,50V	
C 86	Cer, (CK732B1H102K(A3))	1000pF,±10%,50V	
C 87	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 88	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 89	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	i
		0.01µF, ±10%,50V	
C 90	Cer, (CK732B1H103K(A4))		
C 91	Cer, (CK732B1H102K(A3))	1000pF, ±10%,50V	
C 92	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 93	Elect, (CEU4C1E470A)	47µF, 120%, 25V	
C 94	Cer, (CK733F1H104Z(AS))	0.1µF,+80/-20%,50V	
C 95	Elect, (CEO4C1E470A)	47µF, ±20%, 25V	

( ): Manufacturer's part number

• : Selected at factory

Cer, (CK7)3F1HL04X(A5)) 0.4pF,+807-20%,50V Cer, (CK7)2HLH103K(A4)) 0.01pF,+10%,50V

C 41 Cer, (CK712B1H101K(A4)) 0.01mF, +10%, 50V 100mF, -20%, 16V 100mF, -20%, 50V 100mF, -20

14W93336 1/9

( ): Manufacturer's part number

\* : Selected at factory

34W93336 2/9

2pins

3pins

15pins

10pins 3pins 3pins

3.3µH 47µH 10µH 10mH 43nH

22μΗ 47μΗ 22μΗ 22μΗ 6.8μΗ

118nH 0.68µH 1mH 22µH 0.68µH

0.68µH 0.22µH

RATING

NOTE

With socket

34W93336 4/9

DESCRIPTION

Connector, (008261-024200-870)

Connector, (008261-033311-852) Connector,(U-PA1521)

Coil, (NL453232-3R3K) Coil, (NL453232-470K) Coil, (NL453232-100K) Coil, (ELF0708SKI-103K) Coil, (E526HN-100116)

J 10 | Connector (U-PA1021) | J 11 | Plug, (DF1-3P-2.5DSA) | J 12 | Not assigned | Plug, (DF1-3P-2.5DSA) | J 14 | Not assigned

L 6 Coil, (LF8-220K) L 7 Coil, (LF8-470K) L 8 Coil, (NL453232-220K) L 9 Coil, (NL453232-220K) L 10 Coil, (NL453232-6R8K)

L 11 Coil, (E526HN-100118) L 12 Coil, (NL322522-R68K) L 13 Coil, (NL453232-102K) L 14 Coil, (NL453232-220K) L 15 Coil, (NL453232-220K)

L 16 Coil, (NL322522-R68K) L 17 Coil, (NL322522-R22K)

Q 3 Tr,(2SC1623(L5 OR L6))
Q 4 Not assigned

Q 1 IC, (74196) Q 2 IC, (MC4044P)

Q 5 IC, (µPC4570C) Q 6 IC, (AD7533LN) Q 7 IC, (TC74HC574F) Q 8 IC, (TC74HC574F) Q 9 IC, (TC74HC574F)

CKT	DESCRIPTION:	2.500	1
REF	DESCRIPTION	RATING	NOTE
C 96 C 97 C 98 C 99 C100 C101 C102 C103	Cer, (CK733F1H104Z (A5)) Cer, (CC732CH1H390J(Q1)) Cer, (CC732CH1H390J(Q1)) Cer, (CK733F1H104Z (A5)) Tant, (CS734E1C226M) Cer, (CK732B1H102K(A3)) Plast, (ECQ-V1H105JW) Cer, (CK733F1H104Z (A5))	0.1µF,+80/-20%,50V 39pF,+5%,50V 39pF,+5%,50V 0.1µF,+80/-20%,50V 22µF,+20%,16V 1000pF,±10%,50V 1µF,±5%,50V 0.1µF,80/-20%,50V	
C104 C105 C106 C107 C108	Cer, (CK732B1H102K(A3)) Cer, (CK732B1H222K(J3)) Cer, (CK732B1H222K(J3)) Tant, (CS734E1C226M) Tant, (CS734E1C226M)	1000pF, ±10%, 50V 2200pF, ±10%, 50V 2200pF, ±10%, 50V 22µF, ±20%, 16V 22µF, ±20%, 16V	
C109 C110 C111 C112 C113	Tant, (CS734E1C226M) Tant, (CS734E1C226M) Cer, (CK733F1H104Z(A5)) Not assigned Cer, (CC732CH1H101J(A2))	22µF, ±20%,16V 22µF, ±20%,16V 0.1µF, +80/-20%,50V 100pF, ±5%,50V	
C114 C115 C116 C117	Not assigned Not assigned Cer,(CK733F1H104Z(A5)) Tant,(CS734E1C226M)	0.1μF,+80/-20%,50V 22μF,±20%,16V	
C118 C119 C120 C121 C122	Elect, (CE04C1E470A) Not assigned Cer, (CC732CH1H101J(A2)) Cer, (CC732CH1H101J(A2)) Cer, (CC732CH1H151J(E2))	47μF,:20%,25V 100pF,:5%,50V 100pF,:5%,50V 150pF,:5%,50V	
C122 C123 C124 C125	Cer,(CC732CH1H151J(E2)) Cer,(CC732CH1H151J(E2)) Cer,(CC732CH1H471J(S2)) Cer,(CC732CH1H471J(S2)) Cer,(CC732CH1H820J(Y1))	150pF, 15%,50V 470pF, 15%,50V 470pF, 15%,50V	
C127 C128 C129 C130	Cer, (CC732CH1H820J(Y1)) Tant, (CS734E1C226M) Tant, (CS734E1C226M) Tant, (CS734E1C226M)	82pF,±5%,50V 22uF,±20%,16V 22uF,±20%,16V 22uF,±20%,16V	
J 1	Cer,(CK733F1H104Z(A5))  Receptacle,(FL-R-PC(A))	0.1µF,+80/-20%,50V	
J 2 J 3 J 4 J 5	Connector, (27DP-R-PC-1) Receptacle, (FL-R-PC(A)) Connector, (27DP-R-PC-1) Connector, (008261-024200-870)	2pins	
J 6	Connector, (008261-033311-852)	3pins	

34W9333

* : Selected at factory				3445	
Parts	List:	A1-A13,	50K/50M	STEP	SYNTHE

CKT REF	DESCRIPTION	RATING	NOTE
Q 13 Q 14 Q 15 Q 16 Q 17	Di,(1SS97) Di,(1SS97) IC,(µPB571C) IC,(74F191PC) IC,(74F191PC)		
Q 18 Q 19 Q 20 Q 21 Q 22	IC,(74F191PC) IC,(74F191PC) IC,(TC74HC00F) IC,(74F00PC) IC,(74F00PC)		
Q 23 Q 24 Q 25 Q 26 Q 27	IC,(µPC4570C) Di,vari-cap,(1SV50) FET,(2SK55E) FET,(2SK55E) FET,(2SK55E)		
Q 28 Q 29 Q 30	Di,breakdown, {RD5.1MB2(512)} Tr,(2SC2351(R2 OR R3)) Di,breakdown, (RD5.1MB2(512)}	4.97 to 5.24V,200mW 4.97 to 5.24V,200mW	
Q 31 Q 32 Q 33 Q 34 Q 35	Tr,(2SC2351(R2 OR R3)) IC,(11C90DC) IC,(TC74HC574F) IC,(TC4051BP) IC,(74F191PC)		
Q 36 Q 37 Q 38 Q 39 Q 40	IC, (74F191PC) IC, (74F191PC) IC, (MC4044P) IC, (74196) Di, breakdown, (RD5.1MB2(512))	4.97 to 5.24V,200mW	
Q 41 Q 42 Q 43 Q 44	Tr, (2SC3735(B34 OR B35)) IC, (74F00PC) IC, (74F00PC) LED, (TLR226)		
Q 45 Q 46 Q 47 Q 48	IC, (µPC4570C) Di,breakdown, (RD6.2MB2(622)) IC, (µPC4570C) Di,vari-cap,(1SV50)	6.0 to 6.39V,200mW	
Q 49 Q 50 Q 51 Q 52 Q 53	D1, breakdown, (18252) FET, (28K55E) FET, (28K55E) FET, (28K55E) D1, breakdown, (RD5.1MB2(512))	5.9 to 6.5V 250mW	

( ): Manufacturer's part number

\* : Selected at factory

36 3/9	1	):	Manufacturer's part number
	٠	:	Selected at factory

Q 10 LED,(TLR226)
Di,breakdown,
(RD5.1MB2(512))
Q 12 Tr,(2SC2351(R2 OR R3))

CKT REF

J 7

J B

J 9

L 1 L 2 L 3 L 4 L 5

4.97 to 5.24V,200mW

	Parts List: Al	-A13, 50K/50M STEP SY	INTHE
CKT REF	DESCRIPTION	RATING	NOTE
Q 54 Q 55 Q 56	Tr, (2SC3735(B34 OR B35)) Di,breakdown, (RD5.1MB2(512)) Tr,(2SC2351(R2 OR R3))	4.97 to 5.24V,200mW	
Q 57 Q 58 Q 59	Di,breakdown, (RD5.1MB2(512)) Tr,(2SC2351(R2 OR R3)) Di,breakdown, (RD7.5MB2(752))	4.97 to 5.24V,200mW	
Q 60 Q 61 Q 62 Q 63 Q 64 Q 65	Di,breakdown, (RD6.2MB2(622)) Di,(18597) Not assigned Tr,(2SA812(M5 OR M6)) Not assigned Not assigned	6.0 to 6.39V,200mW	
R 1 R 2 R 3 R 4 R 5 R 6 R 7 R 8 R 9 R 10	Not assigned Not assigned Not assigned CM, (RM73828102JD) CM, (RM73828102JD) CM, (RM73828102JD) CM, (RM7382831JD) CM, (RM73828102JD) SIL type, (RRS-4-104JA) SIL type, (RRS-6-104JA)	1.0kû,:5%,1/8W 1.0kû,:5%,1/8W 1.0kû,:5%,1/8W 330û,:5%,1/8W 1.0kû,:5%,1/8W 1.0kû x 4,:5%,1/8W 3.3kû,:5%,1/8W	
R 11 R 12 R 13 R 14 R 15	CM, (RM73B2B332JD) CM, (RM73B2B104JD) CM, (RM73B2B104JD) CM, (RM73B2B820JD) CM, (RM73B2B820JD) CM, (RM73B2B331JD) CM, (RM73B2B100JD)	3.3kn,±5%,1/8W 100kn,±5%,1/8W 100kn,±5%,1/8W 62n,±5%,1/8W 330n,±5%,1/8W	
R 17 R 18 R 19 R 20	CM, (RM73B2B471JD) CM, (RM73B2B470JD) MF, (RE35-YP-243Ω-B) MF, (RE35-YP-243Ω-B) CM, (RM73B2B100JD)	470Ω,±5%,1/8W 47Ω,±5%,1/8W 243Ω,±0.1%,1/8W 243Ω,±0.1%,1/8W 10Ω,±5%,1/8W	
R 22 R 23 R 24 R 25 R 26	CM, (RM73B2B222JD) MF, (RE35-YP-025N-B) MF, (RE35-YP-825N-B) MF, (RE35-YP-1.00KN-B) CM, (RM73B2B100JD)	2.2kΩ,±5%,1/8W 825Ω,±0.1%,1/8W 825Ω,±0.1%,1/8W 1.00kΩ,±0.1%,1/8W 10Ω,±5%,1/8W	
R 27	MF, (RE35-YP-825Ω-B)	825Ω,±0.1%,1/8W	

( ): Manufacturer's part number

\* : Selected at factory

34W93336 6/9

34W93336 5/9

СКТ			
REF	DESCRIPTION	RATING	NOTE
R 28	MF, (RE35-YP-2.15KΩ-B)	2.15kΩ,±0.1%,1/8W	
R 29	MF, (RE35-YP-1.50KΩ-B)	1.50kΩ,±0.1%,1/8W	
R 30	Var,MF, (RJ-6P 200Ω)	200Ω,1/2W	
R 31	MF, (RE35-YP-825Ω-B)	825Ω,±0.1%,1/8W	
R 32	MF, (RE35-YP-301Ω-B)	301Ω,±0.1%,1/8W	
R 33	MF, (RE35-YP-1.00KΩ-B)	1.00kΩ,±0.1%,1/8W	
R 34	CM, (RM73B2B562JD)	5.6kΩ,±5%,1/8W	
R 35	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
R 36	CM, (RM73B2B272JD)	2.7kΩ,±5%,1/8W	
R 37	CM, (RM73B2B122JD)	1.2kΩ,±5%,1/8W	
R 38	CM, (RM73B2B332JD)	3.3kΩ,±5%,1/8W	
R 39	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
R 40	CM, (RM73B2B562JD)	5.6kΩ,±5%,1/8W	
R 41	CM, (RM73B2B821JD)	8200,±58,1/8W	
R 42	CM, (RM73B2B100JD)	10Ω,±5%,1/8W	1
R 43	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	1
R 44	CM. (RM73B2B222JD)	2.2kΩ,±5%,1/8W	
R 45	CM, (RM73B2B820JD)	82Ω, ±5%, 1/8W	
R 46	CM, (RM73B2B331JD)	330Ω,±5%,1/8W	
R 47	CM, (RM73B2B270JD)	27Ω, ±5%, 1/8W	
" "	C., (144, 35252, 405)	1,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	
R 48	CM, (RM73B2B471JD)	470Ω,±5%,1/8W	
R 49	CM, (RM73B2B221JD)	220n,±5%,1/8W	
R 50	CM, (RM73B2B221JD)	220Ω,±5%,1/8W	
R 51	CM, (RM73B2B471JD)	470Ω, ±5%, 1/8W	
R 52	CM, (RM73B2B331JD)	330Ω,±5%,1/8W	
R 53	CM, (RM73B2B820JD)	820,±5%,1/8W	
R 54	CM, (RM73B2B151JD)	1500,±5%,1/8W	
R 55	CM, (RM73B2B560JD)	560,±5%,1/8W	
R 56	CM, (RM73B2B681JD)	680Ω,±5%,1/8W	
R 57	CM, (RM73B2B681JD)	680Ω,±5%,1/8W	
R 58	SIL type, (RRS-4-104JA)	100kΩ × 4,±5%,1/8W	
R 59	SIL type, (RRS-6-104JA)	100kΩ x 6,±5%,1/8W	
R 60	CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8₩	
R 61	CM, (RM73B2B271JD)	270Ω,±5%,1/8W	
R 62	CM. (RM73B2B102JD)	1.0kΩ,±5%,1/8W	
" "-			
R 63	CM, (RM73B2B390JD)	39Ω,±5%,1/8W	
R 64	CF, (ARD25T271J)	270Ω,±5%,1/4W	
R 65	CM, (RM73B2B221JD)	220Ω,±5%,1/8W	
R 66	CM, (RM73B2B470JD)	47Ω,±5%,1/8W	
R 67	MF, (RE35-YP-42.2KΩ-B)	42.2kΩ,±0.1%,1/8W	
	l	40.010.010.1	
R 68	MF, (RE35-YP-42.2KΩ-B)	42.2kΩ,±0.1%,1/8W	1.
R 69 R 70	Not assigned	3.24kΩ,±0.1%,1/8W	
R 71	MF, (RE35-YP-3.24KΩ-B)	J. 24AH, IU. 18, 1/0#	
R 72	Not assigned MF, (RE35-YP-3.24KΩ-B)	3.24kΩ,±0.1%,1/8W	
K /2	ME , (RESS-IP-S.24AW-B)	J. 24Kn, IU. 18,1/0#	
R 73	CM, (RM73B2B100JD)	10Ω,±5%,1/8W	
R 74	CM. (RM73B2B100JD)	10Ω,±5%,1/8W	
" ' '	1		

CKT	DESCRIPTION	PATING	NOTE
REF	DESCRIPTION	RATING	NOTE
R 75	MF, (RE35-YP-3.24KΩ-B)	3.24kΩ,±0.1%,1/8W	
R 76	MF, (RE35-YP-8.25KΩ-B)	8.25kΩ,±0.1%,1/8W	
R 77	MF, (RE35-YP-6.98KΩ-B)	6.98kΩ,±0.1%,1/8W	
R 78	MF, (RE35-YP-3.24KΩ-B)	3.24kΩ,±0.1%,1/8W	
R 79	CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8W	
R 80	CM, (RM73B2B681JD)	680Ω,±5%,1/8W	
R 81	CM, (RM73B2B562JD)	5.6kΩ, ±5%,1/8W	
R 82	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
R 83	CM, (RM73B2B272JD)	2.7kΩ, ±5%,1/8W	
R 84	CM, (RM73B2B122JD)	1.2kΩ,±5%,1/8W	
R 85	CM, (RM73B2B332JD)	3.3kΩ,±5%,1/8W	1
R 86	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	- 1
R 87	CM, (RM73B2B562JD)	5.6kΩ,±5%,1/8W	- 1
R 88	CM, (RM73B2B821JD)	820Ω, ±5%, 1/8W	
R 89	CM, (RM73B2B100JD)	10Ω,±5%,1/8W	
R 90	CM, (RM73B2B330JD)	33Ω, ±5%, 1/8W	
R 91	CM, (RM73B2B271JD)	270Ω,±5%,1/8W	
R 92	CM, (RM73B2B820JD)	82Ω,±5%,1/8W	- 1
R 93	CM, (RM73B2B331JD)	330Ω,±5%,1/8W	
R 94	CM, (RM73B2B151JD)	150Ω, ±5%, 1/8W	
R 95	CM, (RM73B2B750JD)	75Ω,±5%,1/8W	
R 96	CM, (RM73B2B750JD)	75Ω,±5%,1/8W	
R 97	CM, (RM73B2B220JD)	22Ω,±5%,1/8W	
R 98	CM, (RM73B2B390JD)	39Ω,±5%,1/8W	
R 99	CF, (ARD25T271J)	270Ω,±5%,1/4W	
R100	CM, (RM73B2B681JD)	680Ω,±5%,1/8W	
R101	CM, (RM73B2B221JD)	220Ω,±5%,1/8W	
R102	CM, (RM73B2B221JD)	220Ω, ±5%,1/8W	
R103	CM, (RM73B2B331JD)	330Ω,±5%,1/8W	
R104	CF, (ARD25T221J)	220Ω,±5%,1/4W	
	(	000 . 50 1 /00	
R105	CM, (RM73B2B820JD)	82Ω,±5%,1/8W	
R106	CM, (RM73B2B151JD)	150Ω,±5%,1/8W	
R107	CM, (RM73B2B220JD)	22Ω,±5%,1/8W	
R108	CM, (RM73B2B390JD)	39Ω,±5%,1/8W	
R109	CM, (RM73B2B221JD)	220Ω,±5%,1/8W	
2110	GW (PW73P3P3P17D)	3000 -54 1/84	
R110	CM, (RM73B2B391JD)	390Ω,±5%,1/8W	
R111	CM, (RM73B2B510JD)	510,±5%,1/8W	
R112	MF, (RE35-YP-499Ω-B)	499Ω,±0.1%,1/8W	
R113	MF, (RE35-YP-143Ω-B)	143Ω,±0.1%,1/8W	
R114	MF, (RE35-YP-196Ω-B)	196Ω,±0.1%,1/8W	
R115	MF, (RE35-YP-243Ω-B)	243Ω,±0.1%,1/8W	
R116	MF, (RE35-YP-4990-B)	499Ω,±0.1%,1/8W	
R117	MF, (RE35-YP-1.00KΩ-B)	1.00kΩ,±0.1%,1/8W	
R118	MF, (RE35-YP-1.00KΩ-B)	1.00kΩ,±0.1%,1/8W	
R119	CM, (RM73B2B821JD)	8200,±5%,1/8W	
,,,,	011, (141, 352, 562, 762, 762, 762, 762, 762, 762, 762, 7	,,	
R120	CM, (RM73B2B102JD)	1.00kΩ,±5%,1/8W	
R121	CM, (RM73B2B102JD)	1.00kΩ,±5%,1/8W	
	,		1

34W93336 7/9

( ): Manufacturer's part number
\* : Selected at factory

Parts List: Al-Al4, PULSE AMP

34W93336 8/9

Parts List: A1-A13, 50k/50M STEP SYNTHE

CKT REF	DESCRIPTION	RATING	NOTE
R122 R123 R124 R125 R126	MF, (RN14X2E5110D) MF, (RN14K2E5110D) Not assigned Not assigned Not assigned	511Ω, ±0.5%,1/4W 511Ω,±0.5%,1/4W	
R127 R128 R129 R130 R131	Not assigned CM,(RM73B2B150JD) MF,(RN14K2E1000D) MF,(RN14K2E1000D) CM,(RM73B2B471JD)	15Ω,±5\$,1/8W 100Ω,±0.5\$,1/4W 100Ω,±0.5\$,1/4W 470Ω,±5\$,1/8W	
R132 R133 R134	MF, (RE35-YP-121Ω-B) MF, (RN14K2E5110D) MF, (RN14K2E5110D)	121Ω,±0.1%,1/8W 511Ω,±0.5%,1/4W 511Ω,±0.5%,1/4W	
z 1	Mixer, (M-8)		İ
		·	

DESCRIPTION RATING NOTE REF C 1 Not assigned C 2 Cer,(CK732B1H103K(A4)) C 3 Cer,(CK732B1H222K(J3)) C 4 Cer,(CK733F1H104Z(A5)) C 5 Cer,(CK732B1H103K(A4)) 0.01µF,±10%,50V 2200pF,±10%,50V 0.1µF,+80/-20%,50V 0.01µF,±10%,50V Cer, (CK732B1H222K(J3)) Cer, (CK732B1H222K(J3)) Cer, (CK732B1H222K(J3)) Cer, (CC732CH1H100D) Cer, (CK732B1H222K(J3)) 2200pF, ±10%,50V 2200pF, ±10%,50V 2200pF, ±10%,50V 10pF,±0.5%,50V 2200pF,±10%,50V C 6 C 7 C 8 C 9 C 10 Elect, (CE04C1E101A) Cer, (CK732B1H222K(J3)) C 11 C 12 100µF,±20%,25V 2200pF,±10%,50V 1 2 3 Di,breakdown, (RD5.1MB2(512)) Tr,(2SC2369) Di,(1S953) Tr,(2SC2369) Tr,(2SC2369) Q 1 4.97 to 5.24V,200mW Q 2 Q 3 Q 4 Q 5 Di,(15V107) 75Ω,±5%,1/8W 330Ω,±5%,1/8W 220Ω,±5%,1/4W 4.7Ω,±5%,1/8W 150Ω,±5%,1W CM, (RM73B2B750JD) CM, (RM73B2B33JJD) CF, (ARD25T221J) CM, (RM73B2B4R7JD) MF, (RS1FB150RJ) 1 2 3 4 5 MF, (RS1FB150ΩJ) CM, (RM73B2B101JD) CM, (RM73B2B101JD) CM, (RM73B2B472JD) 150Ω,±5%,1W 100Ω,±5%,1/8W 100Ω,±5%,1/8W 4.7kΩ,±5%,1/8W

( ): Manufacturer's part number

\* : Selected at factory

34W93336 9/9

( ): Manufacturer's part number

\* : Selected at factory

34W93337 1/1

CKT REF

DESCRIPTION

			14
REF	DESCRIPTION	RATING	NOTE
C 1 C 2 C 3 C 4 C 5	Not assigned Elect,(CE04Clv330A) Elect,(CE04Clv330A) Elect,(CE04Clv330A) Elect,(CE04Clv330A)	33µF,±20%,35V 33µF,±20%,35V 33µF,±20%,35V 33µF,±20%,35V	
C 6 C 7 C 8 C 9 C 10	Elect, (CE04C1V330A) Tant, (CS734E1C226M) Tant, (CS734E1C226M) Cer, (CK733F1H104Z(A5)) Cer, (CK733F1H104Z(A5))	33µF,±20%,35V 22µF,±20%,16V 22µF,±20%,16V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V	
C 11 C 12 C 13 C 14 C 15	Cer,(CK733F1H104Z(A5)) Tant,(CS734E1C226M) Cer,(CC732CH1H330J(N1)) Cer,(CC733F1H104Z(A5)) Cer,(CK733B1H473K(1S4))	0.1µF,+80/-20%,50V 22µF,±20%,16V 33pF,±5%,50V 0.1µF,+80/-20%,50V 0.047µF,±10%,50V	
C 16 C 17 C 18 C 19 C 20	Cer,(CK733B1H473K(1S4)) Cer,(CK733B1H473K(1S4)) Cer,(CK732B1H222K(J3)) Cer,(CK732B1H222K(J3)) Cer,(CK732B1H472K(S3)) Not assigned		
C 21 C 22 C 23 C 24 C 25	Tant, (CS734E1C226M) Tant, (CS734E1C226M) Tant, (CS734E1C226M) Plast, (ECQ-P1333F2) Cer, (CK733F1H104Z(A5))	22µF,±20%,16V 22µF,±20%,16V 22µF,±20%,16V 33000pF,100V 0.1µF,+80/-20%,50V	
C 26 C 27 C 28 C 29 C 30	Cer,(CK733F1H1042(A5)) Cer,(CK733B1H223K(JJ4)) Cer,(CK733F1H1042(A5)) Cer,(CK732B1H103K(A4)) Cer,(CK732B1H103K(A4))	0.1µF,+80/-20%,50V 0.022µF,±10%,50V 0.1µF,+80/-20%,50V 0.01µF,±10%,50V 0.01µF,±10%,50V	
C 31 C 32 C 33 C 34 C 35	Cer, (CK732B1H103K(A4)) Cer, (CK733F1H104Z(A5)) Cer, (CC733CH1H102J(A3)) Cer, (CC733CH1H102J(A3)) Cer, (CC733CH1H102J(A3))	0.01µF,±10%,50V 0.1µF,+80/-20%,50V 1000pF,±5%,50V 1000pF,±5%,50V 1000pF,±5%,50V	
C 36 C 37 to C 49 C 50	Cer,(CC732CH1H471J(S2)) Cer,(CK733F1H104Z(A5)) Not assigned	470pF,±5%,50V 0.1μF,+80/-20%,50V	
C 51 C 52 C 53 C 54 C 55	Cer,(CC732CH1H101J(A2)) Tant,(CS734E1C226M) Tant,(CS734E1C226M) Tant,(CS734E1C226M) Cer,(CC45CH1H220JY)	100pF, ±5%, 50V 22uF, ±20%, 16V 22uF, ±20%, 16V 22uF, ±20%, 16V 22pF, ±5%, 50V	
C 56 C 57	Cer, (CC450J1H060DY) Cer, (CX733F1H104Z(A5))	6pF,±0.5pF,50V 0.1µF,+80/-20%,50V	

( ): Manufacturer's part number

\* : Selected at factory

Parts List: A1-A15, 20HZ STEP VCO CONT

34W93338 1/6
--------------

REF			 
C 58 C 59 C 60 C 61 C 62	Tant, (CS734E1C226M) Tant, (CS734E1C226M) Cer, (CK733F1H104Z(A5)) Cer, (CK733F1H104Z(A5)) Cer, (CK733F1H104Z(A5)) Cer, (CK733F1H104Z(A5))	22µF,±20%,16V 22µF,±20%,16V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 4700pF,±10%,50V	
C 64 C 65 C 66 C 67	Cer, (CC732CH1H101J(A2)) Tant, (CS734E1C226M) Cer, (CK733F1H104Z(A5)) Cer, (CK732B1H472K(S3))	100pF, ±5%,50V 22µF, ±20%,16V 0.1µF,+80/-20%,50V 4700pF, ±10%,50V	
C 68 C 69 C 70 C 71 C 72	Cer,(CK732B1H472K(S3)) Cer,(CK732B1H222K(J3)) Cer,(CK733F1H104Z(A5)) Cer,(CK733F1H104Z(A5)) Cer,(CK733F1H104Z(A5))	4700pF,±10%,50V 2200pF,±10%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 68pF,±5%,50V	
C 73 C 74 C 75 C 76 C 77	Cer,(CC732CH1H560J(U1)) Cer,(CC732CH1H271J(L2)) Cer,(CC732CH1H471J(S2)) Cer,(CC732CH1H271J(L2)) Not assigned	270pF,±5%,50V 470pF,±5%,50V	
C 78	Not assigned		
J 1 J 2 J 3	Connector, (U-PA1521) Connector, (008261-024200-870) Connector, (008261-033311-852)		
J 4	Connector, (008261-024200-870)		
J 5	Connector, (008261-033311-852) Receptacle, (FL-R-PC(A))		
J 7	Receptacle,(FL-R-PC(A))		
L 1 L 2 L 3 L 4 L 5	Not assigned Coil,(LF8-220K) Coil,(LF8-220K) Coil,(NL453232-4R7K) Coil,(NL453232-4R7K)		
L 6 L 7 L 8 L 9 L 10	Coil, (LF8-101K) Coil, (339T20176F) Coil, (NL453232-470K) Coil, (LF8-101K) Coil, (ELF10105KI-472K)		

( ): Manufacturer's part number

\* : Selected at factory

34W93338 2/6

NOTE

NOTE

DESCRIPTION

Parts List: A1-A15, 20HZ STEP VCO CONT

RATING

	Parts List: A	1-A15, 20HZ STEP VCO CON	NT
CKT REF	DESCRIPTION	RATING	NOTE
L 11 L 12 L 13	Coil, (ELF10105KI-472K) Coil, (NL453232-1R0K) Coil, (NL453232-1R0K)		
Q 1 Q 2 Q 3 Q 4 Q 5	Di,breakdown,(18253) IC,(µPC4570C) IC,(TC74HC574F) IC,(TC74HC574F) IC,(AD7541AKN)	5.9 to 6.5V,250mW	
Q 6 Q 7 Q 8 Q 9 Q 10	IC, (µPC4570C) IC, (µPD5201C) IC, (µPC14305H) IC, (µPC4570C) IC, (µPC4570C)		
Q 11 Q 12 Q 13 Q 14	IC, (uPC4570C) Di,breakdown,	2.5 to 2.9V,200mW	
Q 15 Q 16 Q 17 Q 18	Tr,(2SC2351(R2 OR R3}) Di,breakdown, (RD5.1MB2(512)) Tr,(2SC1623(L5 OR L6)) Di,breakdown, (RD5.1MB2(512))	4.97 to 5.24V,200mW	
Q 19 Q 20 Q 21 Q 22	Tr,(2SC1623(L5 OR L6)) Di,breakdown, (RD5.1MB2(512)) Tr,(2SC1623(L5 OR L6)) IC,(74290)	4.97 to 5.24V,200mW	
Q 23 Q 24 Q 25 Q 26	IC,(74F00PC) Di,breakdown, (RD5.1MB2(512)) Tr,(2SC2351(R2 OR R3)) Tr, (2SC3735(B34 OR B35)	4.97 to 5.24V,200mW	
Q 27 Q 28 Q 29 Q 30	Di,(1SS123(A7)) Not assigned Tr, (2SA1462(Y33 OR Y34) Tr, (2SA1462(Y33 OR Y34)		
Q 31 Q 32 Q 33	IC, (74F191PC) IC, (74F08PC) Di, (1S2835(A3))		

( ): Manufacturer's part number
\* : Selected at factory

34W93338	3/6
	_

	Q 34	Tr,		
		(2SC3735(B34 OR B35))		
	Q 35	IC, (µPC4570C)		
	ľ			
	R 1	SIL type, (RRS-8-104JA)	100kΩ x 8,±5%,1/8W	
	R 2	CM, (RM73B2B104JD)	100kΩ,±5%,1/8W	
	R 3	CM, (RM73B2B104JD) CM, (RM73B2B681JD)	100kΩ,±5%,1/8W   680Ω,±5%,1/8W	
	R 5	CM, (RM73B2B472JD)	4.7kΩ,±5%,1/8W	
	R 6	CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8w	
	R 7	Var,MF,(RJ-6P 2KΩ)	2.0kn,1/2W	
	R 8	MF, (RN14K2E2152D) MF, (RN14K2E5491D)	21.5kΩ,±0.5%,1/4W 5.49kΩ,±0.5%,1/4W	
	R 10	Not assigned	3.49KH, 10.34,1/4W	
	R 11	MF, (RN14K2E1000D)	100Ω,±0.5%,1/4W	
	R 12	MF, (RN14K2E1000D)	1000,±0.5%,1/4W	
	R 13	Var,MF, (RJ-6P 10KΩ)	10kΩ,1/2W	
	R 14 R 15	MF, (RN14K2E1692D) MF, (RN14K2E4991D)	16.9kΩ,±0.5%,1/4W 4.99kΩ,±0.5%,1/4W	
	R 16 R 17	MF, (RN14K2E4991D) CM, (RM73B2B222JD)	4.99kΩ,±0.5%,1/4W 2.2kΩ,±5%,1/8W	
	R 18	MF, (RN14K2E4751D)	4.75kΩ,±0.5%,1/4W	
	R 19	Var,MF, (RJ-6P 500Ω)	500R,1/2W	
	R 20	Not assigned		
	R 21	MF, (RN05E2B1022B)	10.2kΩ,±0.1%,1/8W	
	R 22 R 23	MF, (RN05E2B1131B) CM, (RM73B2B102JD)	1.13kΩ,±0.1%,1/8W 1.0kΩ,±5%,1/8W	
	R 24	Not assigned	1.000,130,1700	
	R 25	CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8W	
	R 26	MF, (RN14K2E3401D)	3.40kΩ,±0.5%,1/4W	
	R 27	MF, (RN14K2E5361D)	5.36kΩ,±0.5%,1/4W	
	R 28 R 29	MF, (RN14K2E5491D) MF, (RN14K2E3321D)	5.49kΩ,±0.5%,1/4W 3.32kΩ,±0.5%,1/4W	
	R 30	MF, (RN14K2E1272D)	12.7kΩ,±0.5%,1/4W	
	R 31	Var,MF, (RJ-6P 500Ω)	500Ω,1/2W	
	R 32	MF, (RN14K2E3921D)	3.92kΩ,±0.5%,I/4W	
	R 33	MF, (RN14K2E3321D) MF, (RN14K2E4991D)	3.32kΩ,±0.5%,1/4W 4.99kΩ,±0.5%,1/4W	
	R 35	MF, (RN14K2E7502D)	75.0kΩ,±0.5%,1/4W	
	R 36	MF, (RN14K2E2262D)	22.6kΩ,±0.5%,1/4W	
	R 37	MF, (RN14K2E3402D)	34.0kΩ,±0.5%,1/4W	
	R 38 R 39	MF, (RN14K2E1692D) MF, (RN14K2E4751D)	16.9kΩ,±0.5%,1/4W 4.75kΩ,±0.5%,1/4W	
	R 40	Not assigned	41,200,123,411,41	
1	R 41	MF, (RN14K2E3651D)	3.65kn,±0.5%,1/4W	
	R 42	MF, (RN14K2E3651D)	3.65kn,±0.5%,1/4W	

( ): Manufacturer's part number

\* : Selected at factory

34W93338 4/6

	Faita List: A		
CKT REF	DESCRIPTION	RATING	NOTE
	WD (DW1 (W2D1(51D)	2 6510 .0 54 1/49	
R 43	MF, (RN14K2E3651D)	3.65kΩ,±0.5%,1/4W	
R 44	MF, (RN14K2E3651D)	3.65kΩ,±0.5%,1/4W	
R 45	MF, (RN14K2E7320D)	732Ω,±0.5%,1/4W	
R 46	Not assigned		
R 47	CM, (RM73B2B470JD)	47Ω,±5%,1/8W	
R 48	CM, (RM73B2B271JD)	270Ω,±5%,1/8W	
R 49	CM, (RM73B2B330JD)	33Ω,±5%,1/8W	
R 50	CM, (RM73B2B121JD)	120Ω,±5%,1/8W	
R 51	CM, (RM73B2B151JD)	150Ω,±5%,1/8W	
R 52	CM, (RM73B2B470JD)	47Ω,±5%,1/8W	
R 53	CM, (RM73B2B101JD)	1000,±5%,1/8W	
R 54	CM, (RM73B2B820JD)	820,±5%,1/8W	
R 55	CM, (RM73B2B820JD)	82Ω, ±5%, 1/8W	1
R 56	CM, (RM73B2B101JD)	100Ω,±5%,1/8W	ı
R 57	CM, (RM73B2B681JD)	6800,±5%,1/8W	
" "	, (, 552230155)	333.,133,1,3,	
R 58	CM, (RM73B2B101JD)	100Ω,±5%,1/8W	1
R 59	CM, (RM73B2B511JD)	5100,±5%,1/8W	1
R 60	Not assigned		
R 61	CM, (RM73B2B101JD)	100Ω,±5%,1/8W	
R 62	CM, (RM73B2B821JD)	820Ω,±5%,1/8W	
R 63	CM, (RM73B2B101JD)	100Ω,±5%,1/8W	ľ
R 64	CM. (RM73B2B511JD)	5100, ±5%, 1/8W	1
R 65	CM. (RM73B2B221JD)	220Ω, ±5%, 1/8W	
R 66	CM, (RM73B2B102JD)	1.0kΩ, ±5%, 1/8W	
R 67	CM, (RM73B2B820JD)	82Ω,±5%,1/8W	
R 68	CM, (RM73B2B331JD)	330Ω,±5%,1/8W	
R 69	CM, (RM73B2B391JD)	390Ω,±5%,1/8W	
R 70	Not assigned		1
R 71	CM, (RM73B2B471JD)	470Ω,±5%,1/8W	
R 72	CM, (RM73B2B392JD)	390Ω,±5%,1/8W	
R 73	CM, (RM73B2B101JD)	100Ω,±5%,1/8W	
R 74	CM, (RM73B2B681JD)	6800,:5%,1/8W	1
R 75	CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8W	
R 76	CM, (RM73B2B181JD)	180Ω, ±5%, 1/8W	1
R 77	CM, (RM73B2B821JD)	820Ω,±5%,1/8W	1
R 78	CM, (RM73B2B681JD)	680Ω,±5%,1/8W	
R 79	CM. (RM73B2B151JD)	150Ω,±5%,1/8W	
R 80	CM, (RM73B2B601JD)	600Ω,±5%,1/8W	
R 81	CM. (RM73B2B391JD)	3900,±5%,1/8W	1
R 82	CM, (RM73B2B101JD)	1000, ±5%, 1/8W	1
	, (,,		
R 83	CM, (RM73B2B183JD)	18kΩ,±5%,1/8W	1
R 84	CM, (RM73B2B331JD)	330Ω,±5%,1/8W	
R 85	CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8W	
R 86	CM, (RM73B2B101JD)	100Ω, ±5%, 1/8W	
R 87	CM, (RM73B2B392JD)	3.9kΩ,±5%,1/8W	
R 88	CM, (RM73B2B471JD)	470Ω,±5%,1/8W	
R 89	CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8W	

CKT REF	DESCRIPTION	RATING	NOTE
R 90 R 91	MF, (RN14K2E1691D) MF, (RN14K2E1501D) MF, (RN14K2E5111D) CM, (RM73B2B101JD) CM, (RM73B2B101JD)	1.69kΩ,±0.5%,1/4W 1.50kΩ,±0.5%,1/4W 5.11kΩ,±0.5%,1/4W 100Ω,±5%,1/8W	
z 1	Mixer,(M-8)		

34W93338 5/6

A1-A16. YTO PLL PD & LOOP FILTER

(	):	Manufacturer's part number
		Selected at factory

DESCRIPTION

34W93338 6/6

NOTE

Parts List: Al-Al6, YTO PLL PD & LOOP FILTER

RATING

	Parts List: Al-A	16, YTO PLL PD & LOOP FILT	ER 15
CKT REF	DESCRIPTION	RATING	NOTE
C 1	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 2	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 3	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 4	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 5	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 6	Cer, (CK732B1H103K(A4))	0.01µF,:10%,50V	
C 7	Cer, (CC732CH1H680J(W1))	68pF,:5%,50V	
C 8	Cer, (CK732B1H103K(A4))	0.01µF,:10%,50V	
C 9	Cer, (CC732CH1H150J(E1))	15pF,:5%,50V	
C 10	Cer, (CK732B1H102K(A3))	1000pF,:10%,50V	
C 11	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 12	Cer, (CC732CH1H101J(A2))	100pF,±5%,50V	
C 13	Cer, (CC732CH1H331J(X2))	330pF,±5%,50V	
C 14	Cer, (CC732CH1H101J(A2))	100pF,±5%,50V	
C 15	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 16	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 17	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 18	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 19	Cer, (CK733F1H104Z(A5))	0.01µF,:10%,50V	
C 20	Cer, (CK732B1H103K(A4))	0.01µF,:10%,50V	
C 21	Cer, (CC732CH1H150J(E1))	15pF, ±5%,50V	
C 22	Cer, (CK732B1H102K(A3))	1000pF, ±10%,50V	
C 23	Cer, (CK732B1H103K(A4))	0.01uF, ±10%,50V	
C 24	Cer, (CK732B1H103K(A4))	0.01uF, ±10%,50V	
C 25	Cer, (CK732B1H102K(A3))	1000pF, ±10%,50V	
C 26	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 27	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 28	Elect, (CE04C1E470A)	47µF,±20%,25V	
C 29	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 30	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 31	Plast, (ECQ-V1H104JW)	0.1µF, ±5%,50V	
C 32	Cer, (CK732B1H103X (A4))	0.01µF, ±10%,50V	
C 33	Cer, (CK733F1H104Z (A5))	0.1µF, ±80/-20%,50V	
C 34	Cer, (CK733F1H104Z (A5))	0.1µF, +80/-20%,50V	
C 35	Cer, (CK733F1H104Z (A5))	0.1µF, +80/-20%,50V	
C 36	Tant, (CS734E1C226M)	22µF,±20%,16V	
C 37	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 38	Cer, (CC732CH1H151J(E2))	150pF,15%,50V	
C 39	Var, cer, (TZ03R300A)	30pF,100V	
C 40	Elect, (CE04C1H220A)	22µF,±20%,50V	
C 41	Cer, (CC732CH1H221J(J2))	220pF,±5%,50V	
C 42	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 43	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 44	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 45	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 46	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 47	Cer, (CK732B1H102K(A3))	1000pF,±10%,50V	

	C 48	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V		
	C 49	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	l	
	C 50	Cer, (CK732B1H102K(A3))	1000pF, ±10%,50V	l	
	C 51	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V		
	C 52	Cer, (CK732B1H102K(A3))	1000pF, ±10%,50V		ľ
		CCI, (CM, SIBIMICIA (MS, )	200061,2200,550		
	C 53	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V		l
	C 54	Cer, (CK732B1H103K(A4))	0.01µF, ±10%,50V	l	
	C 55	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V		
	C 56	Cer, (CK732B1H102K(A3))	1000pF, ±10%, 50V		
	C 57	Elect, (CE04ClE101A)	100µF,±20%,25V		
	C 58	Elect, (CE04C1E101A)	100µF,±20%,25V		
1	C 59	Elect, (CEO4C1A221A)	220µF,±20%,10V	ĺ	
	C 60	Cer, (CK732B1H103K(A4))	0.01µF, ±10%,50V		
	C 61	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V		
	C 62	Plast, (ECQ-VIH104JW)	0.1µF,±5%,50V		
	C 02	Flast, (ECQ-VINIO45W)	U.141,130,304		ĺ
		0 (GE23381111048 (NEXX	0 1 T 100/ 200 FOV		
	C 63	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	I	1
	C 64	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V		
	C 65	Cer, (CC732CH1H180J(G1))	18pF, ±5%, 50V		
	C 66	Elect, (CEO4C1E470A)	47µF,±20%,25V	Į.	
	C 67	Elect, (CE04C1E470A)	47uF,±20%,25V		
	C 68	Cer, (CC45CH1H090DY)	9pF, ±0.5pF,50V		
	C 69	Plast, (ECO-V1H684JW)	0.68µF,±5%,50V		
	J 1	Connector, (27DP-PC			S4J10004K
		TERMINAL CABLE)			
					1
	J 2	Connector, (27DP-R-PC-1)			
	J 3	Connector,			
		(DF1-2S-2.5R24)			
	Ll	Coil, (E526HN-100109)	0.36µH		With case
	L 2	Coil, (E526HN-100109)	0.36μΗ		With case
	L 3	Coil, (NL453232-221K)	220µH		
	L 4	Coil, (NL322522-R15K)	0.15uH		
	L 5	Coil, (NL453232-4R7K)	4.7µH		
	- •				
- 1	L 6	Coil, (NL453232-2R2K)	2.2µH		
- 1	L 7	Coil, (NL453232-100K)	10uH		
- 1			100uH		
- 1	L 8	Coil, (NL453232-101K)		1	
- 1	L 9	Coil, (NL453232-100K)	10µH		
- 1	L 10	Coil, (NL322522-R68K)	0.68µН		
- 1		1		]	
- 1	L 11	Coil, (NL322522~R68K)	0.68µH		
- 1					
ı	Q 1	Di,(16953)		1	
ı	0 2	Di, breakdown,	6.0 to 6.39V,200mW		
ı		(RD6.2MB2(622))			
- 1	Q 3	FET, (25K152-2)			
- 1	0 4	Di,breakdown,	4.97 to 5.24V, 200mW		
ı	· •		4.5, CO 5.240,200MW		
ı		(RD5.1MB2(512))			
ı					
- 1	Q 5	Tr, (2SC2351(R2 OR R3))			
- 1	Q 6	Di,(µPC1663C)			
ı					

( ): Manufacturer's part number
\* : Selected at factory

34W93339 1/5

( ): Manufacturer's part number
\* : Selected at factory

34W93339 2/5

Parts List: Al-Al6, YTO PLL PD & LOOP FILTER

CKT	DESCRIPTION	RATING	NOTE
REF	DESCRIPTION	KATING	NOTE
Q 7	Di,breakdown, (RD6.2MB2(622))	6.0 to 6.39V,200mW	
Q 8	Di,breakdown, (RD6.2MB2(622))	6.0 to 6.39V,200mW	
0 9	Tr, (2SC2351(R2 OR R3))	4 87 4 5 244 200-4	
Q 10 Q 11	Di,breakdown, (RD5.1MB2(512)) Di,(1SS97)	4.97 to 5.24V,200mW	Q'ty 2
0 12 0 13	IC, (MC12040L) IC, (µPC4570C)		Q ty 2
Q 14 Q 15	Di,(1S953) Di,breakdown, (RD9.1EB)	8.5 to 9.6V,400mW	Q'ty 2
Q 16 Q 17	Tr,(2SC2719) Di,breakdown,(1S252)	5.9 to 6.5V,250mW	İ
Q 18 Q 19 Q 20 Q 21	Di, vari-cap, (KV1226Y) FET, (25K55E) FET, (25K55E) Di, breakdown, (RD5.1MB2(512))	4.97 to 5.24V,200mW	į
Q 22 Q 23 Q 24	Tr,(2SC2351(R2 OR R3)) Tr,(2SC2351(R2 OR R3)) Di,breakdown, (RD5.1MB2(512))	4.97 to 5.24V,200mW	
Q 25	Di, (18897)		Q'ty 2
Q 26 Q 27	Tr,(2SC2351(R2 OR R3)) Di,breakdown, (RD5.1MB2(512))	4.97 to 5.24V,200mW	
Q 28 Q 29	FET, (2SK55E) IC, (µPC14305H)		1
Q 30 Q 31 Q 32 Q 33	Tr, (2SC3615) 1C, (74HC123) 1C, (74HC00) Tr, (2SC2901)		
R 1 R 2 R 3	CM, (RM73B2B394JD) CM, (RM73B2B394JD) CM, (RM73B2B331JD)	390kΩ,±5%,1/8W 390kΩ,±5%,1/8W 330Ω,±5%,1/8W	
R 4 R 5	MF, (RN14K2E49R9D) MF, (RN14K2E2000D)	49.9Ω,±0.5%,1/4W 200Ω,±0.5%,1/4W	
R 6 R 7	CM, (RM73B2B561JD) CM, (RM73B2B4R7JD)	560Ω,±5%,1/8W 4.7Ω,±5%,1/8W	
R 8 R 9 R 10	CM, (RM73B2B471JD) CM, (RM73B2B820JD) CM, (RM73B2B510JD)	470Ω,±5%,1/8W 82Ω,±5%,1/8W 51Ω,±5%,1/8W	
R 11 R 12	CM, (RM73B2B510JD) CF, (ARD25T271J)	51Ω,±5%,1/8W : 270Ω,±5%,1/4W	

CKT	DESCRIPTION	RATING	NOTE
REF	OBBORIT TICK	KATING	HOTE
		l	
R 13	CF, (ARD25T271J)	270Ω,±5%,1/4W	
R 14	CF, (ARD25T151J)	150Ω,±5%,1/4W	
R 15	CM, (RM73B2B471JD)	470Ω,±5%,1/8W	i
R 16	CM, (RM73B2B151JD)	150Ω,±5%,1/8W	
R 17	CM, (RM73B2B471JD)	470Ω,±5%,1/8W	
l			
R 18	CM, (RM73B2B390JD)	39Ω,±5%,1/8W	
R 19	CF, (ARD25T271J)	270Ω, ±5%, 1/4W	
R 20	CM, (RM73B2B470JD)	47Ω,±5%,1/8W	
R 21	CM, (RM73B2B680JD)	68Ω,±5%,1/8W	
R 22	CM, (RM73B2B560JD)	56Ω,±5%,1/8W	
l			
R 23	CM, (RM73B2B391JD)	390Ω,±5%,1/8W	
R 24	MF, (RN14K2E5110D)	511Ω,±0.5%,1/4W	
R 25	MF, (RN14K2E5110D)	511Ω,±0.5%,1/4W	
R 26	MF, (RN14K2E5110D)	511Ω,±0.5%,1/4W	
R 27	MF, (RN14K2E5110D)	511Ω,±0.5%,1/4W	111
l			
R 28	MF, (RN14K2E4991D)	4.99kΩ,±0.5%,1/4W	
R 29	MF, (RN14K2E4991D)	4.99kΩ,±0.5%,1/4W	
R 30	MF, (RN14K2E1002D)	10.0kΩ,±0.5%,1/4W	11411
R 31	MF, (RN14K2E1002D)	10.0kΩ,±0.5%,1/4W	
R 32	MF, (RN14K2E4642D)	46.4kΩ,±0.5%,1/4W	
1			
R 33	MF, (RN14K2E1821D)	1.82kΩ,±0.5%,1/4W	
R 34	MF, (RN14K2E1001D)	1.00kΩ,±0.5%,1/4W	Į.
R 35	CM, (RM73B2B330JD)	33Ω,±5%,1/8W	ł
R 36	CM, (RM73B2B821JD)	820Ω,±5%,1/8W	
R 37	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
	1		
R 38	CM, (RM73B2B562JD)	5.6kΩ,±5%,1/8W	1
R 39	CM, (RM73B2B332JD)	3.3kΩ,±5%,1/8W	l
R 40	CM, (RM73B2B122JD)	1.2kn,±5%,1/8W	
R 41	CM, (RM73B2B272JD)	2.7k\O, ±5%,1/8W	
R 42	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
			ì
R 43	CM, (RM73B2B562JD)	5.6kΩ,±5%,1/8W	
R 44	CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8W	l
R 45	MF, (RN14K2E1692D)	16.9kn,±0.5%,1/4W	l
R 46	CF, (ARD25T681J)	680Ω,±5%,1/4W	{
R 47	CM, (RM73B2B221JD)	220Ω, ±5%, 1/8W	
I		, ,	
R 48	CM, (RM73B2B561JD)	560Ω,±5%,1/8W	
R 49	CM, (RM73B2B331JD)	330R, ±5%, 1/8W	
R 50	CM, (RM73B2B820JD)	82Ω, ±5%, 1/8W	l
R 51	CM, (RM73B2B221JD)	220Ω,±5%,1/8W	l
R 52	CM, (RM73B2B561JD)	5600,±5%,1/8W	l
1		,,	l
R 53	CF, (ARD25T271J)	270Ω, ±5%, 1/4W	1
R 54	CM, (RM73B2B390JD)	39 N, ±5%, 1/8W	1
R 55	CM, (RM73B2B470JD)	47Ω,±5%,1/8W	ſ
R 56	CM, (RM73B2B391JD)	3900, ±5%, 1/8W	
R 57	CM, (RM73B2B5913D)	56Ω,±5%,1/8₩	
" " "	C., (141, 32223000D)	33, 133, 1, 0,	
R 58	CM, (RM73B2B680JD)	68Ω.±5%,1/8W	
R 59	CM, (RM73B2B221JD)	220Ω,±5%,1/8W	
( )	, (, SDEDEELOO,	,,	

34W93339 3/5

( ): Manufacturer's part number

\* : Selected at factory

34w93339 4/5

Parts List: A1-A16, YTO PLL PD & LOOP FILTER

	rates bise	AIS, THO PEL PD & LOOP PIL	
CKT REF	DESCRIPTION	RATING	NOTE
R 60 R 61 R 62 R 63 R 64	CM, (RM73B2B681JD) CM, (RM73B2B331JD) CM, (RM73B2B820JD) CM, (RM73B2B470JD) CM, (RM73B2B151JD)	680Ω,±5%,1/8W 330Ω,±5%,1/8W 82Ω,±5%,1/8W 47Ω,±5%,1/8W 150Ω,±5%,1/8W	
R 65 R 66 R 67 R 68 R 69	MF, (RN14K2H22OJ) CM, (RM73B2B47OJD) CM, (RM73B2B221JD) CM, (RM73B2B221JD) CM, (RM73B2B221JD) CM, (RM73B2B103JD)	22Ω, ±5%, 1/2W 47Ω, ±5%, 1/8W 220Ω, ±5%, 1/8W 220Ω, ±5%, 1/8W 10kΩ, ±5%, 1/8W	
R 70 R 71 R 72 R 73 R 74	CM, (RM73B2B103JD) MF, (RN14K2E1243D) CM, (RM73B2B511JD) CM, (RM73B2B511JD) CM, (RM73B2B511JD)	10kΩ,±5%,1/8W 124kΩ,±0.5%,1/4W 510Ω,±5%,1/8W 510Ω,±5%,1/8W 10kΩ,±5%,1/8W	
R 75 R 76	CM, (RM73B2B122JD) CM, (RM73B2B103JD)	1.2kΩ,±5%,1/8W 10kΩ,±5%,1/8W	

( ): Manufacturer's part number
\* : Selected at factory

34W93339 5/5

Parts List: A2. IF BPF

	Parts List: A2, IF BPF			
CKT REF	DESCRIPTION	RATING	NOTE	
C 1 C 2 C 3 C 4 C 5	Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4)) Cer, (CC732CH1H221J(JZ)) Cer, (CC732CH1H100D(A1))			
C 6 C 7 C 8 C 9 C 10	Cer,(CC732CH1H220J(J1)) Cer,(CC732CH1H221J(J2)) Cer,(CK732BH1102K(A3)) Cer,(CK732BH1103K(A4)) Cer,(CK732BH1103K(A4))			
C 11 C 12 C 13 C 14 C 15	Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V 0.01µF,±10%,50V 0.01µF,±10%,50V 0.01µF,±10%,50V 330pF,±5%,50V		
C 16 C 17 C 18 C 19 C 20	Elect, (CE04C1E221A) Cer, (CC45SH1H271JY) Cer, (CC732CH1H221J(J2)) Cer, (CC732CH1H271JY) Cer, (CC732CH1H221J(J2))	270pF,±5%,50V		
C 21 C 22 C 23 C 24 C 25	Cer, (CC45SH1H271JY) Elect, (CE04C1E221A) Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4)) Elect, (CE04C1E221A)	270pF, ±5%, 50V 220µF, ±20%, 25V 0.01µF, ±10%, 50V 0.01µF, ±10%, 50V 220µF, ±20%, 25V		
C 26 C 27 C 28 C 29 C 30	Elect, (CE04C1E221A) Cer, (CK924F1H104T) Cer, (CC732CK1H020C(H0)) Cer, (CK732B1H103K(A4)) Cer, (CC732CH1H221J(J2))	0.01µF,±10%,50V		
C 31 C 32 C 33 C 34 C 35	Cer, (CC732CH1H181J(G2)) Cer, (CK732B1H103K(A4)) Cer, (CK733F1H104Z(A5)) Var, cer, (TZ03Z070A) Var, cer, (TZ03Z070A)	180pF, ±5%,50V 0.01µF, ±10%,50V 0.1µF, +80/-20%,50V 7pF,100V 7pF,100V		
C 36 C 37 C 38 C 39 C 40	Cer, (CC45PH1H330JY) Cer, (CC732CH1H050D(f0)) Cer, (CC45SH1H680JY) Cer, (CK732BH103K(A4)) Var, Cer, (TZ03Z070A)	33pF, ±5%,50V 5pF,±0.5pF,50V 68pF,±5%,50V 0.01µF,±10%,50V 7pF,100V		
C 41 C 42 C 43 C 44 C 45	Cer, (CC45PH1H330JY) Cer, (CC732CX1H02DC(H0)) Cer, (CC45SH1H680JY) Elect, (CE04C1E221A) Elect, (CE04C1E221A)	33pF, ±5%,50V 2pF, ±0.25pF,50V 68pF, ±5%,50V 220uF, ±20%,25V 220uF, ±20%,25V		
C 46 C 47	Cer, (CK732B1H103K(A4)) Cer, (CC732CH1H151J(E2))	0.01µF,±10%,50V 150pF,±5%,50V		

( ): Manufacturer's part number
\* : Selected at factory

34W93318 1/8

CKT REF	DESCRIPTION		
REF	DESCRIPTION	RATING	NOTE
			1.012
C 48	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 49	Not assigned		
C 50	Var,cer,(T2032070A)	7pF,100V	
C 51	Var,cer,(T2032070A)	7pF,100V	
C 52	Var,cer,(T2032070A)	7pF,100V	
C 53	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 54	Cer,(CC732CK1H020C(H0))	2pF,±0.25pF,50V	
C 55	Cer,(CC45SH1H600JY)	68pF, ±5%, 50V	
C 56	Elect, (CE04ClE221A)	220µF, ±20%, 25V	
C 57	Elect, (CE04ClE221A)	220µF,±20%,25V	
C 58	Var,cer,(TZ03Z070A)	7pF,100V	
C 59	Cer,(CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 60	Cer,(CC45PH1H330JY)	33pF, ±5%, 50V	
C 61	Cer, (CC45SH1H680JY)	68pF, 15%, 50V	
C 62	Var,cer, (T2032070A)	7pF,100V	
		-	
C 63	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 64	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 65	Cer, (CC732CH1H331J(N2))	330pF,±5%,50V	
C 66	Cer, (CC732CH1H331J(N2))	330pF, ±5%, 50V	
C 67	Cer, (CC732CH1H121J(C2))		
	,(		
C 68	Cer, (CC732CH1H220J(J1))	22pF, ±5%, 50V	
C 69	Cer, (CC732CH1H101J(A2))	100pF, ±5%, 50V	
C 70	Cer. (CK924F1H104Z)	0.1µF,+80/-20%,50V	
C 71	Cer, (CK924F1H104Z)	0.1µF,+80/-20%,50V	
C 72	Not assigned	0.114.7.007 2007501	
0 /2	not addayned		
C 73	Not assigned		
C 74	Cer, (CC45PH1H330JY)	33pF, 15%, 50V	
C 75	Cer, (CC732CH1H181J(G2))	180pF,±5%,50V	
C 76	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 77	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C //	CEI, (CK, SIBINIOSK (A4,))	0.0141,1104,504	
C 78	Cer, (CC732CH1H050D(f0))	5pF,±0.5pF,50V	
C 79	Elect, (CE04C1E101A)	100µF,±20%,25V	
C 60	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 81	Not assigned	0.0121,1100,300	
C 82	Cer, (CC732CH1H080D(t0))	8pF,±0.5pF,50V	
C 62	CEI, (CC, 32CHIROGOD (CO))	op: , 20. 3pr , 304	
C 83	Cer, (CC732CH1H100D(A1))	10pF, ±0.5pF,50V	
C 84	Cer, (CC/32CH1H100D(A1))	0.01µF,±10%,50V	
C 85	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 86 C 87	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 87	Cer, (CC732CH1H100D(t0))	10pF,±0.5pF,50V	
C 88	Co. (CC732CV1 NO705(-01)	7nP +0 5nP 50V	
	Cer, (CC732CH1H070D(n0))		
C 89	Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V	
C 90	Cer, (CC732CH1H120J(C1))	12pF, ±5%,50V	
C 91	Cer, (CC732CH1H070D(n0))		
C 92	Cer, (CC732CH1H120J(C1))	12pF, ±5%,50V	
	l		
C 93	Cer, (CC732CH1H080D(t0))	8pF, ±0.5pF,50V	
C 94	Cer, (CC732CH1H120J(C1))	12pF, ±5%,50V	

ſ	CKT	DESCRIPTION	RATING		NOTE
ŀ	REF				
1	C 95				
1	C 96				
1	C 97		7pF,±0.5pF,50V 100µF,±20%,10V		
1	C 96				
1	C 3:	Cel, (CC/32CH1H1310 (E2))	130pr,134,304		
-	C100	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V		
-	C101		0.1µF,+80/-20%,50V		
- 1	C102				
-	C103		0.1µF,+80/-20%,50V 0.01µF,±10%,50V		
-	C104	Cer, (CK732B1H103K(A4))	0.01pF, 1108, 50V		
-	C105	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V		
-	C106		0.1µF,+80/-20%,50V		
-1	C107		0.1µF,+80/-20%,50V		
-	C106	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V		
-					
-					
-	J	Connector, (27DP-PC			
-1		TERMINAL CABLE)			
-1	J		64pins		
-		(DIN41612-64PB)	3-4		
-	J 3	(008261-033311-852)	3pins		
-		(000201-033311 032)			
-	J 4	Connector,	2pins		
-		(008261-024200-870)			
-1	J 5		3pins		
-	J é	(008261-033311-852) Connector,	2pins		
-	, ,	(008261-024200-870)	zpins		
-					
-	J		3pins		
- 1	_	(008261-033311-852)			
-	JE	Connector, (008261-024200-870)	2pins		
-	J 9		3pins		
-	•	(008261-033311-852)		l	
-					
-	J 10		2pins		
-		(008261-024200-870)	3pins		
-	J 11	Connector, (008261-033311-852)	3pins		
-	J 12		2pins		
-		(008261-024200-870)	·		
-					
-	J 13	Connector, (008261-033311-852)	3pins		
-	J 14		2pins		
-	0 -	(008261-024200-870)	*P10		
-					
-					
- [		n-1 ev. (CV. 12)			
-	K I				
-	~ 4	MELGY, (5V-12)			

\* : Selected at factory

34W93318 2/8

CKT REF

( ): Manufacturer's part number \* : Selected at factory

Parts List: A2, IF BPF

34w93318 3/8

NOTE

Parts List: A2, IF BPF

	Parts List: AZ, IF BPF				
CKT REF	DESCRIPTION	RATING	NOTE		
к з	Relay, (SV-12)		1		
K 4 K 5	Relay, (SV-12) Relay, (SV-12)				
L 1 L 2	Coil, (NL453232-4R7K) Coil, (10K17-45T)	4.7µH 158nH	With case		
L 3	Coil, (339T25552) Coil, (10K17-45T)	5.46µH 158nH	With case		
L 5	Coil, (NL453232-4R7K)	4.7µH	water case		
L 6 L 7	Coil, (NL453232-1R5K) Coil, (NL453232-1R5K)	1.5µH 1.5µH			
ľ 8	Coil, (33T25551A 10K COIL)	300nH	With case		
L 9	Coil, (33T25551B 10K COIL)	370nH	With case		
L 10	Coil,	300nH	With case		
L 11	(33T25551A 10K COIL) Coil, (NL453232-101K)	100 uH			
L 12	Coil, (NL453232-101K)	100µH			
L 13	Coil, (339T25509)	16.4µH			
L 14 L 15	Not assigned Coil, (339T25509)	16.4µH			
L 16 L 17	Not assigned Coil, (NL453232-101K)	100µH			
L 18	Coil, (NL453232-101K)	100µH			
L 19 L 20	Coil, (339T25509) Not assigned	16.4µH	4		
L 21 L 22	Coil, (339T25509) Not assigned	16.4µH			
L 23	Not assigned				
L 24 L 25	Not assigned Coil, (LF8-101K)	100µH			
L 26	Coil, (LF8-101K)	100µH	l l		
L 27	Coil, (LF8-101K)	100µН			
Q 1	Di,breakdown, (RD5.1MB2(512))	4.97 to 5.24V,200mW			
Q 2	Tr (2SC2369)				
Q 3	Di,breakdown, (RD3.9MB2(392))	3.87 to 4.10V			
Q 4	Tr, (2SC2369)				
Q 5	Tr, (2SC3735(B34 OR B35))				
Q 6	Di,(152835(A3)) Tr,(25C1623(L5 OK L6))				
Q 8	Di,(1S2835(A3))				

Q 9 IC, (TC4051BP) Q 10 IC, (TC4051BP) Q 11 IC, (TC74HC574P) Q 12 IC, (TC74HC574P) Q 13 IC, (TC74HC574P)

DESCRIPTION

Q 14 Di,(152835(A3))
Q 15 Tr,(2SC1623(L5 OR L6))
Tr,
(2SC1462(Y33 OR Y34))
Q 17 Di,breakdown,
(RD6.2M82(622)) 6.0 to 6.39V,200mW IC, (7406)
Di, (182835(A3))
Di, (182835(A3))
Tr, (28C1623(L5 OR L6))
IC, (TC4051BP) Q 18 Q 19 Q 20 Q 21 Q 22 Tr,(2SC1623(L5 OR L6))
Tr,(2SC1623(L5 OR L6))
Tr,(2SC1623(L5 OR L6))
Tr,(2SC1623(L5 OR L6))
Not assigned Q 23 Q 24 Q 25 Q 26 Q 27 Di,(1SS153(A9))
IC,(TC4053BP)
IC,(TC40H000)
Di,breakdown,
(RD5.1MB2(512)) Q 28 Q 29 Q 30 Q 31 4.97 to 5.24V,200mW Q 32 Di,(1SS153(A9)) Q 33 Tr,(2SC1623(L5 OR L6)) Q 34 Tr,(2SC1623(L5 OR L6)) Q 35 Tr,(2SC1623(L5 OR L6)) Q 36 Tr,(2SC1623(L5 OR L6)) Q 37 Tr, (2SC1623(L5 OR L6)) R 1 MF, (LP1/8 150ΩJT51) R 2 CM, (RM73B2B331JD) R 3 CM, (RM73B2B10JD) R 4 Var, MF, (RJ-6F 100Ω) R 5 CM, (RM73B2B331JD) 150Ω,±5%,1/8W 330Ω,±5%,1/8W 10Ω,±5%,1/8W 100Ω,1/2W 330Ω,±5%,1/8W R 6 CM, (RM73B2B220JD) R 7 CM, (RM73B2B820JD) R 8 CM, (RM73B2B820JD) R 9 CM, (RM73B2B820JD) R 10 CM, (RM73B2B331JD) 220,±5%,1/8W 820,±5%,1/8W 820,±5%,1/8W 4.7k0,±5%,1/8W 3300,±5%,1/8W R 11 CM, (RM73B2B510JD) R 12 CM, (RM73B2B680JD) R 13 CM, (RM73B2B510JD) 51Ω,±5%,1/8W 68Ω,±5%,1/8W 51Ω,±5%,1/8W

( ): Manufacturer's part number

\* : Selected at factory

34W93318 4/8

( ): Manufacturer's part number
\* : Selected at factory

34W93318 5/8

CKT	DESCRIPTION	RATING	NOTE
REF			HOIL
R 14	GW (BWZ3B3B6867B)	1600 50 1/00	
	CM, (RM73B2B680JD)	680,±5%,1/8W	
R 15	CM, (RM73B2B181JD)	180Ω,±5%,1/8W	ļ
R 16	CM, (RM73B2B331JD)	330Ω,±5%,1/8W	į
R 17	CM, (RM73B2B331JD)	330Ω,±5%,1/8W	1
R 18	CM, (RM73B2B101JD)	100Ω,±5%,1/8W	į
R 19	CM, (RM73B2B822JD)	8.2kΩ,±5%,1/8W	1
R 20	CM, (RM73B2B221JD)	220Ω,±5%,1/8W	
R 21	CM, (RM73B2B471JD)	470Ω,±5%,1/8W	
R 22	CM, (RM73B2B392JD)	3.9kΩ,±5%,1/8W	
R 23	CM, (RM73B2B471JD)	470Ω,±5%,1/8W	
R 24	CM, (RM73B2B102JD)	1.0kn,±5%,1/8W	
R 25	CM, (RM73B2B331JD)	330Ω, ±5%, 1/8W	
R 26	CM, (RM73B2B271JD)	270Ω,±5%,1/8W	
R 27	CM, (RM73B2B561JD)	560Ω, ±5%, 1/8W	
R 28	CM, (RM73B2B391JD)	3900,±5%,1/8W	1
		1	
R 29	CM, (RM73B2B181JD)	180Ω,±5%,1/8W	
R 30	CM, (RM73B2B561JD)	560Ω,±5%,1/8W	
R 31	CM, (RM73B2B222JD)	2.2kΩ,±5%,1/8W	
R 32	CM, (RM73B2B331JD)	330Ω,±5%,1/8W	
R 33	CM, (RM73B2B331JD)	330Ω, ±5%, 1/8₩	
	un, (1411 522255102)	3302,130,1704	
R 34	CM, (RM73B2B822JD)	8.2k\O,±5%,1/8W	
R 35	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
R 36	CM, (RM73B2B330JD)		Y
R 37	CM, (RM73B2B3300D)	33Ω,±5%,1/8W	
R 38	CM, (RM73B2B682JD)	6.8kΩ,±5%,1/8W	1
1, 20	CEI, (KM / 3BZB13ZUD)	1.5kΩ,±5%,1/8W	
R 39	CM, (RM73B2B822JD)	9 350 459 1/00	
R 40		8.2kΩ, ±5%, 1/8W	
	CM, (RM73B2B122JD)	1.2kΩ,±5%,1/8W	
R 41	CM, (RM73B2B221JD)	220Ω,±5%,1/8W	
R 42	CM, (RM73B2B681JD)	680Ω,±5%,1/8W	
R 43	CM, (RM73B2B152JD)	1.5kΩ,±5%,1/8W	
D 44	Law (DWZ2D2D2D2D)	1	
R 44	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
R 45	CM, (RM73B2B822JD)	8.2kΩ,±5%,1/8W	
R 46	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
R 47	CM, (RM73B2B330JD)	33Ω,±5%,1/8W	
R 48	CM, (RM73B2B682JD)	6.8kΩ,±5%,1/8W	
		4	
R 49	CM, (RM73B2B152JD)	1.5kΩ,±5%,1/8W	
R 50	CM, (RM73B2B471JD)	470Ω,±5%,1/8W	1 1 1 / .
R 51	CM, (RM73B2B822JD)	8.2kΩ, ±5%,1/8W	
R 52	CM, (RM73B2B221JD)	220Ω,±5%,1/8W	
R 53	CM, (RM73B2B471JD)	470Ω,±5%,1/8W	
R 54	CM, (RM73B2B391JD)	390Ω,±5%,1/8W	
R 55	CM, (RM73B2B680JD)	68Ω,±5%,1/8W	
R 56	CM, (RM73B2B101JD)	100Ω,±5%,1/8W	1
R 57	CM, (RM73B2B100JD)	10Ω,±5%,1/8W	
R 58	CM, (RM73B2B392JD)	3.9kΩ,±5%,1/8W	
R 59	CM, (RM73B2B471JD)	470Ω,±5%,1/8W	
R 60	CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8W	

CKT			
REF	DESCRIPTION	RATING	NOTE
R 61	CM, (RM73B2B822JD)	8.2kΩ,±5%,1/8W	
R 62	CM, (RM73B2B103JD)	10kΩ, ±5%, 1/8W	
R 63	CM, (RM73B2B330JD)	33Ω, ±5%, 1/8W	
R 64	CM, (RM73B2B682JD)	6.8kΩ, ±5%, 1/8W	
R 65	CM, (RM73B2B152JD)	1.5kΩ,±5%,1/8W	
	, (	1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 -	
R 66	CM, (RM73B2B391JD)	390Ω,±5%,1/8W	
R 67	CM. (RM73B2B822JD)	8.2kΩ, ±5%, 1/8W	
R 68	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
R 69	Not assigned		
R 70	CM. (RM73B2B330JD)	33Ω,±5%,1/8W	
		1,,	
R 71	CM, (RM73B2B682JD)	6.8kΩ,±5%,1/8W	
R 72	CM, (RM73B2B152JD)	1.5kΩ,±5%,1/8W	
R 73	CM, (RM73B2B471JD)	470Ω,±5%,1/8W	
R 74	CM, (RM73B2B822JD)	8.2kΩ, ±5%, 1/8W	!
R 75	CM, (RM73B2B221JD)	2200,±5%,1/8W	i
	on, (m. obibility)	1230.,230,170	
R 76	CM, (RM73B2B392JD)	3.9kΩ,±5%,1/8W	i
R 77	CM, (RM73B2B121JD)	1200,±5%,1/8W	
R 78	CM, (RM73B2B221JD)	220Ω,±5%,1/8W	
R 79	CM, (RM73B2B392JD)	3.9kΩ,±5%,1/8W	l
R 80	CM, (RM73B2B471JD)	470Ω, ±5%, 1/8W	
l " "	C.1, (1417 5B2 B4 7 10 B)	17011,130,1701	
R 81	CM, (RM73B2B332JD)	3.3kΩ,±5%,1/8W	i
R 82	CM, (RM73B2B473JD)	47kΩ,±5%,1/8W	}
R 83	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	i
R 84	CM, (RM73B2B151JD)	150Ω,±5%,1/8W	
R 85	CM, (RM73B2B822JD)	8.2kΩ,±5%,1/8W	
K 03	C11, (RH13B2B822UD)	0.2811, 138, 1704	
R 86	CM, (RM73B2B471JD)	470Ω,±5%,1/8W	i
R 87	CM. (RM73B2B392JD)	3.9kΩ,±5%,1/8W	
R 88	CM, (RM73B2B471JD)	470Ω,±5%,1/8W	
R 89	CM, (RM73B2B332JD)	3.3kΩ,±5%,1/8W	
R 90	CM, (RM73B2B473JD)	47kΩ,±5%,1/8W	
^ ′ ′	Cit, (Rit) 582 B4 ( 50 B)	1788,136,1768	
R 91	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
R 92	CM, (RM73B2B561JD)	560Ω,±5%,1/8W	
R 93	CM. (RM73B2B392JD)	3.9kΩ,±5%,1/8W	
R 94	CM, (RM73B2B561JD)	5600,±5%,1/8W	
R 95	Not assigned	300.,130,1/04	
L 23	myc assigned		1
R 96	CM, (RM73B2B332JD)	3.3kΩ,±5%,1/8W	
R 97	CM, (RM73B2B3323D)	1.0kΩ,±5%,1/8W	
R 98	CM, (RM73B2B181JD)	1800,±5%,1/8w	
R 99	CM, (RM73B2B1010D)	3.3kΩ,±5%,1/8W	
R100	CM, (RM73B2B332JD)	1.0k\(\alpha\),±5%,1/8W	
KIOO	Cm, (RM/382810200)	1.004,138,1/08	
R101	CM, (RM73B2B471JD)	470Ω,±5%,1/8W	
R101	CM, (RM73B2B4713D)	2.2kΩ,±5%,1/8W	l
R103	CM, (RM73B2B2220D)	680,±5%,1/8W	
R103	MF, (LP1/8 3300JT52)	330Ω,±5%,1/8W	
R104			
KTO2	CF, (ARD25T330J)	33Ω,±5%,1/4W	
R106	CM, (RM73B2B392JD)	3.9kΩ,±5%,1/8W	ŀ
R106	CM, (RM73B2B3923D) CM, (RM73B2B561JD)	560Ω,±5%,1/8W	
KIO/	CH, (M1/382830100)	JUVII, 130, 1/0m	
	<u> </u>		

: Selected at factory

34w93318 6/8

( ): Manufacturer's part number

34W93318 7/8

Parts	List:	Α2,	ΙF	BPF	

CKT REF	DESCRIPTION	RATING	NOTE
R108 Va R109 CM R110 CM R111 CM	x,MF,(RJ-6P 100Ω) 1,(RM73B2B222JD) (,(RM73B2B392JD) 1,(RM73B2B331JD) 1,(RM73B2B151JD)	1000,1/2W 2.2k0,55%,1/8W 3.9k0,:5%,1/8W 3.9k0,:5%,1/8W 1500,:5%,1/8W	
R114 CM R115 CM R116 CM	(,(RM73B2B104JD) (,(RM73B2B104JD) (,(RM73B2B104JD) (,(RM73B2B104JD) (,(RM73B2B104JD) (,(RM73B2B221JD)	100kΩ,:5%,1/8W 100kΩ,:5%,1/8W 100kΩ,:5%,1/8W 100kΩ,:5%,1/8W 220Ω,:5%,1/8W	 
R119 CF R120 CM	i, (RM73B2B222JD) F, (ARD25T680J) I, (RM73B2B510JD) I, (RM73B2B100JD)	2.2kn,±5%,1/8W 680,±5%,1/4W 510,±5%,1/8W 100,±5%,1/8W	
X 2 Cr X 3 Cr	ystal vibrator ystal vibrator ystal vibrator ystal vibrator	3.6MHz(B) 3.6MHz(A) 3.6MHz(C) 3.6MHz(A)	
Z 2 IC Z 3 IC Z 4 IC	xer, (M-9) , (UH4) , (UH4) , (UZ3) , (UH3)	8pins	
2 7 IC 2 8 IC 2 9 IC	C, (UZ3) C, (UH3) C, (UH4) C, (UH3) C, (UH3)		
2 12 IC 2 13 IC 2 14 IC	C, (UZ2) C, (UZ1) C, (UZ1) C, (UZ2) C, (UZ1)		
Z 17 IC	C, (UZ2) C, (UZ1) C, (UZ2)		

( ): Manufacturer's part number 34W93318 8/8

: Selected at factory

. Selected at factory

Parts List: A3, IF LOG/DET DESCRIPTION RATING NOTE REF Elect, (CE04C1E221A) Elect, (CE04C1E221A) Cer, (CK733F1H104Z(A5)) Cer, (CK733F1H104Z(A5)) Cer, (CK733F1H104Z(A5)) 220µF, ±20%, 25V 220µF, ±20%, 25V 0.1µF, +80/-20%, 50V 0.1µF, +80/-20%, 50V 0.1µF, +80/-20%, 50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V Cer,(CK733F1H104Z(A5)) Cer,(CK733F1H104Z(A5)) Cer,(CK733F1H104Z(A5)) Cer,(CK733F1H104Z(A5)) Cer,(CK733F1H104Z(A5)) C 6 C 7 C 8 C 9 C 10 Cer, (CK733F1H104Z(A5)) Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4)) Cer, (CK733F1H104Z(A5)) Cer, (CC732CH1H180J(G1)) C 11 C 12 C 13 C 14 C 15 0.1µF,+80/-20%,50V 0.01µF,±10%,50V 0.01µF,±10%,50V 0.1µF,+80/-20%,50V 18pF,±5%,50V Cer,(CC732CH1H220J(J1)) 22pF,:5%,50V Cer,(CC732CH1H221J(J2)) 220pF,:5%,50V Cer,(CC732CH1H331J(N2)) 330pF,:5%,50V Cer,(CC7332H1H02J(A5)) 0.1µ+80/-20%,50V Cer,(CC733CH1H102J(A3)) 1000pF,:5%,50V C 16 C 17 C 18 C 19 C 20 Tant, (CS732E1V105M) Elect, (CE04C1A101A) Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4)) Not assigned 1µF,±20%,35V 100µF,±20%,10V 0.01µF,±10%,50V 0.01µF,±10%,50V Cer,(CC732CH1H221J(J2)) Cer,(CC732CH1H221J(J2)) Cer,(CC732CH1H3300(N1)) Cer,(CC733CH1H102J(A3)) Cer,(CC733CH1H102J(A3)) C 26 C 27 C 28 C 29 C 30 Plast, (ECQ-P1474F2) Cer, (CC732CH1H100D(A1)) Elect, (CE04C1H100A) Elect, (CE04C1H100A) Cer, (CC924CH1H102J) 0.47µF,±1%,100V 10pF,±0.5pF,50V 10µF,±20%,50V 10µF,±20%,50V 1000pF,±5%,50V 33µF,±20%,35V 1000pF,±10%,50V 0.01µF,±10%,50V 5pF,±0.5pF,50V 220µF,±20%,25V Elect, (CE04C1V330A)
Cer, (CK732B1H102K(A3))
Cer, (CK732B1H103K(A4))
Cer, (CC732CH1H050D(f0))
Elect, (CE04C1E221A) C 36 C 37 C 38 C 39 C 40 Elect, (CE04C1E221A) Elect, (CE04C1E221A) Elect, (CE04C1E221A) Cer, (CK737B1H224K(1J5)) Cer, (CK733F1H104Z(AS)) 220µF, ±20%, 25V 220µF, ±20%, 25V 220µF, ±20%, 25V 0.22µF, ±10%, 50V 0.1µF, +80/-20%, 50V C 46 Cer, (CK732B1H103K(A4)) Cer, (CK733F1H104Z(A5)) 0.01µF,±10%,50V 0.1µF,+80/-20%,50V

( ): Manufacturer's part number

\* : Selected at factory

34W93319 1/9

CKT	DESCRIPTION	RATING	NOTE
REF	-200	A.T.IIIG	HOTE
C 48	Elect, (CE04C1J101A)	100µF, ±20%,63V	
C 49	Elect, (CE04C1A471A)	470µF, ±20%,10V	
C 50	Cer, (CK734B1H104K(1A5))	0.1µF, ±10%,50V	
C 51	Elect, (CE04C1A471A)	470µF, ±20%,10V	
C 52	Cer, (CK732B1H102K(A3))	1000pF, ±10%,50V	
C 53	Cer,(CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 54	Cer,(CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 55	Cer,(CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 56	Cer,(CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 57	Cer,(CK733F1H104Z(A5))	1000pF,:5%,50V	
C 58 C 59 C 60 C 61 C 62	Not assigned Tant, (CS732E1V105M) Elect, (CE04C1E221A) Elect, (CE04C1E221A) Elect, (CE04C1E221A)	1µF,±20%,35V 220µF,±20%,25V 220µF,±20%,25V 220µF,±20%,25V	
C 63	Elect, (CE04C1E221A)	220µF,±20%,25V	
C 64	Cer, (CK733F1H104Z(AS))	0.1µF,+80/-20%,50V	
C 65	Elect, (CE04C1V330A)	33µF,±20%,35V	
C 66	Elect, (CE04C1A471A)	470µF,±20%,10V	
C 67	Cer, (CC732CH1H150J(E1))	15pF,±5%,50V	
C 68	Cer, (CC732CH1H150J(E1))	15pF,:5%,50V	
C 69	Cer, (CK732B1H102K(A3))	1000pF,:10%,50V	
C 70	Cer, (CK732B1H102K(A3))	1000pF,:10%,50V	
C 71	Cer, (CK733F1H104Z(A3))	0.1µF,+80/-20%,50V	
C 72	Cer, (CC732CH1H330J(N1))	33pF,:0.5pF,50V	
C 73	Cer,(CC732CH1H151J(E2))	150pF,±5%,50V	
C 74	Cer,(CK733F1H104Z(AS))	0.1µF,+80/-20%,50V	
C 75	Cer,(CK733F1H104Z(AS))	0.1µF,+80/-20%,50V	
C 76	Elect,(CE04C1H101A)	100µF,±20%,50V	
C 77	Cer,(CK733F1H104Z(AS))	0.1µF,+80/-20%,50V	
C 78	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 79	Cer, (CC732CH1H471J(S2))	470pF,±5%,50V	
C 80	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 81	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 82	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 83	Cer, (CC732CH1H100D(A1))	10pF, ±0.5pF, 50V	
C 84	Cer, (CK733F1H104Z(A5))	0.1µF, +80/-20%, 50V	
C 85	Cer, (CK733F1H104Z(A5))	0.1µF, +80/-20%, 50V	
C 86	Cer, (CK733F1H104Z(A5))	0.1µF, +80/-20%, 50V	
C 87	Cer, (CC732CH1H22OJ(J1))	22pF, ±0.5pF, 50V	
J 1 J 2 J 3	Connector, (27DP-LR-PC) Connector, (DIN41612-64FB) Connector, (008261-033311-852)		

CKT REF	DESCRIPTION	RATING	NOTE
J 4	Connector, (008261-024200-870)		
K 1	Relay,(SV-12)		
L 1 L 2 L 3 L 4 L 5	Coi1, (FS1012-152K) Coi1, (NL453232-471K) Coi1, (NL453232-101K) Coi1, (NL453232-101K) Coi1, (NL453232-221K)	1.5mH 470µН 100µН 100µН 220µН	
L 6 L 7 J. 8 L 9 L 10	Coil, (LF8-101K) Coil, (NL453232-101K) Coil, (LF8-101K) Coil, (LF8-101K) Coil, (LF8-101K)	100µН 100µН 100µН 100µН 100µН	
L 11 L 12 L 13	Coil, (NL453232-101K) Coil, (NL453232-101K) Coil, (NL453232-101K)	100µH 100µH 100µH	
Q 1 Q 2 Q 3 Q 4 Q 5	Di,(1S2835(A3)) Tr,(2SA812(M5 OR M6)) Tr,(2SC2351(R2 OR R3)) Tr,(2SC2351(R2 OR R3)) Tr,(2SC1623(L5 OR R6))		
Q 6 Q 7 Q 8 Q 9 Q 10	Di,(15S97) Di,(1SS97) IC,(µPC4570C) Not assigned Tr,(25C1623(L5 OR L6))		
Q 11 Q 12 Q 13 Q 14 Q 15	IC, (µPC803C) IC, (TC4053BP) IC, (TC4053BP) IC, (T4HC574) IC, (74HC574)		
Q 16 Q 17 Q 18 Q 19 Q 20	Di,breakdown, (RD6.2MB2(622)) Tr,(2SA812(M5 OR M6)) Tr,(2SC1623(L5 OR L6)) Di,(1S2835(A3)) Not assigned	6.0 to 6.39V,200mW	
Q 21 Q 22 Q 23	Not assigned Tr,(2SC1623(L5 OR L6)) IC,(74HC00)		

\* : Selected at factory

34W93319 2/9

( ): Manufacturer's part number

\* : Selected at factory

34W93319 3/9

Parts List: /	۸3,	ΙF	LOG/	DE
---------------	-----	----	------	----

CKT REF	DESCRIPTION	RATING	NOTE
Q 24 Q 25 Q 26 Q 27 Q 28	IC,(uPD71054C) IC,(74HC00) IC,(uPD71054C) Not assigned Tr,(2SC1623(L5 OR L6))		
Q 29 Q 30 Q 31 Q 32 Q 33	IC, (CA3130T) Di, (1SS149H) IC, (LF356N) Not assigned IC, (µPC803C)		
G 34 Q 35 Q 36 Q 37 Q 38	Tr,(upA38A) Di,(1S2835(A3)) IC,(upC4570C) IC,(TC4066BP) IC,(upC803C)		
Q 39 Q 40 Q 41 Q 42 Q 43	Di,(1SS97) Di,(1SS149H) Not assigned IC,(TC4053BP) IC,(µPC803C)		
Q 44 Q 45 Q 46 Q 47 Q 48	IC,(µPC649C) IC,(74HC04) IC,(74HC04) Di,(152835(A3)) IC,(HI-574AKD-5)		
Q 49 Q 50 Q 51 Q 52	Tr, (2SC3735(B34 OR B35)) IC,(74S196) IC,(74LS290) IC,(74HC74)		
Q 53 Q 54 Q 55 Q 56 Q 57	Di,breakdown,(15250) IC,(NE5534A) Not assigned IC,(µPD5201C) IC,(µPD5201C)	5.9 to 6.5V,250mW	
Q 58 Q 59 Q 60 Q 61 Q 62	IC,(µPD5201C) Not assigned IC,(74HC574) IC,(74HC574) Not assigned		
Q 63 Q 64 Q 65 Q 66 Q 67	1C,(µPC259C) IC,(µPC259C) IC,(74HC86) Not assigned Tr,(2SC1623(L5 OR L6))		
Q 68 Q 69	Tr,(2SC1623(L5 OR L6)) Tr,(2SA812(M5 OR M6))		

Parts List: A3, IF LOG/DET

CKT DESCRIPTION RATING NOTE Q 70 IC,(µPC4570C) Q 71 IC,(TC40H000P) Q 72 IC,(µPD5201C) Q 73 Not assigned Q 74 Di,(1SS97) Di, (1SS149H) IC, (µPC803C) IC, (TC4052BP) Di, (1SS97) Di, (1SS97) Q 75 Q 76 Q 77 Q 78 Q 79 IC, (TC74HC123P)
IC, (74HC08)
IC, (NE5534A)
IC, (NE5534A)
IC, (NE5534A) Q 80 Q 81 Q 82 Q 83 Q 84 Tr,(2SA812(M5 OR M6))
Di,breakdown,(1S252)
IC,(upc251C)
Tr,(2SC1623(L5 OR L6))
Tr,(2SC1623(L5 OR L6)) Q 85 Q 86 Q 87 Q 88 Q 89 5.9 to 6.5V,250mW Not assigned Di,breakdown, (RD3.9MB(39 )) Q 90 Q 91 3.7 to 4.1V,200mW CM, (RM73B2B822JD) CM, (RM73B2B123JD) Not assigned CM, (RM73B2B181JD) Var,MF, (RJ-6S 100Ω) 8.2kΩ,±5%,1/8W 12kΩ,±5%,1/8W 150Ω,±5%,1/8W 560Ω,±5%,1/8W 6.8kΩ,±5%,1/8W 5.6kΩ,±5%,1/8W 1.0kΩ,±5%,1/8W CM, (RM73B2B151JD) CM, (RM73B2B561JD) CM, (RM73B2B682JD) CM, (RM73B2B562JD) CM, (RM73B2B102JD) R 6 R 7 R 8 R 9 R 10 6.8kΩ,±5%,1/8W 3.3kΩ,±5%,1/8W 2.7kΩ,±5%,1/8W 820Ω,±5%,1/8W 470Ω,±5%,1/8W CM, (RM73B2B682JD) CM, (RM73B2B332JD) CM, (RM73B2B272JD) CM, (RM73B2B821JD) CM, (RM73B2B871JD) R 11 R 12 R 13 R 14 R 15 CM, (RM73B2B471JD) CM, (RM73B2B181JD) CM, (RM73B2B472JD) CM, (RM73B2B472JD) CM, (RM73B2B562JD) 470Ω,±5%,1/8W 180Ω,±5%,1/8W 4.7kΩ,±5%,1/8W 4.7kΩ,±5%,1/8W 5.6kΩ,±5%,1/8W R 21 CM, (RM73B2B822JD) R 22 Var, MF, (RJ-6S 5KΩ) 8.2kΩ,±5%,1/8W 5.0kΩ,1/2W

( ): Manufacturer's part number

\* : Selected at factory

34W93319 4/9

( ): Manufacturer's part number

\* : Selected at factory

34W93319 5/9

CKT			
REF	DESCRIPTION	RATING	NOTE
	1		
R 23	CM, (RM73B2B102JD)	1.0kn,±5%,1/8W	
R 24	CM, (RM73B2B122JD)	1.2kn,±5%,1/8W	1
R 25	CM, (RM73B2B153JD)	15kΩ,±5%,1/8W	
R 26	CM, (RM73B2B104JD)	100kΩ,±5%,1/8W	
R 27	Not assigned		
R 28	Not assigned		
R 29	Not assigned	1	
R 30	Not assigned		
R 31	CM, (RM73B2B122JD)	1.2kΩ,±5%,1/8W	
R 32	CM, (RM73B2B102JD)	1.0kΩ, ±5%, 1/8W	
		,,	
R 33	CM, (RM73B2B102JD)	1.0kn,±5%,1/8W	
R 34	CM, (RM73B2B391JD)	390Ω,±5%,1/8W	
k 35	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
R 36	Not assigned		
R 37	Not assigned	(E)	
R 38	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
R 39	CM, (RM73B2B561JD)	560Ω,±5%,1/8₩	
R 40	CM, (RM73B2B562JD)	5.6kΩ,±5%,1/8W	
R 41	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
R 42	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
		,	
R 43	Var,MF, (RJ-6S 500Ω)	500Ω,1/2W	
R 44	Not assigned		
R 45	CM, (RM73B2B223JD)	22kΩ,±5%,1/8W	
R 46	CM, (RM73B2B102JD)	1.0kn,±5%,1/8W	
R 47	Var,MF, (RJ-6S 1KΩ)	1.0kΩ,1/2W	
R 48	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	1
R 49	CM, (RM73B2B222JD)	2.2kΩ,±5%,1/8W	
R 50	CM, (RM73B2B223JD)	22kΩ, ±5%, 1/8W	
R 51	CM, (RM73B2B681JD)	680Ω,±5%,1/8W	
R 52	CM, (RM73B2B681JD)	680Ω,±5%,1/8W	
R 53	CM, (RM73B2B681JD)	6000 .50 1/00	
R 54	CM, (RM73B2B1813D)	680Ω,±5%,1/8W 100kΩ,±5%,1/8W	
R 55	CM, (RM73B2B1043D)	2.2kΩ,±5%,1/8W	
R 56	CF, (ARD25T154J)	150kΩ,±5%,1/4W	
R 57	CF, (ARD2511543)	680kΩ,±58,1/4W	l î
,,	0., (	000,11,238,1/4#	1 -
R 58	CM, (RM73B2B332JD)	3.3kΩ,±5%,1/8W	
R 59	CM, (RM73B2B473JD)	47kΩ,±5%,1/8W	
R 60	CM, (RM73B2B333JD)	33kΩ,±5%,1/8W	ſ
R 61	CF, (ARD25T103J)	10kΩ, ±5%, 1/4W	•
R 62	Var,MF, (RJ-6S 10KΩ)	10kΩ,1/2W	
R 63	Var,MF, (RJ-6S 20KΩ)	20kΩ,1/2W	
R 64	CM, (RM73B2B472JD)	4.7kΩ,±5%,1/8W	
R 65	CM, (RM73B2B222JD)	2.2kΩ,±5%,1/8W	
R 66	CM, (RM73B2B2223D)	1.0kΩ,±5%,1/8W	
R 67	CM, (RM73B2B222JD)	2.2kΩ,±58,1/8W	
R 68	Var,MF, (RJ-6S 500KΩ)	500kΩ,1/2W	
R 69	CM, (RM73B2B224JD)	220kΩ,±5%,1/8W	1

CKT	DESCRIPTION	RATING	NOTE
REF	DESCRIPTION	KATING	NOTE
. 70	WT (1771 (D (0037754)	500 50 1/00	
R 70	MF, (LP1/8 68nJT54)	68Ω,±5%,1/8W	
R 71	CM, (RM73B2B681JD)	680Ω,±5%,1/8W	
R 72	CM, (RM73B2B820JD)	82Ω,±5%,1/8W	1
R 73	CM, (RM73B2B471JD)	470Ω,±5%,1/8W	1
R 74	Var,MF,(RJ-6S 1KΩ)	1.0kΩ,1/2W	
R 75	CM, (RM73B2B222JD)	2.2kΩ,±5%,1/8W	
R 76	CF, (ARD25T273J)	27kΩ,±5%,1/4W	*
R 77	CM, (RM73B2B182JD)	1.8kΩ,±5%,1/8W	
R 78	CF, (ARD25T822J)	8.2kΩ,±5%,1/4W	•
R 79	CF, (ARD25T822J)	8.2kΩ,±5%,1/4W	
R 80	CF, (ARD25T273J)	27kΩ,±5%,1/4W	
R 81	CM, (RM73B2B182JD)	1.8kΩ,±5%,1/8W	
R 82	CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8W	1
R 83	CM, (RM73B2B683JD)	68kΩ,±5%,1/8W	I
R 84	Var,MF, (RJ-6S 20KΩ)	20kΩ,1/2W	İ
R 85	CM, (RM73B2B821JD)	820Ω,±5%,1/8W	
R 86	Var, MF, (RJ-6S 500Ω)	500Ω,1/2W	
R 87	CM, (RM73B2B103JD)	10kΩ, ±5%, 1/8W	
R 88	Not assigned	10811,134,17611	
R 89	CM, (RM73B2B105JD)	1MΩ,±5%,1/8W	l
	(141, 352510355)	1,130,1,0	
R 90	Not assigned		
R 91	Not assigned		
R 92	CM, (RM73B2B681JD)	680Ω,±5%,1/8W	
R 93	CM, (RM73B2B472JD)	4.7kΩ,±5%,1/8W	
R 94	CM, (RM73B2B101JD)	100Ω,±5%,1/8W	
R 95	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
R 96	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
R 97	CM, (RM73B2B272JD)	2.7kn,±5%,1/8W	
R 98	Var,MF, (RJ-6S 500Ω)	500Ω,1/2W	
R 99	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
0100	CM (PM72P2PE10YD)	510 +59 1 (9W	
R100 R101	CM, (RM73B2B510JD) CM, (RM73B2B472JD)	51Ω,±5%,1/8W 4.7kΩ,±5%,1/8W	
R101		1.2kΩ,±5%,1/8W	
	CM, (RM73B2B122JD)		
R103 R104	CM, (RM73B2B561JD)	560Ω,±5%,1/8W 470Ω,±5%,1/8W	
K104	CM, (RM73B2B471JD)	7/01/130/1/04	
R105	CM, (RM73B2B103JD)	10kΩ,±5%,1/8W	
R106	Var,MF, (RJ-6S 5KΩ)	5.0kΩ,1/2W	
R107	MF, (RN14K2E4320D)	432Ω,±0.5%,1/4W	
R108	MF, (RN14K2E4220D)	4220,±0.5%,1/4W	
R109	MF, (RN14K2E3570D)	357Ω,±0.5%,1/4W	
R110	MF, (RN14K2E3241D)	3.24kΩ,±0.5%,1/4W	
R111	MF, (RN14K2E1431D)	1.43kΩ,±0.5%,1/4W	
R112	MF, (RN14K2E1001D)	1.00kΩ,±0.5%,1/4W	1
R113	MF, (RN14K2E6340D)	634Ω,±0.5%,1/4W	
R114	MF, (RN14K2E1051D)	1.05k\O,±0.5%,1/4W	
D115	WE (PW) 47253(515)	3 6510 +0 59 1/49	
R115	MF, (RN14K2E3651D)	3.65kΩ,±0.5%,1/4W	
R116	MF, (RN14K2E5760D)	576Ω,±0.5%,1/4W	

: Selected at factory

DESCRIPTION

REF

34W93319 6/9

NOTE

( ): Manufacturer's part number \* : Selected at factory

34w93319 7/9

Parts List: A3, IF LOG/DET

RATING

R117	MF, (RN14K2E40R2D)	40.2Ω,±0.5%,1/4W		
R118	CM, (RM73B2B821JD)	820Ω,±5%,1/8W		
R119	CM, (RM73B2B391JD)	390Ω,±5%,1/8W	!	
R120	CM, (RM73B2B151JD)	150Ω, ±5%, 1/8W		
R121	CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8W		
			}	
R122	CM, (RM73B2B473JD)	47kΩ,±5%,1/8W	:	
R123	CM, (RM73B2B331JD)	330Ω,±5%,1/8W		
R124	CM, (RM73B2B224JD)	220kΩ,±5%,1/8W		
R125	Not assigned			
R126	Not assigned			
1				
R127	Not assigned	!		
R128	CM, (RM73B2B332JD)	' 3.3kΩ,±5%,1/8W		
R1 29	CM, (RM73B2B332JD)	3.3kΩ,±5%,1/8W		
R130	CM, (RM73B2B332JD)	3.3kΩ,±5%,1/8W		
R131	CM, (RM73B2B332JD)	3.3kΩ,±5%,1/8W	:	i
R132	CM, (RM73B2B822JD)	8.2kn,±5%,1/8W	i	
R133	CM, (RM73B2B122JD)	1.2kΩ,±5%,1/8W		
R134	CM, (RM73B2B122JD)	1.2kΩ, ±5%,1/8W		
R1 3 5	CM, (RM73B2B152JD)	1.5kΩ,±5%,1/8W		
R136	CM, (RM73B2B562JD)	5.6kΩ,±5%,1/8W	!	
			ļ	
R137	CM, (RM73B2B391JD)	390Ω, ±5%, 1/8W		
R138	CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8W	;	
R139	CM, (RM73B2B221JD)	2200, ±5%, 1/8W	!	i e
R140	CM, (RM73B2B331JD)	330Ω,±5%,1/8W		
R141	CM, (RM73B2B472JD)	4.7kn,±5%,1/8W	i	
	i .		:	
R142	CM, (RM73B2B271JD)	270Ω,±5%,1/8W		
R143	CF, (ARD25T104J)	100kΩ,±58,1/4W	i	•
R144	CM, (RM73B2B182JD)	1.8kΩ,±5%,1/8W	ŀ	i
R145	MF, (LP1/8 470ΩJT51)	470Ω,±5%,1/8W		ļ
R146	Not assigned		i	ĺ
1			i	ļ
R147	CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8W	i	İ
R148	CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8W	i	Į.
R149	CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8W	I	ļ
R150	Var,MF, (RJ-6S 20KΩ)	20kΩ,1/2W	1	1
RI51	CM, (RM73B2B683JD)	68kΩ,±5%,1/8W		
1			i	I

820Ω,±5%,1/8W 500Ω,1/2W 10kΩ,±5%,1/8W 1MΩ, ±5%, 1/8W

680Ω,±5%,1/8W

100Ω,±5%,1/8W

R164 R165 R166 R167 R168 R169 R170 R171 R172 R173 R174 R175 R176 R177 R178 R179 R180 R181 R182 R183 R184 R185 R186 Z 1 Z 2 Z 3 Z 4

Parts List: A3, IF LOG/DET CKT DESCRIPTION RATING NOTE REF CM, (RM73B2B102JD) CM, (RM73B2B102JD) CM, (RM73B2B103JD) CM, (RM73B2B103JD) CM, (RM73B2B103JD) CM, (RM73B2B103JD) 1.0kΩ,±5%,1/8W 1.0kΩ,±5%,1/8W 10kΩ,±5%,1/8W 10kΩ,±5%,1/8W 10kΩ,±5%,1/8W 10 kΩ, ±5%, 1/8W 47Ω, ±5%, 1/8W 69.8Ω, ±0.5%, 1/4W 680Ω, ±5%, 1/8W 2.7kΩ, ±5%, 1/8W CM, (RM73B2B103JD) CM, (RM73B2B470JD) MF, (RM14K2E69R8D) CM, (RM73B2B681JD) CM, (RM73B2B272JD) CM, (RM73B2B122JD) CM, (RM73B2B563JD) CM, (RM73B2B822JD) CM, (RM73B2B332JD) CM, (RM73B2B101JD) 1.2kΩ,±5%,1/8W 56kΩ,±5%,1/8W 8.2kΩ,±5%,1/8W 3.3kΩ,±5%,1/8W 100Ω,±5%,1/8W 10kΩ,±5%,1/8W 10kΩ,±5%,1/8W 2.2kΩ,±5%,1/8W 6.8kΩ,±5%,1/8W 2.2kΩ,±5%,1/8W CM, (RM73B2B682JD) CM, (RM73B2B102JD) CM, (RM73B2B181JD) 6.8kΩ,±5%,1/8W 1.0kΩ,±5%,1/8W 180Ω,±5%,1/8W IC, (UH5)
IC, (MT07(A))
IC, (MT07(B))
IC, (MT07(C))

( ): Manufacturer's part number

\* : Selected at factory

CM, (RM73B2B821JD) Var,MF, (RJ-6S 500Ω) CM, (RM73B2B103JD) Not assigned CM, (RM73B2B105JD)

Not assigned Not assigned CM, (RM73B2B681JD) Not assigned Not assigned

R162 Not assigned R163 CM, (RM73B2B101JD)

R157 R158 R159 R160 R161

34W93319 8/9

( ): Manufacturer's part number

. Selected at factory

34W93319 9/9

Parts List: A5, PRONT BOARD

RATING

220Ω,±5%,1/4W 220Ω,±5%,1/4W 220Ω,±5%,1/4W 47kΩ,±5%,1/4W 100kΩ,±10%,1/2W

270Ω,±5%,1/4W

NOTE

CKT	DESCRIPTION	RATING	NOTE
REF	DESCRIPTION	AATING	NOTE
В 1	Buzzer, (KMB-06)		i
C 1	Cer,(CK924F1H104Z)	0.1µF,+80/-20%,50V	
C 2 C 3	Cer, (CK924F1H104Z) Cer, (CK924F1H104Z)	0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V	7 1
C 4	Cer, (CK924F1H104Z)	0.1µF,+80/-20%,50V	
C 5	Elect, (CE04C1E470A)	47µF,±20%,25V	
C 6	Tant, (CS-E1A4R7M)	4.7uF, ±208,10V	
C 7	Cer, (CK924F1H104Z) Cer, (CK924F1H104Z)	0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V	
C 9	Cer, (CK924F1H104Z)	0.1µF,+80/-20%,50V	
C 10	Cer, (CK924F1H1042)	0.1µF,+80/-20%,50V	
C 11 C 12	Cer, (CK924F1H104Z)	0.1µF,+80/-20%,50V	
C 13	Cer, (CK924F1H104Z) Cer, (CK924F1H104Z)	0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V	
C 14	Cer, (CK924F1H104Z)	0.1µF,+80/-20%,50V	1
C 15	Cer, (CK924F1H104Z)	0.1µF,+80/-20%,50V	
J 1	Connector,		
J 2	(CNF3-30P-2.54DSA) Plug, (DF1-8P2.5DSA)		
_	1		
0 1	IC,(µPD8279C-2)		1
Q 1 Q 2	Not assigned		
Q 3 O 4	IC, (74HCT138)		
Q 4 Q 5	IC, (74HC14) IC, (74HC74)		
Q 6	IC, (74HCT541)		
Q 7	IC, (74HC02)		1
Q 8 Q 9	IC, (74HCT574) IC, (74HCT138)	1	
Q 10	LED, (LN342GPH)		
Q 11	IC, (TC74HC123P)		
R 1	CF, (ARD25T103J)	10kΩ,±5%,1/4W	1
R 2	Not assigned		
R 3 R 4	Not assigned CF,(ARD25T103J)	10kΩ,±5%,1/4W	
R 5	CF, (ARD25T103J)	10kΩ,±5%,1/4W	

8		Parts Li
	CKT	DESCRIPTION
7	REF	
	R 6 R 7 R 8 R 9 R 10	CF, (ARD25T221J) CF, (ARD25T221J) CF, (ARD25T221J) CF, (ARD25T2721J) CF, (ARD25T473J) VAL, MF (RG161P15SB100KRM) CF, (ARD25T271J)
	S 1 to S 32 S 33 S 34	Key switch (HL20-NS) Key switch, (HL20-LSYG) Key switch, (HL20-NS)
	S 35 S 36 S 37 S 38 S 39	Key switch, (HL20-NS) Key switch, (HL20-NS) Key switch, (HL20-NS) Key switch, (HL20-NS) Key switch, (HL20-NS)
	S 40	Key switch, (HL20-NS)
	z 1 z 2	Rotary encoder, (EC201E050-23.5R) Oscillator, (EXO-3C-16MHz)
		( ): Manufact

34W93320 1/2

( ): Manufacturer's part number
\* : Selected at factory

Manufacturer's part number

\* : Selected at factory

34W93320 2/2

Parts	List:	Α6,	SCAN/YTO	DRIV

	Parts List	: A6, SCAN/YTO DRIVE	10
CKT REF	DESCRIPTION	RATING	NOTE
C 1	Cer, (CK732B1H103K(A4))	0.01µF, ±10%,50V	
C 2	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 3	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 4	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 5	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 6	Plast, (ECQ-V1H474JW)	0.47µF,±5%,50V	
C 7	Plast, (ECQ-V1H105JW)	1µF,±5%,50V	
C 8	Plast, (ECQ-V1H105JW)	1µF,±5%,50V	
C 9	Plast, (ECQ-V1H473JW)	0.047µF,±5%,50V	
C 10	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 11	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 12	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 13	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 14	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 15	Cer, (CK732B1H22ZK(J3))	2200pF,±10%,50V	
C 16	Cer,(CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 17	Elect,(CE04C1E101A)	100µF,±20%,25V	
C 18	Elect,(CE04C1E101A)	100µF,±20%,25V	
C 19	Elect,(CE04C1E101A)	100µF,±20%,25V	
C 20	Cer,(CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 21 C 22 C 23 C 24 C 25	Elect, (CE04C1E101A) Not assigned Not assigned Cer, (CK732B1H103K(A4)) Cer, (CK733F1H104Z(A5))	100µF,±20%,25V 0.01µF,±10%,50V 0.1µF,+80/-20%,50V	
C 26	Cer,(CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 27	Cer,(CK732B1H103K(A4))	0.01µF,±10%,50V	
C 28	Cer,(CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 29	Cer,(CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 30	Cer,(CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 31	Cer,(CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 32	Cer,(CC732CH1H101J(A2))	100pF,±5%,50V	
C 33	Cer,(CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 34	Cer,(CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	
C 35	Tant,(CS734E1C2Z6M)	22µF,±20%,16V	
C 36 C 37 C 38 C 39 C 40	Tant, (CS734E1C226M) Cer, (CK732B1H472K(S3)) Cer, (CK733F1H104Z(A5)) Cer, (CK733F1H104Z(A5)) Cer, (CK733F1H104Z(A5))	22µF,:20%,16V 4700pF,:10%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 1000pF,:10%,50V	
C 41	Cer,(CK733F1H1042(A5))	0.1µF,+80/-20%,50V	
C 42	Cer,(CK733F1H1042(A5))	0.1µF,+80/-20%,50V	
C 43	Cer,(CK733F1H1042(A5))	0.1µF,+80/-20%,50V	
C 44	Cer,(CK733F1H1042(A5))	0.1µF,+80/-20%,50V	
C 45	Cer,(CK733F1H1042(A5))	0.1µF,+80/-20%,50V	
C 46	Cer, (CK732B1H102K(A3))	1000pF, ±10%,50V	
C 47	Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V	

34W93321 1/8

Parts List: A6, SCAN/YTO DRIVE

CVT		CT 1107 DEAN/TTO DICT	
REF	DESCRIPTION	R A TING	NOTE
C 48 C 49 C 50 C 51	Cer, (CK733F1H104z(A5)) Cer, (CK733F1H104z(A5)) Cer, (CK733F1H104z(A5)) Cer, (CK732B1H104z(A4))	0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.01µF,±20%,50V	
C 52	Elect, (CE04C1E470A)	47µF,±20%,25V	.
C 54 C 55 C 56 C 57	Elect, (CE04C1E101A) Cer, (CK733F1H1042 (A5)) Elect, (CS734E1C226M) Plast, (ECQ-V1H474JW) Cer, (CK732B1H103K(A4))	100µF,±20%,25V 0.1µF,+80/-20%,50V 22µF,±20%,16V 0.47µF,±5%,50V 0.01µF,±10%,50V	
C 58 C 59 C 60 C 61 C 62	Elect, (CS734E1C226M) Elect, (CS734E1V475M) Elect, (CE04C1C471A) Cer, (CK732B1H103K(A4)) Plast, (CF922N2A224K)	22µF,±20%,16V 4.7µF,±20%,35V 470µF,±20%,16V 0.01µF,±10%,50V 0.22µF,±10%,100V	
C 63 C 64 C 65 C 66 C 67	Elect, (CE04C1C471A) Cer, (CK733F1H104Z(A5)) Cer, (CC732CH1H471J(S2)) Cer, (CK732B1H472K(S3)) Cer, (CK732B1H472K(S3))	470µF,±20%,16V 0.1µF,+80/-20%,50V	
C 70 C 71	Cer, (CK732B1H222K(J3)) Elect, (CE04C1H100A) Elect, (CS734E1C226M) Cer, (CK733F1H104Z(A5)) Cer, (CK733F1H104Z(A5))	2200pF, ±10%,50V 10pF, ±20%,25V 22µF, ±20%,16V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V	
C 74 C 75 C 76	Cer, (CC732CH1H221 (J2)) Cer, (CK733F1H104Z (A5)) Cer, (CK733F1H104Z (A5)) Cer, (CK733F1H104Z (A5)) Elect, (CE04C1E101A)	220pF, ±5%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 100µF,±20%,25V	
C 80 C 81	Elect,(CE04C1E101A) Elect,(CE04C1E101A) Plast,(CE04C1E101A) Plast,(CE04C1C331A) Cer,(CK924C1H103M)	100µF,±20%,25V 100µF,±20%,25V 1µF,±5%,50V 330µF,±20%,16V 0.01µF,±20%,50V	
C 84 C 85 C 86	Plast,(ECQ-V1H105JW) Cer,(CC732CH1H221J(J2)) Cer,(CK733F1H104Z(A5)) Cer,(CK732B1H102K(A3)) Cer,(CK732B1H102K(A3))	1.0µF,±5%,50V 220pF,±5%,50V 0.1µF,+80/-20%,50V 1000pF,±10%,50V 1000pF,±10%,50V	
C 89 C 90 C 91	Cer,(CK732B1H102K(A3)) Not assigned Cer,(CK733F1H104Z(A5)) Tant,(CS734E1C226M) Tant,(CS734E1C226M)	1000pF,±10%,50V 0.1µF,+80/-20%,50V 22µF,±20%,50V 22µF,±20%,50V	
	Cer,(CC924CH1H681J) Plast,(ECQ-V1H105JW)	680pF,±5%,50V 1.0µF,±5%,50V	

( ): Manufacturer's part number

\* : Selected at factory

( ): Manufacturer's part number
\* : Selected at factory

34W93321 2/8

CKT REF	DESCRIPTION	RATING	NOTE
C 95	Plast, (CF922N2A225K)	2.2µF,±10%,100V	
J 1 J 2 J 3 J 4 J 5 J 6 J 7	Connector, (DIN41612-64PB) Plug, (DF1-5P2.5DS) Connector, (27DF-LR-PC) Plug, (DF18-10P-2.5DS) Connector, (008261-033311-852) Connector, (008261-024200-870) Plug, (DF1-2P-2.5DS)	64pins 5pins 10pins 3pins 2pins 2pins	
K 1 K 2 K 3	Relay,(SV-12) Lead relay,(DIP-5V) Lead relay,(DIP-5V)		
L 1 L 2 L 3 L 4 L 5	Coil, (LF8-100K) Coil, (LF8-100K) Coil, (LF8-100K) Coil, (LF8-100K) Coil, (LF8-100K) Coil, (LF8-100K)	10 uH 10 uH 10 uH 10 uH 10 uH	
Q 1 Q 2 Q 3 Q 4 Q 5	IC, (74HCT574) IC, (µPC624C) IC, (µPC6570C) IC, (TC4053BP) IC, (TC4053BP)		
Q 6 Q 7 Q 8 Q 9	IC, (LF356N)' IC, (µPC4570C) Di, breakdown, (RD5.1MB2(512)) Di, breakdown, (RD5.1MB2(512))	4.97 to 5.24V,200mW 4.97 to 5.24V,200mW	
Q 10 Q 11 Q 12 Q 13 Q 14	IC, (74LS05) Di, (1S2835(A3)) Di, breakdown, (1S252) IC, (µPC4570C) Not assigned	5.9 to 6.5V,250mW	
0 15 0 16	Not assigned Tr, (2SA1462(Y33 OR Y34))		

CKT REF	DESCRIPTION	RATING	NOTE
Q 17 Q 18 Q 19 Q 20 Q 21	Not assigned IC, (74HC74) IC, (74HC08) IC, (74HC00) IC, (74HC51)		
Q 22 Q 23 Q 24 Q 25 Q 26	IC,(74HCT574) IC,(74HCT574) IC,(74HCT574) Not assigned Not assigned		
Q 27 Q 28 Q 29 Q 30 Q 31	IC, (74HCT574) IC, (74HC74) IC, (µPC648C) IC, (µPC4570C) IC, (µPC4570C)		
Q 32 Q 33 Q 34 Q 35 Q 36	IC, (µPC4570C) IC, (µPC271C) IC, (74HCT574) IC, (µPC624C) IC, (µPC4570C)		
Q 37 Q 38 Q 39 Q 40 Q 41	Not assigned Not assigned IC, (74HCT574) IC, (µPC624C) IC, (µPC4570C)		
Q 42 Q 43 Q 44 Q 45 Q 46	Di,breakdown,(RD5.1EB) IC,(TC4052BP) Di,(1S5123(A7)) IC,(µPC4570C) Di,breakdown,(RD5.1EB)	4.8 to 5.4V,400mW	
Q 47 Q 48 Q 49 Q 50 Q 51	IC, (74HC74) IC, (74HC7541) IC, (74HC11) IC, (74HC1138) IC, (74HC7138)		
Q 52 Q 53 Q 54 Q 55	IC, (74HC32) IC, (74HC86) Di, (1S2835(A3)) Di, breakdown, (RD6.2MB2(622))	6.0 to 6.39V,200mW	
Q 56 Q 57 Q 58 Q 59 Q 60	Not assigned Not assigned Not assigned Not assigned Not assigned		
Q 61 Q 62	IC, (74HCT574) IC, (74HCT574)		

34W93321 3/8

( ): Manufacturer's part number

\* : Selected at factory

34W93321 4/8

Parts List: A6, SCAN/YTO DRIVE

PTION		RAT	1NG	

REF	DESCRIPTION	RATING	NOTE
Q 63 Q 64 Q 65 Q 66 Q 67	IC, (AD7541AJN) IC, (TC5020BP) IC, (TC4053BP) IC, (TC4053BP) IC, (TC4053BP) IC, (µPC4570C)		
Q 68 Q 69 Q 70 Q 71 Q 72	IC, (µPC4570C) Tr, (2SC3615) Not assigned Di,breakdown, (1SZ53) IC, (µPC4570C)	5.9 to 6.5V,250mW	
Q 73 Q 74 Q 75 Q 76 Q 77	Tr,(2SB707) Tr,(2SA1151) Tr,(2SD297) Di,(1S2222) IC,(74HC00)		
Q 78 Q 79 Q 80 Q 81 Q 82	Tr,(2SC3615) IC,(µPC4570C) IC,(µPC4570C) Not assigned Tr,(2SA1152)		
Q 83 Q 84	IC, (µPC4570C) IC, (µPC398C)		
R 1 R 2 R 3 R 4 R 5	MF, (RN14K2E4991D) MF, (RN14K2E4991D) MF, (RN14K2E6041D) MF, (RN14K2E4991D) MF, (RN14K2E4991D)	4.99kΩ,±0.5%,1/4W 4.99kΩ,±0.5%,1/4W 6.04kΩ,±0.5%,1/4W 4.99kΩ,±0.5%,1/4W 4.99kΩ,±0.5%,1/4W	
R 6 R 7 R 8 R 9 R 10	CM, (RM73B2B472JD) MF, (RN14K2E2491D) MF, (RN14K2E2491D) MF, (RN14K2E1002D) MF, (RN14K2E1003D)	4.7kΩ,±5%,1/8W 2.49kΩ,±0.5%,1/4W 2.49kΩ,±0.5%,1/4W 10.0kΩ,±0.5%,1/4W 100kΩ,±0.5%,1/4W	
R 11 R 12 R 13	MF, (RN14K2E2003D)  CM, (RM73B2B123JD)  CM, (RM73B2B101JD)	200kΩ,±0.5%,1/4W 12.0kΩ,±5%,1/8W 100Ω,±5%,1/8W	*,Q'ty 5, series
R 14	CM, (RM73B2B682JD)	6.8kΩ,±5%,1/8W	
R 15 R 16 R 17 R 18 R 19	CM, (RM73B2B102JD) CM, (RN14K2E3401D) MF, (RN14K2E8251D) CM, (RM73B2B682JD) CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8W 3.40kΩ,±0.5%,1/4W 8.25kΩ,±0.5%,1/4W 6.5kΩ,±5%,1/8W 1.0kΩ,±5%,1/8W	
R 20 R 21 R 22	CM, (RM73B2B821JD) MF, (RN14K2E1002D) Var,MF, (RJ-6P 500Ω)	820Ω,±5%,1/8W 10.0kΩ,±0.5%,1/4W 500Ω,1/2W	

( ): Manufacturer's part number

\* : Selected at factory

34W93321 5/8

Parts List: A6, SCAN/YTO DRIVE

CKT REF	DESCRIPTION	RATING	NOTE
R 23	MF, (RN14K2E3011D)	3.01kΩ,±0.5%,1/4W	
R 24	CM, (RM73B2B272JD)	2.7kΩ,±5%,1/8W	
R 25	CM, (RM73B2B472JD)	4.7kΩ,±5%,1/8W	
R 26	CM, (RM73B2B222JD)	2.2kΩ,±5%,1/8W	
R 27	CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8W	
R 28	CM. (RM73B2B103JD)	10kΩ,±5%,1/8W	
R 29	MF, (RN14K2E2001D)	2.00kΩ,±0.5%,1/4W	
R 30	MF, (RN14K2E2001D)	2.00kΩ,±0.5%,1/4W	
R 31	MF, (RN14K2E2001D)	2.00kΩ,±0.5%,1/4W	
R 32	MF, (RN14K2E2001D)	2.00kΩ,±0.5%,1/4W	
R 33	MF. (RN14K2E1051D)	1.05kn,±0.5%,1/4W	
R 34	MF, (RN14K2E1051D)	1.05kΩ,±0.5%,1/4W	i
R 35	MF, (RN14K2E4021D)	4.02kn,±0.5%,1/4W	
R 36	MF, (RN14K2E4021D)	4.02kΩ,±0.5%,1/4W	1
R 37	MF, (RN14K2E4991D)	4.99kΩ,±0.5%,1/4W	1
	\ (WATANSTADDID)	4.55811, 20.30, 1/47	
R 38	MF, (RN14K2E1001D).	1.00kΩ,±0.5%,1/4W	
R 39	MF, (RN14K2E1002D)	10.0kΩ,±0.5%,1/4W	
R 40	Var,MF, (RJ-6S 1KΩ)	1.0kΩ,1/2W	
R 41	MF, (RN14K2E1001D)	1.00kΩ,±0.5%,1/4W	į.
R 42	CM, (RM73B2B331JD)	330Ω,±5%,1/8₩	
R 43	Not assigned		İ
R 44	CM, (RM73B2B334JD)	330kΩ,±5%,1/8W	
R 45	Not assigned		
R 46	CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8W	
R 47	CF, (ARD25T102J)	1kΩ,±5%,1/4W	
R 48	Not assigned		
R 49	Not assigned	1	
R 50	Not assigned		
R 51	MF, (RN14K2E4751D)	4.75kΩ.±0.5%,1/4W	
R 52	MF, (RN14K2E4751D)	4.75kΩ,±0.5%,1/4W	
R 53	MF, (RN14K2E4421D)	4.42kΩ,±0.5%,1/4W	
R 54	MF, (RN14K2E4021D)	4.02kΩ,±0.5%,1/4W	
R 55	MF, (RN14K2E4991D)	4.99kΩ,±0.5%,1/4W	
R 56	MF, (RN14K2E5110D)	511Ω,±0.5%,1/4W	
R 57	MF, (RN14K2E43R2D)	43.2Ω,±0.5%,1/4W	
R 58	CM, (RM73B2B102JD)	1.00kΩ,±5%,1/8W	
R 59	CM, (RM73B2B103JD)	10kΩ, 25%, 1/8W	
R 60	CM, (RM73B2B102JD)	1kΩ,±5%,1/8W	
R 61	Not assigned	,,,	
R 62	Not assigned		
R 63	Not assigned		
R 64	CM, (RM73B2B104JD)	100kΩ,±5%,1/8W	
R 65			
	CM, (RM73929473JD)	47kΩ,±5%,1/8W	
R 66	CM, (RM73B2B102JD)	1.00kΩ,±5%,1/8W	
R 67	CM, (RM73B2B103JD)	10.0kΩ,±5%,1/8W	
R 68	CM, (RM73B2B103JD)	10.0kn, ±5%, 1/8W	
R 69	CM, (RM73B2B102JD)	1.00kΩ,±5%,1/8W	1

( ): Manufacturer's part number
\* : Selected at factory

34w93321 6/8

CKT	DESCRIPTION	RATING	NOTE
REF	DESCRIPTION	RATING	NOTE
R 70	CM, (RM73B2B105JD)	1MΩ, ±5%, 1/8W	
R 71	Not assigned	Init, 136,1/0H	
R 72	Not assigned		
R 73	Not assigned	1	
R 74			
K /4	Not assigned	T	
R 75	Not assigned		
R 76	Not assigned		1
R 77	Not assigned		
R 78	Not assigned	1	
R 79	Not assigned		
R 80	Not assigned		
R 81	MF, (RN05E2B1002B)	10.0kΩ,±0.1%,1/8W	
R 82	Var,MF, (RJ-6P 1KΩ)	1.0kΩ,1/2W	
R 83	MF, (RN05E2B1002B)	10.0kΩ,±0.1%,1/8W	
R 84	CM, (RM73B2B3333JD)	33kΩ,±5%,1/8W	
V 04	Cn, (151/302033300)	3300,136,1700	
R 85	CM, (RM73B2B333JD)	33kΩ,±5%,1/8W	
R 86	MF, (RN05E2B1000B)	100Ω, ±0.1%,1/8W	
R 87	MF, (RN05E2B1302B)	13kΩ,±0.1%,1/8W	
R 88	Var,MF,(RJ-6P 1KΩ)	1.0kΩ,1/2W	- 1
R 89	MF, (RN05E2B1002B)	10.0kΩ,±0.1%,1/8W	
R 90	CM, (RM73B2B681JD)	680Ω,±5%,1/8W	
R 91	CF, (ARD25T180J)	180,±5%,1/4W	
R 92	MF, (RN14K2E1002D)	10.0kΩ,±0.5%,1/4W	
R 93	CF, (ARD25T683J)	68kΩ, ±50, 1/4W	1
R 94	MF, (RN14K2E1002D)	10.0kΩ,±0.5%,1/4W	[
R 95	MF, (RN14K2E2152D)	10.050 .0.50 1/40	
R 96	MF, (RN05E2B1000B)	10.0kΩ,±0.5%,1/4W	1
R 97		100Ω,±0.1%,1/8W	
	MF, (RN05E2B3741B)	3.74kΩ,±0,1%,1/8W	1
R 98	MF, (RN05E2B6490B)	649n,±0.1%,1/8W	1
R 99	Var,MF, (RA-12P-500C)	5000,1/2W	
R100	MF, (RN05E2B5621B)	5.62kΩ,±0.1%,1/8W	ł
R101	CF, (ARD25T331J)	330Ω,±5%,1/4W	- 1
R102	MF, (RN05E2B1331B)	1.33kΩ,±0.1%,1/8W	
R103	CF, (ARD25T331J)	330Ω,±5%,1/4W	
R104	WW, (RHF-10-20.5ΩF)	5.62kΩ,±1%,10W	
R105	MF, (RN14K2H100J)	10Ω,±5%,1/2W	
R106	MF. (RN14K2H100J)	100,±50,1/2W	
R107	MF, (RN05E2B1431B)	1.43kΩ,±0.1%,1/8W	
R108	MF, (RN05E2B1001B)		
R109	CF, (ARD25T102J)	1.0kΩ,±0.1%,1/8W	
KI 0 3	Cr, (ARD25T1020)	1.0kΩ,±5%,1/4W	
R110	MF, (RN05E2B3162B)	31.6kΩ,±0.1%,1/8W	
R111	MF, (RN05E2B3162B)	31.6kΩ,±0.1%,1/8W	
R112	MF, (RN05E2B3162B)	31.6ki2,±0.1%,1/8W	
R113	MF, (RN05E2B3161B)	3.16kΩ,±0.1%,1/8W	
R114	MF, (RN14K2E1272D)	12.7kΩ,±0.5%,1/4W	
R115	MF, (RN14K2E1542D)	15.4kΩ,±0.5%,1/4W	
R116	MF, (RN05E2B3011B)	3.01kΩ,±0.1%,1/8W	
	, ,, , , , , , , , , , , , , , ,	3.014,10.10,1700	1

CKT REF	DESCRIPTION	RATING	NOTE
R117 R118 R119 R120 R121	Var, MF, (RA-12P-200C) MF, (RN05E2B3161B) MF, (RN05E2B3161B) MF, (RN14K2E3161D) Var, MF, (RA-12P-500C)	200Ω,1/2W 3.16kΩ,±0.1%,1/8W 3.16kΩ,±0.1%,1/8W 3,16kΩ,±0.5%,1/4W 500Ω,1/2W	
R122 R123 R124 R125 R126	MF, (RN05E2B3321B) MF, (RN14K2E1102D) MF, (RN14K2E6811D) MF, (RN14K2E4891D) Var, MF, (RJ-6P 2K0)	3.32kΩ,±0.1%,1/8W 11.0kΩ,±0.5%,1/4W 6.81kΩ,±0.5%,1/4W 4.99kΩ,±0.5%,1/4W 2.0kΩ,1.2W	
R127 R128 R129 R130 R131	MF, (RN14K2E4991D) MF, (RN14K2E6811D) MF, (RN14K2E6811D) MF, (RN14K2E6980D) MF, (RN14K2E5490D)	4.99kn,±0.5%,1/4W 6.81kn,±0.5%,1/4W 6.81kn,±0.5%,1/4W 698n,±0.5%,1/4W 549n,±0.5%,1/4W	
R132 R133 R134 R135 R136	MF, (RN14K2E5490D) CF, (ARD25T390J) CM, (RM73B2B333JD) CM, (RM73B2B333JD) CM, (RM73B2B305JD)	549Ω,±0.5%,1/4W 39Ω,±5%,1/4W 33kΩ,±5%,1/8W 33kΩ,±5%,1/8W 1MΩ,±5%,1/8W	
R137 R138 R139 R140 R141	CM, (RM73B2B105JD) CM, (RM73B2B334JD) CM, (RM73B2B474JD) CM, (RM73B2B474JD) MF, (RN14K2E6811D)	1MΩ,±5%,1/8W 330kΩ,±5%,1/8W 470kΩ,±5%,1/8W 470kΩ,±5%,1/8W 6.81kΩ,±0.5%,1/4W	
R142 R143	MF, (RN14K2E1332D) MF, (RN05E2B6980B)	13.3kΩ,±0.5%,1/4W 698Ω,±0.5%,1/8W	
		-	

34W93321 7/8

( ): Manufacturer's part number
\* : Selected at factory

34w93321 8/8

Parts List: A7, REF OSC

CKT REF	DESCRIPTION	RATING	NOTE
C 1 C 2 C 3 C 4 C 5	Cer. (CK733F1H104Z(A5)) Elect, (CE04C1E101A) Cer, (CK73F1H104Z(A5)) Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4))	0.1µF,+80/-20%.50V 100µF,±20%,25V 0.1µF,+80/-20%,50V 0.01µF,±10%,50V 0.01µF,±10%,50V	
C 6 C 7 C 8 C 9 C 10	Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4)) Cer, (CC733CH1H102J(A3)) Cer, (CC733CH1H102J(A3)) Cer, (CK733F1H104Z(A5))		
C 11 C 12 C 13 C 14 C 15	Cer,(CK733F1H104Z(A5)) Tant,(CS734E1C226M) Tant,(CS734E1C226M) Cer,(CC732CH1H471J(S2)) Cer,(CK732B1H103K(A4))	0.1µF,+80/-20%,50V 22µF,±20%,16V 22µF,±20%,16V 470pF,±5%,50V 0.01µF,±10%,50V	
C 16 C 17 C 18 C 19 C 20	Cer, (CK732B1H103K(A4)) Tant, (CS734E1C226M) Cer, (CC732CH1H050D(f0)) Cer, (CC732CH1H470J(S1)) Cer, (CC732CH1H470J(S1))	47pF,±5%,50V	
C 21 C 22 C 23 C 24 C 25	Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V 0.01µF,±10%,50V 0.01µF,±10%,50V 0.01µF,±10%,50V 0.01µF,±10%,50V	
C 26 C 27 C 28 C 29 C 30	Tant, (CS734E1C226M) Not assigned Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4))	22µF, ±20%, 16V 0.01µF, ±10%, 50V 0.01µF, ±10%, 50V 0.01µF, ±10%, 50V	
C 31 C 32 C 33 C 34 C 35	Cer, (CK733F1H1042(A5)) Cer, (CK733F1H1042(A5)) Elect, (CE04C1E101A) Elect, (CE04C1E101A) Not assigned	0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 100µF,±20%,25V 100µF,±20%,25V	
C 36 C 37 C 38 C 39 C 40	Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4)) Not assigned Cer, (CK732B1H103K(A4)) Cer, (CK732B1H103K(A4))	0.01µF,±10%,50V 0.01µF,±10%,50V 0.01µF,±10%,50V 0.01µF,±10%,50V	
C 41 C 42 C 43 to C 58	Cer,(CK732BiH103K(A4)) Not assigned Cer,(CK732BiH103K(A4))	0.01µF,±10%,50V	
C 59 C 60	Not assigned Elect, (CE04C1E101A)	100µF,:20%,25V	

Parts List: A7, REF OSC

CKT REF	DESCRIPTION	RATING	NOTE
C 61 C 62 C 63 C 64	Elect, (CE04C1E101A) Elect, (CE04C1E101A) Elect, (CE04C1E101A) Elect, (CE04C1E101A)	100µF,±20%,25V 100µF,±20%,25V 100µF,±20%,25V 100µF,±20%,25V	
J 1	Connector, (U-SA2201)		
L 1 L 2 L 3 L 4 L 5	Coil, (LF8-220K) Coil, (NL453232-1R0K) Coil, (10K17-85T) Not assigned Coil, (NL453232-100K) Coil, (NL453232-220K) Coil, (NL453232-2100K)	22uH 1uH 0.36uH 10uH 22uH	
Q 1 Q 2 Q 3	IC, (7400) Di, (158123(A7)) Tr, (28C3735(B34 OR B35)) Tr, (28C3635(B34 OR B35))		
Q 5 Q 6 Q 7 Q 8	Di,(155123(A7)) Di,(155123(A7)) Di,(152835(A3)) Di,breakdown, (RD2.7MB(27))	2.5 to 2.9V,200mW	
Q 9 Q 10 Q 11 Q 12 Q 13	IC, (µPC4570C) Di, (1SS123(A7)) Tr, (2SC1623(L5 OR L6)) Di,vari-cap,(1SV50) Tr, (2SC2351(R2 OR R3))		
Q 14 Q 15 Q 16 Q 17	Tr,(2SC2351(R2 OR R3)) Tr, (2SA811A(C16 OR C17)) Di,(1SS123(A7)) Di,breakdown, (RD9.1MB2(912))	8.8 to 9.3V,200mW	
Q 18 Q 19 Q 20 Q 21	Not assigned Tr, (2SA1462(Y33 OR Y34)) IC,(74F175PC) IC,(74F02PC)		
Q 22 Q 23	IC,(74390) Tr, (2SC3735(B34 OR B35))		

( ): Manufacturer's part number
\* : Selected at factory

34W93322 1/5

( ): Manufacturer's part number

\* : Selected at factory

34W93322 2/5

CKT	DESCRIPTION	RATING	NOTE
REF	DESCRIPTION	RATING	NOTE
Q 24 Q 25 Q 26 Q 27	Tr, (2SC3735(B34 OR B35)) Tr,(2SC2351(R2 OR R3)) Not assigned Di,breakdown, (RD5.1MB2(512))	4.97 to 5.24V,200mW	
Q 28 Q 29 Q 30 Q 31	Tr,(2SC2351(R2 OR R3)) Di,breakdown, (RD5.1MB2(512)) Tr,(2SC2351(R2 OR R3)) Di,breakdown,	4.97 to 5.24V,200mW	
Q 32 Q 33 Q 34 Q 35	(RD5.1MB2(512))  Tr,(2SC2351(R2 OR R3)) Di,breakdown, (RD5.1MB2(512))  Tr,(2SC2351(R2 OR R3)) IC,(µPC14305H)	4.97 to 5.24V,200mW	
Q 36  R 1 R 2 R 3	IC, (µPC14305H)  CM, (RM73B2B102JD)  CM, (RM73B2B103JD)  CM, (RM73B2B332JD)	1.0ku,:5%,1/8W 10ku,:5%,1/8W 3.3ku,:5%,1/8W	
R 4 R 5 R 6 R 7 R 8 R 9 R 10	CM, (RM73B2B222JD) CM, (RM73B2B22JD) CM, (RM73B2B22JD) CM, (RM73B2B60JD) CM, (RM73B2B60JD) CM, (RM73B2B60JD) CM, (RM73B2B172JD) CM, (RM73B2B172JD)	2.2k0,25%,1/8W 2200,45%,1/8W 1.0k0,25%,1/8W 6000,25%,1/8W 6000,45%,1/8W 1.5k0,25%,1/8W	
R 11 R 12 R 13 R 14 R 15	Not assigned CM, (RM73B2B122JD) CM, (RM73B2B222JD) CM, (RM73B2B222JD) CM, (RM73B2B103JD)	1.2kû,:5%,1/8W 2.2kû,:5%,1/8W 2.2kû,:5%,1/8W 10kû,:5%,1/8W	
R 16 R 17 R 18 R 19 R 20	CM, (RM73B2B223JD) CM, (RM73B2B222JD) Not assigned CM, (RM73B2B102JD) MF, (RN14K2E6041D)	22kΩ,:5%,1/8W 2.2kΩ,:5%,1/8W 1.0kΩ,:5%,1/8W 6.04kΩ,:0.5%,1/4W	
R 21 R 22 R 23 R 24 R 25	MF, (RN14K2E1001D) CM, (RM73B2B103JD) CM, (RM73B2B103JD) CM, (RM73B2B102JD) CM, (RM73B2B102JD) CM, (RM73B2B331JD)	1.00kn,±0.5%,1/4W 10kn,±5%,1/8W 10kn,±5%,1/8W 1.0kn,±5%,1/8W 330n,±5%,1/8W	
R 26 R 27	CM, (RM73B2B332JD) CM, (RM73B2B392JD)	3.3kΩ,±5%,1/8W 3.9kΩ,±5%,1/8W	

REF	DESCRIPTION	RATING	NOTE
R 28	CM, (RM73B2B391JD)	390Ω,±5%,1/BW	1
R 29	CM, (RM73B2B391JD)	390Ω,±5%,1/8W	
R 30	Var,MF, (RJ-6S 5KΩ)	5kΩ,1/2₩	
R 31	CM, (RM73B2B101JD)	100Ω,±5%,1/8W	
R 32	CM, (RM73B2B222JD)	2.2kΩ,±5%,1/8W	
R 33	CM, (RM73B2B822JD)	8.2kΩ,±5%,1/8W	
R 34	CM, (RM73B2B181JD)	180Ω,±5%,1/8W	- 1
R 35	CM, (RM73B2B471JD)	470Ω,±5%,1/BW	
R 36	CM, (RM73B2B151JD)	150Ω,±5%,1/8W	
R 37	CM, (RM73B2B332JD)	3.3kn,±5%,1/8W	
R 38	CM, (RM73B2B221JD)	220Ω,±5%,1/8W	
R 39	CM, (RM73B2B102JD)	1.0kΩ,±5%,1/8W	1
R 40	CM, (RM73B2B181JD)	180Ω,±5%,1/8W	
R 41	CM, (RM73B2B181JD)	180Ω,:5%,1/8W	
R 42	CM, (RM73B2B182JD)	1.8kû,±5%,1/8W	
R 43	CM, (RM73B2B271JD)	270Ω,±5%,1/8W	
R 44	CM, (RM73B2B271JD)	270Ω,±5%,1/8W	
R 45	Not assigned	· ·	
R 46	CM, (RM73B2B122JD)	1.2kΩ,±5%,1/8W	
R 47	CM, (RM73B2B222JD)	2.2kΩ,±5%,1/BW	
R 48	CM, (RM73B2B601JD)	600Ω,±5%,1/8W	
R 49	CM, (RM73B2B222JD)	2.2kn,±5%,1/8w	
R 50	CM, (RM73B2B470JD)	47Ω,±5%,1/8W	
R 51	CM, (RM73B2B181JD)	1800,±5%,1/8W	
R 52	CM, (RM73B2B471JD)	470Ω,±5%,1/8W	
R 53	CM, (RM73B2B561JD)	560Ω,±5%,1/8W	
R 54	CM, (RM73B2B101JD)	100Ω,±5%,1/8W	
R 55	CM, (RM73B2B511JD)	510Ω,±5%,1/8W	
R 56	CM, (RM73B2B470JD)	47Ω,±5%,1/8W	
R 57	CM, (RM73B2B471JD)	470Ω,±5%,1/8W	
R 58	CM, (RM73B2B561JD)	560Ω,±5%,1/BW	
R 59	CM, (RM73B2B101JD)	100Ω,±5%,1/8W	
R 60	CM, (RM73B2B511JD)	,510Ω,±5%,1/8W	
R 61	CM, (RM73B2B470JD)	47Ω,±5%,1/8W	
R 62	CM, (RM73B2B471JD)	470Ω, ±5%, 1/8W	
R 63	CM, (RM73B2B561JD)	5600,±5%,1/8W	
R 64	CM, (RM73B2B101JD)	100Ω, ±5%, 1/8W	
R 65	CM, (RM73B2B511JD)	5100,:5%,1/8W	
R 66	CM, (RM73B2B470JD)	47Ω,±5%,1/8W	
R 67	CM, (RM73B2B471JD)	470Ω,±5%,1/8W	İ
R 68	Cm, (RM73B2B561JD)	560Ω,±5%,1/8W	
R 69	CM, (RM73B2B101JD)	100Ω,±5%,1/8₩	
R 70	CM, (RM73B2B511JD)	5100,±5%,1/8W	
R 71	CM, (RM73B2B470JD)	47Ω,±5%,1/8W	
т 1	Trans, (342T55677H)		

\* : Selected at factory

34W93322 3/5

( ): Manufacturer's part number

Parts List: A8, MAIN CPU

\* : Selected at factory

34W93322 4/5

	Parts List: A7, REF OSC			
CKT REF	DESCRIPTION	RATING	NOTE	
X 1	XTAL, (34X92451)	50MHz		
Z 1	XTAL OSC, (NSA0149B)	10MHz		
			·	
			i	

CKT REF DESCRIPTION RATING NOTE Elect, (SRC10VB-47M) Cer, (CK924F1H104Z) Elect, (CE04C1H220A) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z) 47μF,±20%,50V 0.1μF,+80/-20%,50V 22μF,±20%,50V 0.1μF,+80/-20%,50V 0.1μF,+80/-20%,50V C 1 C 2 C 3 C 4 C 5 C 6 C 7 to C 22 Not assigned Cer, (CK924F1H104Z) 0.1µF,+80/-20%,50V Connector, (DIN41612-96PC) Connector,(U-SA2201) Connector, (008261-033311-852) J 1 96pins 22pins 3pins J 2 J 3 J 4 Connector, (008261-024200-870) Connector, (008261-033311-852) Connector, (008261-024200-870) J 5 3pins J 6 2pins IC, (TC55257APL-12) Not assigned IC, (74HCT245) IC, (74HCT541) IC, (74HCT541) aasaa Not assigned IC,(74HC74) IC,(TC55257APL-12) IC,(74HCT245) IC,(74HCT541) Q 6 Q 7 Q 8 Q 9 Q 10 Q 11 Q 12 Q 13 Q 14 Q 15 IC, (74HC08)
IC, (74HC32)
IC, (74HC138)
IC, (DQ2816A250)
IC, (HD68000P8) With socket IC, (µPD43257AC-15L)
IC, (µPD43257AC-15L)
IC, (µPD71054C)
IC, (µPD27C512D-20)
IC, (µPD27C512D-20) Q 16 Q 17 Q 18 Q 19 Q 20 With socket With socket Q 21 IC, (74HCT138) Q 22 IC, (74HC08) Q 23 IC, (MC1-8501)

( ): Manufacturer's part number \* : Selected at factory

34W93322 5/5

( ): Manufacturer's part number

\* : Selected at factory

34W93323 1/2

Parts List: A8, MAIN CPU

CVA			
CKT REF	DESCRIPTION	RATING	NOTE
Q 24 Q 25 Q 26 Q 27 Q 28	IC, (wPD27C512D-20) IC, (wPD27C512D-20) IC, (74HC161) IC, (74HC10) Di, (18953)		With socket With socket
Q 29 Q 30 Q 31 Q 32 Q 33	Di,(1S953) Not assigned IC,(74HCT245) IC,(74HC365) IC,(74HC154)		
Q 34 Q 35 Q 36	IC, (74HC138) 1C, (74HC365) IC, (74HC32)		
R 1 R 2 R 3 R 4 R 5	SIL type,(RRS-8-472JA) SIL type,(RRS-8-222JA) SIL type,(RRS-8-472JA) SIL type,(RRS-8-222JA) SIL type,(RRS-8-472JA)	4.7kΩ x 8,±5%,1/8W 2.2kΩ x 8,±5%,1/8W 4.7kΩ x 8,±5%,1/8W 2.2kΩ x 8,±5%,1/8W 4.7kΩ x 8,±5%,1/8W	
R 6 R 7 R 8 R 9 R 10	SIL type,(RRS-8-222JA) SIL type,(RRS-8-222JA) SIL type,(RRS-8-472JA) SIL type,(RRS-8-472JA) SIL type,(RRS-8-222JA)	2.2k\(\Omega \times 8,\frac{1}{2}\)8\(\Width\)2.2k\(\Omega \times 8,\frac{1}{2}\)8\(\Width\)4.7k\(\Omega \times 8,\frac{1}{2}\)8\(\Width\)4.7k\(\Omega \times 8,\frac{1}{2}\)8\(\Width\)2.2k\(\Omega \times 8,\frac{1}{2}\)8\(\Width\)	
R 11 R 12 R 13 R 14 R 15	SIL type,(RRS-8-103JA) CF,(ARD25T103J) CF,(ARD25T103J) CF,(ARD25T103J) CF,(ARD25T103J)	10kΩ x 8,±5%,1/8W 10kΩ,±5%,1/4W 10kΩ,±5%,1/4W 10kΩ,±5%,1/4W 10kΩ,±5%,1/4W	
R 16 R 17 R 18 R 19 R 20	CF, (ARD25T103J) CF, (ARD25T103J) Not assigned CF, (ARD25T103J) SIL type, (RRS-8-472JA)	10kΩ,±5%,1/4W 10kΩ,±5%,1/4W 10kΩ,±5%,1/4W 4.7kΩ x 8,±5%,1/8W	
R 21 R 22 R 23	SIL type,(RRS-4-472JA) CF,(ARD25T103J) CF,(ARD25T103J)	4.7kΩ x 4,±5%,1/8W 10kΩ,±5%,1/4W 10kΩ,±5%,1/4W	
Z 1 Z 2	Not assigned XTAL OSC, (EX0-3C-16MHZ)		

DESCRIPTION RATING NOTE REF 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 47µF,±20%,50V Cer, (CK924F1H1042) Cer, (CK924F1H1042) Cer, (CK924F1H1042) Elect, (SRC10VB-47M) Connector, (U-PA2219) Connector, (CNF)-26P-2.54DS) Connector, (008261-033311-852) J 1 J 2 22pins 26pins J 3 J 4 Connector, (008261-024200-870) 1 2 3 4 5 IC, (µPD7210C)
IC, (SN75160AN)
IC, (SN75162AN)
IC, (74HC02)
IC, (74HC74) 10kΩ,±5%,1/4W 10kΩ,±5%,1/4W 1kΩ,±5%,1/4W 1 2 3 Z 1 Lithium battery, (BR3032-1GFR)

Parts List: A9. GP-IB

( ): Manufacturer's part number

: Selected at factory

34W93323 2/2

CKT REF

( ): Manufacturer's part number \* : Selected at factory

RATING

34W93324 1/1

NOTE

Parts List: AlO, DISP CPU

DESCRIPTION

Parts Li	st: AlO, DISP CPU	. 23
DESCRIPTION	RATING	NOTE
Cer, (CK924F1H1042) Cer, (SRC10VB-220M) Cer, (CK924C1H103M) Cer, (CK924F1H1042) Elect, (SRC10VB-47M) Cer, (CC924CH1H3131) Cer, (CK924F1H1042) Cer, (CK924F1H1042) Cer, (CC924CH1H360J) Cer, (CC924CH1H360J)	0.1µF,+80/-20%,50V 220µF,:20%,50V 0.1µF,+80/-20%,50V 47µF,:20%,50V 330F,:5%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 36PF,:5%,50V 36PF,:5%,50V	
Connector, (DIN41612-96PC) Connector, (008261-03-3311-852) Connector, (008261-024200-870) Connector, (008261-033311-852) Connector, (008261-033311-852)	96pins 3pins 2pins 3pins 2pins	
IC, (MC1-8501) Not assigned Not assigned IC, (H063484P8) IC, (74HCT373)		
IC, (74HCT373) IC, (HD6800DP8) IC, (SN74AL574AN) IC, (PAL10L8A2NCSPA-1) IC, (74HCT245)		With socket
IC, (TC55257APL-12) IC, (74HC74) IC, (SN74ALS10N) IC, (74HC04) IC, (74HC04)		
IC, (HM6264ALP-I5) IC, (HM6264ALP-I5) IC, (74HC08) IC, (74I28) IC, (74HCT245)		
	DESCRIPTION  Cer, (CK924F1H1042) Cer, (SRC10VB-220M) Cer, (CK924C1H103M) Cer, (CK924C1H1042) Elect, (SRC10VB-47M) Cer, (CC924CH1H331J) Cer, (CC924CH1H360J) Cer, (CC924CH1H360J) Cer, (CC924CH1H360J) Connector, (DN41612-96PC) Connector, (008261-03-3311-852) Connector, (008261-03-3311-852) Connector, (008261-024200-870)  Connector, (008261-024200-870)	Cer, (CK924F1H104Z)  Cer, (SRC10VB-220M) Cer, (CK924C1H103M) Cer, (CK924C1H103M) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z) Cer, (CC924CH1H36J) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z) Cer, (CK924CH1H36OJ) Cer, (CC924CH1H36OJ)

34W93325 1/3

IC, (TC55257APL-12)
IC, (74HC32)
IC, (PAL14L4A2NCSPA-2)
IC, (74HCT245)
IC, (µPD27C512D-20) Q 21 Q 22 Q 23 Q 24 Q 25 With socket IC, (74HCT245)
IC, (74HCT541)
IC, (74HCT138)
IC, (74HC166)
IC, (TC55257APL-12) Q 26 Q 27 Q 28 Q 29 Q 30 Q 31 Q 32 Q 33 Q 34 Q 35 IC, (74HCT245)
IC, (74HCT541)
IC, (74HCT541)
IC, (74HC166)
IC, (µPD27C512D-20) With socker IC, (TC55257APL-12)
IC, (74HC166)
IC, (74HC166)
IC, (74O7)
IC, (74O9) Q 36 Q 37 Q 38 Q 39 Q 40 Q 41 Q 42 Q 43 Tr,(2SC2718)
IC,(SN74HC14N)
IC,(74HC74) SIL type,(RRS-4-103JA) SIL type,(RRS-8-103JA) Not assigned Not assigned CF,(ARD25T103J) 10kΩ x 4,±5%,1/8W 10kΩ x 8,±5%,1/8W 10kΩ, ±5%, 1/4W R 6 R 7 R 8 R 9 R 10 Not assigned CF, (ARD25T103J) CF, (ARD25T103J) CF, (ARD25T15IJ) CF, (ARD25T221J) 10kΩ,±5%,1/4W 10kΩ,±5%,1/4W 150Ω,±5%,1/4W 220Ω,±5%,1/4W CF, (ARD25T561J) CF, (ARD25T391J) CF, (ARD25T330J) CF, (ARD25T101J) CF, (ARD25T221J) 560Ω,±5%,1/4W 390Ω,±5%,1/4W 33Ω,±5%,1/4W 100Ω,±5%,1/4W 220Ω,±5%,1/4W R 11 R 12 R 13 R 14 R 15 Not assigned CF, (ARD25T221J) Not assigned CF, (ARD25T22IJ) CF, (ARD25T103J) R 16 R 17 R 18 R 19 R 20

220Ω,±5%,1/4W 220Ω,±5%,1/4W 10kΩ,±5%,1/4W

( ): Manufacturer's part number

34W93325 2/3

( ): Manufacturer's part number \* : Selected at factory

\* : Selected at factory

Parts List: A10, DISP CPU

PARTS LIST: ALU, DISP CPU				
CKT REF	DESCRIPTION	RATING	NOTE	
R 23 R 24	CF, (ARD25T391J) CF, (ARD25T121J)	390Ω,±5%,1/4W 120Ω,±5%,1/4W		
Z 1 2 2	XTAL OSC, (EX0-3C-16MHZ) XTAL OSC, (EX0-3C-12.8MHZ)			

Parts List: Al3, MAIN MOTHER BOARD

			24
CKT REF	DESCRIPTION	RATING	NOTE
C 1 C 2 C 3 C 4 C 5	Cer, (CK733P1H104Z(A5)) Cer, (CK733F1H104Z(A5)) Cer, (CK733F1H104Z(A5)) Cer, (CK733F1H104Z(A5)) Cer, (CK733F1H104Z(A5))	0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V	
C 6 C 7 C 8 C 9 C 10	Cer, (CK733F1H104Z(A5)) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z)	0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V	
C 11 C 12 C 13 C 14	Cer, (CK924F1H104Z) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z)	0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V	
J 1	Connector, (DIN41612-64SB)		
J 2	Connector, (DIN41612-64SB)		1
J 3	Connector, (DIN41612-64SB)		
J 4	Connector, (DIN41612-96SC)		
J 5	Connector, (DIN41612-96SC)		
J 6	Connector, (DIN41612-96SC)	1	
J 7	Connector, (DIN41612-6450)		
J 8	Connector, (DIN41612-44SB)		1
J 9	Connector, (U-PA2221)		
J 10 J 11	Not assigned Connector, (DP1-10P2.5DSA)		
W 1	Cable, (34J95168)		

( ): Manufacturer's part number
\* : Selected at factory

34W93325 3/3

( ): Manufacturer's part number
\* : Selected at factory

34W93326 1/1

26

REF Connector, (DIN41612-64PB) J 2 Connector, (U-SA1501) J 3 Connector, (U-SA1501) J 4 Connector, (U-SA1501) J 5 Connector, (U-SA1501)  J 5 Connector, (BC1R) Connector, (DF1-282.5R24) Q 1 Di,(1S953)  R 1 CF,(ARD25T103J) 10kG,:58,1/4W	
J 2 Connector, (U-SAI501) J 3 Connector, (U-SAI501) J 4 Connector, (U-SAI501) J 5 Connector, (U-SAI501) J 6 Connector, (BCIR) GF1-282.5R24) Q 1 Di, (1S953)	
J 4 Connector, (U-SA1501)  J 5 Connector, (BC1R)  J 6 Connector, (DF1-282.5R24)  J Di, (18953)	
J 5 Connector, (BC1R) J 6 Connector, (DF1-282.5R24) Q 1 Di,(18953)	
G Connector, (DF1-282.5R24)  G 1 Di,(18953)	
(DF1-282.5R24) g 1 Di. (18953)	
R 1 CF, (ARD25T103J) . 10kΩ,±5%,1/4W	
·	
i	
:	

Parts List: Al5, LED

CKT REF	DESCRIPTION	RATING	NOTE
0 1 to 0 11 0 12	Not assigned		
Q 12	LED, (LN342GPH)		
l I			
	0.1		

( ): Manufacturer's part number

\* : Selected at factory

34W93327 1/1

( ): Manufacturer's part number

\* : Selected at factory

34W93349 1/1

Dante	1	7.4	DECUI	A TOD

	Parts L	27	
CKT REF	DESCRIPTION	RATING	NOTE
C 1	Cer, (ECK-D2H103PE)	0.01µF,+100/-0%,500V	
C 2	Cer, (ECK-D2H103PE)	0.01µF,+100/-0%,500V	
C 3	Elect, (KME63VB-1000(M))	1000µF,:20%,63V	
C 4	Elect, (KME63VB-1000(M))	1000µF,:20%,63V	
C 5	Elect, (KME63VB-1000(M))	1000µF,:20%,63V	
C 6	Elect, (KME63VB-1000 (M))	1000µF, ±20%, 63V	
C 7	Elect, (KME63VB-1000 (M))	1000µF, ±20%, 63V	
C 8	Elect, (KME63VB-1000 (M))	1000µF, ±20%, 63V	
C 9	Elect, (KME63VB-1000 (M))	1000µF, ±20%, 63V	
C 10	Elect, (KME63VB-1000 (M))	1000µF, ±20%, 63V	
C 11 C 12 C 13 C 14 C 15	Not assigned Elect, (KME63VB-220 (M)) Elect, (KME63VB-220 (M)) Cer, (ECK-D2H151KB2) Elect, (KME25VB-2200 (M))	220µF,±20%,63V 220µF,±20%,63V 150pF,±10%,500V 2200µF,±20%,25V	
C 16	Elect, (KME25VB-220 (M))	220µF,:20%,25V	
C 17	Elect, (KME25VB-100 (M))	100µF,:20%,25V	
C 18	Elect, (KME25VB-100 (M))	100µF,:20%,25V	
C 19	Elect, (KME25VB-100 (M))	100µF,:20%,25V	
C 20	Cer, (ECK-D2H331KB2)	330pF,:10%,500V	
C 21 C 22 C 23 C 24	Elect, (KME6.3VB-4700(M)) Elect,(KME6.3VB-470(M)) Cer,(ECK-D2H101KB2) Elect,(KME50VB-4.7(M))	4700µF,±20%,6.3V 470µF,±20%,6.3V 100pF,±10%,500V 4.7µF,±20%,50V	
C 25	Elect, (KME25VB-2200 (M))	2200µF, ±20%, 25V	
C 26	Elect, (KME25VB-220 (M))	220µF, ±20%, 25V	
C 27	Elect, (KME25VB-100 (M))	100µF, ±20%, 25V	
C 28	Elect, (KME25VB-100 (M))	100µF, ±20%, 25V	
C 29	Elect, (KME25VB-100 (M))	100µF, ±20%, 25V	
C 30	Cer, (ECK-D2H222KB2)	2200pF,:10%,500V	
C 31	Elect, (KME25VB-100(M))	100µF,:20%,25V	
C 32	Elect, (KME25VB-100(M))	100µF,:20%,25V	
C 33	Elect, (KME25VB-47(M))	47µF,:20%,25V	
C 34	Elect, (KME25VB-47(M))	47µF,:20%,25V	
C 35	Elect, (KME50VB-2.2(M))	2.2µF,+20%,50V	
C 36	Elect, (KME25VB-47(M))	47µF,+20%,25V	
C 37	Elect, (KME63VB-220(M))	220µF,+20%,63V	
C 38	Plast, (MDD21J104K)	0.1µF,+10%,63V	
C 39	Plast, (MDD21J104K)	0.1µF,+10%,63V	
C 40	Elect,(KME63VB-10(M))	10μF, ±20%,63V	
J 1	Connector, (DF1-8P-2.5DS) Connector, (DF1-10P-2.5DS)		

Parts List: 24 REGULATOR

22-49A36 1/4

( ): Manufacturer's part number \* : Selected at factory

DESCRIPTION

22-49A36 2/4

Parts List: Z4 REGULATOR

RATING

Parts List: 24 REGULATOR

RATING

NOTE

CKT REF

DESCRIPTION

Connector, (DF1-10P-2.5DS) Connector,(XC5A-4422)

K 1 Relay, (HC4-P-DC24V)

L 1 Choke coil, (HP-034) L 2 Choke coil, (SF-T10-50) L 3 Choke coil, (HP-023) L 4 Choke coil, (SF-T10-50) L 5 Choke coil, (HP-034)

L 6 Choke coil, (SF-T10-50) Choke coil, (TSL0707-101KR66)

F 1 Fuse, (MF51NN250V3.15ADC01)
F 2 Fuse, (MF51NN250V1.6ADC01)
F 3 Fuse, (MF51NN250V1.6ADC01)
Fuse, (MF51NN250V1.6ADC01)

Q 1 Di,(W06C) Q 2 Rectifier,(RBV602) Q 3 Di,(W06C) Q 4 Rectifier,(RBV402) Q 5 IC,(STR7002)

Q 6 Di,(W06C) Q 7 IC,(SI-3122V) Q 8 Di,(W06C) Q 9 IC,(SI-3122V) Q 10 Di,(W06C)

Q 11 IC, (SI-3122V) Q 12 IC, (SI-8053B) Q 13 IC, (SI-8123B) Q 14 Tr, (2SC945) Q 15 Tr, (2SA733)

Q 16 Di, (W06C) Q 17 Di, (W06C) Q 18 IC, (SI-3122V)

CKT REF

M 1 Timer, (TM-O)

СКТ	DESCRIPTION	RATING	NOTE
REF		-	
Q 19 Q 20 Q 21 Q 22 Q 23	Di,(W06C) IC,(SI-3122V) Tr,(2SC3074) Tr,(2SC3074) Di,(1S954)		
Q 24 Q 25 Q 26 Q 27 Q 28	D1,(10DF1) D1,(10DF1) D1,(10DF1) D1,(10DF1) IC,(µPC78N15H)		
Q 29 Q 30 Q 31 Q 32 Q 33	IC, (µPC79N15H) D1, (1S954) D1, (1S954) D1, (1S954) D1, (1S954) D1, (1S954)	8.5 to 9.6V,400mW	
Q 34 Q 35 Q 36 Q 37 Q 38	IC, (TC4093BP) D1, (1S955) D1, (1S955) D1, (1S955) IC, (SI-8021) D1, (1SS99)		
R 1 R 2 R 3 R 4 R 5	CF, (RD25S10KRJ) CF, (RD25S1KRJ) CF, (RD25S1KRJ) CF, (RD25S1KRJ) CF, (RD25S1KRJ) CF, (RD25S3.3KRJ) CF, (RD25S3.3KRJ) Manganin wire	10kΩ,:58,1/4W 1kΩ,:58,1/4W 1kΩ,:58,1/4W 1kΩ,:58,1/4W 3.3kΩ,:58,1/4W 470Ω to 1.2kΩ,:58, 1/4W 470Ω to 30mΩ	* 750Ω 0.75¢
R 8	CF, (RD25S * J)	100 to 470kΩ,±5%,	Approx. 30mm * 390kΩ
R 9 R 10	CF, (RD25S * J) CF, (RD25S * J)	1/4W 470Ω to 1.2kΩ,±5%, 1/4W 100 to 470kΩ,±5%, 1/4W	* 1kΩ * 390kΩ
R 11 R 12 R 13 R 14 R 15	CF, (RD25S1KΩJ) CF, (RD25S51ΩJ) MF, (RSF1B0.51ΩJ) MF, (RSF1B0.51ΩJ) CF, (RD25S * J)	1/4W 1kΩ,±5%,1/4W 51Ω,±5%,1/4W 0.51Ω,±5%,1W 0.51Ω,±5%,1W 22ΩΩ to 1kΩ,±5%,1/4W	* 390Ω
R 16 R 17 R 18 R 19 R 20	CF, (RD25S100RJ) CF, (RD25S5.6KRJ) CF, (RD25S * J) CF, (RD25S ZKRJ) CF, (RD25SZKRJ)	100Ω,±5%,1/4W 5.6kΩ,±5%,1/4W 220Ω to 1kΩ,±5%,1/4W 2kΩ,±5%,1/4W 2kΩ,±5%,1/4W	• 390Ω

( ); Manufacturer's part number

\* ; Selected at factory

22-49A36 3/4

8.2kΩ,:5%,1/4W 1.8kΩ,:5%,1/4W 1kΩ,1/2W 1kΩ,:5%,1/4W 10kΩ,:5%,1/4W		
		22-49A49
	1.8kΩ,±5%,1/4W 1kΩ,1/2W 1kΩ,±5%,1/4W	1.8kΩ,±5%,1/4W 1kΩ,1/2W 1kΩ,±5%,1/4W

( ): Manufacturer's part number

\* : Selected at factory

22-49A36 4/4

Parts List: A16 FILTER

CKT REF DESCRIPTION RATING NOTE Z 1 Filter, (DSS310-55D223S)
Z 2 Filter, (DSS310-55D223S)
Z 3 Filter, (DSS310-55D223S)

Parts List: A4 PTA (OPTION 01)

			K	29
CKT REF	DESCRIPTION	R AT1NG	NOTE	
C 1 C 2 C 3 C 4 C 5	Cer, (CC924CH1H681J) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z)	680pF, ±5%, 50V 0.1µF, +80/-20%, 50V 0.1µF, +80/-20%, 50V 0.1µF, +80/-20%, 50V 0.1µF, +80/-20%, 50V		
C 6 C 7 C 8 C 9 C 10	Cer, (CK924F1H104Z) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z)	0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V		
C 11 C 12 C 13 C 14 C 15	Cer, (CK924F1H104Z) Elect, (CE04C1H220A) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z)	0.1µF,+80/-20%,50V 22µF,±20%,50V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V		
to C 50	Cer,(CK733F1H104Z)	0.1µF,+80/-20%,50V		
J 1 J 2 J 3	Connector, (DIN41612-96PC) Not assigned Connector,	40pins		
J 4	(HIF3BAG-40PA-2.54DS) Connector,		,	
J 5	(DF1-5P-2.5DS) Receptacle, (008261-033311-852)	3pins		
J 6	Receptacle, (008261-024200-870)	2pins		
L 1	Noise filter,(D20C)			
Q 1 Q 2 Q 3 Q 4 Q 5	IC, (MC68881 RC12B) IC, (MC1-8501) IC, (µPD71051C) IC, (µPD71054C) IC, (HD68000P8)		With socke	
Q 6 Q 7 Q 8 Q 9	IC, (HM66204L-12) IC, (HN27C101G-25) IC, (HM66204L-12) IC, (RTC-62421B)		With sock	et
Q 10 Q 11 Q 12 Q 13	Di, (18953) Di, (18953) Di, (18953) Di, (18953)		WILL SOCK	ec

( ): Manufacturer's part number

\* : Selected at factory

34W95267 1/1

NOTE

( ): Manufacturer's part number \* : Selected at factory

34W94043 1/3

Parts List: A4 PTA (OPTION 01)

DESCRIPTION RATING

Q 15 Q 16 Q 17	IC, (74HC74F) IC, (SN74LS14NS) IC, (SN74LS374NS) IC, (SN74LS374NS) IC, (SN74LS374NS) IC, (SN74LS244NS)			
Q 20 Q 21 Q 22	IC, (SN74LS244NS) IC, (TC74HCT138F) IC, (74HC74F) IC, (SN74ALS08NS) IC, (SN74ALS08NS)			
Q 25 Q 26 Q 27	IC, (74HC21F) IC, (TC74HCT138F) IC, (SN74ALS04ANS) IC, (TC74HCT138F) IC, (TC74HCT138F)			
Q 30	IC, (SN74HCT541NS) IC, (SN74HCT541NS) IC, (SN74HCT541NS) IC, (74HC74F) IC, (74HC74F)			
Q 35	IC, (74HC175F) IC, (74HC32F) IC, (SN74HCT541NS) IC, (74HC04F) IC, (SN74HCT541NS)	·		
Q 39 Q 40 Q 41 Q 42 Q 43	IC, (SN74HCT541NS) IC, (TC74HCT245F) IC, (TC74HCT138F) IC, (SN74HCT541NS) IC, (SN74HCT541NS)			
Q 44 Q 45 Q 46 Q 47 Q 48	IC, (TC74HCT245F) IC, (TC74HCT245F) IC, (74HC74F) IC, (74HC10F) IC, (74HC74F)			
Q 49 Q 50 Q 51	IC, (TC74HCT245F) IC, (74HC74F) IC, (74HC00F)			
R 1 R 2 R 3 R 4 R 5	CF, (ARD25T223J) SIP type, (RRS-8-103JA) SIP type, (RRS-4-103JA) SIP type, (RRS-8-103JA) CF, (ARD25T103J)	22kΩ,±5%,1/4W 10kΩ x 8,±5%,1/8W 10kΩ x 4,±5%,1/8W 10kΩ x 8,±5%,1/8W 10kΩ,±5%,1/4W		
ء ۽ ا		1010 . 50 1/45	1	1

Parts List: A4 PTA (OPTION 04)

CKT REF	DESCRIPTION	RATING	NOTE
R 8 R 9 R 10 R 11	CF, (ARD25T102J) CF, (ARD25T103J) CF, (ARD25T103J) CF, (ARD25T103J)	1kΩ,±5%,1/4W 10kΩ,±5%,1/4W 10kΩ,±5%,1/4W 10kΩ,±5%,1/4W	
2 1 2 2 2 3 2 4 2 5	Filter, (DSS310-55D223S) Filter, (DSS310-55D223S) Filter, (DSS310-55D223S) XTAL OSC, (EXO-3C(16MH2)) Battery, (BR2330-1HF)	3.6V	
Z 6	Battery,(BR2330-1HF)	3.6V	
	•		

( ): Manufacturer's part number

10kΩ,±5%,1/4W 1kΩ,±5%,1/4W

. Selected at factory

R 6 CF, (ARD25T103J) R 7 CF, (ARD25T102J)

34₩94043 2/3

( ): Manufacturer's part number

\* : Selected at factory

34W94043 3/3

Parts List: All RS-232C (OPTION 02)

			30
CKT REF	DESCRIPTION	RATING	NOTE
C 1 C 2 C 3 C 4 C 5	Elect, (SRC10VB-47M) Cer, (CK924F1H104Z) Cer, (CK924F1H104Z) Elect, (SRC16VB-10M) Elect, (SRC50VB-4.7M)	47µF,±20%,10V 0.1µF,+80/-20%,50V 0.1µF,+80/-20%,50V 10µF,±20%,16V 4.7µF,±20%,50V	
C 6 C 7 C 8	Elect, (SRC50VB-4.7M) Elect, (SRC16VB-10M) Cer, (CK924F1H104z)	4.7µF,±20%,50V 10µF,±20%,16V 0.1µF,+80/-20%,50V	
J 1 J 2 J 3	Connector, (U-PA2219) Connector, (CNF3-26P-2.54DS) Connector, (008261-033311-852)	22pins 26pins 3pins	
J 4	Connector, (008261-024200-870)	2pins	
Q 1 Q 2 Q 3 Q 4 Q 5	IC, (µPD71054C) IC, (µPD71051C) IC, (74HC365) IC, (74HC02) IC, (MAX238)		
R 1	Cf, (ARD25T102J)	1kΩ,±5%,1/4W	
z 1	Lithium battery, (BR3032-1GFR)		

34W94044 1/1

		•